



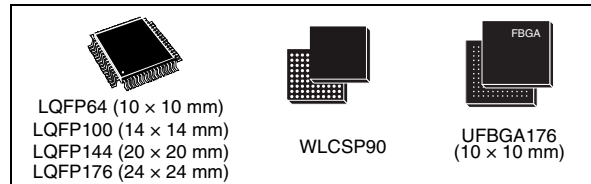
STM32F405xx STM32F407xx

ARM Cortex-M4 32b MCU+FPU, 210DMIPS, up to 1MB Flash/192+4KB RAM, USB OTG HS/FS, Ethernet, 17 TIMs, 3 ADCs, 15 comm. interfaces & camera

Datasheet – production data

Features

- Core: ARM 32-bit Cortex™-M4 CPU with FPU, Adaptive real-time accelerator (ART Accelerator™) allowing 0-wait state execution from Flash memory, frequency up to 168 MHz, memory protection unit, 210 DMIPS/1.25 DMIPS/MHz (Dhrystone 2.1), and DSP instructions
- Memories
 - Up to 1 Mbyte of Flash memory
 - Up to 192+4 Kbytes of SRAM including 64-Kbyte of CCM (core coupled memory) data RAM
 - Flexible static memory controller supporting Compact Flash, SRAM, PSRAM, NOR and NAND memories
- LCD parallel interface, 8080/6800 modes
- Clock, reset and supply management
 - 1.8 V to 3.6 V application supply and I/Os
 - POR, PDR, PVD and BOR
 - 4-to-26 MHz crystal oscillator
 - Internal 16 MHz factory-trimmed RC (1% accuracy)
 - 32 kHz oscillator for RTC with calibration
 - Internal 32 kHz RC with calibration
- Low power
 - Sleep, Stop and Standby modes
 - V_{BAT} supply for RTC, 20×32 bit backup registers + optional 4 KB backup SRAM
- 3×12-bit, 2.4 MSPS A/D converters: up to 24 channels and 7.2 MSPS in triple interleaved mode
- 2×12-bit D/A converters
- General-purpose DMA: 16-stream DMA controller with FIFOs and burst support
- Up to 17 timers: up to twelve 16-bit and two 32-bit timers up to 168 MHz, each with up to 4 IC/OC/PWM or pulse counter and quadrature (incremental) encoder input
- Debug mode
 - Serial wire debug (SWD) & JTAG interfaces
 - Cortex-M4 Embedded Trace Macrocell™



- Up to 140 I/O ports with interrupt capability
 - Up to 136 fast I/Os up to 84 MHz
 - Up to 138 5 V-tolerant I/Os
- Up to 15 communication interfaces
 - Up to 3 × I²C interfaces (SMBus/PMBus)
 - Up to 4 USARTs/2 UARTs (10.5 Mbit/s, ISO 7816 interface, LIN, IrDA, modem control)
 - Up to 3 SPIs (37.5 Mbits/s), 2 with muxed full-duplex I²S to achieve audio class accuracy via internal audio PLL or external clock
 - 2 × CAN interfaces (2.0B Active)
 - SDIO interface
- Advanced connectivity
 - USB 2.0 full-speed device/host/OTG controller with on-chip PHY
 - USB 2.0 high-speed/full-speed device/host/OTG controller with dedicated DMA, on-chip full-speed PHY and ULPI
 - 10/100 Ethernet MAC with dedicated DMA: supports IEEE 1588v2 hardware, MII/RMII
- 8- to 14-bit parallel camera interface up to 54 Mbytes/s
- True random number generator
- CRC calculation unit
- 96-bit unique ID
- RTC: subsecond accuracy, hardware calendar

Table 1. Device summary

| Reference | Part number |
|-------------|--|
| STM32F405xx | STM32F405RG, STM32F405VG, STM32F405ZG, STM32F405OG, STM32F405OE |
| STM32F407xx | STM32F407VG, STM32F407IG, STM32F407ZG, STM32F407VE, STM32F407ZE, STM32F407IE |

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1 Introduction

This datasheet provides the description of the STM32F405xx and STM32F407xx lines of microcontrollers. For more details on the whole STMicroelectronics STM32™ family, please refer to [Section 2.1: Full compatibility throughout the family](#).

The STM32F405xx and STM32F407xx datasheet should be read in conjunction with the STM32F4xx reference manual.

For information on programming, erasing and protection of the internal Flash memory, please refer to the STM32F4xx Flash programming manual (PM0081).

The reference and Flash programming manuals are both available from the STMicroelectronics website www.st.com.

For information on the Cortex™-M4 core please refer to the Cortex™-M4 Technical Reference Manual, available from the www.arm.com website at the following address: <http://infocenter.arm.com/help/index.jsp?topic=/com.arm.doc.ddi0439b/>.

2 Description

The STM32F405xx and STM32F407xx family is based on the high-performance ARM[®] Cortex™-M4 32-bit RISC core operating at a frequency of up to 168 MHz. The Cortex-M4 core features a Floating point unit (FPU) single precision which supports all ARM single-precision data-processing instructions and data types. It also implements a full set of DSP instructions and a memory protection unit (MPU) which enhances application security. The Cortex-M4 core with FPU will be referred to as Cortex-M4F throughout this document.

The STM32F405xx and STM32F407xx family incorporates high-speed embedded memories (Flash memory up to 1 Mbyte, up to 192 Kbytes of SRAM), up to 4 Kbytes of backup SRAM, and an extensive range of enhanced I/Os and peripherals connected to two APB buses, three AHB buses and a 32-bit multi-AHB bus matrix.

All devices offer three 12-bit ADCs, two DACs, a low-power RTC, twelve general-purpose 16-bit timers including two PWM timers for motor control, two general-purpose 32-bit timers, a true random number generator (RNG). They also feature standard and advanced communication interfaces.

- Up to three I²Cs
- Three SPIs, two I²Ss full duplex. To achieve audio class accuracy, the I²S peripherals can be clocked via a dedicated internal audio PLL or via an external clock to allow synchronization.
- Four USARTs plus two UARTs
- An USB OTG full-speed and a USB OTG high-speed with full-speed capability (with the ULPI),
- Two CANs
- An SDIO/MMC interface
- Ethernet and the camera interface available on STM32F407xx devices only.

New advanced peripherals include an SDIO, an enhanced flexible static memory control (FSMC) interface (for devices offered in packages of 100 pins and more), a camera interface for CMOS sensors. Refer to [Table 2: STM32F405xx and STM32F407xx: features and peripheral counts](#) for the list of peripherals available on each part number.

The STM32F405xx and STM32F407xx family operates in the –40 to +105 °C temperature range from a 1.8 to 3.6 V power supply. The supply voltage can drop to 1.7 V when the device operates in the 0 to 70 °C temperature range and an inverted reset signal is applied to PDR_ON. A comprehensive set of power-saving mode allows the design of low-power applications.

The STM32F405xx and STM32F407xx family offers devices in various packages ranging from 64 pins to 176 pins. The set of included peripherals changes with the device chosen.

These features make the STM32F405xx and STM32F407xx microcontroller family suitable for a wide range of applications:

- Motor drive and application control
- Medical equipment
- Industrial applications: PLC, inverters, circuit breakers
- Printers, and scanners
- Alarm systems, video intercom, and HVAC
- Home audio appliances



Figure 5 shows the general block diagram of the device family.

Table 2. STM32F405xx and STM32F407xx: features and peripheral counts

| Peripherals | | STM32F405RG | STM32F405OG | STM32F405VG | STM32F405ZG | STM32F405OE | STM32F407Vx | STM32F407Zx | STM32F407Ix | | | |
|--------------------------|------------------------|----------------------------------|--------------------|-------------|-------------|-------------|-------------|-------------|-------------|------|-----|------|
| Flash memory in Kbytes | | 1024 | | | | 512 | 512 | 1024 | 512 | 1024 | 512 | 1024 |
| SRAM in Kbytes | System | 192(112+16+64) | | | | | | | | | | |
| | Backup | 4 | | | | | | | | | | |
| FSMC memory controller | | No | Yes ⁽¹⁾ | | | | | | | | | |
| Ethernet | | No | | | | | Yes | | | | | |
| Timers | General-purpose | 10 | | | | | | | | | | |
| | Advanced-control | 2 | | | | | | | | | | |
| | Basic | 2 | | | | | | | | | | |
| | IWDG | Yes | | | | | | | | | | |
| | WWDG | Yes | | | | | | | | | | |
| | RTC | Yes | | | | | | | | | | |
| Random number generator | | Yes | | | | | | | | | | |
| Communication interfaces | SPI / I ² S | 3/2 (full duplex) ⁽²⁾ | | | | | | | | | | |
| | I ² C | 3 | | | | | | | | | | |
| | USART/UART | 4/2 | | | | | | | | | | |
| | USB OTG FS | Yes | | | | | | | | | | |
| | USB OTG HS | Yes | | | | | | | | | | |
| | CAN | 2 | | | | | | | | | | |
| | SDIO | Yes | | | | | | | | | | |
| Camera interface | | No | | | | | Yes | | | | | |
| GPIOs | | 51 | 72 | 82 | 114 | 72 | 82 | 114 | 140 | | | |
| 12-bit ADC | | 3 | | | | | | | | | | |
| Number of channels | | 16 | 13 | 16 | 24 | 13 | 16 | 24 | 24 | | | |
| 12-bit DAC | | Yes | | | | | | | | | | |
| Number of channels | | 2 | | | | | | | | | | |
| Maximum CPU frequency | | 168 MHz | | | | | | | | | | |

**Table 2. STM32F405xx and STM32F407xx: features and peripheral counts (continued)**

| Peripherals | STM32F405RG | STM32F405OG | STM32F405VG | STM32F405ZG | STM32F405OE | STM32F407Vx | STM32F407Zx | STM32F407Ix |
|------------------------|--|-------------|-------------|-------------|-------------|-------------|-------------|---------------------|
| Operating voltage | 1.8 to 3.6 V ⁽³⁾ | | | | | | | |
| Operating temperatures | Ambient temperatures: -40 to +85 °C / -40 to +105 °C | | | | | | | |
| | Junction temperature: -40 to + 125 °C | | | | | | | |
| Package | LQFP64 | WLCSP90 | LQFP100 | LQFP144 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 LQFP176 |

1. For the LQFP100 package, only FSMC Bank1 or Bank2 are available. Bank1 can only support a multiplexed NOR/PSRAM memory using the NE1 Chip Select. Bank2 can only support a 16- or 8-bit NAND Flash memory using the NCE2 Chip Select. The interrupt line cannot be used since Port G is not available in this package.
2. The SPI2 and SPI3 interfaces give the flexibility to work in an exclusive way in either the SPI mode or the I2S audio mode.
3. V_{DD}/V_{DDA} minimum value of 1.7 V is obtained when the device operates in the 0 to 70 °C temperature range and an inverted reset signal is applied to PDR_ON.

2.1 Full compatibility throughout the family

The STM32F405xx and STM32F407xx are part of the STM32F4 family. They are fully pin-to-pin, software and feature compatible with the STM32F2xx devices, allowing the user to try different memory densities, peripherals, and performances (FPU, higher frequency) for a greater degree of freedom during the development cycle.

The STM32F405xx and STM32F407xx devices maintain a close compatibility with the whole STM32F10xxx family. All functional pins are pin-to-pin compatible. The STM32F405xx and STM32F407xx, however, are not drop-in replacements for the STM32F10xxx devices: the two families do not have the same power scheme, and so their power pins are different. Nonetheless, transition from the STM32F10xxx to the STM32F40x family remains simple as only a few pins are impacted.

[Figure 4](#), [Figure 3](#), [Figure 2](#), and [Figure 1](#) give compatible board designs between the STM32F40x, STM32F2xxx, and STM32F10xxx families.

Figure 1. Compatible board design between STM32F10xx/STM32F4xx for LQFP64

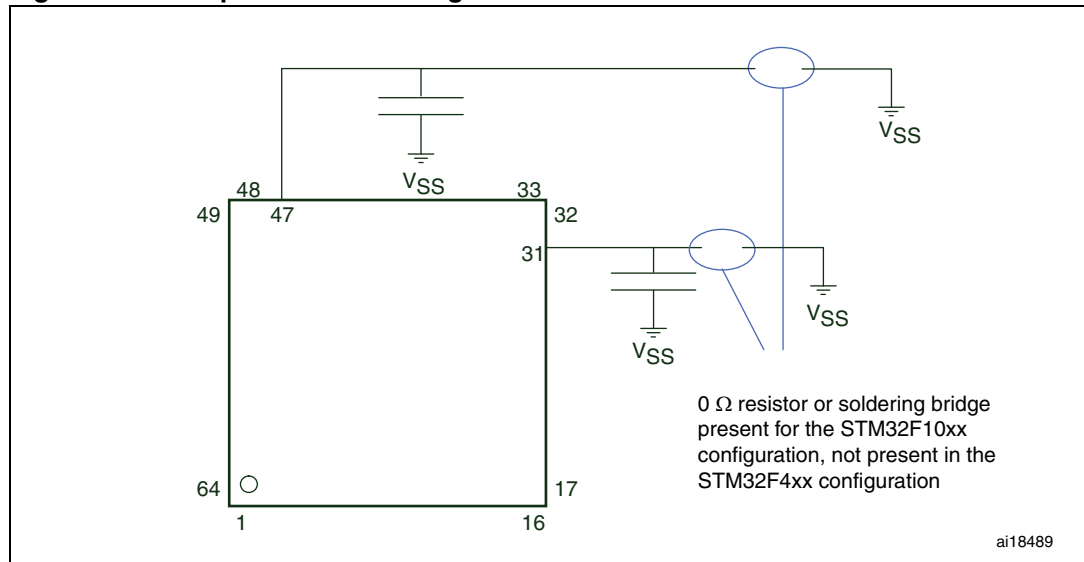


Figure 2. Compatible board design STM32F10xx/STM32F2xx/STM32F4xx for LQFP100 package

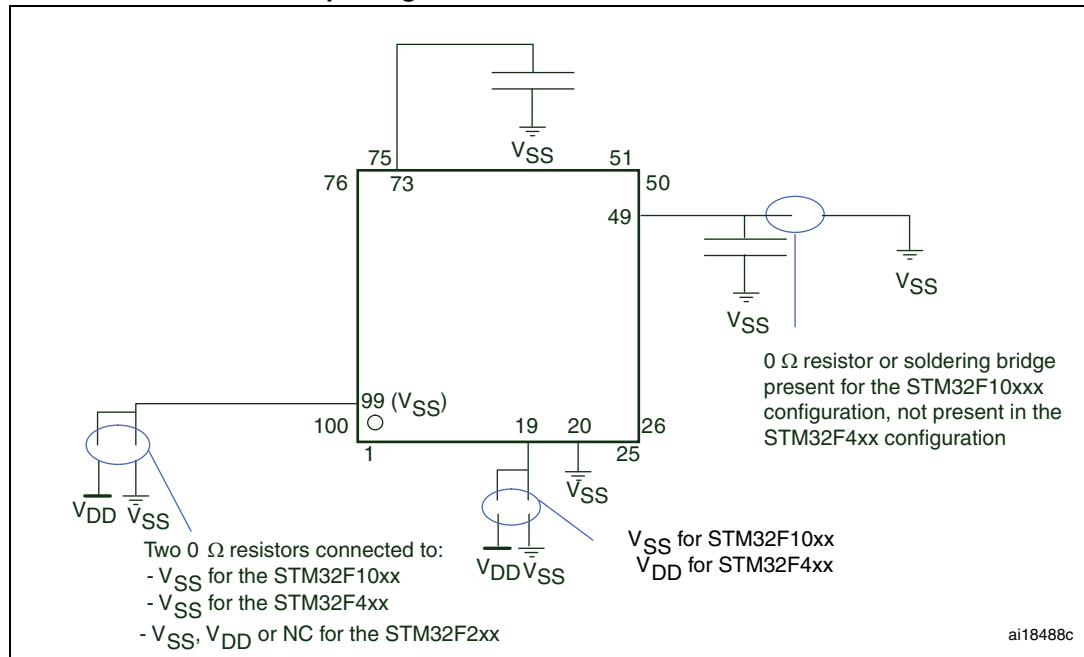


Figure 3. Compatible board design between STM32F10xx/STM32F2xx/STM32F4xx for LQFP144 package

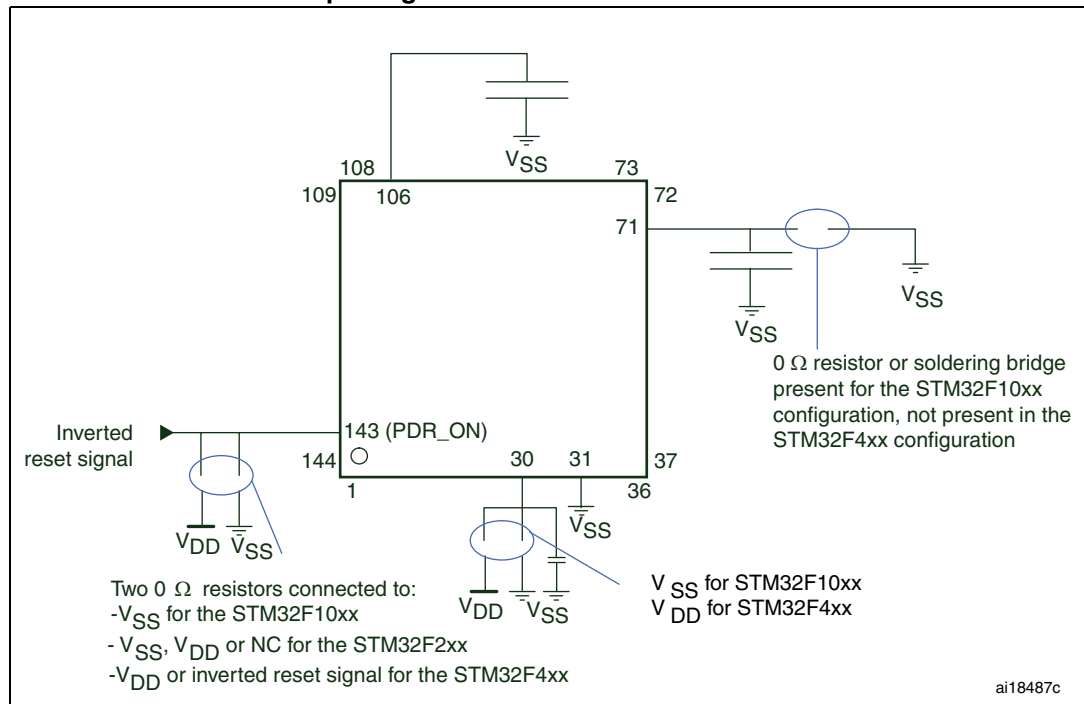
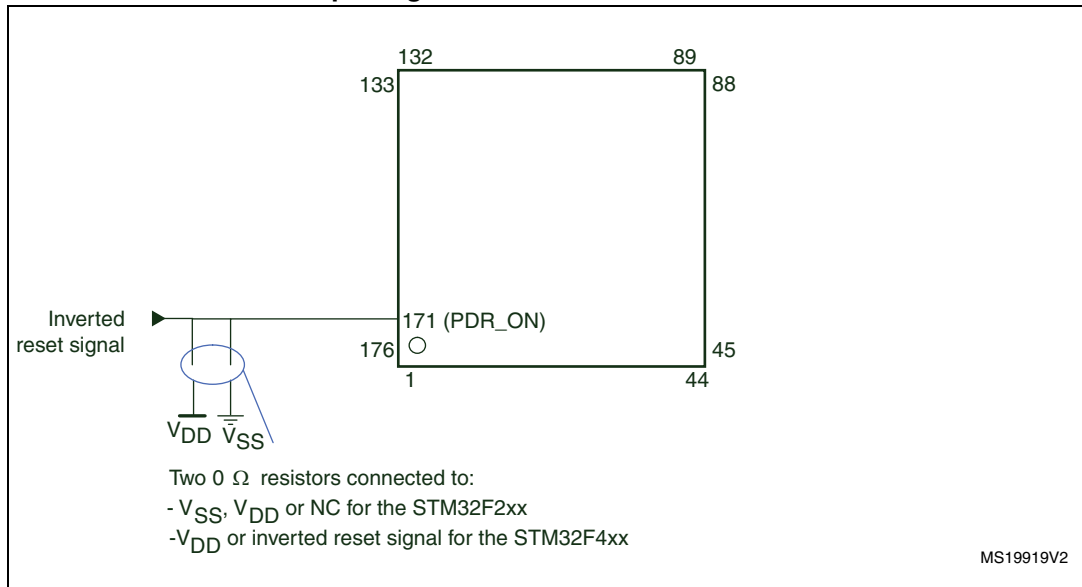
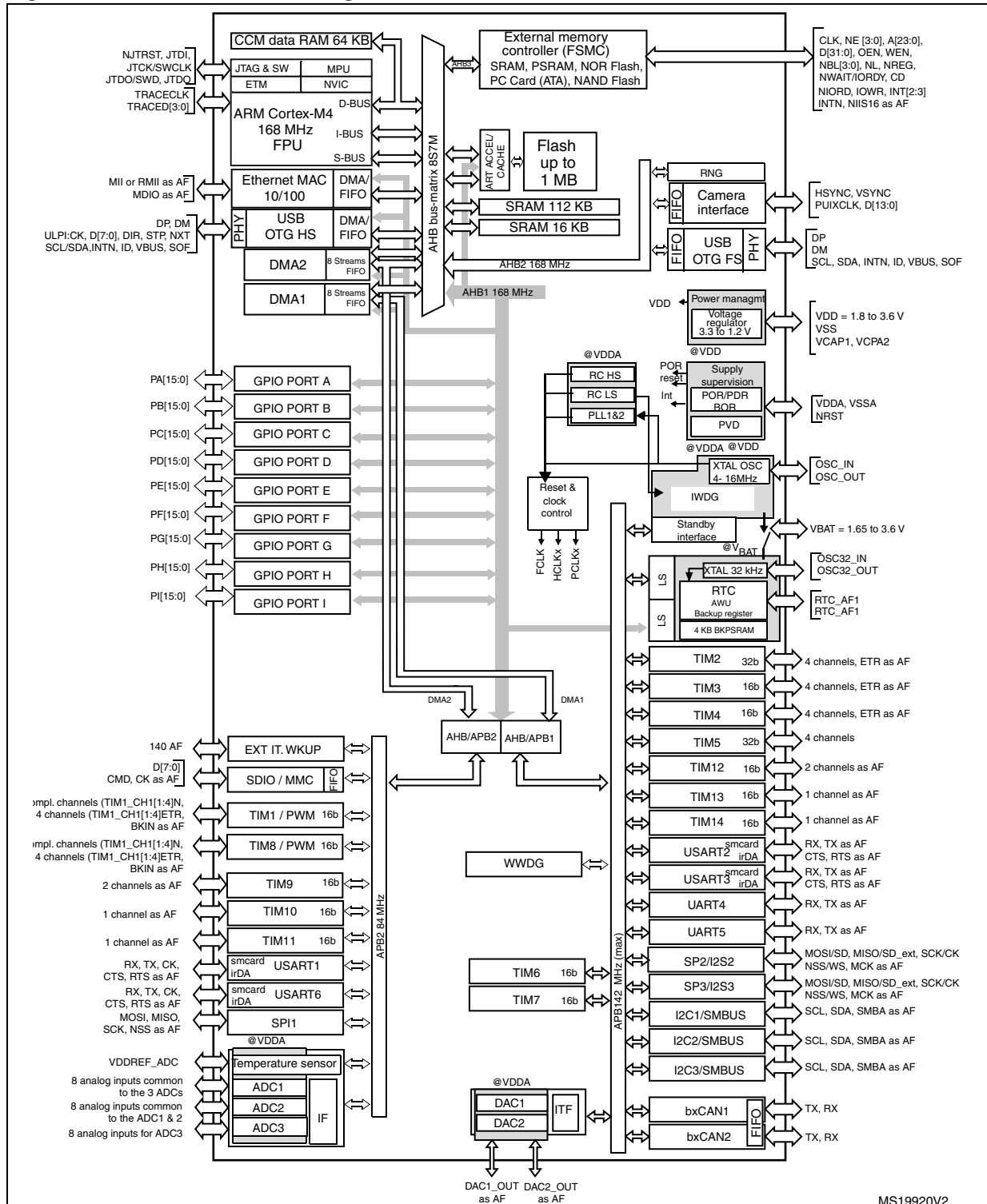


Figure 4. Compatible board design between STM32F2xx and STM32F4xx for LQFP176 package



2.2 Device overview

Figure 5. STM32F40x block diagram



1. The timers connected to APB2 are clocked from TIMxCLK up to 168 MHz, while the timers connected to APB1 are clocked

from TIMxCLK up to 84 MHz.

2. The camera interface and ethernet are available only on STM32F407xx devices.

2.2.1 ARM® Cortex™-M4F core with embedded Flash and SRAM

The ARM Cortex-M4F processor is the latest generation of ARM processors for embedded systems. It was developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts.

The ARM Cortex-M4F 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The processor supports a set of DSP instructions which allow efficient signal processing and complex algorithm execution.

Its single precision FPU (floating point unit) speeds up software development by using metalanguage development tools, while avoiding saturation.

The STM32F405xx and STM32F407xx family is compatible with all ARM tools and software.

Figure 5 shows the general block diagram of the STM32F40x family.

Note: Cortex-M4F is binary compatible with Cortex-M3.

2.2.2 Adaptive real-time memory accelerator (ART Accelerator™)

The ART Accelerator™ is a memory accelerator which is optimized for STM32 industry-standard ARM® Cortex™-M4F processors. It balances the inherent performance advantage of the ARM Cortex-M4F over Flash memory technologies, which normally requires the processor to wait for the Flash memory at higher frequencies.

To release the processor full 210 DMIPS performance at this frequency, the accelerator implements an instruction prefetch queue and branch cache, which increases program execution speed from the 128-bit Flash memory. Based on CoreMark benchmark, the performance achieved thanks to the ART accelerator is equivalent to 0 wait state program execution from Flash memory at a CPU frequency up to 168 MHz.

2.2.3 Memory protection unit

The memory protection unit (MPU) is used to manage the CPU accesses to memory to prevent one task to accidentally corrupt the memory or resources used by any other active task. This memory area is organized into up to 8 protected areas that can in turn be divided up into 8 subareas. The protection area sizes are between 32 bytes and the whole 4 gigabytes of addressable memory.

The MPU is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

2.2.4 Embedded Flash memory

The STM32F40x devices embed a Flash memory of 512 Kbytes or 1 Mbytes available for storing programs and data.

2.2.5 CRC (cyclic redundancy check) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a fixed generator polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a software signature during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

2.2.6 Embedded SRAM

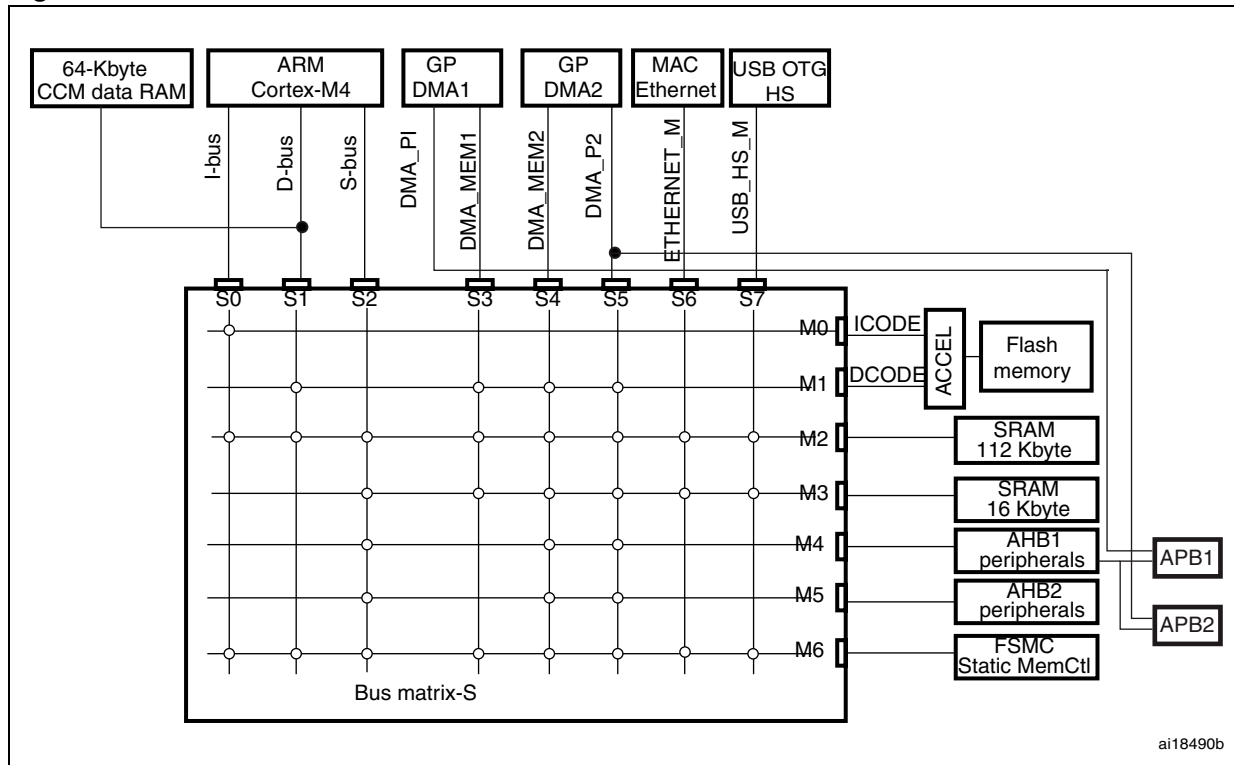
All STM32F40x products embed:

- Up to 192 Kbytes of system SRAM including 64 Kbytes of CCM (core coupled memory) data RAM
RAM memory is accessed (read/write) at CPU clock speed with 0 wait states.
- 4 Kbytes of backup SRAM
This area is accessible only from the CPU. Its content is protected against possible unwanted write accesses, and is retained in Standby or VBAT mode.

2.2.7 Multi-AHB bus matrix

The 32-bit multi-AHB bus matrix interconnects all the masters (CPU, DMAs, Ethernet, USB HS) and the slaves (Flash memory, RAM, FSMC, AHB and APB peripherals) and ensures a seamless and efficient operation even when several high-speed peripherals work simultaneously.

Figure 6. Multi-AHB matrix



2.2.8 DMA controller (DMA)

The devices feature two general-purpose dual-port DMAs (DMA1 and DMA2) with 8 streams each. They are able to manage memory-to-memory, peripheral-to-memory and memory-to-peripheral transfers. They feature dedicated FIFOs for APB/AHB peripherals, support burst transfer and are designed to provide the maximum peripheral bandwidth (AHB/APB).

The two DMA controllers support circular buffer management, so that no specific code is needed when the controller reaches the end of the buffer. The two DMA controllers also have a double buffering feature, which automates the use and switching of two memory buffers without requiring any special code.

Each stream is connected to dedicated hardware DMA requests, with support for software trigger on each stream. Configuration is made by software and transfer sizes between source and destination are independent.

The DMA can be used with the main peripherals:

- SPI and I²S
- I²C
- USART
- General-purpose, basic and advanced-control timers TIMx
- DAC
- SDIO
- Camera interface (DCMI)
- ADC.

2.2.9 Flexible static memory controller (FSMC)

The FSMC is embedded in the STM32F405xx and STM32F407xx family. It has four Chip Select outputs supporting the following modes: PCCard/Compact Flash, SRAM, PSRAM, NOR Flash and NAND Flash.

Functionality overview:

- Write FIFO
- Maximum FSMC_CLK frequency for synchronous accesses is 60 MHz.

LCD parallel interface

The FSMC can be configured to interface seamlessly with most graphic LCD controllers. It supports the Intel 8080 and Motorola 6800 modes, and is flexible enough to adapt to specific LCD interfaces. This LCD parallel interface capability makes it easy to build cost-effective graphic applications using LCD modules with embedded controllers or high performance solutions using external controllers with dedicated acceleration.

2.2.10 Nested vectored interrupt controller (NVIC)

The STM32F405xx and STM32F407xx embed a nested vectored interrupt controller able to manage 16 priority levels, and handle up to 82 maskable interrupt channels plus the 16 interrupt lines of the Cortex™-M4F.

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Allows early processing of interrupts
- Processing of late arriving, higher-priority interrupts
- Support tail chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimum interrupt latency.

2.2.11 External interrupt/event controller (EXTI)

The external interrupt/event controller consists of 23 edge-detector lines used to generate interrupt/event requests. Each line can be independently configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the Internal APB2 clock period. Up to 140 GPIOs can be connected to the 16 external interrupt lines.

2.2.12 Clocks and startup

On reset the 16 MHz internal RC oscillator is selected as the default CPU clock. The 16 MHz internal RC oscillator is factory-trimmed to offer 1% accuracy over the full temperature range. The application can then select as system clock either the RC oscillator or an external 4-26 MHz clock source. This clock can be monitored for failure. If a failure is detected, the system automatically switches back to the internal RC oscillator and a software interrupt is generated (if enabled). This clock source is input to a PLL thus allowing to increase the frequency up to 168 MHz. Similarly, full interrupt management of the PLL

clock entry is available when necessary (for example if an indirectly used external oscillator fails).

Several prescalers allow the configuration of the three AHB buses, the high-speed APB (APB2) and the low-speed APB (APB1) domains. The maximum frequency of the three AHB buses is 168 MHz while the maximum frequency of the high-speed APB domains is 84 MHz. The maximum allowed frequency of the low-speed APB domain is 42 MHz.

The devices embed a dedicated PLL (PLL12S) which allows to achieve audio class performance. In this case, the I²S master clock can generate all standard sampling frequencies from 8 kHz to 192 kHz.

2.2.13 Boot modes

At startup, boot pins are used to select one out of three boot options:

- Boot from user Flash
- Boot from system memory
- Boot from embedded SRAM

The boot loader is located in system memory. It is used to reprogram the Flash memory by using USART1 (PA9/PA10), USART3 (PC10/PC11 or PB10/PB11), CAN2 (PB5/PB13), USB OTG FS in Device mode (PA11/PA12) through DFU (device firmware upgrade).

2.2.14 Power supply schemes

- $V_{DD} = 1.8$ to 3.6 V: external power supply for I/Os and the internal regulator (when enabled), provided externally through V_{DD} pins.
- V_{SSA} , $V_{DDA} = 1.8$ to 3.6 V: external analog power supplies for ADC, DAC, Reset blocks, RCs and PLL. V_{DDA} and V_{SSA} must be connected to V_{DD} and V_{SS} , respectively.
- $V_{BAT} = 1.65$ to 3.6 V: power supply for RTC, external clock 32 kHz oscillator and backup registers (through power switch) when V_{DD} is not present.

Refer to [Figure 19: Power supply scheme](#) for more details.

Note: V_{DD}/V_{DDA} minimum value of 1.7 V is obtained when the device operates in the 0 to 70 °C temperature range and an inverted reset signal is applied to PDR_ON.

2.2.15 Power supply supervisor

The power supply supervisor is enabled by holding PDR_ON high.

The device has an integrated power-on reset (POR) / power-down reset (PDR) circuitry coupled with a Brownout reset (BOR) circuitry. At power-on, BOR is always active, and ensures proper operation starting from 1.8 V. After the 1.8 V BOR threshold level is reached, the option byte loading process starts, either to confirm or modify default thresholds, or to disable BOR permanently. Three BOR thresholds are available through option bytes. The device remains in reset mode when V_{DD} is below a specified threshold, $V_{POR/PDR}$ or V_{BOR} , without the need for an external reset circuit.

The device also features an embedded programmable voltage detector (PVD) that monitors the V_{DD}/V_{DDA} power supply and compares it to the V_{PVD} threshold. An interrupt can be generated when V_{DD}/V_{DDA} drops below the V_{PVD} threshold and/or when V_{DD}/V_{DDA} is higher than the V_{PVD} threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

All packages, except for the LQFP64 and LQFP100, have an internal reset controlled through the PDR_ON signal.

2.2.16 Voltage regulator

The regulator has eight operating modes:

- Regulator ON/internal reset ON
 - Main regulator mode (MR)
 - Low power regulator (LPR)
 - Power-down
- Regulator ON/internal reset OFF
 - Main regulator mode (MR)
 - Low power regulator (LPR)
 - Power-down
- Regulator OFF/internal reset ON
- Regulator OFF/internal reset OFF

Regulator ON

- Regulator ON/internal reset ON

The regulator ON/internal reset ON mode is always enabled on LQFP64 and LQFP100 package.

On LQFP144 package, this mode is activated by setting PDR_ON to V_{DD} .

On UFBGA176 package, the internal regulator must be activated by connecting BYPASS_REG to V_{SS} , and PDR_ON to V_{DD} .

On LQFP176 packages, the internal reset must be activated by connecting PDR_ON to V_{DD} .

There are three low-power modes:

 - MR is used in the nominal regulation mode (Run)
 - LPR is used in the Stop modes
 - Power-down is used in Standby mode: the regulator output is in high impedance: the kernel circuitry is powered down, inducing zero consumption (but the contents of the registers and SRAM are lost).
- Regulator ON/internal reset OFF

The regulator ON with internal reset OFF mode is not available on LQFP64 and LQFP100 packages.

On LQFP144, and LQFP176 packages, the internal reset is controlled by applying an inverted reset signal to PDR_ON pin.

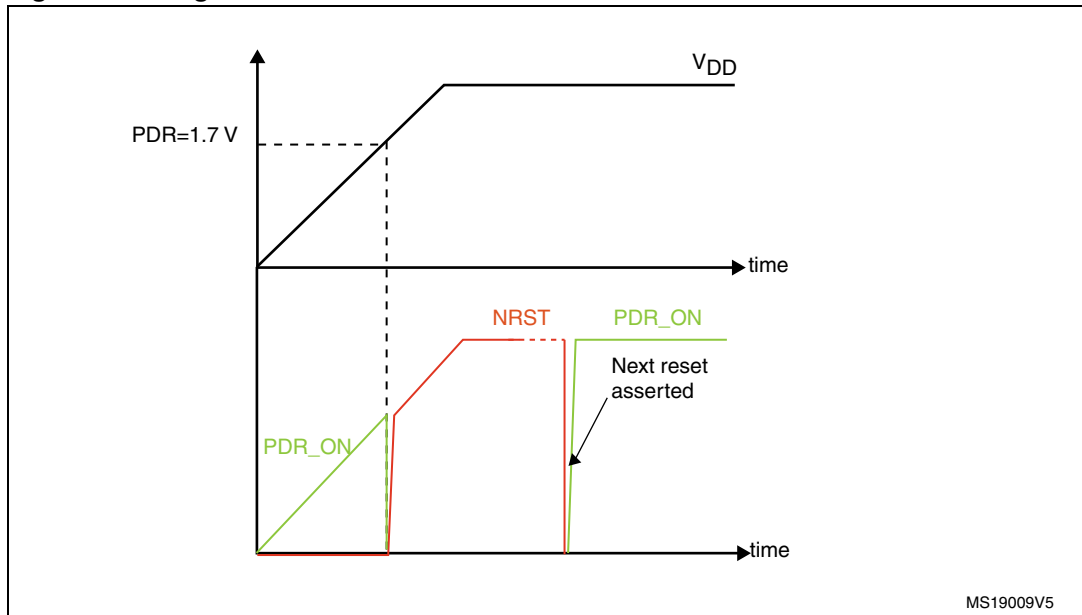
On UFBGA176 package, the internal regulator must be activated by connecting BYPASS_REG to V_{SS} .

On LQFP176 packages, the internal reset must be activated by applying an inverted reset signal to PDR_ON pin.

V_{DD}/V_{DDA} minimum value of 1.7 V is obtained when the device operates in the 0 to 70 °C temperature range and an inverted reset signal is applied to PDR_ON.

The NRST pin should be controlled by an external reset controller to keep the device under reset when V_{DD} is below 1.8 V (see [Figure 7](#)).

Figure 7. Regulator ON/internal reset OFF



Regulator OFF

This mode allows to power the device as soon as V_{DD} reaches 1.8 V.

- Regulator OFF/internal reset ON

This mode is available only on UFBGA and WLCSP90 packages. It is activated by setting `BYPASS_REG` and `PDR_ON` pins to V_{DD} .

The regulator OFF/internal reset ON mode allows to supply externally a 1.2 V voltage source through V_{CAP_1} and V_{CAP_2} pins, in addition to V_{DD} .

The following conditions must be respected:

- V_{DD} should always be higher than V_{CAP_1} and V_{CAP_2} to avoid current injection between power domains.
- If the time for V_{CAP_1} and V_{CAP_2} to reach 1.08 V is faster than the time for V_{DD} to reach 1.8 V, then `PA0` should be connected to the `NRST` pin (see [Figure 8](#)). Otherwise, `PA0` should be asserted low externally during POR until V_{DD} reaches 1.8 V (see [Figure 9](#)).
- If V_{CAP_1} and V_{CAP_2} go below 1.08 V and V_{DD} is higher than 1.7 V, then a reset must be asserted on `PA0` pin.

In regulator OFF/internal reset ON mode, `PA0` cannot be used as a GPIO pin since it allows to reset the part of the 1.2 V logic which is not reset by the `NRST` pin, when the internal voltage regulator is off.

- Regulator OFF/internal reset OFF

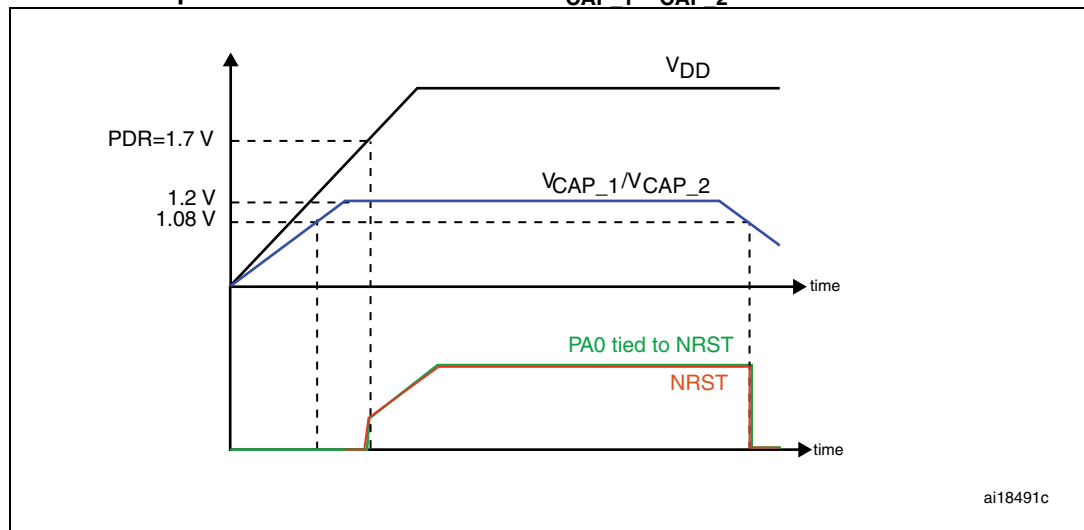
This mode is available only on UFBGA and WLCSP packages. It is activated by setting `BYPASS_REG` pin to V_{DD} and by applying an inverted reset signal to `PDR_ON`, and

allows to supply externally a 1.2 V voltage source through V_{CAP_1} and V_{CAP_2} pins, in addition to V_{DD} .

The following conditions must be respected:

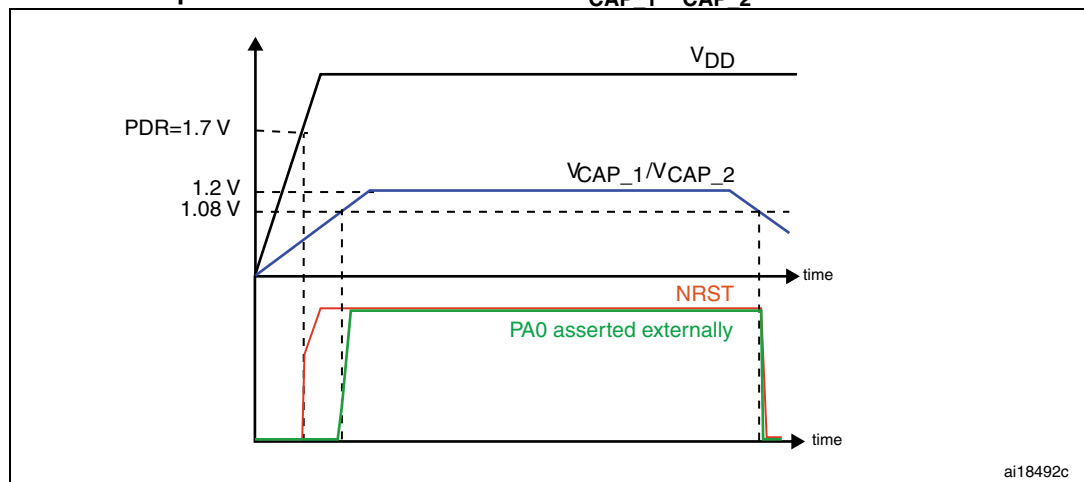
- V_{DD} should always be higher than V_{CAP_1} and V_{CAP_2} to avoid current injection between power domains.
- PA0 should be kept low to cover both conditions: until V_{CAP_1} and V_{CAP_2} reach 1.08 V and until V_{DD} reaches 1.8 V (see [Figure 8](#)).
- NRST should be controlled by an external reset controller to keep the device under reset when V_{DD} is below 1.8 V (see [Figure 9](#)).

Figure 8. Startup in regulator OFF mode: slow V_{DD} slope - power-down reset risen after V_{CAP_1}/V_{CAP_2} stabilization



1. This figure is valid both whatever the internal reset mode (on or off).

Figure 9. Startup in regulator OFF mode: fast V_{DD} slope - power-down reset risen before V_{CAP_1}/V_{CAP_2} stabilization



1. This figure is valid both whatever the internal reset mode (on or off).

2.2.17 Real-time clock (RTC), backup SRAM and backup registers

The backup domain of the STM32F405xx and STM32F407xx includes:

- The real-time clock (RTC)
- 4 Kbytes of backup SRAM
- 20 backup registers

The real-time clock (RTC) is an independent BCD timer/counter. Dedicated registers contain the second, minute, hour (in 12/24 hour), week day, date, month, year, in BCD (binary-coded decimal) format. Correction for 28, 29 (leap year), 30, and 31 day of the month are performed automatically. The RTC provides a programmable alarm and programmable periodic interrupts with wakeup from Stop and Standby modes. The sub-seconds value is also available in binary format.

It is clocked by a 32.768 kHz external crystal, resonator or oscillator, the internal low-power RC oscillator or the high-speed external clock divided by 128. The internal low-speed RC has a typical frequency of 32 kHz. The RTC can be calibrated using an external 512 Hz output to compensate for any natural quartz deviation.

Two alarm registers are used to generate an alarm at a specific time and calendar fields can be independently masked for alarm comparison. To generate a periodic interrupt, a 16-bit programmable binary auto-reload downcounter with programmable resolution is available and allows automatic wakeup and periodic alarms from every 120 μ s to every 36 hours.

A 20-bit prescaler is used for the time base clock. It is by default configured to generate a time base of 1 second from a clock at 32.768 kHz.

The 4-Kbyte backup SRAM is an EEPROM-like memory area. It can be used to store data which need to be retained in VBAT and standby mode. This memory area is disabled by default to minimize power consumption (see [Section 2.2.18: Low-power modes](#)). It can be enabled by software.

The backup registers are 32-bit registers used to store 80 bytes of user application data when V_{DD} power is not present. Backup registers are not reset by a system, a power reset, or when the device wakes up from the Standby mode (see [Section 2.2.18: Low-power modes](#)).

Additional 32-bit registers contain the programmable alarm subseconds, seconds, minutes, hours, day, and date.

Like backup SRAM, the RTC and backup registers are supplied through a switch that is powered either from the V_{DD} supply when present or from the V_{BAT} pin.

2.2.18 Low-power modes

The STM32F405xx and STM32F407xx support three low-power modes to achieve the best compromise between low power consumption, short startup time and available wakeup sources:

- **Sleep mode**

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.

- **Stop mode**

The Stop mode achieves the lowest power consumption while retaining the contents of SRAM and registers. All clocks in the 1.2 V domain are stopped, the PLL, the HSI RC

and the HSE crystal oscillators are disabled. The voltage regulator can also be put either in normal or in low-power mode.

The device can be woken up from the Stop mode by any of the EXTI line (the EXTI line source can be one of the 16 external lines, the PVD output, the RTC alarm / wakeup / tamper / time stamp events, the USB OTG FS/HS wakeup or the Ethernet wakeup).

- **Standby mode**

The Standby mode is used to achieve the lowest power consumption. The internal voltage regulator is switched off so that the entire 1.2 V domain is powered off. The PLL, the HSI RC and the HSE crystal oscillators are also switched off. After entering Standby mode, the SRAM and register contents are lost except for registers in the backup domain and the backup SRAM when selected.

The device exits the Standby mode when an external reset (NRST pin), an IWDG reset, a rising edge on the WKUP pin, or an RTC alarm / wakeup / tamper /time stamp event occurs.

The standby mode is not supported when the embedded voltage regulator is bypassed and the 1.2 V domain is controlled by an external power.

Note: When in Standby mode, only an RTC alarm/event or an external reset can wake up the device provided V_{DD} is supplied by an external battery.

2.2.19 V_{BAT} operation

The V_{BAT} pin allows to power the device V_{BAT} domain from an external battery, an external supercapacitor, or from V_{DD} when no external battery and an external supercapacitor are present.

V_{BAT} operation is activated when V_{DD} is not present.

The V_{BAT} pin supplies the RTC, the backup registers and the backup SRAM.

Note: When the microcontroller is supplied from V_{BAT} , external interrupts and RTC alarm/events do not exit it from V_{BAT} operation.

2.2.20 Timers and watchdogs

The STM32F405xx and STM32F407xx devices include two advanced-control timers, eight general-purpose timers, two basic timers and two watchdog timers.

All timer counters can be frozen in debug mode.

[Table 3](#) compares the features of the advanced-control, general-purpose and basic timers.

Table 3. Timer feature comparison

| Timer type | Timer | Counter resolution | Counter type | Prescaler factor | DMA request generation | Capture/compare channels | Complementary output | Max interface clock (MHz) | Max timer clock (MHz) |
|------------------|--------------|--------------------|-------------------|---------------------------------|------------------------|--------------------------|----------------------|---------------------------|-----------------------|
| Advanced-control | TIM1, TIM8 | 16-bit | Up, Down, Up/down | Any integer between 1 and 65536 | Yes | 4 | Yes | 84 | 168 |
| General purpose | TIM2, TIM5 | 32-bit | Up, Down, Up/down | Any integer between 1 and 65536 | Yes | 4 | No | 42 | 84 |
| | TIM3, TIM4 | 16-bit | Up, Down, Up/down | Any integer between 1 and 65536 | Yes | 4 | No | 42 | 84 |
| | TIM9 | 16-bit | Up | Any integer between 1 and 65536 | No | 2 | No | 84 | 168 |
| | TIM10, TIM11 | 16-bit | Up | Any integer between 1 and 65536 | No | 1 | No | 84 | 168 |
| | TIM12 | 16-bit | Up | Any integer between 1 and 65536 | No | 2 | No | 42 | 84 |
| | TIM13, TIM14 | 16-bit | Up | Any integer between 1 and 65536 | No | 1 | No | 42 | 84 |
| Basic | TIM6, TIM7 | 16-bit | Up | Any integer between 1 and 65536 | Yes | 0 | No | 42 | 84 |

Advanced-control timers (TIM1, TIM8)

The advanced-control timers (TIM1, TIM8) can be seen as three-phase PWM generators multiplexed on 6 channels. They have complementary PWM outputs with programmable inserted dead times. They can also be considered as complete general-purpose timers. Their 4 independent channels can be used for:

- Input capture
- Output compare
- PWM generation (edge- or center-aligned modes)
- One-pulse mode output

If configured as standard 16-bit timers, they have the same features as the general-purpose TIMx timers. If configured as 16-bit PWM generators, they have full modulation capability (0-100%).

The advanced-control timer can work together with the TIMx timers via the Timer Link feature for synchronization or event chaining.

TIM1 and TIM8 support independent DMA request generation.

General-purpose timers (TIMx)

There are ten synchronizable general-purpose timers embedded in the STM32F40x devices (see [Table 3](#) for differences).

- **TIM2, TIM3, TIM4, TIM5**

The STM32F40x include 4 full-featured general-purpose timers: TIM2, TIM5, TIM3, and TIM4. The TIM2 and TIM5 timers are based on a 32-bit auto-reload up/downcounter and a 16-bit prescaler. The TIM3 and TIM4 timers are based on a 16-bit auto-reload up/downcounter and a 16-bit prescaler. They all feature 4 independent channels for input capture/output compare, PWM or one-pulse mode output. This gives up to 16 input capture/output compare/PWMs on the largest packages.

The TIM2, TIM3, TIM4, TIM5 general-purpose timers can work together, or with the other general-purpose timers and the advanced-control timers TIM1 and TIM8 via the Timer Link feature for synchronization or event chaining.

Any of these general-purpose timers can be used to generate PWM outputs.

TIM2, TIM3, TIM4, TIM5 all have independent DMA request generation. They are capable of handling quadrature (incremental) encoder signals and the digital outputs from 1 to 4 hall-effect sensors.

- **TIM9, TIM10, TIM11, TIM12, TIM13, and TIM14**

These timers are based on a 16-bit auto-reload upcounter and a 16-bit prescaler. TIM10, TIM11, TIM13, and TIM14 feature one independent channel, whereas TIM9 and TIM12 have two independent channels for input capture/output compare, PWM or one-pulse mode output. They can be synchronized with the TIM2, TIM3, TIM4, TIM5 full-featured general-purpose timers. They can also be used as simple time bases.

Basic timers TIM6 and TIM7

These timers are mainly used for DAC trigger and waveform generation. They can also be used as a generic 16-bit time base.

TIM6 and TIM7 support independent DMA request generation.

Independent watchdog

The independent watchdog is based on a 12-bit downcounter and 8-bit prescaler. It is clocked from an independent 32 kHz internal RC and as it operates independently from the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free-running timer for application timeout management. It is hardware- or software-configurable through the option bytes.

Window watchdog

The window watchdog is based on a 7-bit downcounter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in debug mode.

SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard downcounter. It features:

- A 24-bit downcounter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source.

2.2.21 Inter-integrated circuit interface (I²C)

Up to three I²C bus interfaces can operate in multimaster and slave modes. They can support the Standard- and Fast-modes. They support the 7/10-bit addressing mode and the 7-bit dual addressing mode (as slave). A hardware CRC generation/verification is embedded.

They can be served by DMA and they support SMBus 2.0/PMBus.

2.2.22 Universal synchronous/asynchronous receiver transmitters (USART)

The STM32F405xx and STM32F407xx embed four universal synchronous/asynchronous receiver transmitters (USART1, USART2, USART3 and USART6) and two universal asynchronous receiver transmitters (UART4 and UART5).

These six interfaces provide asynchronous communication, IrDA SIR ENDEC support, multiprocessor communication mode, single-wire half-duplex communication mode and have LIN Master/Slave capability. The USART1 and USART6 interfaces are able to communicate at speeds of up to 10.5 Mbit/s. The other available interfaces communicate at up to 5.25 bit/s.

USART1, USART2, USART3 and USART6 also provide hardware management of the CTS and RTS signals, Smart Card mode (ISO 7816 compliant) and SPI-like communication capability. All interfaces can be served by the DMA controller.

Table 4. USART feature comparison

| USART name | Standard features | Modem (RTS/CTS) | LIN | SPI master | IrDA | Smartcard (ISO 7816) | Max. baud rate in Mbit/s (oversampling by 16) | Max. baud rate in Mbit/s (oversampling by 8) | APB mapping |
|------------|-------------------|-----------------|-----|------------|------|----------------------|---|--|--------------------|
| USART1 | X | X | X | X | X | X | 5.25 | 10.5 | APB2 (max. 84 MHz) |
| USART2 | X | X | X | X | X | X | 2.62 | 5.25 | APB1 (max. 42 MHz) |
| USART3 | X | X | X | X | X | X | 2.62 | 5.25 | APB1 (max. 42 MHz) |
| UART4 | X | - | X | - | X | - | 2.62 | 5.25 | APB1 (max. 42 MHz) |
| UART5 | X | - | X | - | X | - | 2.62 | 5.25 | APB1 (max. 42 MHz) |
| USART6 | X | X | X | X | X | X | 5.25 | 10.5 | APB2 (max. 84 MHz) |

2.2.23 Serial peripheral interface (SPI)

The STM32F40x feature up to three SPIs in slave and master modes in full-duplex and simplex communication modes. SPI1 can communicate at up to 37.5 Mbits/s, SPI2 and SPI3 can communicate at up to 21 Mbit/s. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes. All SPIs can be served by the DMA controller.

The SPI interface can be configured to operate in TI mode for communications in master mode and slave mode.

2.2.24 Inter-integrated sound (I²S)

Two standard I²S interfaces (multiplexed with SPI2 and SPI3) are available. They can be operated in master or slave mode, in full duplex and simplex communication modes, and can be configured to operate with a 16-/32-bit resolution as an input or output channel. Audio sampling frequencies from 8 kHz up to 192 kHz are supported. When either or both of the I²S interfaces is/are configured in master mode, the master clock can be output to the external DAC/CODEC at 256 times the sampling frequency.

All I²Sx can be served by the DMA controller.

2.2.25 Audio PLL (PLLI2S)

The devices feature an additional dedicated PLL for audio I²S application. It allows to achieve error-free I²S sampling clock accuracy without compromising on the CPU performance, while using USB peripherals.

The PLLI2S configuration can be modified to manage an I²S sample rate change without disabling the main PLL (PLL) used for CPU, USB and Ethernet interfaces.

The audio PLL can be programmed with very low error to obtain sampling rates ranging from 8 KHz to 192 KHz.

In addition to the audio PLL, a master clock input pin can be used to synchronize the I2S flow with an external PLL (or Codec output).

2.2.26 Secure digital input/output interface (SDIO)

An SD/SDIO/MMC host interface is available, that supports MultiMediaCard System Specification Version 4.2 in three different databus modes: 1-bit (default), 4-bit and 8-bit.

The interface allows data transfer at up to 48 MHz, and is compliant with the SD Memory Card Specification Version 2.0.

The SDIO Card Specification Version 2.0 is also supported with two different databus modes: 1-bit (default) and 4-bit.

The current version supports only one SD/SDIO/MMC4.2 card at any one time and a stack of MMC4.1 or previous.

In addition to SD/SDIO/MMC, this interface is fully compliant with the CE-ATA digital protocol Rev1.1.

2.2.27 Ethernet MAC interface with dedicated DMA and IEEE 1588 support

Peripheral available only on the STM32F407xx devices.

The STM32F407xx devices provide an IEEE-802.3-2002-compliant media access controller (MAC) for ethernet LAN communications through an industry-standard medium-independent interface (MII) or a reduced medium-independent interface (RMII). The STM32F407xx requires an external physical interface device (PHY) to connect to the physical LAN bus (twisted-pair, fiber, etc.). the PHY is connected to the STM32F407xx MII port using 17 signals for MII or 9 signals for RMII, and can be clocked using the 25 MHz (MII) from the STM32F407xx.

The STM32F407xx includes the following features:

- Supports 10 and 100 Mbit/s rates
- Dedicated DMA controller allowing high-speed transfers between the dedicated SRAM and the descriptors (see the STM32F46x reference manual for details)
- Tagged MAC frame support (VLAN support)
- Half-duplex (CSMA/CD) and full-duplex operation
- MAC control sublayer (control frames) support
- 32-bit CRC generation and removal
- Several address filtering modes for physical and multicast address (multicast and group addresses)
- 32-bit status code for each transmitted or received frame
- Internal FIFOs to buffer transmit and receive frames. The transmit FIFO and the receive FIFO are both 2 Kbytes.
- Supports hardware PTP (precision time protocol) in accordance with IEEE 1588 2008 (PTP V2) with the time stamp comparator connected to the TIM2 input
- Triggers interrupt when system time becomes greater than target time

2.2.28 Controller area network (bxCAN)

The two CANs are compliant with the 2.0A and B (active) specifications with a bitrate up to 1 Mbit/s. They can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers. Each CAN has three transmit mailboxes, two receive FIFOs with 3 stages and 28 shared scalable filter banks (all of them can be used even if one CAN is used). 256 bytes of SRAM are allocated for each CAN.

2.2.29 Universal serial bus on-the-go full-speed (OTG_FS)

The STM32F405xx and STM32F407xx embed an USB OTG full-speed device/host/OTG peripheral with integrated transceivers. The USB OTG FS peripheral is compliant with the USB 2.0 specification and with the OTG 1.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG full-speed controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator. The major features are:

- Combined Rx and Tx FIFO size of 320 × 35 bits with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 4 bidirectional endpoints
- 8 host channels with periodic OUT support
- HNP/SNP/IP inside (no need for any external resistor)
- For OTG/Host modes, a power switch is needed in case bus-powered devices are connected

2.2.30 Universal serial bus on-the-go high-speed (OTG_HS)

The STM32F405xx and STM32F407xx devices embed a USB OTG high-speed (up to 480 Mb/s) device/host/OTG peripheral. The USB OTG HS supports both full-speed and high-speed operations. It integrates the transceivers for full-speed operation (12 MB/s) and features a UTMI low-pin interface (ULPI) for high-speed operation (480 MB/s). When using the USB OTG HS in HS mode, an external PHY device connected to the ULPI is required.

The USB OTG HS peripheral is compliant with the USB 2.0 specification and with the OTG 1.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG full-speed controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator.

The major features are:

- Combined Rx and Tx FIFO size of 1 Kbit × 35 with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 6 bidirectional endpoints
- 12 host channels with periodic OUT support
- Internal FS OTG PHY support
- External HS or HS OTG operation supporting ULPI in SDR mode. The OTG PHY is connected to the microcontroller ULPI port through 12 signals. It can be clocked using the 60 MHz output.
- Internal USB DMA
- HNP/SNP/IP inside (no need for any external resistor)
- for OTG/Host modes, a power switch is needed in case bus-powered devices are connected

2.2.31 Digital camera interface (DCMI)

The camera interface is *not* available in STM32F405xx devices.

STM32F407xx products embed a camera interface that can connect with camera modules and CMOS sensors through an 8-bit to 14-bit parallel interface, to receive video data. The camera interface can sustain a data transfer rate up to 54 Mbyte/s at 54 MHz. It features:

- Programmable polarity for the input pixel clock and synchronization signals
- Parallel data communication can be 8-, 10-, 12- or 14-bit
- Supports 8-bit progressive video monochrome or raw bayer format, YCbCr 4:2:2 progressive video, RGB 565 progressive video or compressed data (like JPEG)
- Supports continuous mode or snapshot (a single frame) mode
- Capability to automatically crop the image

2.2.32 Random number generator (RNG)

All STM32F405xx and STM32F407xx products embed an RNG that delivers 32-bit random numbers generated by an integrated analog circuit.

2.2.33 General-purpose input/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain, with or without pull-up or pull-down), as input (floating, with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high-current-capable and have speed selection to better manage internal noise, power consumption and electromagnetic emission.

The I/O configuration can be locked if needed by following a specific sequence in order to avoid spurious writing to the I/Os registers.

Fast I/O handling allowing maximum I/O toggling up to 84 MHz.

2.2.34 Analog-to-digital converters (ADCs)

Three 12-bit analog-to-digital converters are embedded and each ADC shares up to 16 external channels, performing conversions in the single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

Additional logic functions embedded in the ADC interface allow:

- Simultaneous sample and hold
- Interleaved sample and hold

The ADC can be served by the DMA controller. An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

To synchronize A/D conversion and timers, the ADCs could be triggered by any of TIM1, TIM2, TIM3, TIM4, TIM5, or TIM8 timer.

2.2.35 Temperature sensor

The temperature sensor has to generate a voltage that varies linearly with temperature. The conversion range is between 1.8 V and 3.6 V. The temperature sensor is internally connected to the ADC1_IN16 input channel which is used to convert the sensor output voltage into a digital value.

As the offset of the temperature sensor varies from chip to chip due to process variation, the internal temperature sensor is mainly suitable for applications that detect temperature changes instead of absolute temperatures. If an accurate temperature reading is needed, then an external temperature sensor part should be used.

2.2.36 Digital-to-analog converter (DAC)

The two 12-bit buffered DAC channels can be used to convert two digital signals into two analog voltage signal outputs.

This dual digital Interface supports the following features:

- two DAC converters: one for each output channel
- 8-bit or 12-bit monotonic output
- left or right data alignment in 12-bit mode
- synchronized update capability
- noise-wave generation
- triangular-wave generation
- dual DAC channel independent or simultaneous conversions
- DMA capability for each channel
- external triggers for conversion
- input voltage reference V_{REF+}

Eight DAC trigger inputs are used in the device. The DAC channels are triggered through the timer update outputs that are also connected to different DMA streams.

2.2.37 Serial wire JTAG debug port (SWJ-DP)

The ARM SWJ-DP interface is embedded, and is a combined JTAG and serial wire debug port that enables either a serial wire debug or a JTAG probe to be connected to the target.

Debug is performed using 2 pins only instead of 5 required by the JTAG (JTAG pins could be re-use as GPIO with alternate function): the JTAG TMS and TCK pins are shared with SWDIO and SWCLK, respectively, and a specific sequence on the TMS pin is used to switch between JTAG-DP and SW-DP.

2.2.38 Embedded Trace Macrocell™

The ARM Embedded Trace Macrocell provides a greater visibility of the instruction and data flow inside the CPU core by streaming compressed data at a very high rate from the STM32F40x through a small number of ETM pins to an external hardware trace port analyzer (TPA) device. The TPA is connected to a host computer using USB, Ethernet, or any other high-speed channel. Real-time instruction and data flow activity can be recorded and then formatted for display on the host computer that runs the debugger software. TPA hardware is commercially available from common development tool vendors.

The Embedded Trace Macrocell operates with third party debugger software tools.

3 Pinouts and pin description

Figure 10. STM32F40x LQFP64 pinout

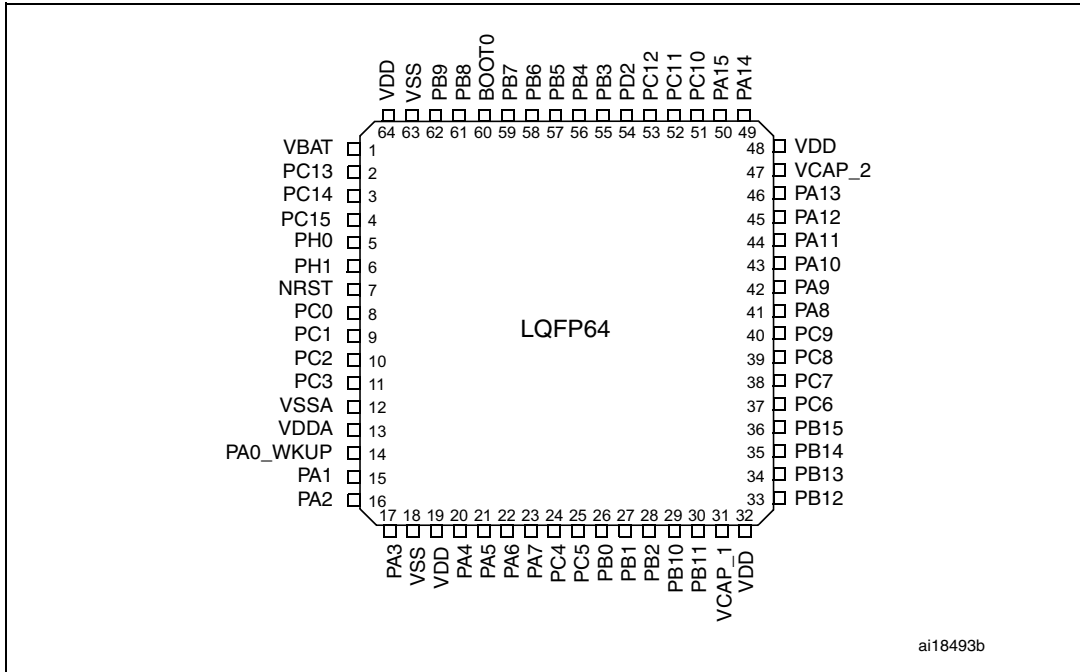
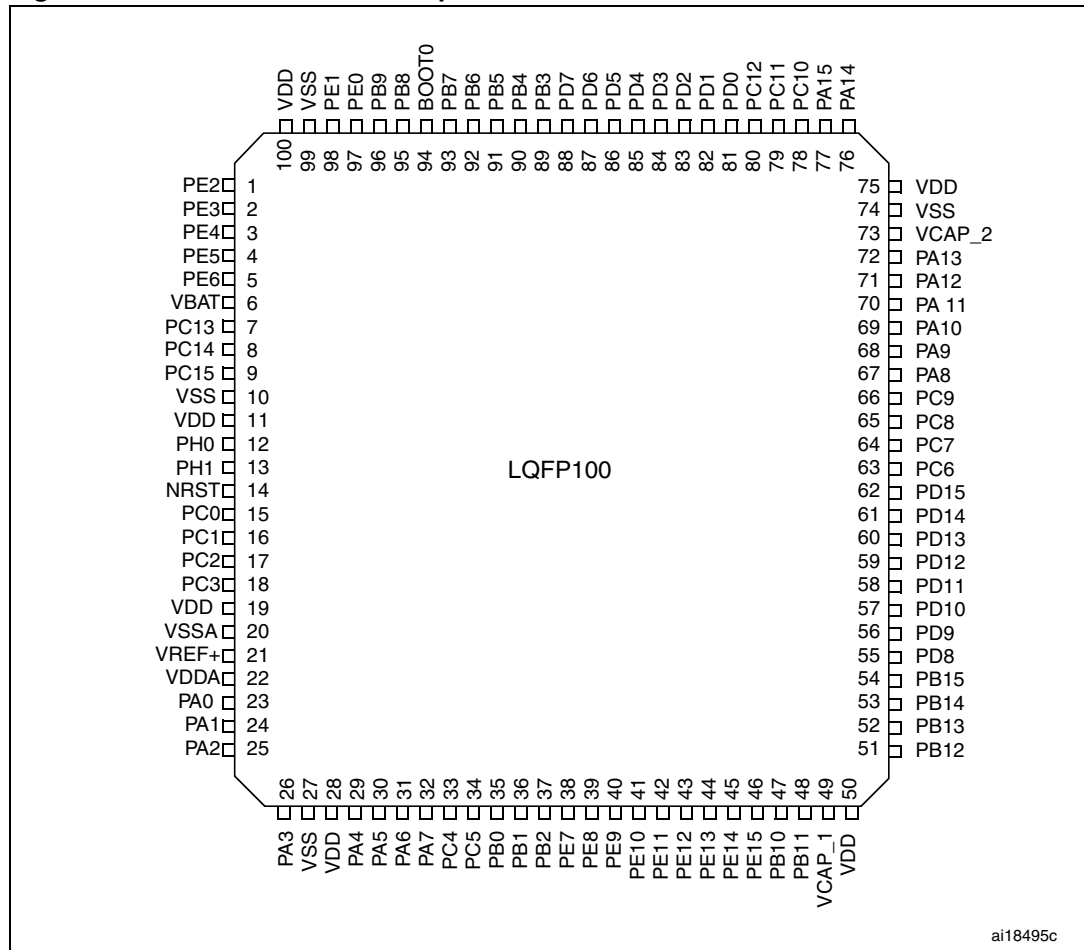
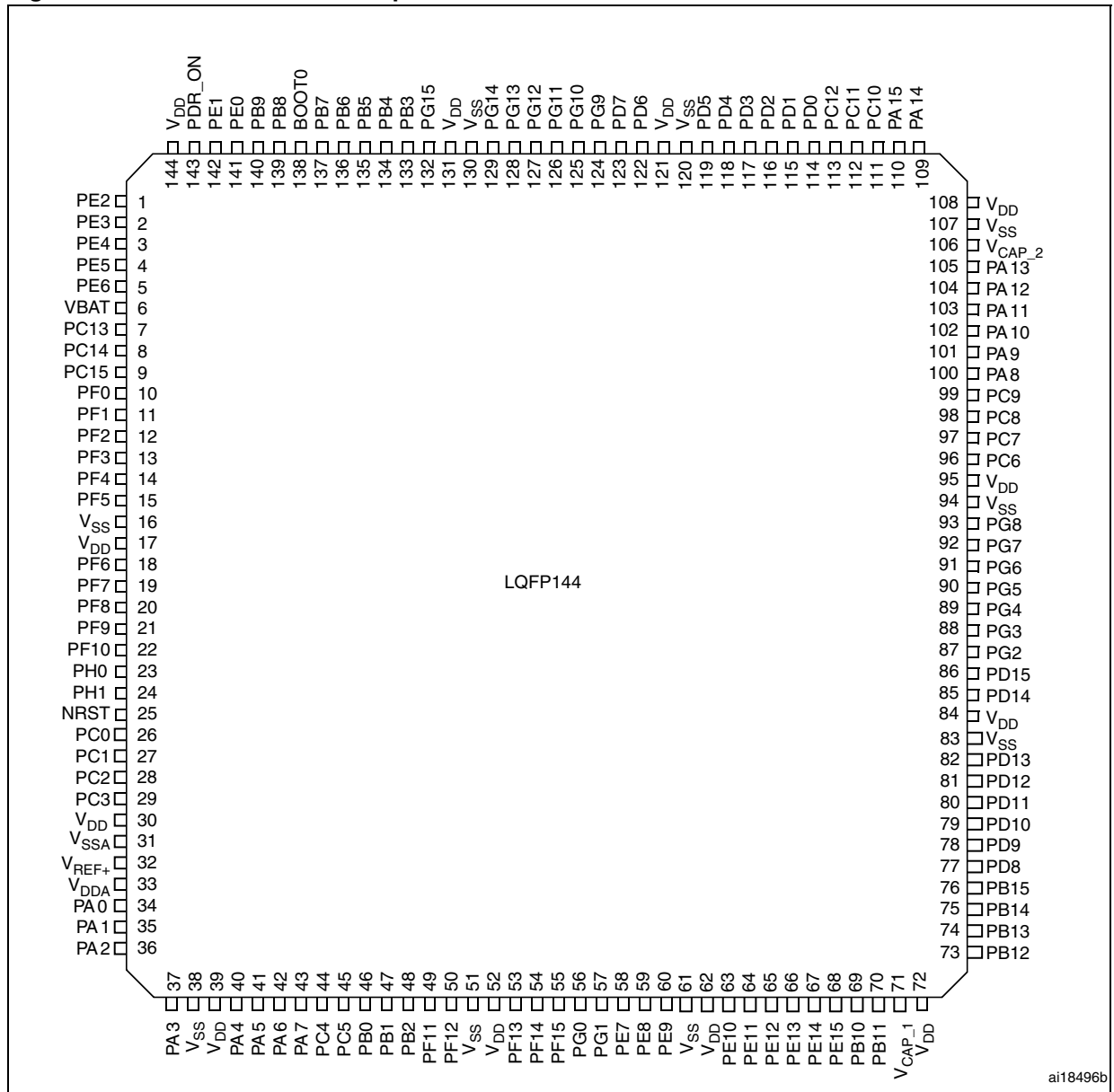


Figure 11. STM32F40x LQFP100 pinout



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Figure 12. STM32F40x LQFP144 pinout



ai18496b

Figure 13. STM32F40x LQFP176 pinout

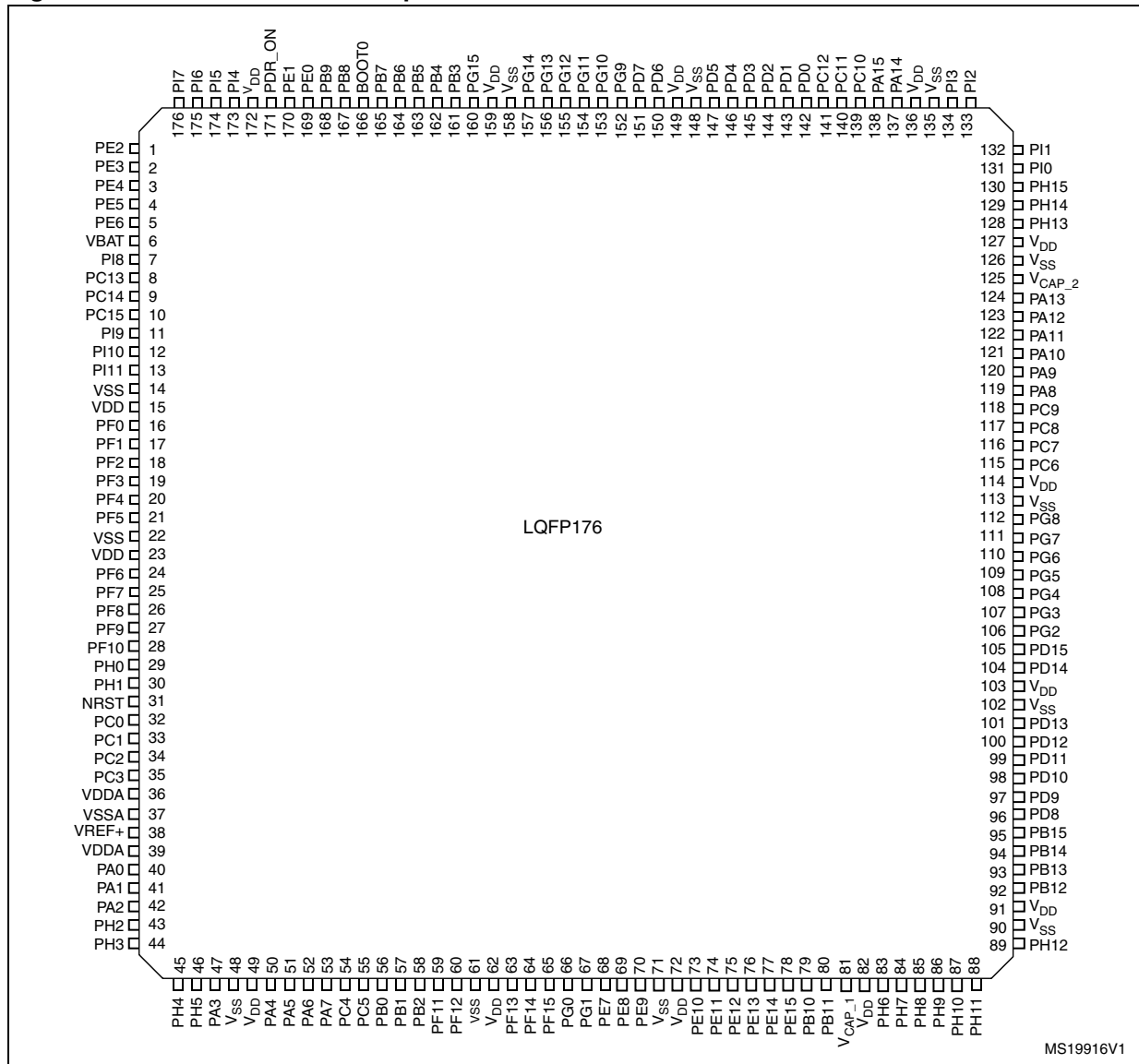


Figure 14. STM32F40x UFBGA176 ballout

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | | | | | |
|---|-------|-----|------|------------|-----|--------|------|------|------|--------|------|------|------|------|------|--------|------|------|------|-----|
| A | PE3 | PE2 | PE1 | PE0 | PB8 | PB5 | PG14 | PG13 | PB4 | PB3 | PD7 | PC12 | PA15 | PA14 | PA13 | | | | | |
| B | PE4 | PE5 | PE6 | PB9 | PB7 | PB6 | PG15 | PG12 | PG11 | PG10 | PD6 | PD0 | PC11 | PC10 | PA12 | | | | | |
| C | VBAT | PI7 | PI6 | PI5 | VDD | PDR_ON | VDD | VDD | VDD | PG9 | PD5 | PD1 | PI3 | PI2 | PA11 | | | | | |
| D | PC13 | PI8 | PI9 | PI4 | VSS | BOOT0 | VSS | VSS | VSS | PD4 | PD3 | PD2 | PH15 | PH1 | PA10 | | | | | |
| E | PC14 | PF0 | PI10 | PI11 | | | | | | | | PH13 | PH14 | PH10 | PA9 | | | | | |
| F | PC15 | VSS | VDD | PH2 | VSS | | | | | VSS | | | | | VSS | VCAP_2 | PC9 | PA8 | | |
| G | PH0 | VSS | VDD | PH3 | VSS | | | | | VSS | | | | | VSS | VDD | PC8 | PC7 | | |
| H | PH1 | PF2 | PF1 | PH4 | VSS | | | | | VSS | | | | | VSS | VDD | PG8 | PC6 | | |
| J | NRST | PF3 | PF4 | PH5 | VSS | | | | | VSS | | | | | VDD | VDD | PG7 | PG6 | | |
| K | PF7 | PF6 | PF5 | VDD | VSS | | | | | VSS | | | | | PH12 | PG5 | PG4 | PG3 | | |
| L | PF10 | PF9 | PF8 | BYPASS_REG | | | | | | | | | | | | | PH11 | PH10 | PD15 | PG2 |
| M | VSSA | PC0 | PC1 | PC2 | PC3 | PB2 | PG1 | VSS | VSS | VCAP_1 | PH6 | PH8 | PH9 | PD14 | PD13 | | | | | |
| N | VREF- | PA1 | PA0 | PA4 | PC4 | PF13 | PG0 | VDD | VDD | VDD | PE13 | PH7 | PD12 | PD11 | PD10 | | | | | |
| P | VREF+ | PA2 | PA6 | PA5 | PC5 | PF12 | PF15 | PE8 | PE9 | PE11 | PE14 | PB12 | PB13 | PD9 | PD8 | | | | | |
| R | VDDA | PA3 | PA7 | PB1 | PB0 | PF11 | PF14 | PE7 | PE10 | PE12 | PE15 | PB10 | PB11 | PB14 | PB15 | | | | | |

ai18497b

1. This figure shows the package top view.

Figure 15. STM32F40x WLCSP90 ballout

| | | | | | | | | | | |
|---|------|------------|--------|-------|------|------|--------|------|------|--------|
| | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| A | VBAT | PC13 | PDR_ON | BOOT0 | PB4 | PD7 | PD4 | PC12 | PA14 | VDD |
| B | PC14 | PC15 | VDD | PB7 | PB3 | PD6 | PD2 | PA15 | PI1 | VCAP_2 |
| C | PA0 | VSS | PB9 | PB6 | PD5 | PD1 | PC11 | PI0 | PA12 | PA11 |
| D | PC2 | BYPASS_REG | PB8 | PB5 | PD0 | PC10 | PA13 | PA10 | PA9 | PA8 |
| E | PC0 | PC3 | VSS | VSS | VDD | VSS | VDD | PC9 | PC8 | PC7 |
| F | PH0 | PH1 | PA1 | VDD | PE10 | PE14 | VCAP_1 | PC6 | PD14 | PD15 |
| G | NRST | VDDA | PA5 | PB0 | PE7 | PE13 | PE15 | PD10 | PD12 | PD11 |
| H | VSSA | PA3 | PA6 | PB1 | PE8 | PE12 | PB10 | PD9 | PD8 | PB15 |
| J | PA2 | PA4 | PA7 | PB2 | PE9 | PE11 | PB11 | PB12 | PB14 | PB13 |

MS30402V1

1. This figure shows the package bump view.

Table 5. Legend/abbreviations used in the pinout table

| Name | Abbreviation | Definition |
|---------------|---|---|
| Pin name | Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name | |
| Pin type | S | Supply pin |
| | I | Input only pin |
| | I/O | Input / output pin |
| I/O structure | FT | 5 V tolerant I/O |
| | FTf | 5 V tolerant I/O, FM+ capable |
| | TTa | 3.3 V tolerant I/O directly connected to ADC |
| | TC | Standard 3.3V I/O |
| | B | Dedicated BOOT0 pin |
| | RST | Bidirectional reset pin with embedded weak pull-up resistor |
| Notes | Unless otherwise specified by a note, all I/Os are set as floating inputs during and after reset | |

Table 5. Legend/abbreviations used in the pinout table (continued)

| Name | Abbreviation | Definition |
|----------------------|--------------|--|
| Alternate functions | | Functions selected through GPIOx_AFR registers |
| Additional functions | | Functions directly selected/enabled through peripheral registers |

Table 6. STM32F40x pin and ball definitions

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|--------|--|--------------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| - | - | 1 | 1 | A2 | 1 | PE2 | I/O | FT | | TRACECLK/ FSMC_A23 / ETH_MII_TXD3 / EVENTOUT | |
| - | - | 2 | 2 | A1 | 2 | PE3 | I/O | FT | | TRACED0/FSMC_A19 / EVENTOUT | |
| - | - | 3 | 3 | B1 | 3 | PE4 | I/O | FT | | TRACED1/FSMC_A20 / DCMI_D4/ EVENTOUT | |
| - | - | 4 | 4 | B2 | 4 | PE5 | I/O | FT | | TRACED2 / FSMC_A21 / TIM9_CH1 / DCMI_D6 / EVENTOUT | |
| - | - | 5 | 5 | B3 | 5 | PE6 | I/O | FT | | TRACED3 / FSMC_A22 / TIM9_CH2 / DCMI_D7 / EVENTOUT | |
| 1 | A10 | 6 | 6 | C1 | 6 | V _{BAT} | S | | | | |
| - | - | - | - | D2 | 7 | PI8 | I/O | FT | (2)(3) | EVENTOUT | RTC_AF2 |
| 2 | A9 | 7 | 7 | D1 | 8 | PC13 | I/O | FT | (2)(3) | EVENTOUT | RTC_AF1 |
| 3 | B10 | 8 | 8 | E1 | 9 | PC14-OSC32_IN (PC14) | I/O | FT | (2)(3) | EVENTOUT | OSC32_IN ⁽⁴⁾ |
| 4 | B9 | 9 | 9 | F1 | 10 | PC15- OSC32_OUT (PC15) | I/O | FT | (2)(3) | EVENTOUT | OSC32_OUT ⁽⁴⁾ |
| - | - | - | - | D3 | 11 | PI9 | I/O | FT | | CAN1_RX / EVENTOUT | |
| - | - | - | - | E3 | 12 | PI10 | I/O | FT | | ETH_MII_RX_ER / EVENTOUT | |
| - | - | - | - | E4 | 13 | PI11 | I/O | FT | | OTG_HS_ULPI_DIR / EVENTOUT | |
| - | - | - | - | F2 | 14 | V _{SS} | S | | | | |
| - | - | - | - | F3 | 15 | V _{DD} | S | | | | |
| - | - | - | 10 | E2 | 16 | PF0 | I/O | FT | | FSMC_A0 / I2C2_SDA / EVENTOUT | |
| - | - | - | 11 | H3 | 17 | PF1 | I/O | FT | | FSMC_A1 / I2C2_SCL / EVENTOUT | |
| - | - | - | 12 | H2 | 18 | PF2 | I/O | FT | | FSMC_A2 / I2C2_SMBA / EVENTOUT | |
| - | - | - | 13 | J2 | 19 | PF3 | I/O | FT | (4) | FSMC_A3/EVENTOUT | ADC3_IN9 |
| - | - | - | 14 | J3 | 20 | PF4 | I/O | FT | (4) | FSMC_A4/EVENTOUT | ADC3_IN14 |
| - | - | - | 15 | K3 | 21 | PF5 | I/O | FT | (4) | FSMC_A5/EVENTOUT | ADC3_IN15 |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|---|------------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| - | C9 | 10 | 16 | G2 | 22 | V _{SS} | S | | | | |
| - | B8 | 11 | 17 | G3 | 23 | V _{DD} | S | | | | |
| - | - | - | 18 | K2 | 24 | PF6 | I/O | FT | (4) | TIM10_CH1 / FSMC_NIORD/ EVENTOUT | ADC3_IN4 |
| - | - | - | 19 | K1 | 25 | PF7 | I/O | FT | (4) | TIM11_CH1/FSMC_NREG/ EVENTOUT | ADC3_IN5 |
| - | - | - | 20 | L3 | 26 | PF8 | I/O | FT | (4) | TIM13_CH1 / FSMC_NIOWR/ EVENTOUT | ADC3_IN6 |
| - | - | - | 21 | L2 | 27 | PF9 | I/O | FT | (4) | TIM14_CH1 / FSMC_CD/ EVENTOUT | ADC3_IN7 |
| - | - | - | 22 | L1 | 28 | PF10 | I/O | FT | (4) | FSMC_INTR/ EVENTOUT | ADC3_IN8 |
| 5 | F10 | 12 | 23 | G1 | 29 | PH0-OSC_IN (PH0) | I/O | FT | | EVENTOUT | OSC_IN ⁽⁴⁾ |
| 6 | F9 | 13 | 24 | H1 | 30 | PH1-OSC_OUT (PH1) | I/O | FT | | EVENTOUT | OSC_OUT ⁽⁴⁾ |
| 7 | G10 | 14 | 25 | J1 | 31 | NRST | I/O | RST | | | |
| 8 | E10 | 15 | 26 | M2 | 32 | PC0 | I/O | FT | (4) | OTG_HS_ULPI_STP/ EVENTOUT | ADC123_IN10 |
| 9 | - | 16 | 27 | M3 | 33 | PC1 | I/O | FT | (4) | ETH_MDC/ EVENTOUT | ADC123_IN11 |
| 10 | D10 | 17 | 28 | M4 | 34 | PC2 | I/O | FT | (4) | SPI2_MISO / OTG_HS_ULPI_DIR / TH_MII_TXD2 /I2S2ext_SD/ EVENTOUT | ADC123_IN12 |
| 11 | E9 | 18 | 29 | M5 | 35 | PC3 | I/O | FT | (4) | SPI2_MOSI / I2S2_SD / OTG_HS_ULPI_NXT / ETH_MII_TX_CLK/ EVENTOUT | ADC123_IN13 |
| - | - | 19 | 30 | G3 | 36 | V _{DD} | S | | | | |
| 12 | H10 | 20 | 31 | M1 | 37 | V _{SSA} | S | | | | |
| - | - | - | - | N1 | - | V _{REF-} | S | | | | |
| - | - | 21 | 32 | P1 | 38 | V _{REF+} | S | | | | |
| 13 | G9 | 22 | 33 | R1 | 39 | V _{DDA} | S | | | | |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|--|--------------------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| 14 | C10 | 23 | 34 | N3 | 40 | PA0-WKUP (PA0) | I/O | FT | (5) | USART2_CTS/ UART4_TX/ ETH_MII_CRX / TIM2_CH1_ETR/ TIM5_CH1 / TIM8_ETR/ EVENTOUT | ADC123_IN0/WKUP ⁽⁴⁾ |
| 15 | F8 | 24 | 35 | N2 | 41 | PA1 | I/O | FT | (4) | USART2_RTS / UART4_RX/ ETH_RMII_REF_CLK / ETH_MII_RX_CLK / TIM5_CH2 / TIMM2_CH2/ EVENTOUT | ADC123_IN1 |
| 16 | J10 | 25 | 36 | P2 | 42 | PA2 | I/O | FT | (4) | USART2_TX/TIM5_CH3 / TIM9_CH1 / TIM2_CH3 / ETH_MDIO/ EVENTOUT | ADC123_IN2 |
| - | - | - | - | F4 | 43 | PH2 | I/O | FT | | ETH_MII_CRX/EVENTOUT | |
| - | - | - | - | G4 | 44 | PH3 | I/O | FT | | ETH_MII_COL/EVENTOUT | |
| - | - | - | - | H4 | 45 | PH4 | I/O | FT | | I2C2_SCL / OTG_HS_ULPI_NXT/ EVENTOUT | |
| - | - | - | - | J4 | 46 | PH5 | I/O | FT | | I2C2_SDA/ EVENTOUT | |
| 17 | H9 | 26 | 37 | R2 | 47 | PA3 | I/O | FT | (4) | USART2_RX/TIM5_CH4 / TIM9_CH2 / TIM2_CH4 / OTG_HS_ULPI_D0 / ETH_MII_COL/ EVENTOUT | ADC123_IN3 |
| 18 | E5 | 27 | 38 | - | 48 | V _{SS} | S | | | | |
| | D9 | | | L4 | - | BYPASS_REG | I | FT | | | |
| 19 | E4 | 28 | 39 | K4 | 49 | V _{DD} | S | | | | |
| 20 | J9 | 29 | 40 | N4 | 50 | PA4 | I/O | TC | (4) | SPI1_NSS / SPI3_NSS / USART2_CK / DCMI_HSYNC / OTG_HS_SOF/ I2S3_WS/ EVENTOUT | ADC12_IN4 /DAC1_OUT |
| 21 | G8 | 30 | 41 | P4 | 51 | PA5 | I/O | TC | (4) | SPI1_SCK/ OTG_HS_ULPI_CK / TIM2_CH1_ETR/ TIM8_CHIN/ EVENTOUT | ADC12_IN5/ DAC2_OUT |
| 22 | H8 | 31 | 42 | P3 | 52 | PA6 | I/O | FT | (4) | SPI1_MISO / TIM8_BKIN/TIM13_CH1 / DCMI_PIXCLK/ TIM3_CH1 / TIM1_BKIN/ EVENTOUT | ADC12_IN6 |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|---|----------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| 23 | J8 | 32 | 43 | R3 | 53 | PA7 | I/O | FT | (4) | SPI1_MOSI/ TIM8_CH1N / TIM14_CH1/TIM3_CH2/ ETH_MII_RX_DV / TIM1_CH1N / RMII_CRD_DV/ EVENTOUT | ADC12_IN7 |
| 24 | - | 33 | 44 | N5 | 54 | PC4 | I/O | FT | (4) | ETH_RMII_RX_D0 / ETH_MII_RX_D0/ EVENTOUT | ADC12_IN14 |
| 25 | - | 34 | 45 | P5 | 55 | PC5 | I/O | FT | (4) | ETH_RMII_RX_D1 / ETH_MII_RX_D1/ EVENTOUT | ADC12_IN15 |
| 26 | G7 | 35 | 46 | R5 | 56 | PB0 | I/O | FT | (4) | TIM3_CH3 / TIM8_CH2N/ OTG_HS_ULPI_D1/ ETH_MII_RXD2 / TIM1_CH2N/ EVENTOUT | ADC12_IN8 |
| 27 | H7 | 36 | 47 | R4 | 57 | PB1 | I/O | FT | (4) | TIM3_CH4 / TIM8_CH3N/ OTG_HS_ULPI_D2/ ETH_MII_RXD3 / TIM1_CH3N/ EVENTOUT | ADC12_IN9 |
| 28 | J7 | 37 | 48 | M6 | 58 | PB2-BOOT1 (PB2) | I/O | FT | | EVENTOUT | |
| - | - | - | 49 | R6 | 59 | PF11 | I/O | FT | | DCMI_12/ EVENTOUT | |
| - | - | - | 50 | P6 | 60 | PF12 | I/O | FT | | FSMC_A6/ EVENTOUT | |
| - | - | - | 51 | M8 | 61 | V _{SS} | S | | | | |
| - | - | - | 52 | N8 | 62 | V _{DD} | S | | | | |
| - | - | - | 53 | N6 | 63 | PF13 | I/O | FT | | FSMC_A7/ EVENTOUT | |
| - | - | - | 54 | R7 | 64 | PF14 | I/O | FT | | FSMC_A8/ EVENTOUT | |
| - | - | - | 55 | P7 | 65 | PF15 | I/O | FT | | FSMC_A9/ EVENTOUT | |
| - | - | - | 56 | N7 | 66 | PG0 | I/O | FT | | FSMC_A10/ EVENTOUT | |
| - | - | - | 57 | M7 | 67 | PG1 | I/O | FT | | FSMC_A11/ EVENTOUT | |
| - | G6 | 38 | 58 | R8 | 68 | PE7 | I/O | FT | | FSMC_D4/TIM1_ETR/ EVENTOUT | |
| - | H6 | 39 | 59 | P8 | 69 | PE8 | I/O | FT | | FSMC_D5/ TIM1_CH1N/ EVENTOUT | |
| - | J6 | 40 | 60 | P9 | 70 | PE9 | I/O | FT | | FSMC_D6/TIM1_CH1/ EVENTOUT | |
| - | - | - | 61 | M9 | 71 | V _{SS} | S | | | | |
| - | - | - | 62 | N9 | 72 | V _{DD} | S | | | | |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|--|----------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| - | F6 | 41 | 63 | R9 | 73 | PE10 | I/O | FT | | FSMC_D7/TIM1_CH2N/ EVENTOUT | |
| - | J5 | 42 | 64 | P10 | 74 | PE11 | I/O | FT | | FSMC_D8/TIM1_CH2/ EVENTOUT | |
| - | H5 | 43 | 65 | R10 | 75 | PE12 | I/O | FT | | FSMC_D9/TIM1_CH3N/ EVENTOUT | |
| - | G5 | 44 | 66 | N11 | 76 | PE13 | I/O | FT | | FSMC_D10/TIM1_CH3/ EVENTOUT | |
| - | F5 | 45 | 67 | P11 | 77 | PE14 | I/O | FT | | FSMC_D11/TIM1_CH4/ EVENTOUT | |
| - | G4 | 46 | 68 | R11 | 78 | PE15 | I/O | FT | | FSMC_D12/TIM1_BKIN/ EVENTOUT | |
| 29 | H4 | 47 | 69 | R12 | 79 | PB10 | I/O | FT | | SPI2_SCK / I2S2_CK / I2C2_SCL/ USART3_TX / OTG_HS_ULPI_D3 / ETH_MII_RX_ER / TIM2_CH3/ EVENTOUT | |
| 30 | J4 | 48 | 70 | R13 | 80 | PB11 | I/O | FT | | I2C2_SDA/USART3_RX/ OTG_HS_ULPI_D4 / ETH_RMII_TX_EN/ ETH_MII_TX_EN / TIM2_CH4/ EVENTOUT | |
| 31 | F4 | 49 | 71 | M10 | 81 | V _{CAP_1} | S | | | | |
| 32 | - | 50 | 72 | N10 | 82 | V _{DD} | S | | | | |
| - | - | - | - | M11 | 83 | PH6 | I/O | FT | | I2C2_SMBA / TIM12_CH1 / ETH_MII_RXD2/ EVENTOUT | |
| - | - | - | - | N12 | 84 | PH7 | I/O | FT | | I2C3_SCL / ETH_MII_RXD3/ EVENTOUT | |
| - | - | - | - | M12 | 85 | PH8 | I/O | FT | | I2C3_SDA / DCMI_HSYNC/ EVENTOUT | |
| - | - | - | - | M13 | 86 | PH9 | I/O | FT | | I2C3_SMBA / TIM12_CH2/ DCMI_D0/ EVENTOUT | |
| - | - | - | - | L13 | 87 | PH10 | I/O | FT | | TIM5_CH1 / DCMI_D1/ EVENTOUT | |
| - | - | - | - | L12 | 88 | PH11 | I/O | FT | | TIM5_CH2 / DCMI_D2/ EVENTOUT | |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|---|----------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| - | - | - | - | K12 | 89 | PH12 | I/O | FT | | TIM5_CH3 / DCMI_D3/ EVENTOUT | |
| - | - | - | - | H12 | 90 | V _{SS} | S | | | | |
| - | - | - | - | J12 | 91 | V _{DD} | S | | | | |
| 33 | J3 | 51 | 73 | P12 | 92 | PB12 | I/O | FT | | SPI2_NSS / I2S2_WS / I2C2_SMBA/ USART3_CK/ TIM1_BKIN / CAN2_RX / OTG_HS_ULPI_D5/ ETH_RMII_TXD0 / ETH_MII_TXD0/ OTG_HS_ID/ EVENTOUT | |
| 34 | J1 | 52 | 74 | P13 | 93 | PB13 | I/O | FT | | SPI2_SCK / I2S2_CK / USART3_CTS/ TIM1_CH1N /CAN2_TX / OTG_HS_ULPI_D6 / ETH_RMII_TXD1 / ETH_MII_TXD1/ EVENTOUT | OTG_HS_VBUS |
| 35 | J2 | 53 | 75 | R14 | 94 | PB14 | I/O | FT | | SPI2_MISO/ TIM1_CH2N / TIM12_CH1 / OTG_HS_DM/ USART3_RTS / TIM8_CH2N/I2S2ext_SD/ EVENTOUT | |
| 36 | H1 | 54 | 76 | R15 | 95 | PB15 | I/O | FT | | SPI2_MOSI / I2S2_SD/ TIM1_CH3N / TIM8_CH3N / TIM12_CH2 / OTG_HS_DP/ EVENTOUT | |
| - | H2 | 55 | 77 | P15 | 96 | PD8 | I/O | FT | | FSMC_D13 / USART3_TX/ EVENTOUT | |
| - | H3 | 56 | 78 | P14 | 97 | PD9 | I/O | FT | | FSMC_D14 / USART3_RX/ EVENTOUT | |
| - | G3 | 57 | 79 | N15 | 98 | PD10 | I/O | FT | | FSMC_D15 / USART3_CK/ EVENTOUT | |
| - | G1 | 58 | 80 | N14 | 99 | PD11 | I/O | FT | | FSMC_CLE / FSMC_A16/USART3_CTS/ EVENTOUT | |
| - | G2 | 59 | 81 | N13 | 100 | PD12 | I/O | FT | | FSMC_ALE/ FSMC_A17/TIM4_CH1 / USART3_RTS/ EVENTOUT | |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|---|----------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| - | - | 60 | 82 | M15 | 101 | PD13 | I/O | FT | | FSMC_A18/TIM4_CH2/ EVENTOUT | |
| - | - | - | 83 | - | 102 | V _{SS} | S | | | | |
| - | - | - | 84 | J13 | 103 | V _{DD} | S | | | | |
| - | F2 | 61 | 85 | M14 | 104 | PD14 | I/O | FT | | FSMC_D0/TIM4_CH3/ EVENTOUT/ EVENTOUT | |
| - | F1 | 62 | 86 | L14 | 105 | PD15 | I/O | FT | | FSMC_D1/TIM4_CH4/ EVENTOUT | |
| - | - | - | 87 | L15 | 106 | PG2 | I/O | FT | | FSMC_A12/ EVENTOUT | |
| - | - | - | 88 | K15 | 107 | PG3 | I/O | FT | | FSMC_A13/ EVENTOUT | |
| - | - | - | 89 | K14 | 108 | PG4 | I/O | FT | | FSMC_A14/ EVENTOUT | |
| - | - | - | 90 | K13 | 109 | PG5 | I/O | FT | | FSMC_A15/ EVENTOUT | |
| - | - | - | 91 | J15 | 110 | PG6 | I/O | FT | | FSMC_INT2/ EVENTOUT | |
| - | - | - | 92 | J14 | 111 | PG7 | I/O | FT | | FSMC_INT3/USART6_CK/ EVENTOUT | |
| - | - | - | 93 | H14 | 112 | PG8 | I/O | FT | | USART6_RTS / ETH_PPS_OUT/ EVENTOUT | |
| - | - | - | 94 | G12 | 113 | V _{SS} | S | | | | |
| - | - | - | 95 | H13 | 114 | V _{DD} | S | | | | |
| 37 | F3 | 63 | 96 | H15 | 115 | PC6 | I/O | FT | | I2S2_MCK / TIM8_CH1/SDIO_D6 / USART6_TX / DCMI_D0/TIM3_CH1/ EVENTOUT | |
| 38 | E1 | 64 | 97 | G15 | 116 | PC7 | I/O | FT | | I2S3_MCK / TIM8_CH2/SDIO_D7 / USART6_RX / DCMI_D1/TIM3_CH2/ EVENTOUT | |
| 39 | E2 | 65 | 98 | G14 | 117 | PC8 | I/O | FT | | TIM8_CH3/SDIO_D0 /TIM3_CH3/ USART6_CK / DCMI_D2/ EVENTOUT | |
| 40 | E3 | 66 | 99 | F14 | 118 | PC9 | I/O | FT | | I2S_CKIN/ MCO2 / TIM8_CH4/SDIO_D1 / /I2C3_SDA / DCMI_D3 / TIM3_CH4/ EVENTOUT | |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|---|----------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| 41 | D1 | 67 | 100 | F15 | 119 | PA8 | I/O | FT | | MCO1 / USART1_CK/ TIM1_CH1/ I2C3_SCL/ OTG_FS_SOF/ EVENTOUT | |
| 42 | D2 | 68 | 101 | E15 | 120 | PA9 | I/O | FT | | USART1_TX/ TIM1_CH2 / I2C3_SMBA / DCMI_D0/ EVENTOUT | OTG_FS_VBUS |
| 43 | D3 | 69 | 102 | D15 | 121 | PA10 | I/O | FT | | USART1_RX/ TIM1_CH3/ OTG_FS_ID/DCMI_D1/ EVENTOUT | |
| 44 | C1 | 70 | 103 | C15 | 122 | PA11 | I/O | FT | | USART1_CTS / CAN1_RX / TIM1_CH4 / OTG_FS_DM/ EVENTOUT | |
| 45 | C2 | 71 | 104 | B15 | 123 | PA12 | I/O | FT | | USART1_RTS / CAN1_TX/ TIM1_ETR/ OTG_FS_DP/ EVENTOUT | |
| 46 | F8 | 72 | 105 | A15 | 124 | PA13 (JTMS-SWDIO) | I/O | FT | | JTMS-SWDIO/ EVENTOUT | |
| 47 | B1 | 73 | 106 | F13 | 125 | V _{CAP_2} | S | | | | |
| - | E7 | 74 | 107 | F12 | 126 | V _{SS} | S | | | | |
| 48 | E6 | 75 | 108 | G13 | 127 | V _{DD} | S | | | | |
| - | - | - | - | E12 | 128 | PH13 | I/O | FT | | TIM8_CH1N / CAN1_TX/ EVENTOUT | |
| - | - | - | - | E13 | 129 | PH14 | I/O | FT | | TIM8_CH2N / DCMI_D4/ EVENTOUT | |
| - | - | - | - | D13 | 130 | PH15 | I/O | FT | | TIM8_CH3N / DCMI_D11/ EVENTOUT | |
| - | C3 | - | - | E14 | 131 | PI0 | I/O | FT | | TIM5_CH4 / SPI2_NSS / I2S2_WS / DCMI_D13/ EVENTOUT | |
| - | B2 | - | - | D14 | 132 | PI1 | I/O | FT | | SPI2_SCK / I2S2_CK / DCMI_D8/ EVENTOUT | |
| - | - | - | - | C14 | 133 | PI2 | I/O | FT | | TIM8_CH4 / SPI2_MISO / DCMI_D9 / I2S2ext_SD/ EVENTOUT | |
| - | - | - | - | C13 | 134 | PI3 | I/O | FT | | TIM8_ETR / SPI2_MOSI / I2S2_SD / DCMI_D10/ EVENTOUT | |
| - | - | - | - | D9 | 135 | V _{SS} | S | | | | |
| - | - | - | - | C9 | 136 | V _{DD} | S | | | | |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|---|----------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| 49 | A2 | 76 | 109 | A14 | 137 | PA14 (JTCK-SWCLK) | I/O | FT | | JTCK-SWCLK/ EVENTOUT | |
| 50 | B3 | 77 | 110 | A13 | 138 | PA15 (JTDI) | I/O | FT | | JTDI/ SPI3_NSS/ I2S3_WS/TIM2_CH1_ETR / SPI1_NSS / EVENTOUT | |
| 51 | D5 | 78 | 111 | B14 | 139 | PC10 | I/O | FT | | SPI3_SCK / I2S3_CK/ UART4_TX/SDIO_D2 / DCMI_D8 / USART3_TX/ EVENTOUT | |
| 52 | C4 | 79 | 112 | B13 | 140 | PC11 | I/O | FT | | UART4_RX/ SPI3_MISO / SDIO_D3 / DCMI_D4/USART3_RX / I2S3ext_SD/ EVENTOUT | |
| 53 | A3 | 80 | 113 | A12 | 141 | PC12 | I/O | FT | | UART5_TX/SDIO_CK / DCMI_D9 / SPI3_MOSI /I2S3_SD / USART3_CK/ EVENTOUT | |
| - | D6 | 81 | 114 | B12 | 142 | PD0 | I/O | FT | | FSMC_D2/CAN1_RX/ EVENTOUT | |
| - | C5 | 82 | 115 | C12 | 143 | PD1 | I/O | FT | | FSMC_D3 / CAN1_TX/ EVENTOUT | |
| 54 | B4 | 83 | 116 | D12 | 144 | PD2 | I/O | FT | | TIM3_ETR/UART5_RX/ SDIO_CMD / DCMI_D11/ EVENTOUT | |
| - | - | 84 | 117 | D11 | 145 | PD3 | I/O | FT | | FSMC_CLK/USART2_CTS / EVENTOUT | |
| - | A4 | 85 | 118 | D10 | 146 | PD4 | I/O | FT | | FSMC_NOE/USART2_RTS / EVENTOUT | |
| - | C6 | 86 | 119 | C11 | 147 | PD5 | I/O | FT | | FSMC_NWE/USART2_TX/ EVENTOUT | |
| - | - | - | 120 | D8 | 148 | V _{SS} | S | | | | |
| - | - | - | 121 | C8 | 149 | V _{DD} | S | | | | |
| - | B5 | 87 | 122 | B11 | 150 | PD6 | I/O | FT | | FSMC_NWAIT/ USART2_RX/ EVENTOUT | |
| - | A5 | 88 | 123 | A11 | 151 | PD7 | I/O | FT | | USART2_CK/FSMC_NE1/ FSMC_NCE2/ EVENTOUT | |
| - | - | - | 124 | C10 | 152 | PG9 | I/O | FT | | USART6_RX / FSMC_NE2/FSMC_NCE3/ EVENTOUT | |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|--|----------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| - | - | - | 125 | B10 | 153 | PG10 | I/O | FT | | FSMC_NCE4_1/ FSMC_NE3/ EVENTOUT | |
| - | - | - | 126 | B9 | 154 | PG11 | I/O | FT | | FSMC_NCE4_2 / ETH_MII_TX_EN/ ETH_RMII_TX_EN/ EVENTOUT | |
| - | - | - | 127 | B8 | 155 | PG12 | I/O | FT | | FSMC_NE4 / USART6_RTS/ EVENTOUT | |
| - | - | - | 128 | A8 | 156 | PG13 | I/O | FT | | FSMC_A24 / USART6_CTS /ETH_MII_TXD0/ ETH_RMII_TXD0/ EVENTOUT | |
| - | - | - | 129 | A7 | 157 | PG14 | I/O | FT | | FSMC_A25 / USART6_TX /ETH_MII_TXD1/ ETH_RMII_TXD1/ EVENTOUT | |
| - | E8 | - | 130 | D7 | 158 | V _{SS} | S | | | | |
| - | F7 | - | 131 | C7 | 159 | V _{DD} | S | | | | |
| - | - | - | 132 | B7 | 160 | PG15 | I/O | FT | | USART6_CTS / DCMI_D13/ EVENTOUT | |
| 55 | B6 | 89 | 133 | A10 | 161 | PB3 (JTDO/ TRACESWO) | I/O | FT | | JTDO/ TRACESWO/ SPI3_SCK / I2S3_CK / TIM2_CH2 / SPI1_SCK/ EVENTOUT | |
| 56 | A6 | 90 | 134 | A9 | 162 | PB4 (NJTRST) | I/O | FT | | NJTRST/ SPI3_MISO / TIM3_CH1 / SPI1_MISO / I2S3ext_SD/ EVENTOUT | |
| 57 | D7 | 91 | 135 | A6 | 163 | PB5 | I/O | FT | | I2C1_SMBA/ CAN2_RX / OTG_HS_ULPI_D7 / ETH_PPS_OUT/TIM3_CH 2 / SPI1_MOSI/ SPI3_MOSI / DCMI_D10 / I2S3_SD/ EVENTOUT | |
| 58 | C7 | 92 | 136 | B6 | 164 | PB6 | I/O | FT | | I2C1_SCL/ TIM4_CH1 / CAN2_TX / DCMI_D5/USART1_TX/ EVENTOUT | |

Table 6. STM32F40x pin and ball definitions (continued)

| Pin number | | | | | | Pin name (function after reset) ⁽¹⁾ | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|------------|---------|---------|---------|----------|---------|--|----------|---------------|-------|---|----------------------|
| LQFP64 | WLCSP90 | LQFP100 | LQFP144 | UFBGA176 | LQFP176 | | | | | | |
| 59 | B7 | 93 | 137 | B5 | 165 | PB7 | I/O | FT | | I2C1_SDA / FSMC_NL / DCMI_VSYNC / USART1_RX/ TIM4_CH2/ EVENTOUT | |
| 60 | A7 | 94 | 138 | D6 | 166 | BOOT0 | I | B | | | V _{PP} |
| 61 | D8 | 95 | 139 | A5 | 167 | PB8 | I/O | FT | | TIM4_CH3/SDIO_D4/ TIM10_CH1 / DCMI_D6 / ETH_MII_TXD3 / I2C1_SCL/ CAN1_RX/ EVENTOUT | |
| 62 | C8 | 96 | 140 | B4 | 168 | PB9 | I/O | FT | | SPI2_NSS/ I2S2_WS / TIM4_CH4/ TIM11_CH1/ SDIO_D5 / DCMI_D7 / I2C1_SDA / CAN1_TX/ EVENTOUT | |
| - | - | 97 | 141 | A4 | 169 | PE0 | I/O | FT | | TIM4_ETR / FSMC_NBL0 / DCMI_D2/ EVENTOUT | |
| - | - | 98 | 142 | A3 | 170 | PE1 | I/O | FT | | FSMC_NBL1 / DCMI_D3/ EVENTOUT | |
| 63 | - | 99 | - | D5 | - | V _{SS} | S | | | | |
| - | A8 | - | 143 | C6 | 171 | PDR_ON | I | FT | | | |
| 64 | A1 | 100 | 144 | C5 | 172 | V _{DD} | S | | | | |
| - | - | - | - | D4 | 173 | PI4 | I/O | FT | | TIM8_BKIN / DCMI_D5/ EVENTOUT | |
| - | - | - | - | C4 | 174 | PI5 | I/O | FT | | TIM8_CH1 / DCMI_VSYNC/ EVENTOUT | |
| - | - | - | - | C3 | 175 | PI6 | I/O | FT | | TIM8_CH2 / DCMI_D6/ EVENTOUT | |
| - | - | - | - | C2 | 176 | PI7 | I/O | FT | | TIM8_CH3 / DCMI_D7/ EVENTOUT | |

- Function availability depends on the chosen device.
- PC13, PC14, PC15 and PI8 are supplied through the power switch. Since the switch only sinks a limited amount of current (3 mA), the use of GPIOs PC13 to PC15 and PI8 in output mode is limited:
 - The speed should not exceed 2 MHz with a maximum load of 30 pF.
 - These I/Os must not be used as a current source (e.g. to drive an LED).
- Main function after the first backup domain power-up. Later on, it depends on the contents of the RTC registers even after reset (because these registers are not reset by the main reset). For details on how to manage these I/Os, refer to the RTC register description sections in the STM32F4xx reference manual, available from the STMicroelectronics website: www.st.com.
- FT = 5 V tolerant except when in analog mode or oscillator mode (for PC14, PC15, PH0 and PH1).

- 5. If the device is delivered in an UFBGA176 or WLCSP90 and the BYPASS_REG pin is set to VDD (Regulator off/internal reset ON mode), then PA0 is used as an internal Reset (active low).

Table 7. FSMC pin definition

| Pins ⁽¹⁾ | FSMC | | | | LQFP100 ⁽²⁾ | WLCSP90 ⁽²⁾ |
|---------------------|-------|----------------|---------------|-------------|------------------------|------------------------|
| | CF | NOR/PSRAM/SRAM | NOR/PSRAM Mux | NAND 16 bit | | |
| PE2 | | A23 | A23 | | Yes | |
| PE3 | | A19 | A19 | | Yes | |
| PE4 | | A20 | A20 | | Yes | |
| PE5 | | A21 | A21 | | Yes | |
| PE6 | | A22 | A22 | | Yes | |
| PF0 | A0 | A0 | | | - | - |
| PF1 | A1 | A1 | | | - | - |
| PF2 | A2 | A2 | | | - | - |
| PF3 | A3 | A3 | | | - | - |
| PF4 | A4 | A4 | | | - | - |
| PF5 | A5 | A5 | | | - | - |
| PF6 | NIORD | | | | - | - |
| PF7 | NREG | | | | - | - |
| PF8 | NIOWR | | | | - | - |
| PF9 | CD | | | | - | - |
| PF10 | INTR | | | | - | - |
| PF12 | A6 | A6 | | | - | - |
| PF13 | A7 | A7 | | | - | - |
| PF14 | A8 | A8 | | | - | - |
| PF15 | A9 | A9 | | | - | - |
| PG0 | A10 | A10 | | | - | - |
| PG1 | | A11 | | | - | - |
| PE7 | D4 | D4 | DA4 | D4 | Yes | Yes |
| PE8 | D5 | D5 | DA5 | D5 | Yes | Yes |
| PE9 | D6 | D6 | DA6 | D6 | Yes | Yes |
| PE10 | D7 | D7 | DA7 | D7 | Yes | Yes |
| PE11 | D8 | D8 | DA8 | D8 | Yes | Yes |
| PE12 | D9 | D9 | DA9 | D9 | Yes | Yes |
| PE13 | D10 | D10 | DA10 | D10 | Yes | Yes |
| PE14 | D11 | D11 | DA11 | D11 | Yes | Yes |
| PE15 | D12 | D12 | DA12 | D12 | Yes | Yes |

Table 7. FSMC pin definition (continued)

| Pins ⁽¹⁾ | FSMC | | | | LQFP100 ⁽²⁾ | WLCSP90 ⁽²⁾ |
|---------------------|--------|--------------------|---------------|-------------|------------------------|------------------------|
| | CF | NOR/PSRAM/ SRAM | NOR/PSRAM Mux | NAND 16 bit | | |
| PD8 | D13 | D13 | DA13 | D13 | Yes | Yes |
| PD9 | D14 | D14 | DA14 | D14 | Yes | Yes |
| PD10 | D15 | D15 | DA15 | D15 | Yes | Yes |
| PD11 | | A16 | A16 | CLE | Yes | Yes |
| PD12 | | A17 | A17 | ALE | Yes | Yes |
| PD13 | | A18 | A18 | | Yes | |
| PD14 | D0 | D0 | DA0 | D0 | Yes | |
| PD15 | D1 | D1 | DA1 | D1 | Yes | |
| PG2 | | A12 | | | - | - |
| PG3 | | A13 | | | - | - |
| PG4 | | A14 | | | - | - |
| PG5 | | A15 | | | - | - |
| PG6 | | | | INT2 | - | - |
| PG7 | | | | INT3 | - | - |
| PD0 | D2 | D2 | DA2 | D2 | Yes | Yes |
| PD1 | D3 | D3 | DA3 | D3 | Yes | Yes |
| PD3 | | CLK | CLK | | Yes | |
| PD4 | NOE | NOE | NOE | NOE | Yes | Yes |
| PD5 | NWE | NWE | NWE | NWE | Yes | Yes |
| PD6 | NWAIT | NWAIT | NWAIT | NWAIT | Yes | Yes |
| PD7 | | NE1 | NE1 | NCE2 | Yes | Yes |
| PG9 | | NE2 | NE2 | NCE3 | - | - |
| PG10 | NCE4_1 | NE3 | NE3 | | - | - |
| PG11 | NCE4_2 | | | | - | - |
| PG12 | | NE4 | NE4 | | - | - |
| PG13 | | A24 | A24 | | - | - |
| PG14 | | A25 | A25 | | - | - |
| PB7 | | NADV | NADV | | Yes | Yes |
| PE0 | | NBL0 | NBL0 | | Yes | |
| PE1 | | NBL1 | NBL1 | | Yes | |

1. Full FSMC features are available on LQFP144, LQFP176, and UFBGA176. The features available on smaller packages are given in the dedicated package column.
2. Ports F and G are not available in devices delivered in 100-pin packages.


Table 8. Alternate function mapping

| Port | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF11 | AF12 | AF13 | AF014 | AF15 |
|--------|------|----------------------|----------------------|--------------|-----------|----------------------------|-----------------------|------------------------|--------------------|---------------------------|-------------------|----------------|----------------------|------------------------------------|------------|----------|
| | SYS | TIM1/2 | TIM3/4/5 | TIM8/9/10/11 | I2C1/2/3 | SPI1/SPI2/ I2S2/I2S2ext | SPI3/I2Sext/ I2S3 | USART1/2/3/ I2S3ext | UART4/5/ USART6 | CAN1/CAN2/ TIM12/13/14 | OTG_FS/ OTG_HS | ETH | FSMC/SDIO/ OTG_FS | DCMI | | |
| Port A | PA0 | | TIM2_CH1 TIM2_ETR | TIM5_CH1 | TIM8_ETR | | | | USART2_CTS | UART4_TX | | | | ETH_MII_CRS | | EVENTOUT |
| | PA1 | | TIM2_CH2 | TIM5_CH2 | | | | | USART2_RTS | UART4_RX | | | | ETH_MII_RX_CLK ETH_RMII_REF_CLK | | EVENTOUT |
| | PA2 | | TIM2_CH3 | TIM5_CH3 | TIM9_CH1 | | | | USART2_TX | | | | | ETH_MDIO | | EVENTOUT |
| | PA3 | | TIM2_CH4 | TIM5_CH4 | TIM9_CH2 | | | | USART2_RX | | | OTG_HS_ULPI_D0 | | ETH_MII_COL | | EVENTOUT |
| | PA4 | | | | | | SPI1_NSS | SPI3_NSS I2S3_WS | USART2_CK | | | | | OTG_HS_SOF | DCMI_HSYNC | EVENTOUT |
| | PA5 | | TIM2_CH1 TIM2_ETR | | TIM8_CH1N | | SPI1_SCK | | | | | OTG_HS_ULPI_CK | | | | EVENTOUT |
| | PA6 | | TIM1_BKIN | TIM3_CH1 | TIM8_BKIN | | SPI1_MISO | | | | TIM13_CH1 | | | | DCMI_PIXCK | EVENTOUT |
| | PA7 | | TIM1_CH1N | TIM3_CH2 | TIM8_CH1N | | SPI1_MOSI | | | | TIM14_CH1 | | | ETH_MII_RX_DV ETH_RMII_CRS_DV | | EVENTOUT |
| | PA8 | MCO1 | TIM1_CH1 | | | I2C3_SCL | | | USART1_CK | | | OTG_FS_SOF | | | | EVENTOUT |
| | PA9 | | TIM1_CH2 | | | I2C3_SMBA | | | USART1_TX | | | | | | DCMI_D0 | EVENTOUT |
| | PA10 | | TIM1_CH3 | | | | | | USART1_RX | | | OTG_FS_ID | | | DCMI_D1 | EVENTOUT |
| | PA11 | | TIM1_CH4 | | | | | | USART1_CTS | | CAN1_RX | OTG_FS_DM | | | | EVENTOUT |
| | PA12 | | TIM1_ETR | | | | | | USART1_RTS | | CAN1_TX | OTG_FS_DP | | | | EVENTOUT |
| | PA13 | JTMS-SWDIO | | | | | | | | | | | | | | EVENTOUT |
| | PA14 | JTCK-SWCLK | | | | | | | | | | | | | | EVENTOUT |
| PA15 | JTDI | TIM2_CH1 TIM2_ETR | | | | SPI1_NSS | SPI3_NSS/ I2S3S_WS | | | | | | | | EVENTOUT | |



Table 8. Alternate function mapping (continued)

| Port | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF11 | AF12 | AF13 | AF014 | AF15 | |
|--------|----------|-------------------|-----------|--------------|-----------|----------------------------|----------------------|------------------------|--------------------|---------------------------|-----------------|-------------------------------|---------------------------------|-----------|------------|----------|----------|
| | SYS | TIM1/2 | TIM3/4/5 | TIM8/9/10/11 | I2C1/2/3 | SPI1/SPI2/ I2S2/I2S2ext | SPI3/I2Sext/ I2S3 | USART1/2/3/ I2S3ext | UART4/5/ USART6 | CAN1/CAN2/ TIM12/13/14 | OTG_FS/ OTG_HS | ETH | FSMC/SDIO/ OTG_FS | DCMI | | | |
| Port B | PB0 | | TIM1_CH2N | TIM3_CH3 | TIM8_CH2N | | | | | | OTG_HS_ULPI_D1 | ETH_MII_RXD2 | | | | EVENTOUT | |
| | PB1 | | TIM1_CH3N | TIM3_CH4 | TIM8_CH3N | | | | | | OTG_HS_ULPI_D2 | ETH_MII_RXD3 | | | | EVENTOUT | |
| | PB2 | | | | | | | | | | | | | | | EVENTOUT | |
| | PB3 | JTDO/ TRACESWO | TIM2_CH2 | | | | SPI1_SCK | SPI3_SCK I2S3_CK | | | | | | | | | EVENTOUT |
| | PB4 | NJTRST | | TIM3_CH1 | | | SPI1_MISO | SPI3_MISO | I2S3ext_SD | | | | | | | | EVENTOUT |
| | PB5 | | | TIM3_CH2 | | I2C1_SMBA | SPI1_MOSI | SPI3_MOSI I2S3_SD | | | CAN2_RX | OTG_HS_ULPI_D7 | ETH_PPS_OUT | | DCMI_D10 | | EVENTOUT |
| | PB6 | | | TIM4_CH1 | | I2C1_SCL | | | USART1_TX | | CAN2_TX | | | | DCMI_D5 | | EVENTOUT |
| | PB7 | | | TIM4_CH2 | | I2C1_SDA | | | USART1_RX | | | | | FSMC_NL | DCMI_VSYNC | | EVENTOUT |
| | PB8 | | | TIM4_CH3 | TIM10_CH1 | I2C1_SCL | | | | | CAN1_RX | | ETH_MII_TXD3 | SDIO_D4 | DCMI_D6 | | EVENTOUT |
| | PB9 | | | TIM4_CH4 | TIM11_CH1 | I2C1_SDA | SPI2_NSS I2S2_WS | | | | CAN1_TX | | | SDIO_D5 | DCMI_D7 | | EVENTOUT |
| | PB10 | | TIM2_CH3 | | | I2C2_SCL | SPI2_SCK I2S2_CK | | USART3_TX | | | OTG_HS_ULPI_D3 | ETH_MII_RX_ER | | | | EVENTOUT |
| | PB11 | | TIM2_CH4 | | | I2C2_SDA | | | USART3_RX | | | OTG_HS_ULPI_D4 | ETH_MII_TX_EN ETH_RMII_TX_EN | | | | EVENTOUT |
| | PB12 | | TIM1_BKIN | | | I2C2_SMBA | SPI2_NSS I2S2_WS | | USART3_CK | | CAN2_RX | OTG_HS_ULPI_D5 | ETH_MII_TXD0 ETH_RMII_TXD0 | OTG_HS_ID | | | EVENTOUT |
| | PB13 | | TIM1_CH1N | | | | SPI2_SCK I2S2_CK | | USART3_CTS | | CAN2_TX | OTG_HS_ULPI_D6 | ETH_MII_TXD1 ETH_RMII_TXD1 | | | | EVENTOUT |
| | PB14 | | TIM1_CH2N | | TIM8_CH2N | | SPI2_MISO | I2S2ext_SD | USART3_RTS | | TIM12_CH1 | | | OTG_HS_DM | | | EVENTOUT |
| PB15 | RTC_50Hz | TIM1_CH3N | | TIM8_CH3N | | SPI2_MOSI I2S2_SD | | | | TIM12_CH2 | | | OTG_HS_DP | | | EVENTOUT | |
| Port C | PC0 | | | | | | | | | | OTG_HS_ULPI_STP | | | | | EVENTOUT | |
| | PC1 | | | | | | | | | | | ETH_MDC | | | | EVENTOUT | |
| | PC2 | | | | | | SPI2_MISO | I2S2ext_SD | | | OTG_HS_ULPI_DIR | ETH_MII_TXD2 | | | | EVENTOUT | |
| | PC3 | | | | | | SPI2_MOSI I2S2_SD | | | | OTG_HS_ULPI_NXT | ETH_MII_TX_CLK | | | | EVENTOUT | |
| | PC4 | | | | | | | | | | | ETH_MII_RXD0 ETH_RMII_RXD0 | | | | EVENTOUT | |
| | PC5 | | | | | | | | | | | ETH_MII_RXD1 ETH_RMII_RXD1 | | | | EVENTOUT | |
| | PC6 | | | TIM3_CH1 | TIM8_CH1 | | I2S2_MCK | | | USART6_TX | | | | SDIO_D6 | DCMI_D0 | | EVENTOUT |
| | PC7 | | | TIM3_CH2 | TIM8_CH2 | | | I2S3_MCK | | USART6_RX | | | | SDIO_D7 | DCMI_D1 | | EVENTOUT |
| | PC8 | | | TIM3_CH3 | TIM8_CH3 | | | | | USART6_CK | | | | SDIO_D0 | DCMI_D2 | | EVENTOUT |
| | PC9 | MCO2 | | TIM3_CH4 | TIM8_CH4 | I2C3_SDA | I2S_CKIN | | | | | | | SDIO_D1 | DCMI_D3 | | EVENTOUT |
| | PC10 | | | | | | | SPI3_SCK/ I2S3S_CK | USART3_TX/ | UART4_TX | | | | SDIO_D2 | DCMI_D8 | | EVENTOUT |
| | PC11 | | | | | | I2S3ext_SD | SPI3_MISO/ | USART3_RX | UART4_RX | | | | SDIO_D3 | DCMI_D4 | | EVENTOUT |
| | PC12 | | | | | | | SPI3_MOSI I2S3_SD | USART3_CK | UART5_TX | | | | SDIO_CK | DCMI_D9 | | EVENTOUT |
| | PC13 | | | | | | | | | | | | | | | | |
| | PC14 | | | | | | | | | | | | | | | | |
| PC15 | | | | | | | | | | | | | | | | | |


Table 8. Alternate function mapping (continued)

| Port | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF11 | AF12 | AF13 | AF014 | AF15 |
|--------|------|-----------|-----------|--------------|----------|----------------------------|----------------------|------------------------|--------------------|---------------------------|----------------|--------------|------------------------|----------|----------|----------|
| | SYS | TIM1/2 | TIM3/4/5 | TIM8/9/10/11 | I2C1/2/3 | SPI1/SPI2/ I2S2/I2S2ext | SPI3/I2Sext/ I2S3 | USART1/2/3/ I2S3ext | UART4/5/ USART6 | CAN1/CAN2/ TIM12/13/14 | OTG_FS/ OTG_HS | ETH | FSMC/SDIO/ OTG_FS | DCMI | | |
| Port D | PD0 | | | | | | | | | CAN1_RX | | | FSMC_D2 | | | EVENTOUT |
| | PD1 | | | | | | | | | CAN1_TX | | | FSMC_D3 | | | EVENTOUT |
| | PD2 | | | TIM3_ETR | | | | | UART5_RX | | | | SDIO_CMD | DCMI_D11 | | EVENTOUT |
| | PD3 | | | | | | | USART2_CTS | | | | | FSMC_CLK | | | EVENTOUT |
| | PD4 | | | | | | | USART2_RTS | | | | | FSMC_NOE | | | EVENTOUT |
| | PD5 | | | | | | | USART2_TX | | | | | FSMC_NWE | | | EVENTOUT |
| | PD6 | | | | | | | USART2_RX | | | | | FSMC_NWAIT | | | EVENTOUT |
| | PD7 | | | | | | | USART2_CK | | | | | FSMC_NE1/ FSMC_NCE2 | | | EVENTOUT |
| | PD8 | | | | | | | USART3_TX | | | | | FSMC_D13 | | | EVENTOUT |
| | PD9 | | | | | | | USART3_RX | | | | | FSMC_D14 | | | EVENTOUT |
| | PD10 | | | | | | | USART3_CK | | | | | FSMC_D15 | | | EVENTOUT |
| | PD11 | | | | | | | USART3_CTS | | | | | FSMC_A16 | | | EVENTOUT |
| | PD12 | | | TIM4_CH1 | | | | | USART3_RTS | | | | FSMC_A17 | | | EVENTOUT |
| | PD13 | | | TIM4_CH2 | | | | | | | | | FSMC_A18 | | | EVENTOUT |
| | PD14 | | | TIM4_CH3 | | | | | | | | | FSMC_D0 | | | EVENTOUT |
| PD15 | | | TIM4_CH4 | | | | | | | | | FSMC_D1 | | | EVENTOUT | |
| Port E | PE0 | | TIM4_ETR | | | | | | | | | | FSMC_NBL0 | DCMI_D2 | | EVENTOUT |
| | PE1 | | | | | | | | | | | | FSMC_BLN1 | DCMI_D3 | | EVENTOUT |
| | PE2 | TRACECLK | | | | | | | | | | ETH_MII_TXD3 | FSMC_A23 | | | EVENTOUT |
| | PE3 | TRACED0 | | | | | | | | | | | FSMC_A19 | | | EVENTOUT |
| | PE4 | TRACED1 | | | | | | | | | | | FSMC_A20 | DCMI_D4 | | EVENTOUT |
| | PE5 | TRACED2 | | | TIM9_CH1 | | | | | | | | FSMC_A21 | DCMI_D6 | | EVENTOUT |
| | PE6 | TRACED3 | | | TIM9_CH2 | | | | | | | | FSMC_A22 | DCMI_D7 | | EVENTOUT |
| | PE7 | | TIM1_ETR | | | | | | | | | | FSMC_D4 | | | EVENTOUT |
| | PE8 | | TIM1_CH1N | | | | | | | | | | FSMC_D5 | | | EVENTOUT |
| | PE9 | | TIM1_CH1 | | | | | | | | | | FSMC_D6 | | | EVENTOUT |
| | PE10 | | TIM1_CH2N | | | | | | | | | | FSMC_D7 | | | EVENTOUT |
| | PE11 | | TIM1_CH2 | | | | | | | | | | FSMC_D8 | | | EVENTOUT |
| | PE12 | | TIM1_CH3N | | | | | | | | | | FSMC_D9 | | | EVENTOUT |
| | PE13 | | TIM1_CH3 | | | | | | | | | | FSMC_D10 | | | EVENTOUT |
| | PE14 | | TIM1_CH4 | | | | | | | | | | FSMC_D11 | | | EVENTOUT |
| PE15 | | TIM1_BKIN | | | | | | | | | | FSMC_D12 | | | EVENTOUT | |



Table 8. Alternate function mapping (continued)

| Port | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF11 | AF12 | AF13 | AF014 | AF15 |
|--------|------|--------|----------|--------------|-----------|----------------------------|----------------------|------------------------|--------------------|---------------------------|----------------|---------------------------------|--------------------------|------|----------|----------|
| | SYS | TIM1/2 | TIM3/4/5 | TIM8/9/10/11 | I2C1/2/3 | SPI1/SPI2/ I2S2/I2S2ext | SPI3/I2Sext/ I2S3 | USART1/2/3/ I2S3ext | UART4/5/ USART6 | CAN1/CAN2/ TIM12/13/14 | OTG_FS/ OTG_HS | ETH | FSMC/SDIO/ OTG_FS | DCMI | | |
| Port F | PF0 | | | | I2C2_SDA | | | | | | | | FSMC_A0 | | | EVENTOUT |
| | PF1 | | | | I2C2_SCL | | | | | | | | FSMC_A1 | | | EVENTOUT |
| | PF2 | | | | I2C2_SMB4 | | | | | | | | FSMC_A2 | | | EVENTOUT |
| | PF3 | | | | | | | | | | | | FSMC_A3 | | | EVENTOUT |
| | PF4 | | | | | | | | | | | | FSMC_A4 | | | EVENTOUT |
| | PF5 | | | | | | | | | | | | FSMC_A5 | | | EVENTOUT |
| | PF6 | | | | TIM10_CH1 | | | | | | | | FSMC_NIORD | | | EVENTOUT |
| | PF7 | | | | TIM11_CH1 | | | | | | | | FSMC_NREG | | | EVENTOUT |
| | PF8 | | | | | | | | | TIM13_CH1 | | | FSMC_NIOWR | | | EVENTOUT |
| | PF9 | | | | | | | | | TIM14_CH1 | | | FSMC_CD | | | EVENTOUT |
| | PF10 | | | | | | | | | | | | FSMC_INTR | | | EVENTOUT |
| | PF11 | | | | | | | | | | | | DCMI_D12 | | | EVENTOUT |
| | PF12 | | | | | | | | | | | | FSMC_A6 | | | EVENTOUT |
| | PF13 | | | | | | | | | | | | FSMC_A7 | | | EVENTOUT |
| | PF14 | | | | | | | | | | | | FSMC_A8 | | | EVENTOUT |
| PF15 | | | | | | | | | | | | FSMC_A9 | | | EVENTOUT | |
| Port G | PG0 | | | | | | | | | | | | FSMC_A10 | | | EVENTOUT |
| | PG1 | | | | | | | | | | | | FSMC_A11 | | | EVENTOUT |
| | PG2 | | | | | | | | | | | | FSMC_A12 | | | EVENTOUT |
| | PG3 | | | | | | | | | | | | FSMC_A13 | | | EVENTOUT |
| | PG4 | | | | | | | | | | | | FSMC_A14 | | | EVENTOUT |
| | PG5 | | | | | | | | | | | | FSMC_A15 | | | EVENTOUT |
| | PG6 | | | | | | | | | | | | FSMC_INT2 | | | EVENTOUT |
| | PG7 | | | | | | | | USART6_CK | | | | FSMC_INT3 | | | EVENTOUT |
| | PG8 | | | | | | | | USART6_RTS | | | ETH_PPS_OUT | | | | EVENTOUT |
| | PG9 | | | | | | | | USART6_RX | | | | FSMC_NE2/ FSMC_NCE3 | | | EVENTOUT |
| | PG10 | | | | | | | | | | | | FSMC_NCE4_1/ FSMC_NE3 | | | EVENTOUT |
| | PG11 | | | | | | | | | | | ETH_MII_TX_EN ETH_RMII_TX_EN | FSMC_NCE4_2 | | | EVENTOUT |
| | PG12 | | | | | | | | USART6_RTS | | | | FSMC_NE4 | | | EVENTOUT |
| | PG13 | | | | | | | | UART6_CTS | | | ETH_MII_TXD0 ETH_RMII_TXD0 | FSMC_A24 | | | EVENTOUT |
| | PG14 | | | | | | | | USART6_TX | | | ETH_MII_TXD1 ETH_RMII_TXD1 | FSMC_A25 | | | EVENTOUT |
| PG15 | | | | | | | | USART6_CTS | | | | DCMI_D13 | | | EVENTOUT | |

Table 8. Alternate function mapping (continued)

| Port | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF11 | AF12 | AF13 | AF014 | AF15 |
|--------|------|--------|----------|--------------|-----------|----------------------------|----------------------|------------------------|--------------------|---------------------------|-------------------|---------------|----------------------|------------|----------|----------|
| | SYS | TIM1/2 | TIM3/4/5 | TIM8/9/10/11 | I2C1/2/3 | SPI1/SPI2/ I2S2/I2S2ext | SPI3/I2Sext/ I2S3 | USART1/2/3/ I2S3ext | UART4/5/ USART6 | CAN1/CAN2/ TIM12/13/14 | OTG_FS/ OTG_HS | ETH | FSMC/SDIO/ OTG_FS | DCMI | | |
| Port H | PH0 | | | | | | | | | | | | | | | |
| | PH1 | | | | | | | | | | | | | | | |
| | PH2 | | | | | | | | | | | ETH_MII_CRS | | | | EVENTOUT |
| | PH3 | | | | | | | | | | | ETH_MII_COL | | | | EVENTOUT |
| | PH4 | | | | | I2C2_SCL | | | | | OTG_HS_ULPI_NXT | | | | | EVENTOUT |
| | PH5 | | | | | I2C2_SDA | | | | | | | | | | EVENTOUT |
| | PH6 | | | | | I2C2_SMBA | | | | TIM12_CH1 | | ETH_MII_RXD2 | | | | EVENTOUT |
| | PH7 | | | | | I2C3_SCL | | | | | | ETH_MII_RXD3 | | | | EVENTOUT |
| | PH8 | | | | | I2C3_SDA | | | | | | | | DCMI_HSYNC | | EVENTOUT |
| | PH9 | | | | | I2C3_SMBA | | | | TIM12_CH2 | | | | DCMI_D0 | | EVENTOUT |
| | PH10 | | | TIM5_CH1 | | | | | | | | | | DCMI_D1 | | EVENTOUT |
| | PH11 | | | TIM5_CH2 | | | | | | | | | | DCMI_D2 | | EVENTOUT |
| | PH12 | | | TIM5_CH3 | | | | | | | | | | DCMI_D3 | | EVENTOUT |
| | PH13 | | | | TIM8_CH1N | | | | | | CAN1_TX | | | | | EVENTOUT |
| | PH14 | | | | TIM8_CH2N | | | | | | | | | DCMI_D4 | | EVENTOUT |
| PH15 | | | | TIM8_CH3N | | | | | | | | | DCMI_D11 | | EVENTOUT | |
| Port I | PI0 | | TIM5_CH4 | | | SPI2_NSS I2S2_WS | | | | | | | DCMI_D13 | | EVENTOUT | |
| | PI1 | | | | | SPI2_SCK I2S2_CK | | | | | | | DCMI_D8 | | EVENTOUT | |
| | PI2 | | | TIM8_CH4 | | SPI2_MISO | I2S2ext_SD | | | | | | DCMI_D9 | | EVENTOUT | |
| | PI3 | | | TIM8_ETR | | SPI2_MOSI I2S2_SD | | | | | | | DCMI_D10 | | EVENTOUT | |
| | PI4 | | | | TIM8_BKIN | | | | | | | | DCMI_D5 | | EVENTOUT | |
| | PI5 | | | | TIM8_CH1 | | | | | | | | DCMI_VSYNC | | EVENTOUT | |
| | PI6 | | | | TIM8_CH2 | | | | | | | | DCMI_D6 | | EVENTOUT | |
| | PI7 | | | | TIM8_CH3 | | | | | | | | DCMI_D7 | | EVENTOUT | |
| | PI8 | | | | | | | | | | | | | | | |
| | PI9 | | | | | | | | | | CAN1_RX | | | | | EVENTOUT |
| | PI10 | | | | | | | | | | | ETH_MII_RX_ER | | | | EVENTOUT |
| PI11 | | | | | | | | | | OTG_HS_ULPI_DIR | | | | | EVENTOUT | |

4 Memory mapping

The memory map is shown in *Figure 16*.

Figure 16. STM32F40x memory map

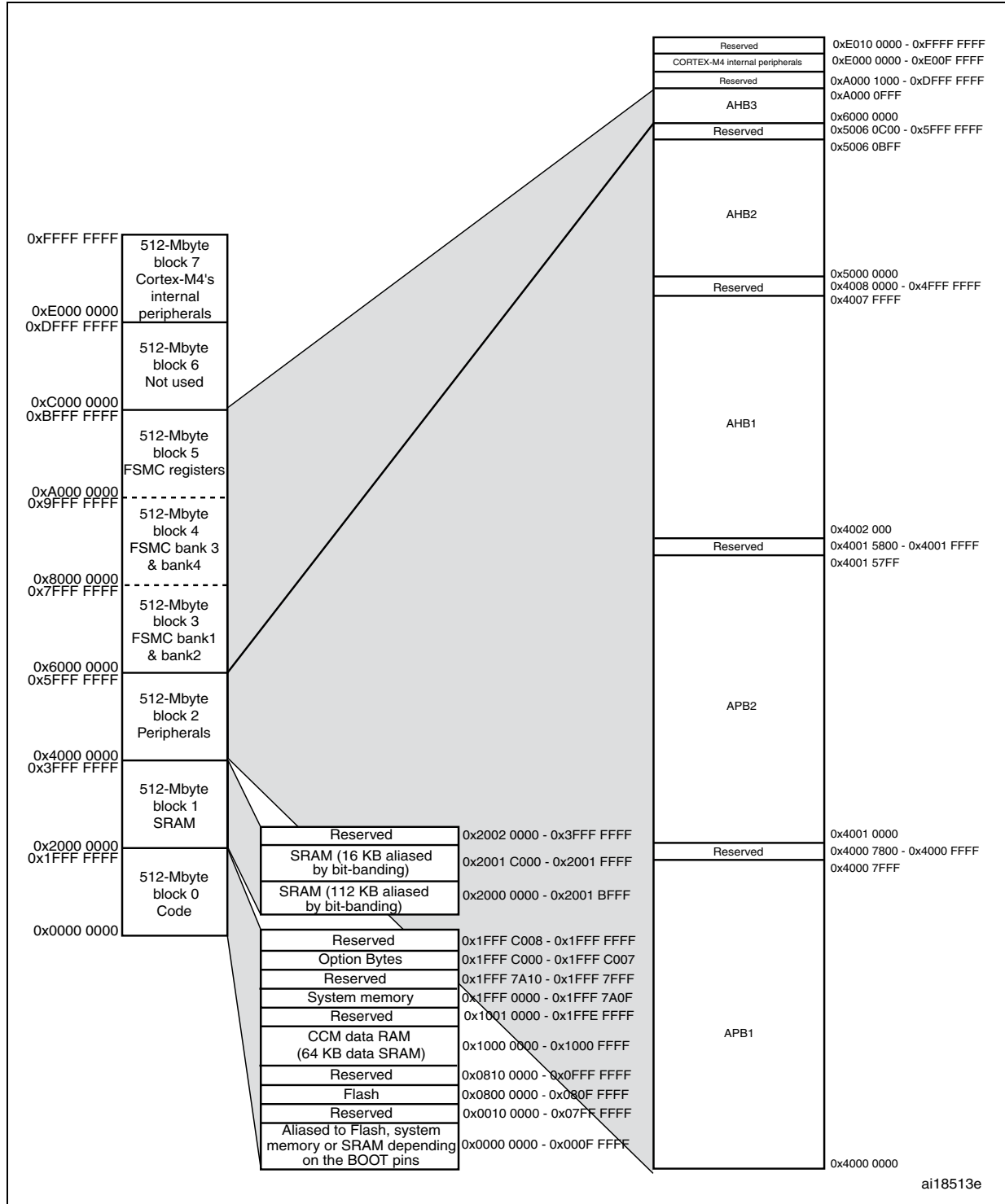


Table 9. STM32F40x register boundary addresses

| Bus | Boundary address | Peripheral |
|-----------|---------------------------|--------------------------------|
| | 0xE00F FFFF - 0xFFFF FFFF | Reserved |
| Cortex-M4 | 0xE000 0000 - 0xE00F FFFF | Cortex-M4 internal peripherals |
| | 0xA000 1000 - 0xDFFF FFFF | Reserved |
| AHB3 | 0xA000 0000 - 0xA000 0FFF | FSMC control register |
| | 0x9000 0000 - 0x9FFF FFFF | FSMC bank 4 |
| | 0x8000 0000 - 0x8FFF FFFF | FSMC bank 3 |
| | 0x7000 0000 - 0x7FFF FFFF | FSMC bank 2 |
| | 0x6000 0000 - 0x6FFF FFFF | FSMC bank 1 |
| | 0x5006 0C00- 0x5FFF FFFF | Reserved |
| AHB2 | 0x5006 0800 - 0x5006 0BFF | RNG |
| | 0x5005 0400 - 0x5006 07FF | Reserved |
| | 0x5005 0000 - 0x5005 03FF | DCMI |
| | 0x5004 0000- 0x5004 FFFF | Reserved |
| | 0x5000 0000 - 0x5003 FFFF | USB OTG FS |
| | 0x4008 0000- 0x4FFF FFFF | Reserved |

Table 9. STM32F40x register boundary addresses (continued)

| Bus | Boundary address | Peripheral |
|------|---------------------------|--------------------------|
| AHB1 | 0x4004 0000 - 0x4007 FFFF | USB OTG HS |
| | 0x4002 9400 - 0x4003 FFFF | Reserved |
| | 0x4002 9000 - 0x4002 93FF | ETHERNET MAC |
| | 0x4002 8C00 - 0x4002 8FFF | |
| | 0x4002 8800 - 0x4002 8BFF | |
| | 0x4002 8400 - 0x4002 87FF | |
| | 0x4002 8000 - 0x4002 83FF | |
| | 0x4002 6800 - 0x4002 7FFF | |
| | 0x4002 6400 - 0x4002 67FF | DMA2 |
| | 0x4002 6000 - 0x4002 63FF | DMA1 |
| | 0x4002 5000 - 0x4002 5FFF | Reserved |
| | 0x4002 4000 - 0x4002 4FFF | BKPSRAM |
| | 0x4002 3C00 - 0x4002 3FFF | Flash interface register |
| | 0x4002 3800 - 0x4002 3BFF | RCC |
| | 0x4002 3400 - 0x4002 37FF | Reserved |
| | 0x4002 3000 - 0x4002 33FF | CRC |
| | 0x4002 2400 - 0x4002 2FFF | Reserved |
| | 0x4002 2000 - 0x4002 23FF | GPIOI |
| | 0x4002 1C00 - 0x4002 1FFF | GPIOH |
| | 0x4002 1800 - 0x4002 1BFF | GPIOG |
| | 0x4002 1400 - 0x4002 17FF | GPIOF |
| | 0x4002 1000 - 0x4002 13FF | GPIOE |
| | 0x4002 0C00 - 0x4002 0FFF | GIPOD |
| | 0x4002 0800 - 0x4002 0BFF | GPIOC |
| | 0x4002 0400 - 0x4002 07FF | GPIOB |
| | 0x4002 0000 - 0x4002 03FF | GPIOA |
| | | 0x4001 5800- 0x4001 FFFF |

Table 9. STM32F40x register boundary addresses (continued)

| Bus | Boundary address | Peripheral |
|------|---------------------------|--------------------------|
| APB2 | 0x4001 4C00 - 0x4001 57FF | Reserved |
| | 0x4001 4800 - 0x4001 4BFF | TIM11 |
| | 0x4001 4400 - 0x4001 47FF | TIM10 |
| | 0x4001 4000 - 0x4001 43FF | TIM9 |
| | 0x4001 3C00 - 0x4001 3FFF | EXTI |
| | 0x4001 3800 - 0x4001 3BFF | SYSCFG |
| | 0x4001 3400 - 0x4001 37FF | Reserved |
| | 0x4001 3000 - 0x4001 33FF | SPI1 |
| | 0x4001 2C00 - 0x4001 2FFF | SDIO |
| | 0x4001 2400 - 0x4001 2BFF | Reserved |
| | 0x4001 2000 - 0x4001 23FF | ADC1 - ADC2 - ADC3 |
| | 0x4001 1800 - 0x4001 1FFF | Reserved |
| | 0x4001 1400 - 0x4001 17FF | USART6 |
| | 0x4001 1000 - 0x4001 13FF | USART1 |
| | 0x4001 0800 - 0x4001 0FFF | Reserved |
| | 0x4001 0400 - 0x4001 07FF | TIM8 |
| | 0x4001 0000 - 0x4001 03FF | TIM1 |
| | | 0x4000 7800- 0x4000 FFFF |

Table 9. STM32F40x register boundary addresses (continued)

| Bus | Boundary address | Peripheral |
|---------------------------|---------------------------|---------------------|
| APB1 | 0x4000 7800 - 0x4000 7FFF | Reserved |
| | 0x4000 7400 - 0x4000 77FF | DAC |
| | 0x4000 7000 - 0x4000 73FF | PWR |
| | 0x4000 6C00 - 0x4000 6FFF | Reserved |
| | 0x4000 6800 - 0x4000 6BFF | CAN2 |
| | 0x4000 6400 - 0x4000 67FF | CAN1 |
| | 0x4000 6000 - 0x4000 63FF | Reserved |
| | 0x4000 5C00 - 0x4000 5FFF | I2C3 |
| | 0x4000 5800 - 0x4000 5BFF | I2C2 |
| | 0x4000 5400 - 0x4000 57FF | I2C1 |
| | 0x4000 5000 - 0x4000 53FF | UART5 |
| | 0x4000 4C00 - 0x4000 4FFF | UART4 |
| | 0x4000 4800 - 0x4000 4BFF | USART3 |
| | 0x4000 4400 - 0x4000 47FF | USART2 |
| | 0x4000 4000 - 0x4000 43FF | I2S3ext |
| | 0x4000 3C00 - 0x4000 3FFF | SPI3 / I2S3 |
| | 0x4000 3800 - 0x4000 3BFF | SPI2 / I2S2 |
| | 0x4000 3400 - 0x4000 37FF | I2S2ext |
| | 0x4000 3000 - 0x4000 33FF | IWDG |
| | 0x4000 2C00 - 0x4000 2FFF | WWDG |
| | 0x4000 2800 - 0x4000 2BFF | RTC & BKP Registers |
| | 0x4000 2400 - 0x4000 27FF | Reserved |
| | 0x4000 2000 - 0x4000 23FF | TIM14 |
| | 0x4000 1C00 - 0x4000 1FFF | TIM13 |
| | 0x4000 1800 - 0x4000 1BFF | TIM12 |
| | 0x4000 1400 - 0x4000 17FF | TIM7 |
| | 0x4000 1000 - 0x4000 13FF | TIM6 |
| | 0x4000 0C00 - 0x4000 0FFF | TIM5 |
| | 0x4000 0800 - 0x4000 0BFF | TIM4 |
| | 0x4000 0400 - 0x4000 07FF | TIM3 |
| 0x4000 0000 - 0x4000 03FF | TIM2 | |

5 Electrical characteristics

5.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to V_{SS} .

5.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at $T_A = 25\text{ }^\circ\text{C}$ and $T_A = T_{A\text{max}}$ (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation ($\text{mean} \pm 3\sigma$).

5.1.2 Typical values

Unless otherwise specified, typical data are based on $T_A = 25\text{ }^\circ\text{C}$, $V_{DD} = 3.3\text{ V}$ (for the $1.8\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ voltage range). They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated ($\text{mean} \pm 2\sigma$).

5.1.3 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

5.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in [Figure 17](#).

5.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in [Figure 18](#).

Figure 17. Pin loading conditions

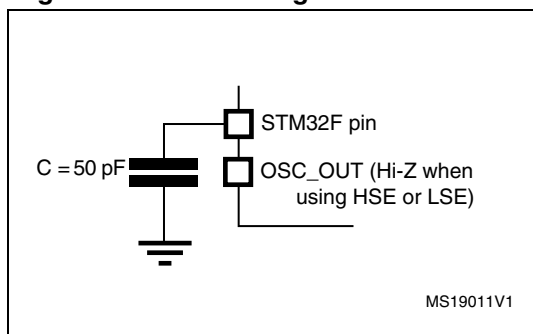
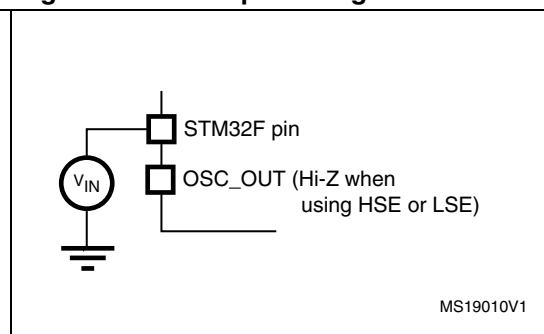
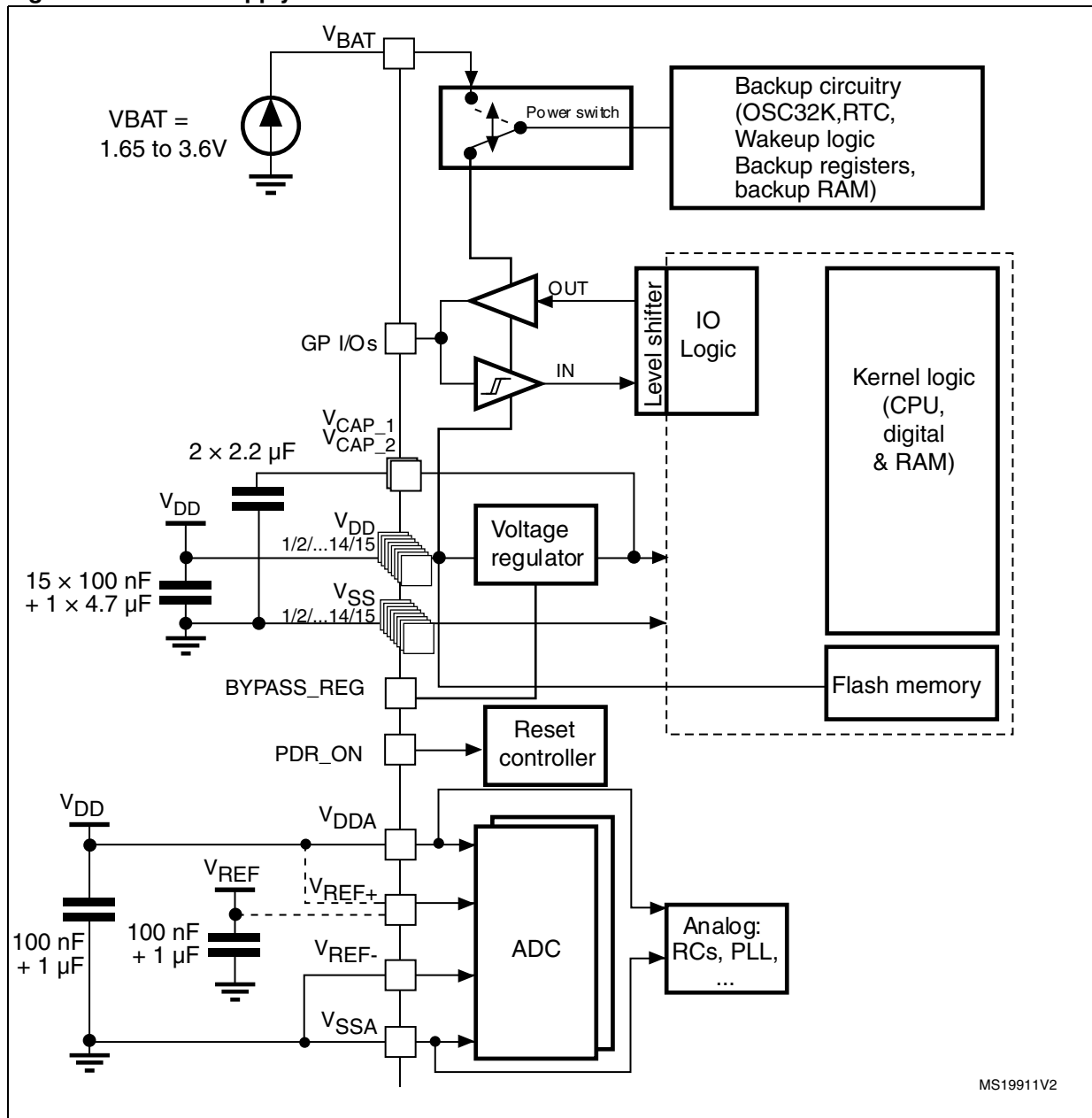


Figure 18. Pin input voltage



5.1.6 Power supply scheme

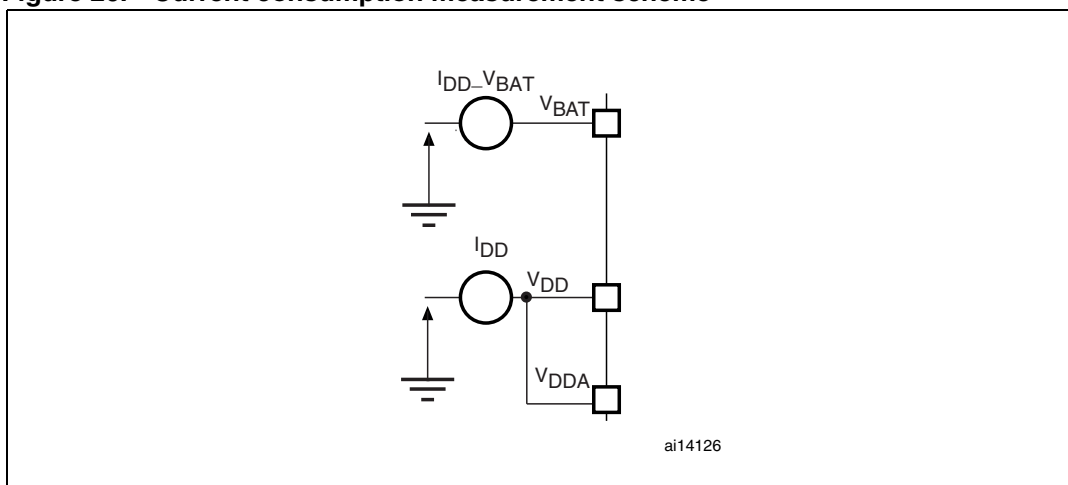
Figure 19. Power supply scheme



1. Each power supply pair must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB to ensure the good functionality of the device.
2. To connect BYPASS_REG and PDR_ON pins, refer to [Section 2.2.16: Voltage regulator](#).
3. The two 2.2 μF ceramic capacitors should not be connected when the voltage regulator is OFF.
4. The 4.7 μF ceramic capacitor must be connected to one of the V_{DD} pins.
5. V_{DDA}=V_{DD} and V_{SSA}=V_{SS}.

5.1.7 Current consumption measurement

Figure 20. Current consumption measurement scheme



5.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in [Table 10: Voltage characteristics](#), [Table 11: Current characteristics](#), and [Table 12: Thermal characteristics](#) may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 10. Voltage characteristics

| Symbol | Ratings | Min | Max | Unit |
|----------------------|---|---|------------|------|
| $V_{DD}-V_{SS}$ | External main supply voltage (including V_{DDA} , V_{DD}) ⁽¹⁾ | -0.3 | 4.0 | V |
| V_{IN} | Input voltage on five-volt tolerant pin ⁽²⁾ | $V_{SS}-0.3$ | $V_{DD}+4$ | |
| | Input voltage on any other pin | $V_{SS}-0.3$ | 4.0 | |
| $ ΔV_{DDx} $ | Variations between different V_{DD} power pins | - | 50 | mV |
| $ V_{SSx} - V_{SS} $ | Variations between all the different ground pins | - | 50 | |
| $V_{ESD(HBM)}$ | Electrostatic discharge voltage (human body model) | see Section 5.3.14: Absolute maximum ratings (electrical sensitivity) | | |

1. All main power (V_{DD} , V_{DDA}) and ground (V_{SS} , V_{SSA}) pins must always be connected to the external power supply, in the permitted range.
2. V_{IN} maximum value must always be respected. Refer to [Table 11](#) for the values of the maximum allowed injected current.

Table 11. Current characteristics

| Symbol | Ratings | Max. | Unit |
|--------------------------------------|---|-------|------|
| I_{VDD} | Total current into V_{DD} power lines (source) ⁽¹⁾ | 150 | mA |
| I_{VSS} | Total current out of V_{SS} ground lines (sink) ⁽¹⁾ | 150 | |
| I_{IO} | Output current sunk by any I/O and control pin | 25 | |
| | Output current source by any I/Os and control pin | 25 | |
| $I_{INJ(PIN)}$ ⁽²⁾ | Injected current on five-volt tolerant I/O ⁽³⁾ | -5/+0 | |
| | Injected current on any other pin ⁽⁴⁾ | ±5 | |
| $\Sigma I_{INJ(PIN)}$ ⁽⁴⁾ | Total injected current (sum of all I/O and control pins) ⁽⁵⁾ | ±25 | |

1. All main power (V_{DD} , V_{DDA}) and ground (V_{SS} , V_{SSA}) pins must always be connected to the external power supply, in the permitted range.
2. Negative injection disturbs the analog performance of the device. See note in [Section 5.3.20: 12-bit ADC characteristics](#).
3. Positive injection is not possible on these I/Os. A negative injection is induced by $V_{IN} < V_{SS}$. $I_{INJ(PIN)}$ must never be exceeded. Refer to [Table 10](#) for the values of the maximum allowed input voltage.
4. A positive injection is induced by $V_{IN} > V_{DD}$ while a negative injection is induced by $V_{IN} < V_{SS}$. $I_{INJ(PIN)}$ must never be exceeded. Refer to [Table 10](#) for the values of the maximum allowed input voltage.
5. When several inputs are submitted to a current injection, the maximum $\Sigma I_{INJ(PIN)}$ is the absolute sum of the positive and negative injected currents (instantaneous values).

Table 12. Thermal characteristics

| Symbol | Ratings | Value | Unit |
|-----------|------------------------------|-------------|------|
| T_{STG} | Storage temperature range | -65 to +150 | °C |
| T_J | Maximum junction temperature | 125 | °C |

5.3 Operating conditions

5.3.1 General operating conditions

Table 13. General operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------------------|---|---|--------------------|-----|------|
| f_{HCLK} | Internal AHB clock frequency | VOS bit in PWR_CR register = 0 ⁽¹⁾ | 0 | 144 | MHz |
| | | VOS bit in PWR_CR register= 1 | 0 | 168 | |
| f_{PCLK1} | Internal APB1 clock frequency | | 0 | 42 | |
| f_{PCLK2} | Internal APB2 clock frequency | | 0 | 84 | |
| V_{DD} | Standard operating voltage | | 1.8 ⁽²⁾ | 3.6 | V |
| V_{DDA} ⁽³⁾⁽⁴⁾ | Analog operating voltage (ADC limited to 1.2 M samples) | Must be the same potential as V_{DD} ⁽⁵⁾ | 1.8 ⁽²⁾ | 3.6 | V |
| | Analog operating voltage (ADC limited to 1.4 M samples) | | 2.4 | 3.6 | |
| V_{BAT} | Backup operating voltage | | 1.65 | 3.6 | V |

Table 13. General operating conditions (continued)

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------|--|--------------------------------------|-----|-----|------|
| V_{CAP1} | When the internal regulator is ON, V_{CAP_1} and V_{CAP_2} pins are used to connect a stabilization capacitor. When the internal regulator is OFF (BYPASS_REG connected to V_{DD}), V_{CAP_1} and V_{CAP_2} must be supplied from 1.2 V. | | | | |
| V_{CAP2} | | | 1.1 | 1.3 | V |
| P_D | Power dissipation at $T_A = 85\text{ °C}$ for suffix 6 or $T_A = 105\text{ °C}$ for suffix 7 ⁽⁶⁾ | LQFP64 | - | 435 | mW |
| | | LQFP100 | - | 465 | |
| | | LQFP144 | - | 500 | |
| | | LQFP176 | - | 526 | |
| | | UFBGA176 | - | 513 | |
| | | WLCSP90 | - | 543 | |
| T_A | Ambient temperature for 6 suffix version | Maximum power dissipation | -40 | 85 | °C |
| | | Low power dissipation ⁽⁷⁾ | -40 | 105 | |
| | Ambient temperature for 7 suffix version | Maximum power dissipation | -40 | 105 | °C |
| | | Low power dissipation ⁽⁷⁾ | -40 | 125 | |
| T_J | Junction temperature range | 6 suffix version | -40 | 105 | °C |
| | | 7 suffix version | -40 | 125 | |

- The average expected gain in power consumption when $VOS = 0$ compared to $VOS = 1$ is around 10% for the whole temperature range, when the system clock frequency is between 30 and 144 MHz.
- If an inverted reset signal is applied to PDR_ON, this value can be lowered to 1.7 V when the device operates in a reduced temperature range (0 to 70 °C).
- When the ADC is used, refer to [Table 67: ADC characteristics](#).
- If V_{REF+} pin is present, it must respect the following condition: $V_{DDA} - V_{REF+} < 1.2\text{ V}$.
- It is recommended to power V_{DD} and V_{DDA} from the same source. A maximum difference of 300 mV between V_{DD} and V_{DDA} can be tolerated during power-up and power-down operation.
- If T_A is lower, higher P_D values are allowed as long as T_J does not exceed T_{Jmax} .
- In low power dissipation state, T_A can be extended to this range as long as T_J does not exceed T_{Jmax} .

Table 14. Limitations depending on the operating power supply range

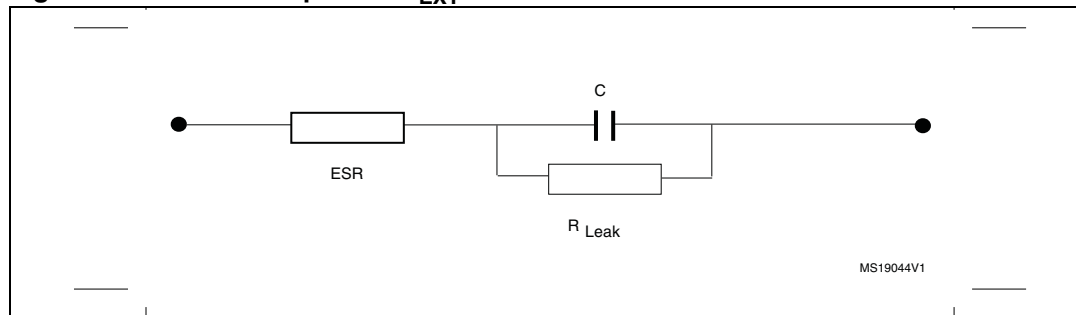
| Operating power supply range | ADC operation | Maximum Flash memory access frequency (f _{Flashmax}) | Number of wait states at maximum CPU frequency ⁽¹⁾ | I/O operation | Maximum FSMC_CLK frequency for synchronous accesses | Possible Flash memory operations |
|---|--------------------------------|--|---|--|--|---|
| V _{DD} = 1.8 to 2.1 V ⁽²⁾ | Conversion time up to 1.2 Msps | 16 MHz with no Flash memory wait state ⁽³⁾ | 7 ⁽³⁾⁽⁴⁾ | – Degraded speed performance – No I/O compensation | up to 30 MHz | 8-bit erase and program operations only |
| V _{DD} = 2.1 to 2.4 V | Conversion time up to 1.2 Msps | 18 MHz with no Flash memory wait state | 7 ⁽⁴⁾ | – Degraded speed performance – No I/O compensation | up to 30 MHz | 16-bit erase and program operations |
| V _{DD} = 2.4 to 2.7 V | Conversion time up to 2.4 Msps | 24 MHz with no Flash memory wait state | 6 ⁽⁴⁾ | – Degraded speed performance – I/O compensation works | up to 48 MHz | 16-bit erase and program operations |
| V _{DD} = 2.7 to 3.6 V ⁽⁵⁾ | Conversion time up to 2.4 Msps | 30 MHz with no Flash memory wait state | 5 ⁽⁴⁾ | – Full-speed operation – I/O compensation works | – up to 60 MHz when V _{DD} = 3.0 to 3.6 V – up to 48 MHz when V _{DD} = 2.7 to 3.0 V | 32-bit erase and program operations |

1. The number of wait states can be reduced by reducing the CPU frequency.
2. If an inverted reset signal is applied to PDR_ON, this value can be lowered to 1.7 V when the device operates in a reduced temperature range (0 to 70 °C).
3. Prefetch is not available. Refer to AN3430 application note for details on how to adjust performance and power.
4. Thanks to the ART accelerator and the 128-bit Flash memory, the number of wait states given here does not impact the execution speed from Flash memory since the ART accelerator allows to achieve a performance equivalent to 0 wait state program execution.
5. The voltage range for OTG USB FS can drop down to 2.7 V. However it is degraded between 2.7 and 3 V.

5.3.2 VCAP1/VCAP2 external capacitor

Stabilization for the main regulator is achieved by connecting an external capacitor C_{EXT} to the VCAP1/VCAP2 pins. C_{EXT} is specified in [Table 15](#).

Figure 21. External capacitor C_{EXT}



1. Legend: ESR is the equivalent series resistance.

Table 15. VCAP1/VCAP2 operating conditions

| Symbol | Parameter | Conditions |
|------------------|-----------------------------------|------------|
| C _{EXT} | Capacitance of external capacitor | 2.2 μF |
| ESR | ESR of external capacitor | < 2 Ω |

5.3.3 Operating conditions at power-up / power-down (regulator ON)

Subject to general operating conditions for T_A .

Table 16. Operating conditions at power-up / power-down (regulator ON)

| Symbol | Parameter | Min | Max | Unit |
|-----------|-------------------------|-----|-----|------|
| t_{VDD} | V_{DD} rise time rate | 20 | ∞ | μs/V |
| | V_{DD} fall time rate | 20 | ∞ | |

5.3.4 Operating conditions at power-up / power-down (regulator OFF)

Subject to general operating conditions for T_A .

Table 17. Operating conditions at power-up / power-down (regulator OFF)⁽¹⁾

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------|--|------------|-----|-----|------|
| t_{VDD} | V_{DD} rise time rate | Power-up | 20 | ∞ | μs/V |
| | V_{DD} fall time rate | Power-down | 20 | ∞ | |
| t_{VCAP} | V_{CAP_1} and V_{CAP_2} rise time rate | Power-up | 20 | ∞ | |
| | V_{CAP_1} and V_{CAP_2} fall time rate | Power-down | 20 | ∞ | |

1. To reset the internal logic at power-down, a reset must be applied on pin PA0 when V_{DD} reach below 1.08 V.

5.3.5 Embedded reset and power control block characteristics

The parameters given in [Table 18](#) are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 13](#).

Table 18. Embedded reset and power control block characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------------------|---|-----------------------------|---------------------|------|------|------|
| V_{PVD} | Programmable voltage detector level selection | PLS[2:0]=000 (rising edge) | 2.09 | 2.14 | 2.19 | V |
| | | PLS[2:0]=000 (falling edge) | 1.98 | 2.04 | 2.08 | V |
| | | PLS[2:0]=001 (rising edge) | 2.23 | 2.30 | 2.37 | V |
| | | PLS[2:0]=001 (falling edge) | 2.13 | 2.19 | 2.25 | V |
| | | PLS[2:0]=010 (rising edge) | 2.39 | 2.45 | 2.51 | V |
| | | PLS[2:0]=010 (falling edge) | 2.29 | 2.35 | 2.39 | V |
| | | PLS[2:0]=011 (rising edge) | 2.54 | 2.60 | 2.65 | V |
| | | PLS[2:0]=011 (falling edge) | 2.44 | 2.51 | 2.56 | V |
| | | PLS[2:0]=100 (rising edge) | 2.70 | 2.76 | 2.82 | V |
| | | PLS[2:0]=100 (falling edge) | 2.59 | 2.66 | 2.71 | V |
| | | PLS[2:0]=101 (rising edge) | 2.86 | 2.93 | 2.99 | V |
| | | PLS[2:0]=101 (falling edge) | 2.65 | 2.84 | 3.02 | V |
| | | PLS[2:0]=110 (rising edge) | 2.96 | 3.03 | 3.10 | V |
| | | PLS[2:0]=110 (falling edge) | 2.85 | 2.93 | 2.99 | V |
| | | PLS[2:0]=111 (rising edge) | 3.07 | 3.14 | 3.21 | V |
| PLS[2:0]=111 (falling edge) | 2.95 | 3.03 | 3.09 | V | | |
| $V_{PVDhyst}^{(3)}$ | PVD hysteresis | | - | 100 | - | mV |
| $V_{POR/PDR}$ | Power-on/power-down reset threshold | Falling edge | 1.60 ⁽¹⁾ | 1.68 | 1.76 | V |
| | | Rising edge | 1.64 | 1.72 | 1.80 | V |
| $V_{PDRhyst}^{(3)}$ | PDR hysteresis | | - | 40 | - | mV |

Table 18. Embedded reset and power control block characteristics (continued)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------|---|---|------|------|------|---------------|
| V_{BOR1} | Brownout level 1 threshold | Falling edge | 2.13 | 2.19 | 2.24 | V |
| | | Rising edge | 2.23 | 2.29 | 2.33 | V |
| V_{BOR2} | Brownout level 2 threshold | Falling edge | 2.44 | 2.50 | 2.56 | V |
| | | Rising edge | 2.53 | 2.59 | 2.63 | V |
| V_{BOR3} | Brownout level 3 threshold | Falling edge | 2.75 | 2.83 | 2.88 | V |
| | | Rising edge | 2.85 | 2.92 | 2.97 | V |
| V_{12} | 1.2 V domain voltage ⁽²⁾⁽³⁾ | VOS bit in PWR_CR register = 0 | 1.08 | 1.14 | 1.20 | V |
| | | VOS bit in PWR_CR register = 1 | 1.20 | 1.26 | 1.32 | V |
| $V_{BORhyst}^{(3)}$ | BOR hysteresis | | - | 100 | - | mV |
| $T_{RSTTEMPO}^{(3)(4)}$ | Reset temporization | | 0.5 | 1.5 | 3.0 | ms |
| $I_{RUSH}^{(3)}$ | InRush current on voltage regulator power-on (POR or wakeup from Standby) | | - | 160 | 200 | mA |
| $E_{RUSH}^{(3)}$ | InRush energy on voltage regulator power-on (POR or wakeup from Standby) | $V_{DD} = 1.8\text{ V}$, $T_A = 105\text{ }^\circ\text{C}$, $I_{RUSH} = 171\text{ mA}$ for $31\text{ }\mu\text{s}$ | - | - | 5.4 | μC |

1. The product behavior is guaranteed by design down to the minimum $V_{POR/PDR}$ value.
2. The average expected gain in power consumption when VOS = 0 compared to VOS = 1 is around 10% for the whole temperature range, when the system clock frequency is between 30 and 144 MHz.
3. Guaranteed by design, not tested in production.
4. The reset temporization is measured from the power-on (POR reset or wakeup from V_{BAT}) to the instant when first instruction is read by the user application code.

5.3.6 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The current consumption is measured as described in [Figure 20: Current consumption measurement scheme](#).

All Run mode current consumption measurements given in this section are performed using a CoreMark-compliant code.

Typical and maximum current consumption

The MCU is placed under the following conditions:

- At startup, all I/O pins are configured as analog inputs by firmware.
- All peripherals are disabled except if it is explicitly mentioned.
- The Flash memory access time is adjusted to f_{HCLK} frequency (0 wait state from 0 to 30 MHz, 1 wait state from 30 to 60 MHz, 2 wait states from 60 to 90 MHz, 3 wait states from 90 to 120 MHz, 4 wait states from 120 to 150 MHz, and 5 wait states from 150 to 168 MHz).
- When the peripherals are enabled HCLK is the system clock, $f_{PCLK1} = f_{HCLK}/4$, and $f_{PCLK2} = f_{HCLK}/2$, except is explicitly mentioned.
- The maximum values are obtained for $V_{DD} = 3.6\text{ V}$ and maximum ambient temperature (T_A), and the typical values for $T_A = 25\text{ °C}$ and $V_{DD} = 3.3\text{ V}$ unless otherwise specified.

Table 19. Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator disabled)

| Symbol | Parameter | Conditions | f_{HCLK} | Typ | Max ⁽¹⁾ | | Unit |
|----------|----------------------------|--|------------|----------------------|----------------------|-----------------------|------|
| | | | | $T_A = 25\text{ °C}$ | $T_A = 85\text{ °C}$ | $T_A = 105\text{ °C}$ | |
| I_{DD} | Supply current in Run mode | External clock ⁽²⁾ , all peripherals enabled ⁽³⁾⁽⁴⁾ | 168 MHz | 93 | 109 | 117 | mA |
| | | | 144 MHz | 76 | 89 | 96 | |
| | | | 120 MHz | 67 | 79 | 86 | |
| | | | 90 MHz | 53 | 65 | 73 | |
| | | | 60 MHz | 37 | 49 | 56 | |
| | | | 30 MHz | 20 | 32 | 39 | |
| | | | 25 MHz | 16 | 27 | 35 | |
| | | | 16 MHz | 11 | 23 | 30 | |
| | | | 8 MHz | 6 | 18 | 25 | |
| | | | 4 MHz | 4 | 16 | 23 | |
| | | 2 MHz | 3 | 15 | 22 | | |
| | | External clock ⁽²⁾ , all peripherals disabled ⁽³⁾⁽⁴⁾ | 168 MHz | 46 | 61 | 69 | |
| | | | 144 MHz | 40 | 52 | 60 | |
| | | | 120 MHz | 37 | 48 | 56 | |
| | | | 90 MHz | 30 | 42 | 50 | |
| | | | 60 MHz | 22 | 33 | 41 | |
| | | | 30 MHz | 12 | 24 | 31 | |
| | | | 25 MHz | 10 | 21 | 29 | |
| | | | 16 MHz | 7 | 19 | 26 | |
| | | | 8 MHz | 4 | 16 | 23 | |
| 4 MHz | 3 | | 15 | 22 | | | |
| 2 MHz | 2 | 14 | 21 | | | | |

1. Based on characterization, tested in production at V_{DD} max and f_{HCLK} max with peripherals enabled.
 2. External clock is 4 MHz and PLL is on when $f_{HCLK} > 25\text{ MHz}$.

3. When analog peripheral blocks such as (ADCs, DACs, HSE, LSE, HSI,LSI) are on, an additional power consumption should be considered.
4. When the ADC is ON (ADON bit set in the ADC_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.

Table 20. Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator enabled) or RAM ⁽¹⁾

| Symbol | Parameter | Conditions | f _{HCLK} | Typ | Max ⁽²⁾ | | Unit |
|-----------------|----------------------------|--|-----------------------|------------------------|------------------------|-------------------------|------|
| | | | | T _A = 25 °C | T _A = 85 °C | T _A = 105 °C | |
| I _{DD} | Supply current in Run mode | External clock ⁽³⁾ , all peripherals enabled ⁽⁴⁾⁽⁵⁾ | 168 MHz | 87 | 102 | 109 | mA |
| | | | 144 MHz | 67 | 80 | 86 | |
| | | | 120 MHz | 56 | 69 | 75 | |
| | | | 90 MHz | 44 | 56 | 62 | |
| | | | 60 MHz | 30 | 42 | 49 | |
| | | | 30 MHz | 16 | 28 | 35 | |
| | | | 25 MHz | 12 | 24 | 31 | |
| | | | 16 MHz ⁽⁶⁾ | 9 | 20 | 28 | |
| | | | 8 MHz | 5 | 17 | 24 | |
| | | | 4 MHz | 3 | 15 | 22 | |
| | | 2 MHz | 2 | 14 | 21 | | |
| | | External clock ⁽³⁾ , all peripherals disabled ⁽⁴⁾⁽⁵⁾ | 168 MHz | 40 | 54 | 61 | |
| | | | 144 MHz | 31 | 43 | 50 | |
| | | | 120 MHz | 26 | 38 | 45 | |
| | | | 90 MHz | 20 | 32 | 39 | |
| | | | 60 MHz | 14 | 26 | 33 | |
| | | | 30 MHz | 8 | 20 | 27 | |
| | | | 25 MHz | 6 | 18 | 25 | |
| | | | 16 MHz ⁽⁶⁾ | 5 | 16 | 24 | |
| | | | 8 MHz | 3 | 15 | 22 | |
| 4 MHz | 2 | | 14 | 21 | | | |
| 2 MHz | 2 | 14 | 21 | | | | |

1. Code and data processing running from SRAM1 using boot pins.
2. Based on characterization, tested in production at V_{DD} max and f_{HCLK} max with peripherals enabled.
3. External clock is 4 MHz and PLL is on when f_{HCLK} > 25 MHz.
4. When the ADC is ON (ADON bit set in the ADC_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.
5. When analog peripheral blocks such as ADCs, DACs, HSE, LSE, HSI, or LSI are ON, an additional power consumption should be considered.
6. In this case HCLK = system clock/2.

Figure 22. Typical current consumption vs temperature, Run mode, code with data processing running from Flash (ART accelerator ON) or RAM, and peripherals OFF

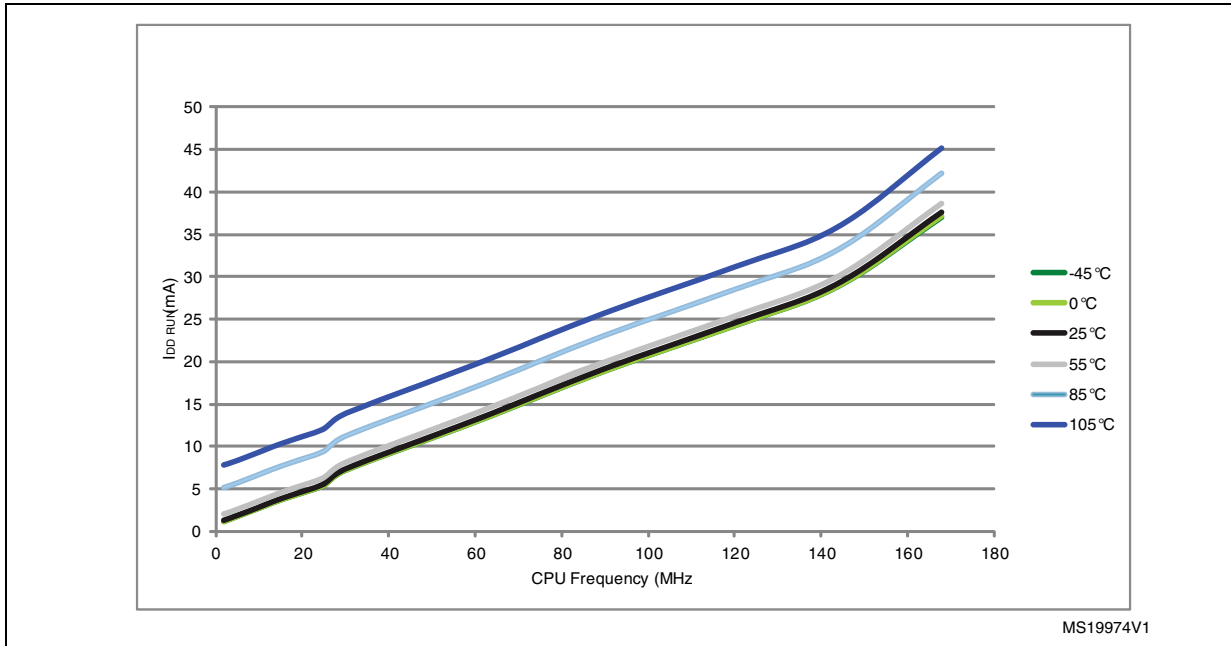


Figure 23. Typical current consumption vs temperature, Run mode, code with data processing running from Flash (ART accelerator ON) or RAM, and peripherals ON

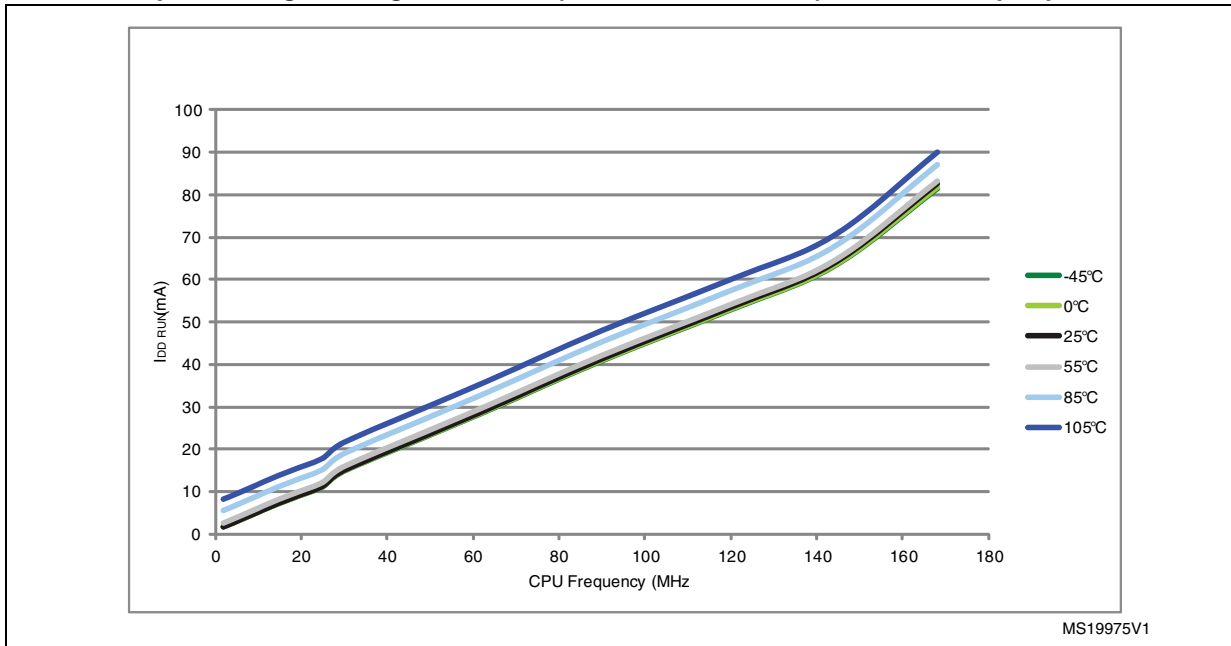


Figure 24. Typical current consumption vs temperature, Run mode, code with data processing running from Flash (ART accelerator OFF) or RAM, and peripherals OFF

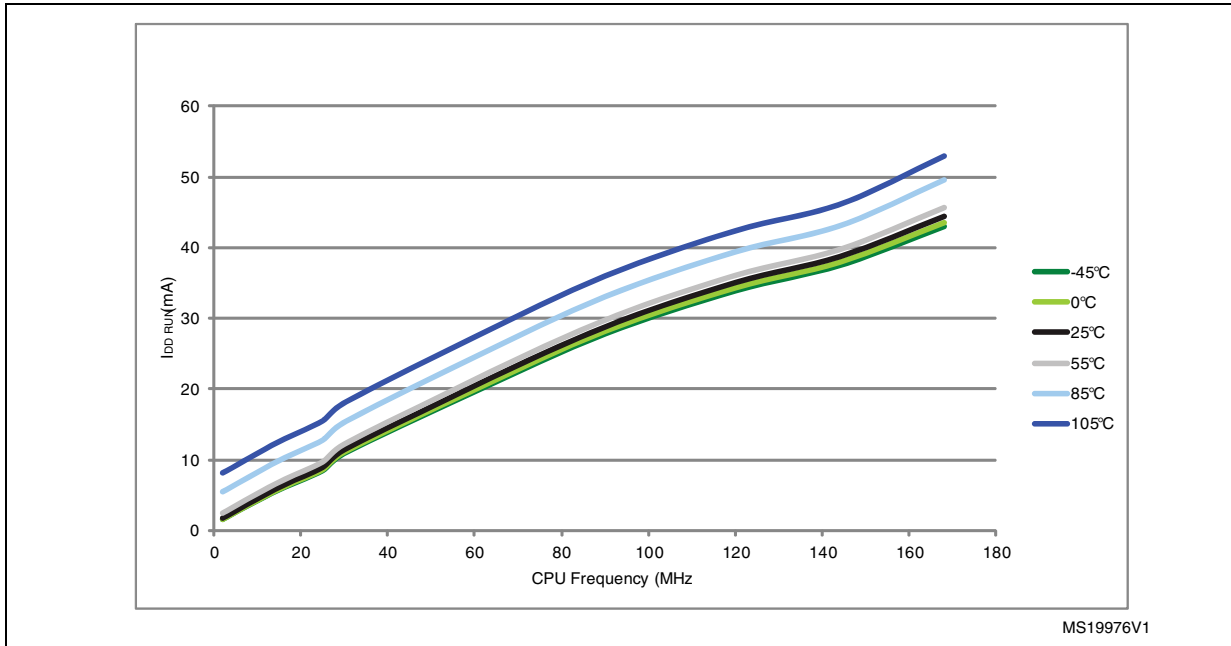


Figure 25. Typical current consumption vs temperature, Run mode, code with data processing running from Flash (ART accelerator OFF) or RAM, and peripherals ON

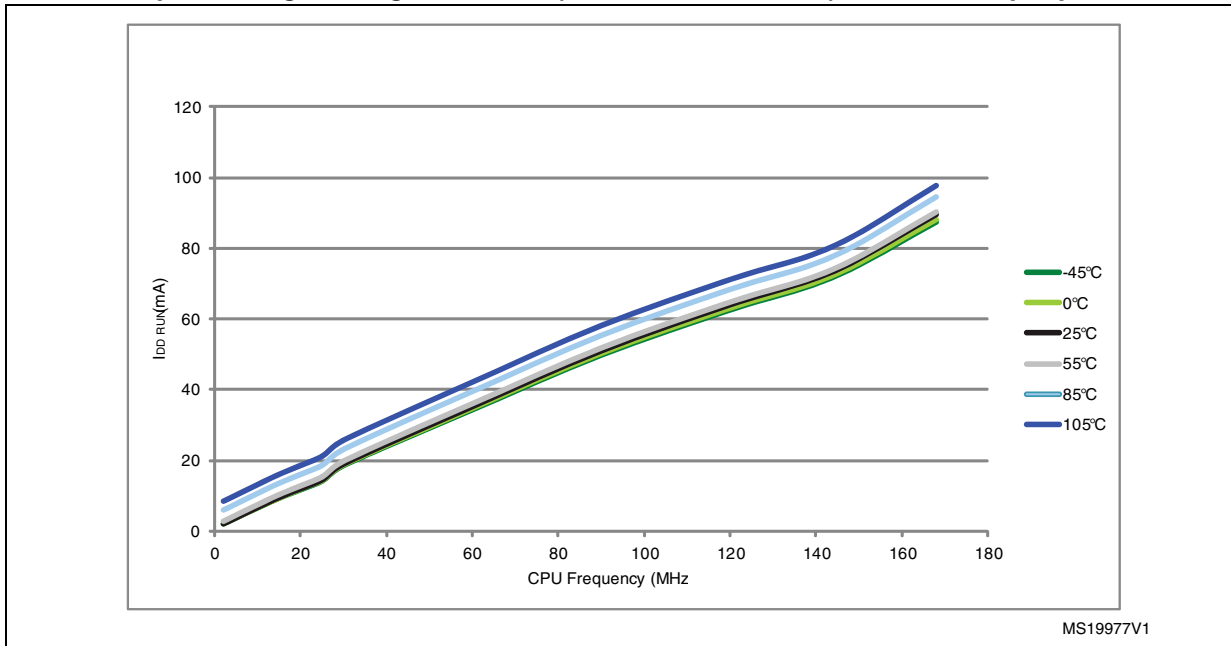


Table 21. Typical and maximum current consumption in Sleep mode

| Symbol | Parameter | Conditions | f _{HCLK} | Typ | Max ⁽¹⁾ | | Unit |
|-----------------|------------------------------|--|-------------------|------------------------|------------------------|-------------------------|------|
| | | | | T _A = 25 °C | T _A = 85 °C | T _A = 105 °C | |
| I _{DD} | Supply current in Sleep mode | External clock ⁽²⁾ , all peripherals enabled ⁽³⁾ | 168 MHz | 59 | 77 | 84 | mA |
| | | | 144 MHz | 46 | 61 | 67 | |
| | | | 120 MHz | 38 | 53 | 60 | |
| | | | 90 MHz | 30 | 44 | 51 | |
| | | | 60 MHz | 20 | 34 | 41 | |
| | | | 30 MHz | 11 | 24 | 31 | |
| | | | 25 MHz | 8 | 21 | 28 | |
| | | | 16 MHz | 6 | 18 | 25 | |
| | | | 8 MHz | 3 | 16 | 23 | |
| | | | 4 MHz | 2 | 15 | 22 | |
| | | 2 MHz | 2 | 14 | 21 | | |
| | | External clock ⁽²⁾ , all peripherals disabled | 168 MHz | 12 | 27 | 35 | |
| | | | 144 MHz | 9 | 22 | 29 | |
| | | | 120 MHz | 8 | 20 | 28 | |
| | | | 90 MHz | 7 | 19 | 26 | |
| | | | 60 MHz | 5 | 17 | 24 | |
| | | | 30 MHz | 3 | 16 | 23 | |
| | | | 25 MHz | 2 | 15 | 22 | |
| | | | 16 MHz | 2 | 14 | 21 | |
| | | | 8 MHz | 1 | 14 | 21 | |
| 4 MHz | 1 | | 13 | 21 | | | |
| 2 MHz | 1 | 13 | 21 | | | | |

1. Based on characterization, tested in production at V_{DD} max and f_{HCLK} max with peripherals enabled.
2. External clock is 4 MHz and PLL is on when f_{HCLK} > 25 MHz.
3. Add an additional power consumption of 1.6 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is ON (ADON bit is set in the ADC_CR2 register).

Table 22. Typical and maximum current consumptions in Stop mode

| Symbol | Parameter | Conditions | Typ | Max | | | | Unit |
|----------------------|---|---|------------------------|------------------------|------------------------|-------------------------|----|------|
| | | | T _A = 25 °C | T _A = 25 °C | T _A = 85 °C | T _A = 105 °C | | |
| I _{DD_STOP} | Supply current in Stop mode with main regulator in Run mode | Flash in Stop mode, low-speed and high-speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog) | 0.60 | 2.10 | 11.00 | 20.00 | mA | |
| | | Flash in Deep power down mode, low-speed and high-speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog) | 0.55 | 2.10 | 11.00 | 20.00 | | |
| | Supply current in Stop mode with main regulator in Low Power mode | Flash in Stop mode, low-speed and high-speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog) | 0.40 | 1.30 | 8.00 | 15.00 | | |
| | | Flash in Deep power down mode, low-speed and high-speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog) | 0.35 | 1.30 | 8.00 | 15.00 | | |

Table 23. Typical and maximum current consumptions in Standby mode⁽¹⁾

| Symbol | Parameter | Conditions | Typ | | | Max | | Unit |
|----------------------|--------------------------------|--|-------------------------|-------------------------|-------------------------|-------------------------|-------------------------|------|
| | | | T _A = 25 °C | | | T _A = 85 °C | T _A = 105 °C | |
| | | | V _{DD} = 1.8 V | V _{DD} = 2.4 V | V _{DD} = 3.3 V | V _{DD} = 3.6 V | | |
| I _{DD_STBY} | Supply current in Standby mode | Backup SRAM ON, low-speed oscillator and RTC ON | 3.0 | 3.4 | 4.0 | TBD ⁽²⁾ | TBD ⁽²⁾ | µA |
| | | Backup SRAM OFF, low-speed oscillator and RTC ON | 2.4 | 2.7 | 3.3 | TBD ⁽²⁾ | TBD ⁽²⁾ | |
| | | Backup SRAM ON, RTC OFF | 2.4 | 2.6 | 3.0 | 12.5 ⁽²⁾ | 24.8 ⁽²⁾ | |
| | | Backup SRAM OFF, RTC OFF | 1.7 | 1.9 | 2.2 | 9.8 ⁽²⁾ | 19.2 ⁽²⁾ | |

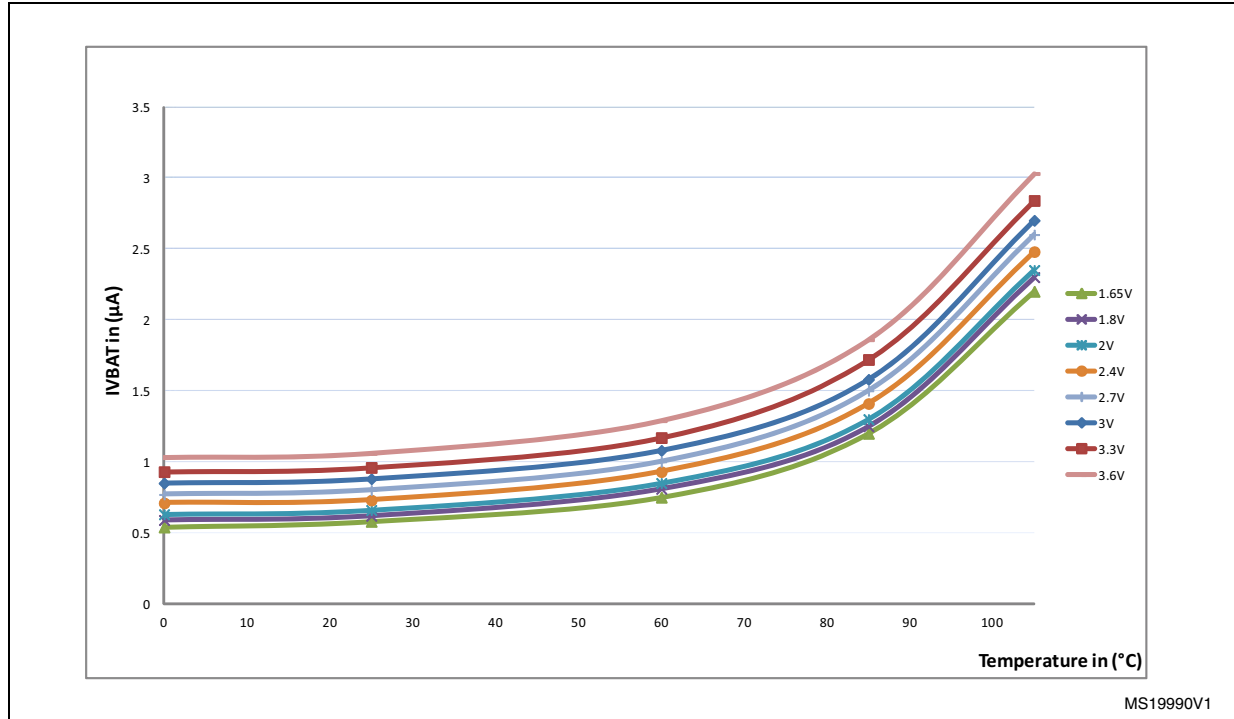
1. TBD stands for “to be defined”.
2. Based on characterization, not tested in production.

Table 24. Typical and maximum current consumptions in V_{BAT} mode⁽¹⁾

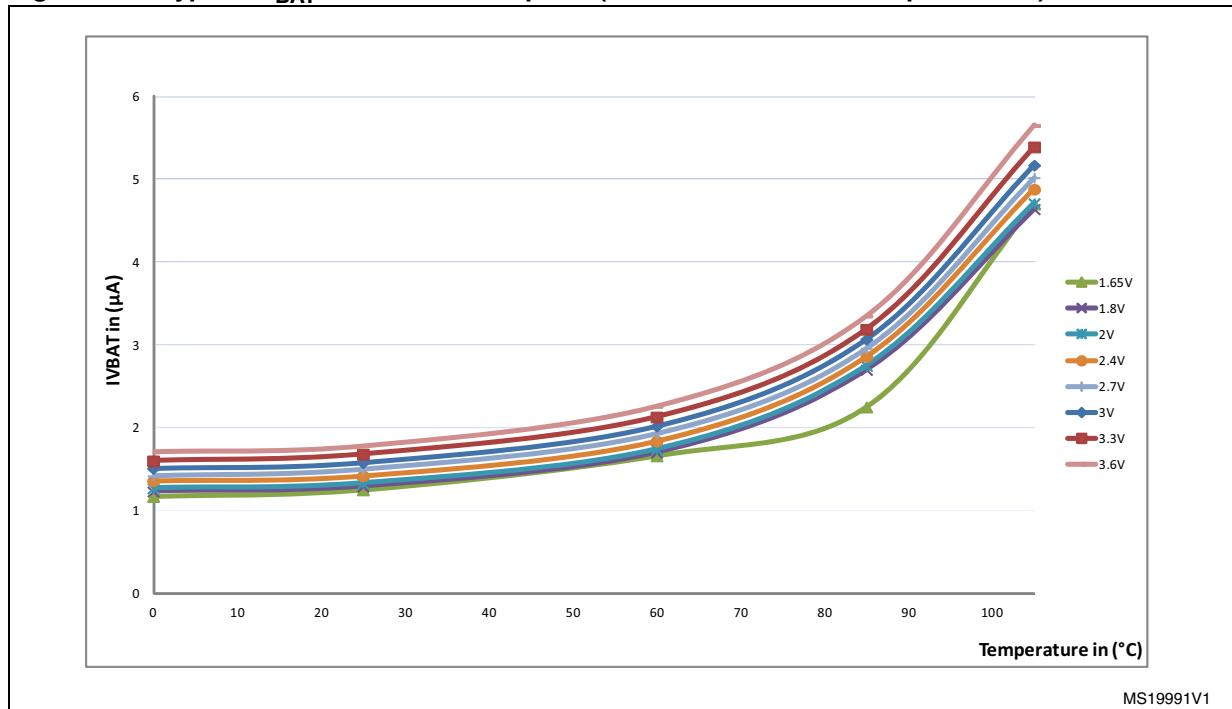
| Symbol | Parameter | Conditions | Typ | | | Max | | Unit |
|----------------------|------------------------------|--|--------------------------|--------------------------|--------------------------|--------------------------|-------------------------|------|
| | | | T _A = 25 °C | | | T _A = 85 °C | T _A = 105 °C | |
| | | | V _{BAT} = 1.8 V | V _{BAT} = 2.4 V | V _{BAT} = 3.3 V | V _{BAT} = 3.6 V | | |
| I _{DD_VBAT} | Backup domain supply current | Backup SRAM ON, low-speed oscillator and RTC ON | 1.29 | 1.42 | 1.68 | TBD ⁽²⁾ | TBD ⁽²⁾ | μA |
| | | Backup SRAM OFF, low-speed oscillator and RTC ON | 0.62 | 0.73 | 0.96 | TBD ⁽²⁾ | TBD ⁽²⁾ | |
| | | Backup SRAM ON, RTC OFF | 0.79 | 0.81 | 0.86 | 9 ⁽²⁾ | 16 ⁽²⁾ | |
| | | Backup SRAM OFF, RTC OFF | 0.10 | 0.10 | 0.10 | 5 ⁽²⁾ | 7 ⁽²⁾ | |

1. TBD stands for "to be defined".
2. Based on characterization, not tested in production.

Figure 26. Typical V_{BAT} current consumption (LSE and RTC ON/backup RAM OFF)



MS19990V1

Figure 27. Typical V_{BAT} current consumption (LSE and RTC ON/backup RAM ON)

MS19991V1

I/O system current consumption

The current consumption of the I/O system has two components: static and dynamic.

I/O static current consumption

All the I/Os used as inputs with pull-up generate current consumption when the pin is externally held low. The value of this current consumption can be simply computed by using the pull-up/pull-down resistors values given in [Table 46: I/O static characteristics](#).

For the output pins, any external pull-down or external load must also be considered to estimate the current consumption.

Additional I/O current consumption is due to I/Os configured as inputs if an intermediate voltage level is externally applied. This current consumption is caused by the input Schmitt trigger circuits used to discriminate the input value. Unless this specific configuration is required by the application, this supply current consumption can be avoided by configuring these I/Os in analog mode. This is notably the case of ADC input pins which should be configured as analog inputs.

Caution: Any floating input pin can also settle to an intermediate voltage level or switch inadvertently, as a result of external electromagnetic noise. To avoid current consumption related to floating pins, they must either be configured in analog mode, or forced internally to a definite digital value. This can be done either by using pull-up/down resistors or by configuring the pins in output mode.

I/O dynamic current consumption

In addition to the internal peripheral current consumption measured previously (see [Table 26: Peripheral current consumption](#)), the I/Os used by an application also contribute to the current consumption. When an I/O pin switches, it uses the current from the MCU supply

voltage to supply the I/O pin circuitry and to charge/discharge the capacitive load (internal or external) connected to the pin:

$$I_{SW} = V_{DD} \times f_{SW} \times C$$

where

I_{SW} is the current sunk by a switching I/O to charge/discharge the capacitive load

V_{DD} is the MCU supply voltage

f_{SW} is the I/O switching frequency

C is the total capacitance seen by the I/O pin: $C = C_{INT} + C_{EXT}$

The test pin is configured in push-pull output mode and is toggled by software at a fixed frequency.

Table 25. Switching output I/O current consumption

| Symbol | Parameter | Conditions ⁽¹⁾ | I/O toggling frequency (f _{SW}) | Typ | Unit |
|---|-----------------------|---|---|------|------|
| I _{DDIO} | I/O switching current | V _{DD} = 3.3 V ⁽²⁾ C = C _{INT} | 2 MHz | 0.02 | mA |
| | | | 8 MHz | 0.14 | |
| | | | 25 MHz | 0.51 | |
| | | | 50 MHz | 0.86 | |
| | | | 60 MHz | 1.30 | |
| | | V _{DD} = 3.3 V C _{EXT} = 0 pF C = C _{INT} + C _{EXT} + C _S | 2 MHz | 0.10 | |
| | | | 8 MHz | 0.38 | |
| | | | 25 MHz | 1.18 | |
| | | | 50 MHz | 2.47 | |
| | | | 60 MHz | 2.86 | |
| | | V _{DD} = 3.3 V C _{EXT} = 10 pF C = C _{INT} + C _{EXT} + C _S | 2 MHz | 0.17 | |
| | | | 8 MHz | 0.66 | |
| | | | 25 MHz | 1.70 | |
| | | | 50 MHz | 2.65 | |
| | | V _{DD} = 3.3 V C _{EXT} = 22 pF C = C _{INT} + C _{EXT} + C _S | 60 MHz | 3.48 | |
| | | | 2 MHz | 0.23 | |
| | | | 8 MHz | 0.95 | |
| | | | 25 MHz | 3.20 | |
| | | V _{DD} = 3.3 V C _{EXT} = 33 pF C = C _{INT} + C _{EXT} + C _S | 50 MHz | 4.69 | |
| | | | 60 MHz | 8.06 | |
| 2 MHz | 0.30 | | | | |
| 8 MHz | 1.22 | | | | |
| V _{DD} = 3.3 V C _{EXT} = 33 pF C = C _{INT} + C _{EXT} + C _S | 25 MHz | 3.90 | | | |
| | 50 MHz | 8.82 | | | |
| | 60 MHz | -(³) | | | |

- C_S is the PCB board capacitance including the pad pin. C_S = 7 pF (estimated value).
- This test is performed by cutting the LQFP package pin (pad removal).
- At 60 MHz, C maximum load is specified 30 pF.

On-chip peripheral current consumption

The current consumption of the on-chip peripherals is given in [Table 26](#). The MCU is placed under the following conditions:

- At startup, all I/O pins are configured as analog pins by firmware.
- All peripherals are disabled unless otherwise mentioned
- The code is running from Flash memory and the Flash memory access time is equal to 5 wait states at 168 MHz.
- The code is running from Flash memory and the Flash memory access time is equal to 4 wait states at 144 MHz, and the power scale mode is set to 2.
- ART accelerator and Cache off.
- The given value is calculated by measuring the difference of current consumption
 - with all peripherals clocked off
 - with one peripheral clocked on (with only the clock applied)
- When the peripherals are enabled: HCLK is the system clock, $f_{PCLK1} = f_{HCLK}/4$, and $f_{PCLK2} = f_{HCLK}/2$.
- The typical values are obtained for $V_{DD} = 3.3\text{ V}$ and $T_A = 25\text{ °C}$, unless otherwise specified.

Table 26. Peripheral current consumption

| Peripheral ⁽¹⁾ | | 168 MHz | 144 MHz | Unit |
|--|---------------|---------|---------|------|
| AHB1 | GPIO A | 0.49 | 0.36 | mA |
| | GPIO B | 0.45 | 0.33 | |
| | GPIO C | 0.45 | 0.34 | |
| | GPIO D | 0.45 | 0.34 | |
| | GPIO E | 0.47 | 0.35 | |
| | GPIO F | 0.45 | 0.33 | |
| | GPIO G | 0.44 | 0.33 | |
| | GPIO H | 0.45 | 0.34 | |
| | GPIO I | 0.44 | 0.33 | |
| | OTG_HS + ULPI | 4.57 | 3.55 | |
| | CRC | 0.07 | 0.06 | |
| | BKPSRAM | 0.11 | 0.08 | |
| | DMA1 | 6.15 | 4.75 | |
| | DMA2 | 6.24 | 4.8 | |
| ETH_MAC + ETH_MAC_TX ETH_MAC_RX ETH_MAC_PTP | 3.28 | 2.54 | | |
| AHB2 | OTG_FS | 4.59 | 3.69 | mA |
| | DCMI | 1.04 | 0.80 | |

Table 26. Peripheral current consumption (continued)

| Peripheral ⁽¹⁾ | | 168 MHz | 144 MHz | Unit |
|---------------------------------------|------------------------------|-----------|-----------|------|
| AHB3 | FSMC | 2.18 | 1.67 | mA |
| APB1 | TIM2 | 0.80 | 0.61 | |
| | TIM3 | 0.58 | 0.44 | |
| | TIM4 | 0.62 | 0.48 | |
| | TIM5 | 0.79 | 0.61 | |
| | TIM6 | 0.15 | 0.11 | |
| | TIM7 | 0.16 | 0.12 | |
| | TIM12 | 0.33 | 0.26 | |
| | TIM13 | 0.27 | 0.21 | |
| | TIM14 | 0.27 | 0.21 | |
| | PWR | 0.04 | 0.03 | |
| | USART2 | 0.17 | 0.13 | |
| | USART3 | 0.17 | 0.13 | |
| | UART4 | 0.17 | 0.13 | |
| | UART5 | 0.17 | 0.13 | |
| | I2C1 | 0.17 | 0.13 | |
| | I2C2 | 0.18 | 0.13 | |
| | I2C3 | 0.18 | 0.13 | |
| | SPI2/I2S2 ⁽²⁾ | 0.17/0.16 | 0.13/0.12 | |
| | SPI3/I2S3 ⁽²⁾ | 0.16/0.14 | 0.12/0.12 | |
| | CAN1 | 0.27 | 0.21 | |
| | CAN2 | 0.26 | 0.20 | |
| | DAC | 0.14 | 0.10 | |
| | DAC channel 1 ⁽³⁾ | 0.91 | 0.89 | |
| | DAC channel 2 ⁽⁴⁾ | 0.91 | 0.89 | |
| DAC channel 1 and 2 ⁽³⁾⁽⁴⁾ | 1.69 | 1.68 | | |
| WWDG | 0.04 | 0.04 | | |

Table 26. Peripheral current consumption (continued)

| Peripheral ⁽¹⁾ | | 168 MHz | 144 MHz | Unit |
|---------------------------|---------------------|---------|---------|------|
| APB2 | SDIO | 0.64 | 0.54 | mA |
| | TIM1 | 1.47 | 1.14 | |
| | TIM8 | 1.58 | 1.22 | |
| | TIM9 | 0.68 | 0.54 | |
| | TIM10 | 0.45 | 0.36 | |
| | TIM11 | 0.47 | 0.38 | |
| | ADC1 ⁽⁵⁾ | 2.20 | 2.10 | |
| | ADC2 ⁽⁵⁾ | 2.04 | 1.93 | |
| | ADC3 ⁽⁵⁾ | 2.10 | 2.00 | |
| | SPI1 | 0.14 | 0.12 | |
| | USART1 | 0.34 | 0.27 | |
| | USART6 | 0.34 | 0.28 | |

1. HSE oscillator with 4 MHz crystal and PLL are ON.
2. I2SMOD bit set in SPI_I2SCFGR register, and then the I2SE bit set to enable I2S peripheral.
3. EN1 bit is set in DAC_CR register.
4. EN2 bit is set in DAC_CR register.
5. ADON bit set in ADC_CR2 register.

5.3.7 Wakeup time from low-power mode

The wakeup times given in [Table 27](#) is measured on a wakeup phase with a 16 MHz HSI RC oscillator. The clock source used to wake up the device depends from the current operating mode:

- Stop or Standby mode: the clock source is the RC oscillator
- Sleep mode: the clock source is the clock that was set before entering Sleep mode.

All timings are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 13](#).

Table 27. Low-power mode wakeup timings

| Symbol | Parameter | Min ⁽¹⁾ | Typ ⁽¹⁾ | Max ⁽¹⁾ | Unit |
|--|--|--------------------|--------------------|--------------------|------|
| t _{WUSLEEP} ⁽²⁾ | Wakeup from Sleep mode | - | 1 | - | μs |
| t _{WUSTOP} ⁽²⁾ | Wakeup from Stop mode (regulator in Run mode) | - | 13 | - | μs |
| | Wakeup from Stop mode (regulator in low power mode) | - | 17 | 40 | |
| | Wakeup from Stop mode (regulator in low power mode and Flash memory in Deep power down mode) | - | 110 | - | |
| t _{WUSTDBY} ⁽²⁾⁽³⁾ | Wakeup from Standby mode | 260 | 375 | 480 | μs |

1. Based on characterization, not tested in production.
2. The wakeup times are measured from the wakeup event to the point in which the application code reads the first instruction.
3. t_{WUSTDBY} minimum and maximum values are given at 105 °C and -45 °C, respectively.

5.3.8 External clock source characteristics

High-speed external user clock generated from an external source

The characteristics given in [Table 28](#) result from tests performed using an high-speed external clock source, and under ambient temperature and supply voltage conditions summarized in [Table 13](#).

Table 28. High-speed external user clock characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------------------|---|----------------------------------|-------------|-----|-------------|---------|
| f_{HSE_ext} | External user clock source frequency ⁽¹⁾ | | 1 | - | 50 | MHz |
| V_{HSEH} | OSC_IN input pin high level voltage | | $0.7V_{DD}$ | - | V_{DD} | V |
| V_{HSEL} | OSC_IN input pin low level voltage | | V_{SS} | - | $0.3V_{DD}$ | |
| $t_{w(HSE)}$ $t_{w(HSE)}$ | OSC_IN high or low time ⁽¹⁾ | | 5 | - | - | ns |
| $t_{r(HSE)}$ $t_{f(HSE)}$ | OSC_IN rise or fall time ⁽¹⁾ | | - | - | 10 | |
| $C_{in(HSE)}$ | OSC_IN input capacitance ⁽¹⁾ | | - | 5 | - | pF |
| $DuCy_{(HSE)}$ | Duty cycle | | 45 | - | 55 | % |
| I_L | OSC_IN Input leakage current | $V_{SS} \leq V_{IN} \leq V_{DD}$ | - | - | ± 1 | μA |

1. Guaranteed by design, not tested in production.

Low-speed external user clock generated from an external source

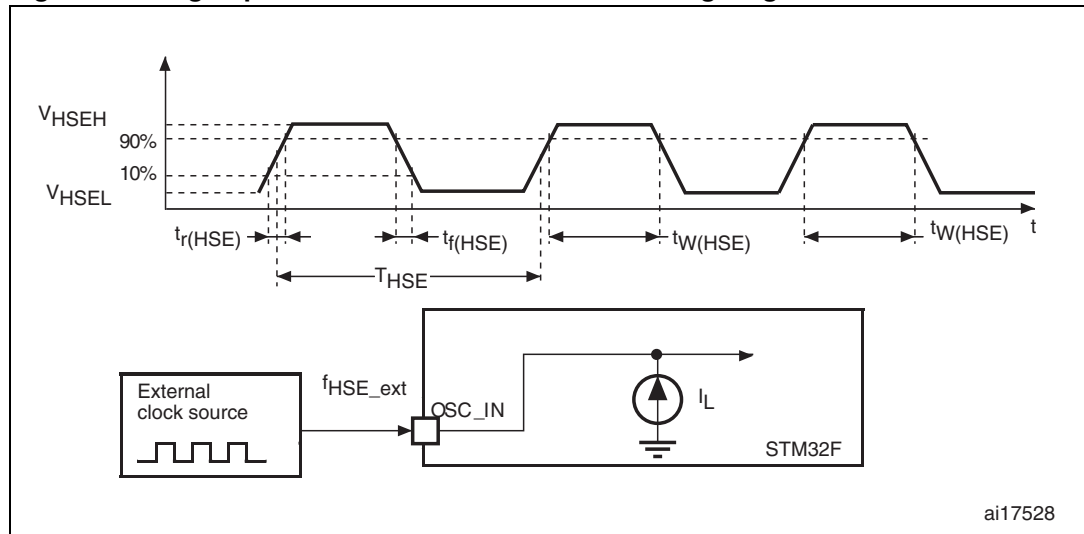
The characteristics given in [Table 29](#) result from tests performed using an low-speed external clock source, and under ambient temperature and supply voltage conditions summarized in [Table 13](#).

Table 29. Low-speed external user clock characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------------------|---|----------------------------------|-------------|--------|-------------|---------|
| f_{LSE_ext} | User External clock source frequency ⁽¹⁾ | | - | 32.768 | 1000 | kHz |
| V_{LSEH} | OSC32_IN input pin high level voltage | | $0.7V_{DD}$ | - | V_{DD} | V |
| V_{LSEL} | OSC32_IN input pin low level voltage | | V_{SS} | - | $0.3V_{DD}$ | |
| $t_{w(LSE)}$ $t_{f(LSE)}$ | OSC32_IN high or low time ⁽¹⁾ | | 450 | - | - | ns |
| $t_{r(LSE)}$ $t_{f(LSE)}$ | OSC32_IN rise or fall time ⁽¹⁾ | | - | - | 50 | |
| $C_{in(LSE)}$ | OSC32_IN input capacitance ⁽¹⁾ | | - | 5 | - | pF |
| $DuCy_{(LSE)}$ | Duty cycle | | 30 | - | 70 | % |
| I_L | OSC32_IN Input leakage current | $V_{SS} \leq V_{IN} \leq V_{DD}$ | - | - | ± 1 | μA |

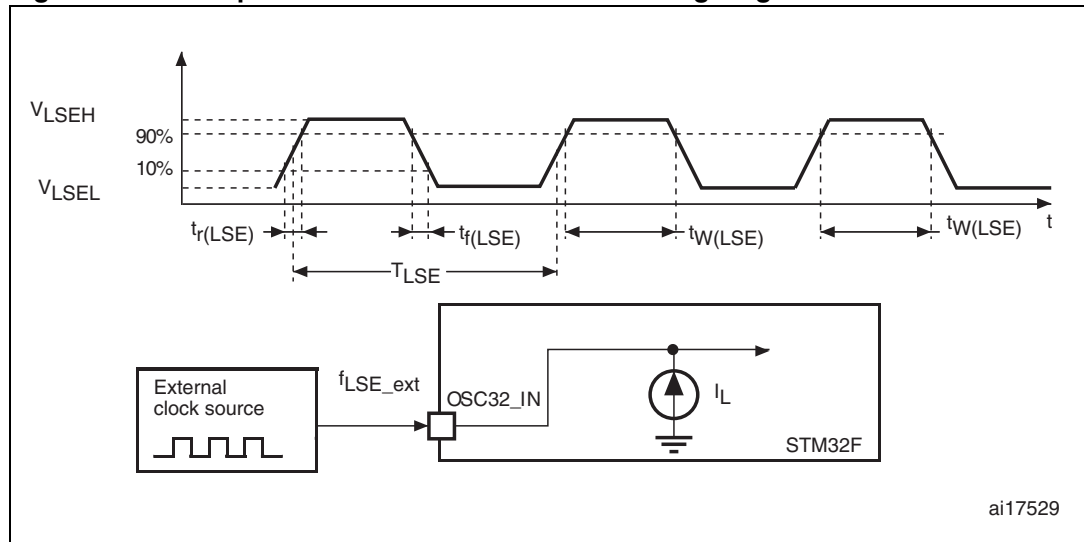
1. Guaranteed by design, not tested in production.

Figure 28. High-speed external clock source AC timing diagram



ai17528

Figure 29. Low-speed external clock source AC timing diagram



ai17529

High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 26 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in [Table 30](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

Table 30. HSE 4-26 MHz oscillator characteristics^{(1) (2)}

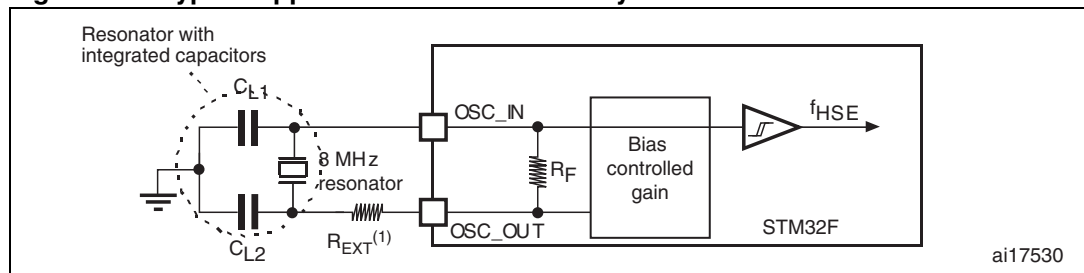
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------------|-----------------------------|---|-----|-----|-----|---------------|
| f_{OSC_IN} | Oscillator frequency | | 4 | - | 26 | MHz |
| R_F | Feedback resistor | | - | 200 | - | k Ω |
| I_{DD} | HSE current consumption | $V_{DD}=3.3\text{ V}$, ESR= 30 Ω , $C_L=5\text{ pF}@25\text{ MHz}$ | - | 449 | - | μA |
| | | $V_{DD}=3.3\text{ V}$, ESR= 30 Ω , $C_L=10\text{ pF}@25\text{ MHz}$ | - | 532 | - | |
| g_m | Oscillator transconductance | Startup | 5 | - | - | mA/V |
| $t_{SU(HSE)}^{(3)}$ | Startup time | V_{DD} is stabilized | - | 2 | - | ms |

1. Resonator characteristics given by the crystal/ceramic resonator manufacturer.
2. Based on characterization, not tested in production.
3. $t_{SU(HSE)}$ is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer

For C_{L1} and C_{L2} , it is recommended to use high-quality external ceramic capacitors in the 5 pF to 25 pF range (typ.), designed for high-frequency applications, and selected to match the requirements of the crystal or resonator (see [Figure 30](#)). C_{L1} and C_{L2} are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of C_{L1} and C_{L2} . PCB and MCU pin capacitance must be included (10 pF can be used as a rough estimate of the combined pin and board capacitance) when sizing C_{L1} and C_{L2} .

Note: For information on electing the crystal, refer to the application note AN2867 “Oscillator design guide for ST microcontrollers” available from the ST website www.st.com.

Figure 30. Typical application with an 8 MHz crystal



1. R_{EXT} value depends on the crystal characteristics.

Low-speed external clock generated from a crystal/ceramic resonator

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in [Table 31](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

Table 31. LSE oscillator characteristics ($f_{LSE} = 32.768 \text{ kHz}$) (1)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------------|-----------------------------|------------------------|-----|------|-----|-----------|
| R_F | Feedback resistor | | - | 18.4 | - | $M\Omega$ |
| I_{DD} | LSE current consumption | | - | - | 1 | μA |
| g_m | Oscillator Transconductance | | 2.8 | - | - | $\mu A/V$ |
| $t_{SU(LSE)}^{(2)}$ | startup time | V_{DD} is stabilized | - | 2 | - | s |

1. Guaranteed by design, not tested in production.
2. $t_{SU(LSE)}$ is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer

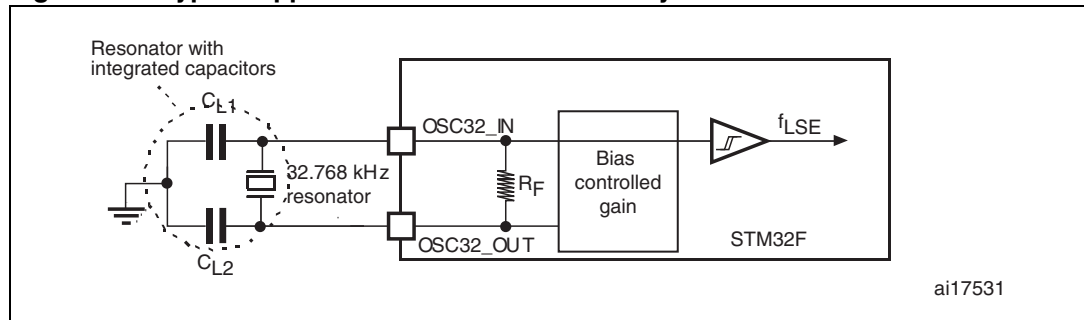
Note: For C_{L1} and C_{L2} it is recommended to use high-quality external ceramic capacitors in the 5 pF to 15 pF range selected to match the requirements of the crystal or resonator (see Figure 31). C_{L1} and C_{L2} , are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of C_{L1} and C_{L2} . Load capacitance C_L has the following formula: $C_L = C_{L1} \times C_{L2} / (C_{L1} + C_{L2}) + C_{stray}$ where C_{stray} is the pin capacitance and board or trace PCB-related capacitance. Typically, it is between 2 pF and 7 pF.

Note: For information on electing the crystal, refer to the application note AN2867 “Oscillator design guide for ST microcontrollers” available from the ST website www.st.com.

Caution: To avoid exceeding the maximum value of C_{L1} and C_{L2} (15 pF) it is strongly recommended to use a resonator with a load capacitance $C_L \leq 7 \text{ pF}$. Never use a resonator with a load capacitance of 12.5 pF.

Example: if you choose a resonator with a load capacitance of $C_L = 6 \text{ pF}$, and $C_{stray} = 2 \text{ pF}$, then $C_{L1} = C_{L2} = 8 \text{ pF}$.

Figure 31. Typical application with a 32.768 kHz crystal



5.3.9 Internal clock source characteristics

The parameters given in [Table 32](#) and [Table 33](#) are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 13](#).

High-speed internal (HSI) RC oscillator

Low-speed internal (LSI) RC oscillator

Table 32. HSI oscillator characteristics ⁽¹⁾

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|------------------------------|----------------------------------|--|-------------------------|-----|-----|------|---|
| f_{HSI} | Frequency | | - | 16 | - | MHz | |
| ACC_{HSI} | Accuracy of the HSI oscillator | User-trimmed with the RCC_CR register ⁽²⁾ | - | - | 1 | % | |
| | | Factory-calibrated | $T_A = -40$ to 105 °C | -8 | - | 4.5 | % |
| | | | $T_A = -10$ to 85 °C | -4 | - | 4 | % |
| | | | $T_A = 25$ °C | -1 | - | 1 | % |
| $t_{su(HSI)}$ ⁽³⁾ | HSI oscillator startup time | | - | 2.2 | 4 | μs | |
| $I_{DD(HSI)}$ | HSI oscillator power consumption | | - | 60 | 80 | μA | |

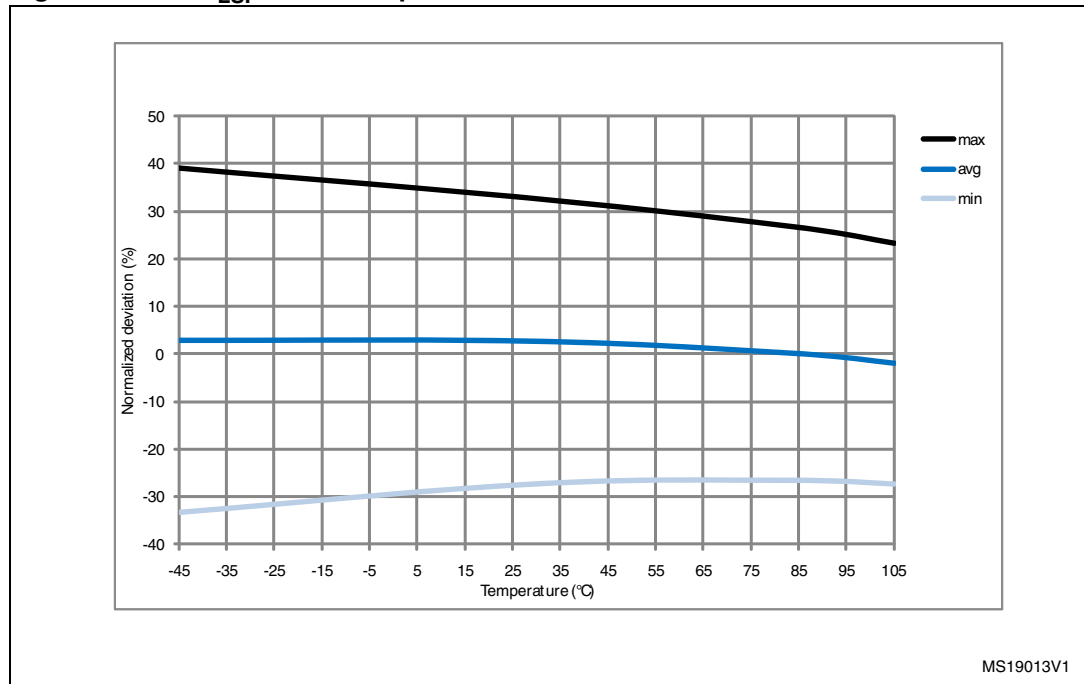
- $V_{DD} = 3.3$ V, $T_A = -40$ to 105 °C unless otherwise specified.
- Refer to application note AN2868 “STM32F10xxx internal RC oscillator (HSI) calibration” available from the ST website www.st.com.
- Guaranteed by design, not tested in production.

Table 33. LSI oscillator characteristics ⁽¹⁾

| Symbol | Parameter | Min | Typ | Max | Unit |
|------------------------------|----------------------------------|-----|-----|-----|------|
| f_{LSI} ⁽²⁾ | Frequency | 17 | 32 | 47 | kHz |
| $t_{su(LSI)}$ ⁽³⁾ | LSI oscillator startup time | - | 15 | 40 | μs |
| $I_{DD(LSI)}$ ⁽³⁾ | LSI oscillator power consumption | - | 0.4 | 0.6 | μA |

- $V_{DD} = 3$ V, $T_A = -40$ to 105 °C unless otherwise specified.
- Based on characterization, not tested in production.
- Guaranteed by design, not tested in production.

Figure 32. ACC_{LSI} versus temperature



5.3.10 PLL characteristics

The parameters given in [Table 34](#) and [Table 35](#) are derived from tests performed under temperature and V_{DD} supply voltage conditions summarized in [Table 13](#).

Table 34. Main PLL characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------------|------------------------------------|--------------------|---------------------|-----|------|------|
| f _{PLL_IN} | PLL input clock ⁽¹⁾ | | 0.95 ⁽²⁾ | 1 | 2.10 | MHz |
| f _{PLL_OUT} | PLL multiplier output clock | | 24 | - | 168 | MHz |
| f _{PLL48_OUT} | 48 MHz PLL multiplier output clock | | - | 48 | 75 | MHz |
| f _{VCO_OUT} | PLL VCO output | | 192 | - | 432 | MHz |
| t _{LOCK} | PLL lock time | VCO freq = 192 MHz | 75 | - | 200 | μs |
| | | VCO freq = 432 MHz | 100 | - | 300 | |

Table 34. Main PLL characteristics (continued)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--------------------------------------|--|--|--------------|-----|--------------|------|----|
| Jitter ⁽³⁾ | Cycle-to-cycle jitter | System clock 120 MHz | RMS | - | 25 | - | ps |
| | | | peak to peak | - | ±150 | - | |
| | Period Jitter | | RMS | - | 15 | - | |
| | | | peak to peak | - | ±200 | - | |
| | Main clock output (MCO) for RMI Ethernet | Cycle to cycle at 50 MHz on 1000 samples | - | 32 | - | | |
| | Main clock output (MCO) for MII Ethernet | Cycle to cycle at 25 MHz on 1000 samples | - | 40 | - | | |
| | Bit Time CAN jitter | Cycle to cycle at 1 MHz on 1000 samples | - | 330 | - | | |
| I _{DD(PLL)} ⁽⁴⁾ | PLL power consumption on VDD | VCO freq = 192 MHz VCO freq = 432 MHz | 0.15 0.45 | - | 0.40 0.75 | mA | |
| I _{DDA(PLL)} ⁽⁴⁾ | PLL power consumption on VDDA | VCO freq = 192 MHz VCO freq = 432 MHz | 0.30 0.55 | - | 0.40 0.85 | mA | |

1. Take care of using the appropriate division factor M to obtain the specified PLL input clock values. The M factor is shared between PLL and PLLI2S.
2. Guaranteed by design, not tested in production.
3. The use of 2 PLLs in parallel could degraded the Jitter up to +30%.
4. Based on characterization, not tested in production.

Table 35. PLLI2S (audio PLL) characteristics⁽¹⁾

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|-------------------------|-----------------------------------|---|---------------------|-----|------|------|----|
| f _{PLLI2S_IN} | PLLI2S input clock ⁽²⁾ | | 0.95 ⁽³⁾ | 1 | 2.10 | MHz | |
| f _{PLLI2S_OUT} | PLLI2S multiplier output clock | | - | - | 216 | MHz | |
| f _{VCO_OUT} | PLLI2S VCO output | | 192 | - | 432 | MHz | |
| t _{LOCK} | PLLI2S lock time | VCO freq = 192 MHz | 75 | - | 200 | µs | |
| | | VCO freq = 432 MHz | 100 | - | 300 | | |
| Jitter ⁽⁴⁾ | Master I2S clock jitter | Cycle to cycle at 12,343 MHz on 48KHz period, N=432, P=4, R=5 | RMS | - | 90 | - | ps |
| | | | peak to peak | - | ±280 | - | |
| | | Average frequency of 12,343 MHz N = 432, P = 4, R = 5 on 256 samples | TBD | - | TBD | ps | |
| | WS I2S clock jitter | Cycle to cycle at 48 KHz on 1000 samples | - | 400 | - | ps | |

Table 35. PLLI2S (audio PLL) characteristics⁽¹⁾ (continued)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------|---------------------------------------|--|--------------|-----|--------------|------|
| $I_{DD(PLLI2S)}^{(5)}$ | PLLI2S power consumption on V_{DD} | VCO freq = 192 MHz VCO freq = 432 MHz | 0.15 0.45 | - | 0.40 0.75 | mA |
| $I_{DDA(PLLI2S)}^{(5)}$ | PLLI2S power consumption on V_{DDA} | VCO freq = 192 MHz VCO freq = 432 MHz | 0.30 0.55 | - | 0.40 0.85 | mA |

1. TBD stands for "to be defined".
2. Take care of using the appropriate division factor M to have the specified PLL input clock values.
3. Guaranteed by design, not tested in production.
4. Value given with main PLL running.
5. Based on characterization, not tested in production.

5.3.11 PLL spread spectrum clock generation (SSCG) characteristics

The spread spectrum clock generation (SSCG) feature allows to reduce electromagnetic interferences (see [Table 42: EMI characteristics](#)). It is available only on the main PLL.

Table 36. SSCG parameters constraint

| Symbol | Parameter | Min | Typ | Max ⁽¹⁾ | Unit |
|-------------------|-----------------------|------|-----|--------------------|------|
| f_{Mod} | Modulation frequency | - | - | 10 | KHz |
| md | Peak modulation depth | 0.25 | - | 2 | % |
| MODEPER * INCSTEP | | - | - | $2^{15}-1$ | - |

1. Guaranteed by design, not tested in production.

Equation 1

The frequency modulation period (MODEPER) is given by the equation below:

$$\text{MODEPER} = \text{round}[f_{\text{PLL_IN}} / (4 \times f_{\text{Mod}})]$$

$f_{\text{PLL_IN}}$ and f_{Mod} must be expressed in Hz.

As an example:

If $f_{\text{PLL_IN}} = 1 \text{ MHz}$, and $f_{\text{MOD}} = 1 \text{ kHz}$, the modulation depth (MODEPER) is given by equation 1:

$$\text{MODEPER} = \text{round}[10^6 / (4 \times 10^3)] = 250$$

Equation 2

Equation 2 allows to calculate the increment step (INCSTEP):

$$\text{INCSTEP} = \text{round}[(2^{15} - 1) \times \text{md} \times \text{PLL}_N / (100 \times 5 \times \text{MODEPER})]$$

$f_{\text{VCO_OUT}}$ must be expressed in MHz.

With a modulation depth (md) = $\pm 2 \%$ (4 % peak to peak), and $\text{PLL}_N = 240$ (in MHz):

$$\text{INCSTEP} = \text{round}[(2^{15} - 1) \times 2 \times 240 / (100 \times 5 \times 250)] = 126 \text{md}(\text{quantitized})\%$$

An amplitude quantization error may be generated because the linear modulation profile is obtained by taking the quantized values (rounded to the nearest integer) of MODPER and INCSTEP. As a result, the achieved modulation depth is quantized. The percentage quantized modulation depth is given by the following formula:

$$\text{md}_{\text{quantized}}\% = (\text{MODEPER} \times \text{INCSTEP} \times 100 \times 5) / ((2^{15} - 1) \times \text{PLL}_N)$$

As a result:

$$\text{md}_{\text{quantized}}\% = (250 \times 126 \times 100 \times 5) / ((2^{15} - 1) \times 240) = 2.002\%(\text{peak})$$

Figure 33 and Figure 34 show the main PLL output clock waveforms in center spread and down spread modes, where:

- F0 is f_{PLL_OUT} nominal.
- T_{mode} is the modulation period.
- md is the modulation depth.

Figure 33. PLL output clock waveforms in center spread mode

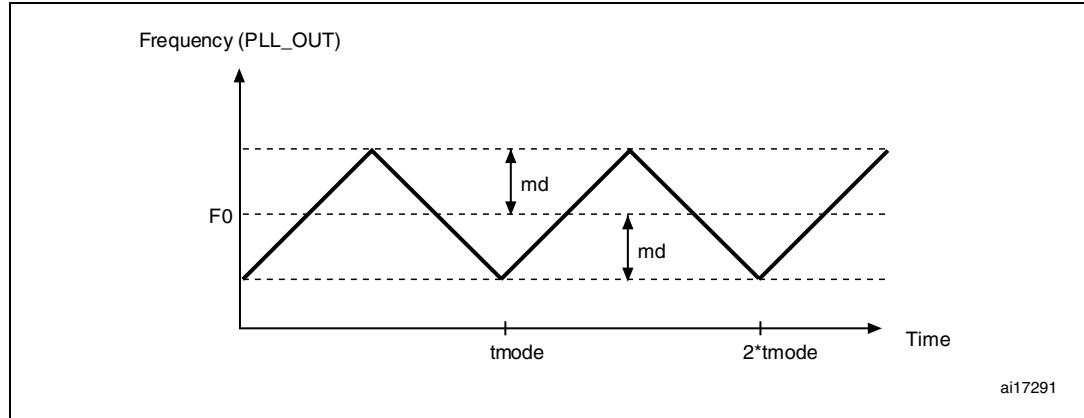
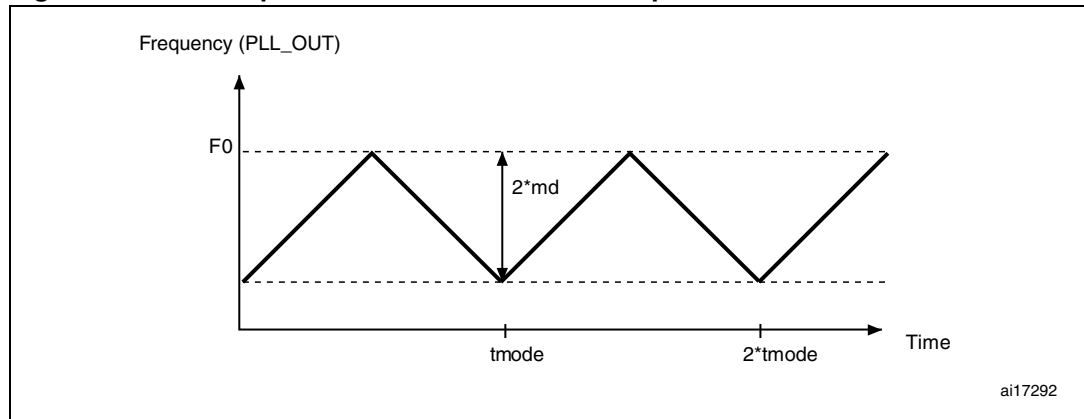


Figure 34. PLL output clock waveforms in down spread mode



5.3.12 Memory characteristics

Flash memory

The characteristics are given at $T_A = -40$ to 105 °C unless otherwise specified.

The devices are shipped to customers with the Flash memory erased.

Table 37. Flash memory characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------|----------------|---|-----|-----|-----|------|
| I_{DD} | Supply current | Write / Erase 8-bit mode, $V_{DD} = 1.8$ V | - | 5 | - | mA |
| | | Write / Erase 16-bit mode, $V_{DD} = 2.1$ V | - | 8 | - | |
| | | Write / Erase 32-bit mode, $V_{DD} = 3.3$ V | - | 12 | - | |

Table 38. Flash memory programming

| Symbol | Parameter | Conditions | Min ⁽¹⁾ | Typ | Max ⁽¹⁾ | Unit |
|-------------------------|----------------------------|---|--------------------|------|--------------------|------|
| t _{prog} | Word programming time | Program/erase parallelism (PSIZE) = x 8/16/32 | - | 16 | 100 ⁽²⁾ | μs |
| t _{ERASE16KB} | Sector (16 KB) erase time | Program/erase parallelism (PSIZE) = x 8 | - | 400 | 800 | ms |
| | | Program/erase parallelism (PSIZE) = x 16 | - | 300 | 600 | |
| | | Program/erase parallelism (PSIZE) = x 32 | - | 250 | 500 | |
| t _{ERASE64KB} | Sector (64 KB) erase time | Program/erase parallelism (PSIZE) = x 8 | - | 1200 | 2400 | ms |
| | | Program/erase parallelism (PSIZE) = x 16 | - | 700 | 1400 | |
| | | Program/erase parallelism (PSIZE) = x 32 | - | 550 | 1100 | |
| t _{ERASE128KB} | Sector (128 KB) erase time | Program/erase parallelism (PSIZE) = x 8 | - | 2 | 4 | s |
| | | Program/erase parallelism (PSIZE) = x 16 | - | 1.3 | 2.6 | |
| | | Program/erase parallelism (PSIZE) = x 32 | - | 1 | 2 | |
| t _{ME} | Mass erase time | Program/erase parallelism (PSIZE) = x 8 | - | 16 | 32 | s |
| | | Program/erase parallelism (PSIZE) = x 16 | - | 11 | 22 | |
| | | Program/erase parallelism (PSIZE) = x 32 | - | 8 | 16 | |
| V _{prog} | Programming voltage | 32-bit program operation | 2.7 | - | 3.6 | V |
| | | 16-bit program operation | 2.1 | - | 3.6 | V |
| | | 8-bit program operation | 1.8 | - | 3.6 | V |

1. Based on characterization, not tested in production.
2. The maximum programming time is measured after 100K erase operations.

Table 39. Flash memory programming with V_{PP}

| Symbol | Parameter | Conditions | Min ⁽¹⁾ | Typ | Max ⁽¹⁾ | Unit |
|-------------------------|----------------------------|--|--------------------|-----|--------------------|------|
| t _{prog} | Double word programming | T _A = 0 to +40 °C V _{DD} = 3.3 V V _{PP} = 8.5 V | - | 16 | 100 ⁽²⁾ | μs |
| t _{ERASE16KB} | Sector (16 KB) erase time | | - | 230 | - | ms |
| t _{ERASE64KB} | Sector (64 KB) erase time | | - | 490 | - | |
| t _{ERASE128KB} | Sector (128 KB) erase time | | - | 875 | - | |
| t _{ME} | Mass erase time | | - | 6.9 | - | s |
| V _{prog} | Programming voltage | | 2.7 | - | 3.6 | V |

Table 39. Flash memory programming with V_{PP} (continued)

| Symbol | Parameter | Conditions | Min ⁽¹⁾ | Typ | Max ⁽¹⁾ | Unit |
|---------------------------------|---|------------|--------------------|-----|--------------------|------|
| V _{PP} | V _{PP} voltage range | | 7 | - | 9 | V |
| I _{PP} | Minimum current sunk on the V _{PP} pin | | 10 | - | - | mA |
| t _{VPP} ⁽³⁾ | Cumulative time during which V _{PP} is applied | | - | - | 1 | hour |

1. Guaranteed by design, not tested in production.
2. The maximum programming time is measured after 100K erase operations.
3. V_{PP} should only be connected during programming/erasing.

Table 40. Flash memory endurance and data retention

| Symbol | Parameter | Conditions | Value | Unit |
|------------------|----------------|---|--------------------|---------|
| | | | Min ⁽¹⁾ | |
| N _{END} | Endurance | T _A = -40 to +85 °C (6 suffix versions) T _A = -40 to +105 °C (7 suffix versions) | 10 | kcycles |
| t _{RET} | Data retention | 1 kcycle ⁽²⁾ at T _A = 85 °C | 30 | Years |
| | | 1 kcycle ⁽²⁾ at T _A = 105 °C | 10 | |
| | | 10 kcycles ⁽²⁾ at T _A = 55 °C | 20 | |

1. Based on characterization, not tested in production.
2. Cycling performed over the whole temperature range.

5.3.13 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports), the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- **Electrostatic discharge (ESD)** (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- **FTB:** A burst of fast transient voltage (positive and negative) is applied to V_{DD} and V_{SS} through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in [Table 41](#). They are based on the EMS levels and classes defined in application note AN1709.

Table 41. EMS characteristics

| Symbol | Parameter | Conditions | Level/Class |
|------------|---|--|-------------|
| V_{FESD} | Voltage limits to be applied on any I/O pin to induce a functional disturbance | $V_{DD} = 3.3\text{ V}$, LQFP176, $T_A = +25\text{ °C}$, $f_{HCLK} = 168\text{ MHz}$, conforms to IEC 61000-4-2 | 2B |
| V_{EFTB} | Fast transient voltage burst limits to be applied through 100 pF on V_{DD} and V_{SS} pins to induce a functional disturbance | $V_{DD} = 3.3\text{ V}$, LQFP176, $T_A = +25\text{ °C}$, $f_{HCLK} = 168\text{ MHz}$, conforms to IEC 61000-4-2 | 4A |

Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

Software recommendations

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical Data corruption (control registers...)

Prequalification trials

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

Electromagnetic Interference (EMI)

The electromagnetic field emitted by the device are monitored while a simple application, executing EEMBC² code, is running. This emission test is compliant with SAE IEC61967-2 standard which specifies the test board and the pin loading.

Table 42. EMI characteristics

| Symbol | Parameter | Conditions | Monitored frequency band | Max vs. [f _{HSE} /f _{CPU}] | Unit |
|------------------|------------|---|--------------------------|---|------|
| | | | | 25/168 MHz | |
| S _{EMI} | Peak level | V _{DD} = 3.3 V, T _A = 25 °C, LQFP176 package, conforming to SAE J1752/3 EEMBC, code running from Flash with ART accelerator enabled | 0.1 to 30 MHz | 32 | dBµV |
| | | | 30 to 130 MHz | 25 | |
| | | | 130 MHz to 1GHz | 29 | |
| | | | SAE EMI Level | 4 | - |
| | | V _{DD} = 3.3 V, T _A = 25 °C, LQFP176 package, conforming to SAE J1752/3 EEMBC, code running from Flash with ART accelerator and clock dithering enabled | 0.1 to 30 MHz | 19 | dBµV |
| | | | 30 to 130 MHz | 16 | |
| | | | 130 MHz to 1GHz | 18 | |
| | | | SAE EMI level | 3.5 | - |

5.3.14 Absolute maximum ratings (electrical sensitivity)

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts × (n+1) supply pins). This test conforms to the JESD22-A114/C101 standard.

Table 43. ESD absolute maximum ratings

| Symbol | Ratings | Conditions | Class | Maximum value ⁽¹⁾ | Unit |
|-----------------------|---|---|-------|------------------------------|------|
| V _{ESD(HBM)} | Electrostatic discharge voltage (human body model) | T _A = +25 °C conforming to JESD22-A114 | 2 | 2000 ⁽²⁾ | V |
| V _{ESD(CDM)} | Electrostatic discharge voltage (charge device model) | T _A = +25 °C conforming to JESD22-C101 | II | 500 | |

1. Based on characterization results, not tested in production.
2. On V_{BAT} pin, V_{ESD(HBM)} is limited to 1000 V.

Static latchup

Two complementary static tests are required on six parts to assess the latchup performance:

- A supply overvoltage is applied to each power supply pin
- A current injection is applied to each input, output and configurable I/O pin

These tests are compliant with EIA/JESD 78A IC latchup standard.

Table 44. Electrical sensitivities

| Symbol | Parameter | Conditions | Class |
|--------|-----------------------|--|------------|
| LU | Static latch-up class | T _A = +105 °C conforming to JESD78A | II level A |

5.3.15 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below V_{SS} or above V_{DD} (for standard, 3 V-capable I/O pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.

Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error above a certain limit (>5 LSB TUE), out of spec current injection on adjacent pins or other functional failure (for example reset, oscillator frequency deviation).

The test results are given in [Table 45](#).

Table 45. I/O current injection susceptibility

| Symbol | Description | Functional susceptibility | | Unit |
|------------------|-----------------------------------|---------------------------|--------------------|------|
| | | Negative injection | Positive injection | |
| I _{INJ} | Injected current on all FT pins | -5 | +0 | mA |
| | Injected current on any other pin | -5 | +5 | |

5.3.16 I/O port characteristics

General input/output characteristics

Unless otherwise specified, the parameters given in [Table 46](#) are derived from tests performed under the conditions summarized in [Table 13](#). All I/Os are CMOS and TTL compliant.

Table 46. I/O static characteristics

| Symbol | Parameter | | Conditions | Min | Typ | Max | Unit |
|----------------|---|-----------------------------------|--|--------------------|-----|--------------|---------------|
| V_{IL} | Input low level voltage | | TTL ports $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | $V_{SS}-0.3$ | - | 0.8 | V |
| $V_{IH}^{(1)}$ | TTa/TC ⁽²⁾ I/O input high level voltage | | | 2.0 | - | $V_{DD}+0.3$ | |
| | FT ⁽³⁾ I/O input high level voltage | | | 2.0 | - | 5.5 | |
| V_{IL} | Input low level voltage | | CMOS ports $1.8\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | $V_{SS}-0.3$ | - | $0.3V_{DD}$ | V |
| $V_{IH}^{(1)}$ | TTa/TC I/O input high level voltage | | | $0.7V_{DD}$ | - | $3.6^{(4)}$ | |
| | FT I/O input high level voltage | | | | - | $5.2^{(4)}$ | |
| V_{hys} | I/O Schmitt trigger voltage hysteresis ⁽⁵⁾ | | CMOS ports $2.0\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | - | 200 | - | mV |
| | IO FT Schmitt trigger voltage hysteresis ⁽⁵⁾ | | | $5\% V_{DD}^{(4)}$ | - | - | |
| I_{lkg} | I/O input leakage current ⁽⁶⁾ | | $V_{SS} \leq V_{IN} \leq V_{DD}$ | - | - | ± 1 | μA |
| | I/O FT input leakage current ⁽⁶⁾ | | $V_{IN} = 5\text{ V}$ | - | - | 3 | |
| R_{PU} | Weak pull-up equivalent resistor ⁽⁷⁾ | All pins except for PA10 and PB12 | $V_{IN} = V_{SS}$ | 30 | 40 | 50 | k Ω |
| | | PA10 and PB12 | | 8 | 11 | 15 | |
| R_{PD} | Weak pull-down equivalent resistor | All pins except for PA10 and PB12 | $V_{IN} = V_{DD}$ | 30 | 40 | 50 | |
| | | PA10 and PB12 | | 8 | 11 | 15 | |
| $C_{IO}^{(8)}$ | I/O pin capacitance | | | | 5 | | pF |

1. If V_{IH} maximum value cannot be respected, the injection current must be limited externally to $I_{INJ(PIN)}$ maximum value.
2. TTa = 3.3 V tolerant I/O directly connected to ADC; TC = standard 3.3 V I/O.
3. FT = 5 V tolerant.
4. With a minimum of 100 mV.
5. Hysteresis voltage between Schmitt trigger switching levels. Based on characterization, not tested in production.
6. Leakage could be higher than the maximum value, if negative current is injected on adjacent pins.
7. Pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This MOS/NMOS contribution to the series resistance is minimum (~10% order).
8. Guaranteed by design, not tested in production.

All I/Os are CMOS and TTL compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters.

Output driving current

The GPIOs (general purpose input/outputs) can sink or source up to ±8 mA, and sink or source up to ±20 mA (with a relaxed V_{OL}/V_{OH}) except PC13, PC14 and PC15 which can sink or source up to ±3mA. When using the PC13 to PC15 GPIOs in output mode, the speed should not exceed 2 MHz with a maximum load of 30 pF.

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in [Section 5.2](#). In particular:

- The sum of the currents sourced by all the I/Os on V_{DD} , plus the maximum Run consumption of the MCU sourced on V_{DD} , cannot exceed the absolute maximum rating I_{VDD} (see [Table 11](#)).
- The sum of the currents sunk by all the I/Os on V_{SS} plus the maximum Run consumption of the MCU sunk on V_{SS} cannot exceed the absolute maximum rating I_{VSS} (see [Table 11](#)).

Output voltage levels

Unless otherwise specified, the parameters given in [Table 47](#) are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 13](#). All I/Os are CMOS and TTL compliant.

Table 47. Output voltage characteristics⁽¹⁾

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------------|---|---|--------------|-----|------|
| $V_{OL}^{(2)}$ | Output low level voltage for an I/O pin when 8 pins are sunk at same time | TTL port $I_{IO} = +8 \text{ mA}$ $2.7 \text{ V} < V_{DD} < 3.6 \text{ V}$ | - | 0.4 | V |
| $V_{OH}^{(3)}$ | Output high level voltage for an I/O pin when 8 pins are sourced at same time | | $V_{DD}-0.4$ | - | |
| $V_{OL}^{(2)}$ | Output low level voltage for an I/O pin when 8 pins are sunk at same time | CMOS port $I_{IO} = +8 \text{ mA}$ $2.7 \text{ V} < V_{DD} < 3.6 \text{ V}$ | - | 0.4 | V |
| $V_{OH}^{(3)}$ | Output high level voltage for an I/O pin when 8 pins are sourced at same time | | 2.4 | - | |
| $V_{OL}^{(2)(4)}$ | Output low level voltage for an I/O pin when 8 pins are sunk at same time | $I_{IO} = +20 \text{ mA}$ $2.7 \text{ V} < V_{DD} < 3.6 \text{ V}$ | - | 1.3 | V |
| $V_{OH}^{(3)(4)}$ | Output high level voltage for an I/O pin when 8 pins are sourced at same time | | $V_{DD}-1.3$ | - | |
| $V_{OL}^{(2)(4)}$ | Output low level voltage for an I/O pin when 8 pins are sunk at same time | $I_{IO} = +6 \text{ mA}$ $2 \text{ V} < V_{DD} < 2.7 \text{ V}$ | - | 0.4 | V |
| $V_{OH}^{(3)(4)}$ | Output high level voltage for an I/O pin when 8 pins are sourced at same time | | $V_{DD}-0.4$ | - | |

1. PC13, PC14, PC15 and PI8 are supplied through the power switch. Since the switch only sinks a limited amount of current (3 mA), the use of GPIOs PC13 to PC15 and PI8 in output mode is limited: the speed should not exceed 2 MHz with a maximum load of 30 pF and these I/Os must not be used as a current source (e.g. to drive an LED).
2. The I_{IO} current sunk by the device must always respect the absolute maximum rating specified in [Table 11](#) and the sum of I_{IO} (I/O ports and control pins) must not exceed I_{VSS} .
3. The I_{IO} current sourced by the device must always respect the absolute maximum rating specified in [Table 11](#) and the sum of I_{IO} (I/O ports and control pins) must not exceed I_{VDD} .

4. Based on characterization data, not tested in production.

Input/output AC characteristics

The definition and values of input/output AC characteristics are given in [Figure 35](#) and [Table 48](#), respectively.

Unless otherwise specified, the parameters given in [Table 48](#) are derived from tests performed under the ambient temperature and V_{DD} supply voltage conditions summarized in [Table 13](#).

Table 48. I/O AC characteristics⁽¹⁾⁽²⁾⁽³⁾

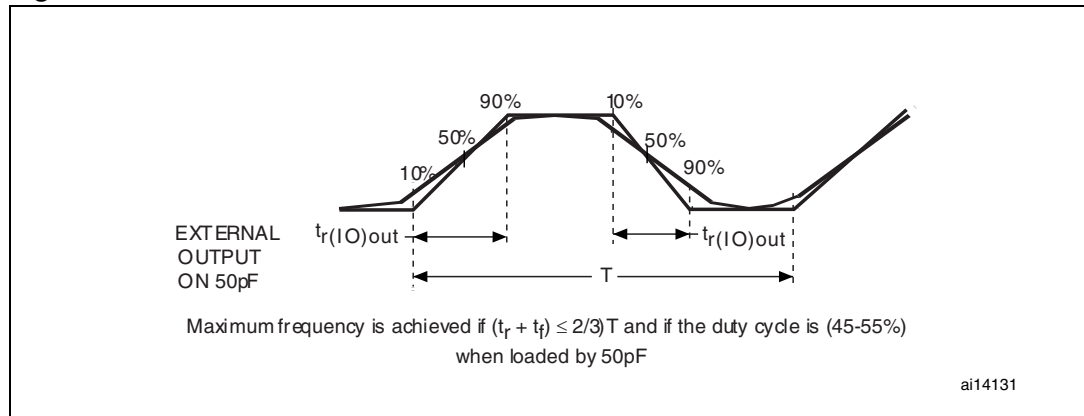
| OSPEEDRy [1:0] bit value ⁽¹⁾ | Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|------------------------------------|------------------------------------|--|-----|-----|---------------------|------|
| 00 | f _{max(IO)out} | Maximum frequency ⁽⁴⁾ | C _L = 50 pF, V _{DD} > 2.70 V | - | - | 2 | MHz |
| | | | C _L = 50 pF, V _{DD} > 1.8 V | - | - | 2 | |
| | | | C _L = 10 pF, V _{DD} > 2.70 V | - | - | TBD | |
| | | | C _L = 10 pF, V _{DD} > 1.8 V | - | - | TBD | |
| | t _{f(IO)out} | Output high to low level fall time | C _L = 50 pF, V _{DD} = 1.8 V to 3.6 V | - | - | TBD | ns |
| t _{r(IO)out} | Output low to high level rise time | - | | - | TBD | | |
| 01 | f _{max(IO)out} | Maximum frequency ⁽⁴⁾ | C _L = 50 pF, V _{DD} > 2.70 V | - | - | 25 | MHz |
| | | | C _L = 50 pF, V _{DD} > 1.8 V | - | - | 12.5 ⁽⁵⁾ | |
| | | | C _L = 10 pF, V _{DD} > 2.70 V | - | - | 50 ⁽⁵⁾ | |
| | | | C _L = 10 pF, V _{DD} > 1.8 V | - | - | TBD | |
| | t _{f(IO)out} | Output high to low level fall time | C _L = 50 pF, V _{DD} < 2.7 V | - | - | TBD | ns |
| | | | C _L = 10 pF, V _{DD} > 2.7 V | - | - | TBD | |
| | t _{r(IO)out} | Output low to high level rise time | C _L = 50 pF, V _{DD} < 2.7 V | - | - | TBD | ns |
| C _L = 10 pF, V _{DD} > 2.7 V | | | - | - | TBD | | |
| 10 | f _{max(IO)out} | Maximum frequency ⁽⁴⁾ | C _L = 40 pF, V _{DD} > 2.70 V | - | - | 50 ⁽⁵⁾ | MHz |
| | | | C _L = 40 pF, V _{DD} > 1.8 V | - | - | 25 | |
| | | | C _L = 10 pF, V _{DD} > 2.70 V | - | - | 100 ⁽⁵⁾ | |
| | | | C _L = 10 pF, V _{DD} > 1.8 V | - | - | TBD | |
| | t _{f(IO)out} | Output high to low level fall time | C _L = 50 pF, 2.4 < V _{DD} < 2.7 V | - | - | TBD | ns |
| | | | C _L = 10 pF, V _{DD} > 2.7 V | - | - | TBD | |
| | t _{r(IO)out} | Output low to high level rise time | C _L = 50 pF, 2.4 < V _{DD} < 2.7 V | - | - | TBD | ns |
| C _L = 10 pF, V _{DD} > 2.7 V | | | - | - | TBD | | |

Table 48. I/O AC characteristics⁽¹⁾⁽²⁾⁽³⁾ (continued)

| OSPEEDRy [1:0] bit value ⁽¹⁾ | Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|-------------------------|---|---|-----|-----|--------------------|------|
| 11 | F _{max(IO)out} | Maximum frequency ⁽⁴⁾ | C _L = 30 pF, V _{DD} > 2.70 V | - | - | 100 ⁽⁵⁾ | MHz |
| | | | C _L = 30 pF, V _{DD} > 1.8 V | - | - | 50 ⁽⁵⁾ | |
| | | | C _L = 10 pF, V _{DD} > 2.70 V | - | - | 200 ⁽⁵⁾ | |
| | | | C _L = 10 pF, V _{DD} > 1.8 V | - | - | TBD | |
| | t _{f(IO)out} | Output high to low level fall time | C _L = 20 pF, 2.4 < V _{DD} < 2.7 V | - | - | TBD | ns |
| | | | C _L = 10 pF, V _{DD} > 2.7 V | - | - | TBD | |
| | t _{r(IO)out} | Output low to high level rise time | C _L = 20 pF, 2.4 < V _{DD} < 2.7 V | - | - | TBD | ns |
| | | | C _L = 10 pF, V _{DD} > 2.7 V | - | - | TBD | |
| - | t _{EXTIpw} | Pulse width of external signals detected by the EXTI controller | | 10 | - | - | ns |

1. Based on characterization data, not tested in production.
2. The I/O speed is configured using the OSPEEDRy[1:0] bits. Refer to the STM32F20/21xxx reference manual for a description of the GPIOx_SPEEDR GPIO port output speed register.
3. TBD stands for "to be defined".
4. The maximum frequency is defined in [Figure 35](#).
5. For maximum frequencies above 50 MHz, the compensation cell should be used.

Figure 35. I/O AC characteristics definition



5.3.17 NRST pin characteristics

The NRST pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor, R_{PU} (see [Table 46](#)).

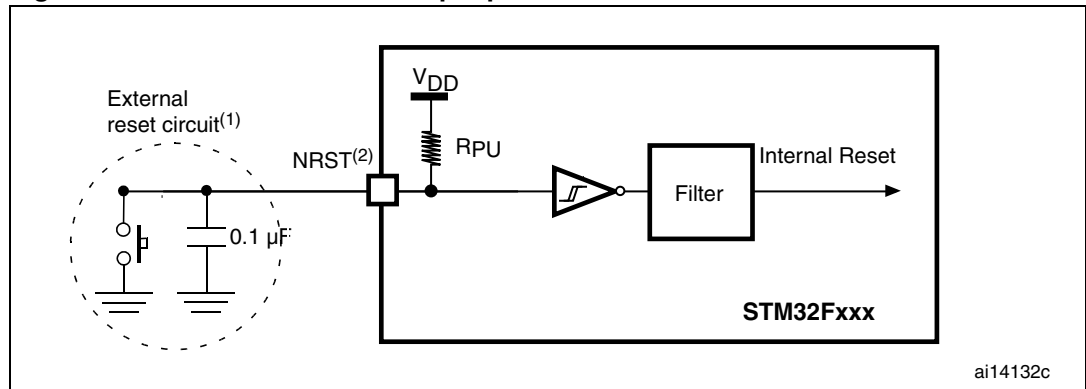
Unless otherwise specified, the parameters given in [Table 49](#) are derived from tests performed under the ambient temperature and V_{DD} supply voltage conditions summarized in [Table 13](#).

Table 49. NRST pin characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------------|---|-----------------------|------|-----|--------------|------------|
| $V_{IL(NRST)}^{(1)}$ | NRST Input low level voltage | | -0.5 | - | 0.8 | V |
| $V_{IH(NRST)}^{(1)}$ | NRST Input high level voltage | | 2 | - | $V_{DD}+0.5$ | |
| $V_{hys(NRST)}$ | NRST Schmitt trigger voltage hysteresis | | - | 200 | - | mV |
| R_{PU} | Weak pull-up equivalent resistor ⁽²⁾ | $V_{IN} = V_{SS}$ | 30 | 40 | 50 | k Ω |
| $V_{F(NRST)}^{(1)}$ | NRST Input filtered pulse | | - | - | 100 | ns |
| $V_{NF(NRST)}^{(1)}$ | NRST Input not filtered pulse | $V_{DD} > 2.7 V$ | 300 | - | - | ns |
| T_{NRST_OUT} | Generated reset pulse duration | Internal Reset source | 20 | - | - | μs |

1. Guaranteed by design, not tested in production.
2. The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance must be minimum (~10% order).

Figure 36. Recommended NRST pin protection



1. The reset network protects the device against parasitic resets.
2. The user must ensure that the level on the NRST pin can go below the $V_{IL(NRST)}$ max level specified in [Table 49](#). Otherwise the reset is not taken into account by the device.

5.3.18 TIM timer characteristics

The parameters given in [Table 50](#) and [Table 51](#) are guaranteed by design.

Refer to [Section 5.3.16: I/O port characteristics](#) for details on the input/output alternate function characteristics (output compare, input capture, external clock, PWM output).

Table 50. Characteristics of TIMx connected to the APB1 domain⁽¹⁾

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---|--|----------------------|----------------------|---------------|
| $t_{res(TIM)}$ | Timer resolution time | AHB/APB1 prescaler distinct from 1, $f_{TIMxCLK} = 84$ MHz | 1 | - | $t_{TIMxCLK}$ |
| | | | 11.9 | - | ns |
| | | AHB/APB1 prescaler = 1, $f_{TIMxCLK} = 42$ MHz | 1 | - | $t_{TIMxCLK}$ |
| | | | 23.8 | - | ns |
| f_{EXT} | Timer external clock frequency on CH1 to CH4 | $f_{TIMxCLK} = 84$ MHz APB1 = 42 MHz | 0 | $f_{TIMxCLK}/2$ | MHz |
| | | | 0 | 42 | MHz |
| Res_{TIM} | Timer resolution | | - | 16/32 | bit |
| | | | 1 | 65536 | $t_{TIMxCLK}$ |
| $t_{COUNTER}$ | 16-bit counter clock period when internal clock is selected | | 0.0119 | 780 | μ s |
| | | | 1 | - | $t_{TIMxCLK}$ |
| | 32-bit counter clock period when internal clock is selected | | 0.0119 | 51130563 | μ s |
| | | | - | 65536×65536 | $t_{TIMxCLK}$ |
| t_{MAX_COUNT} | Maximum possible count | - | 65536×65536 | $t_{TIMxCLK}$ | |
| | | - | 51.1 | s | |

1. TIMx is used as a general term to refer to the TIM2, TIM3, TIM4, TIM5, TIM6, TIM7, and TIM12 timers.

Table 51. Characteristics of TIMx connected to the APB2 domain⁽¹⁾

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---|---|------|-----------------|---------------|
| $t_{res(TIM)}$ | Timer resolution time | AHB/APB2 prescaler distinct from 1, $f_{TIMxCLK} = 168$ MHz | 1 | - | $t_{TIMxCLK}$ |
| | | | 5.95 | - | ns |
| | | AHB/APB2 prescaler = 1, $f_{TIMxCLK} = 84$ MHz | 1 | - | $t_{TIMxCLK}$ |
| | | | 11.9 | - | ns |
| f_{EXT} | Timer external clock frequency on CH1 to CH4 | $f_{TIMxCLK} = 168$ MHz APB2 = 84 MHz | 0 | $f_{TIMxCLK}/2$ | MHz |
| | | | 0 | 84 | MHz |
| Res_{TIM} | Timer resolution | | - | 16 | bit |
| $t_{COUNTER}$ | 16-bit counter clock period when internal clock is selected | | 1 | 65536 | $t_{TIMxCLK}$ |
| t_{MAX_COUNT} | Maximum possible count | | - | 32768 | $t_{TIMxCLK}$ |

1. TIMx is used as a general term to refer to the TIM1, TIM8, TIM9, TIM10, and TIM11 timers.

5.3.19 Communications interfaces

I²C interface characteristics

Unless otherwise specified, the parameters given in [Table 52](#) are derived from tests performed under the ambient temperature, f_{PCLK1} frequency and V_{DD} supply voltage conditions summarized in [Table 13](#).

The STM32F405xx and STM32F407xx I²C interface meets the requirements of the standard I²C communication protocol with the following restrictions: the I/O pins SDA and SCL are mapped to are not “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and V_{DD} is disabled, but is still present.

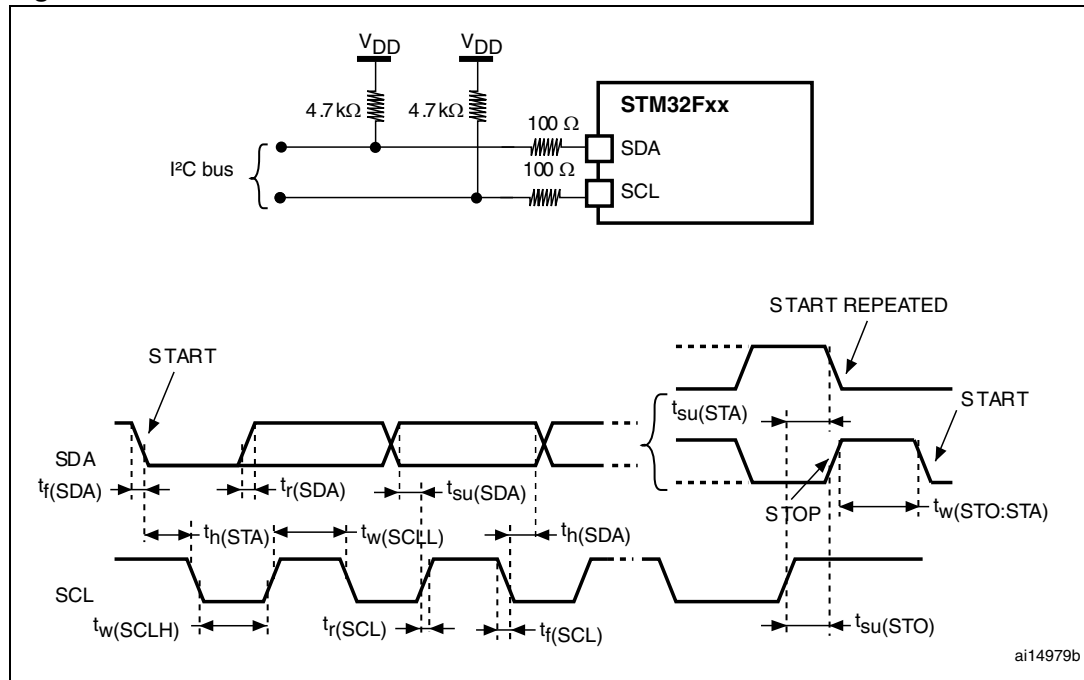
The I²C characteristics are described in [Table 52](#). Refer also to [Section 5.3.16: I/O port characteristics](#) for more details on the input/output alternate function characteristics (SDA and SCL).

Table 52. I²C characteristics

| Symbol | Parameter | Standard mode I ² C ⁽¹⁾ | | Fast mode I ² C ⁽¹⁾⁽²⁾ | | Unit |
|--|---|---|------|--|--------------------|------|
| | | Min | Max | Min | Max | |
| t _{w(SCLL)} | SCL clock low time | 4.7 | - | 1.3 | - | μs |
| t _{w(SCLH)} | SCL clock high time | 4.0 | - | 0.6 | - | |
| t _{su(SDA)} | SDA setup time | 250 | - | 100 | - | ns |
| t _{h(SDA)} | SDA data hold time | 0 | - | 0 | 900 ⁽³⁾ | |
| t _{r(SDA)} t _{r(SCL)} | SDA and SCL rise time | - | 1000 | 20 + 0.1C _b | 300 | |
| t _{f(SDA)} t _{f(SCL)} | SDA and SCL fall time | - | 300 | - | 300 | |
| t _{h(STA)} | Start condition hold time | 4.0 | - | 0.6 | - | μs |
| t _{su(STA)} | Repeated Start condition setup time | 4.7 | - | 0.6 | - | |
| t _{su(STO)} | Stop condition setup time | 4.0 | - | 0.6 | - | μs |
| t _{w(STO:STA)} | Stop to Start condition time (bus free) | 4.7 | - | 1.3 | - | μs |
| C _b | Capacitive load for each bus line | - | 400 | - | 400 | pF |

1. Guaranteed by design, not tested in production.
2. f_{CLK1} must be at least 2 MHz to achieve standard mode I²C frequencies. It must be at least 4 MHz to achieve fast mode I²C frequencies, and a multiple of 10 MHz to reach the 400 kHz maximum I²C fast mode clock.
3. The maximum data hold time has only to be met if the interface does not stretch the low period of SCL signal.

Figure 37. I²C bus AC waveforms and measurement circuit



1. Measurement points are done at CMOS levels: 0.3V_{DD} and 0.7V_{DD}.

Table 53. SCL frequency (f_{PCLK1} = 42 MHz, V_{DD} = 3.3 V)⁽¹⁾⁽²⁾

| f _{SCL} (kHz) | I2C_CCR value |
|------------------------|-------------------------|
| | R _P = 4.7 kΩ |
| 400 | 0x8019 |
| 300 | 0x8021 |
| 200 | 0x8032 |
| 100 | 0x0096 |
| 50 | 0x012C |
| 20 | 0x02EE |

1. R_P = External pull-up resistance, f_{SCL} = I²C speed,
2. For speeds around 200 kHz, the tolerance on the achieved speed is of ±5%. For other speed ranges, the tolerance on the achieved speed ±2%. These variations depend on the accuracy of the external components used to design the application.

I²S - SPI interface characteristics

Unless otherwise specified, the parameters given in [Table 54](#) for SPI or in [Table 55](#) for I²S are derived from tests performed under the ambient temperature, f_{PCLKx} frequency and V_{DD} supply voltage conditions summarized in [Table 13](#).

Refer to [Section 5.3.16: I/O port characteristics](#) for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI and WS, CK, SD for I²S).

Table 54. SPI characteristics⁽¹⁾⁽²⁾

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--|----------------------------------|--|-------------|--------------|------|
| f_{SCK} $1/t_c(SCK)$ | SPI clock frequency | Master mode | - | 37.5 | MHz |
| | | Slave mode | - | 37.5 | |
| $t_{r(SCL)}$ $t_{f(SCL)}$ | SPI clock rise and fall time | Capacitive load: C = 30 pF | - | 8 | ns |
| DuCy(SCK) | SPI slave input clock duty cycle | Slave mode | 30 | 70 | % |
| $t_{su(NSS)}^{(3)}$ | NSS setup time | Slave mode | $4t_{PCLK}$ | - | ns |
| $t_{h(NSS)}^{(3)}$ | NSS hold time | Slave mode | $2t_{PCLK}$ | - | |
| $t_{w(SCLH)}^{(3)}$ $t_{w(SCLL)}^{(3)}$ | SCK high and low time | Master mode, $f_{PCLK} = \text{TBD MHz}$ | TBD | TBD | |
| $t_{su(MI)}^{(3)}$ $t_{su(SI)}^{(3)}$ | Data input setup time | Master mode | 5 | - | |
| | | Slave mode | 5 | - | |
| $t_{h(MI)}^{(3)}$ $t_{h(SI)}^{(3)}$ | Data input hold time | Master mode | 5 | - | |
| | | Slave mode | 4 | - | |
| $t_{a(SO)}^{(3)(4)}$ | Data output access time | Slave mode, $f_{PCLK} = 20 \text{ MHz}$ | 0 | $3 t_{PCLK}$ | |
| $t_{dis(SO)}^{(3)(5)}$ | Data output disable time | Slave mode | 2 | 10 | |
| $t_{v(SO)}^{(3)(1)}$ | Data output valid time | Slave mode (after enable edge) | - | 25 | |
| $t_{v(MO)}^{(3)(1)}$ | Data output valid time | Master mode (after enable edge) | - | 5 | |
| $t_{h(SO)}^{(3)}$ $t_{h(MO)}^{(3)}$ | Data output hold time | Slave mode (after enable edge) | 15 | - | |
| | | Master mode (after enable edge) | 2 | - | |

1. Remapped SPI1 characteristics to be determined.
2. TBD stands for "to be defined".
3. Based on characterization, not tested in production.
4. Min time is for the minimum time to drive the output and the max time is for the maximum time to validate the data.
5. Min time is for the minimum time to invalidate the output and the max time is for the maximum time to put the data in Hi-Z

Figure 38. SPI timing diagram - slave mode and CPHA = 0

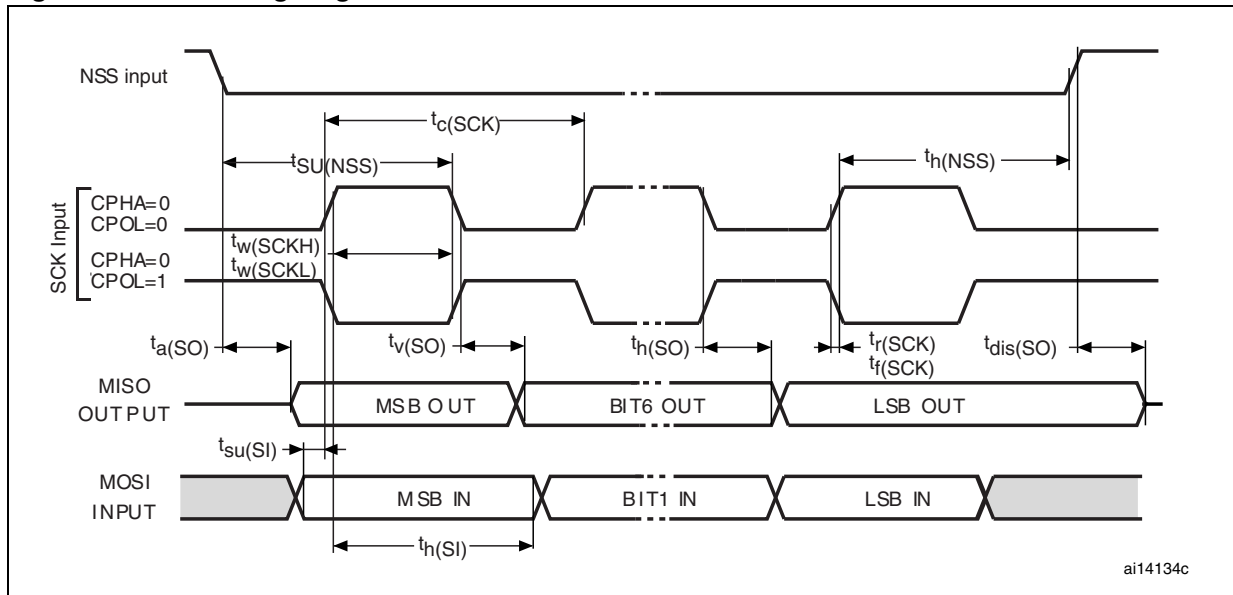
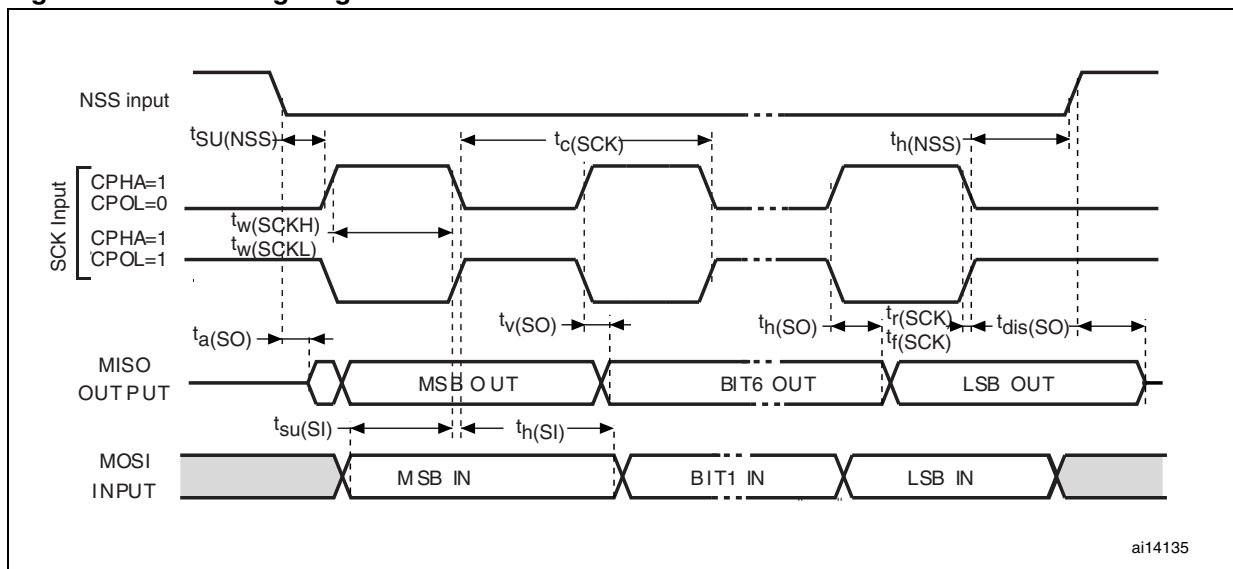
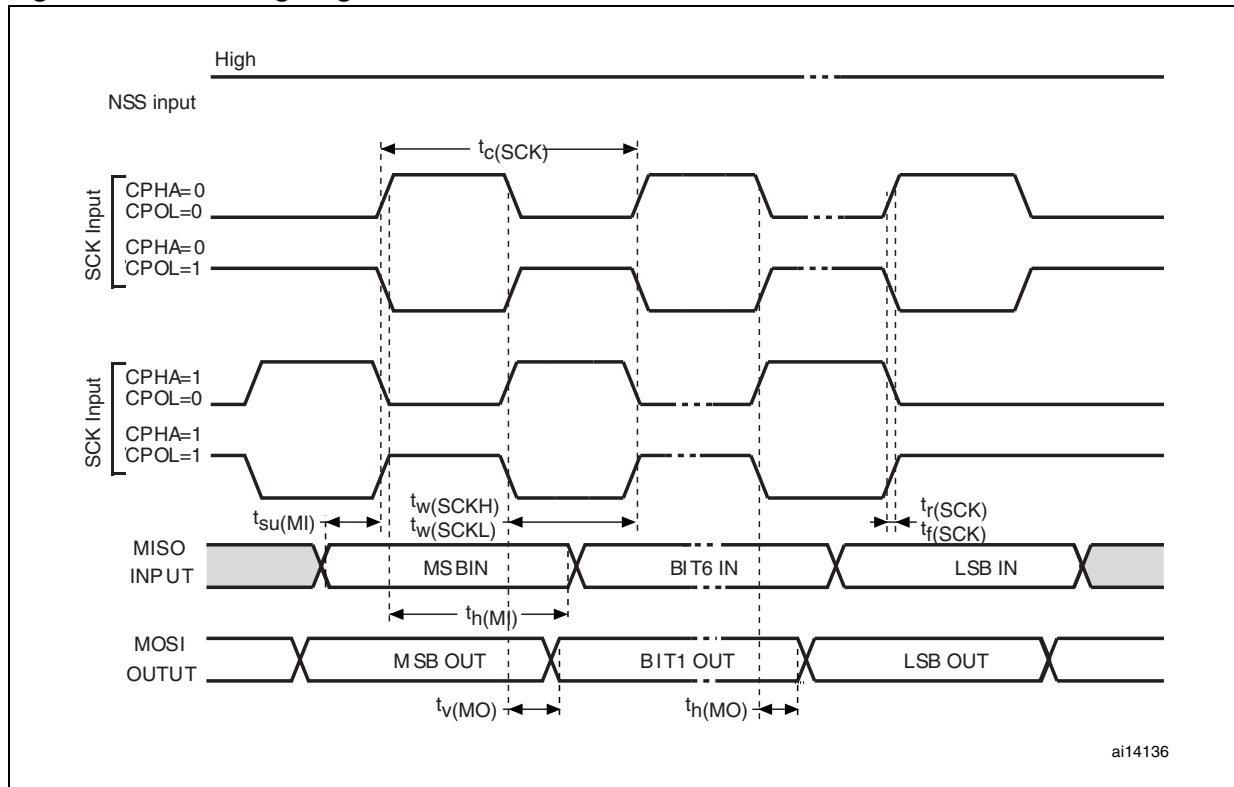


Figure 39. SPI timing diagram - slave mode and CPHA = 1⁽¹⁾



1. Measurement points are done at CMOS levels: 0.3V_{DD} and 0.7V_{DD}.

Figure 40. SPI timing diagram - master mode⁽¹⁾



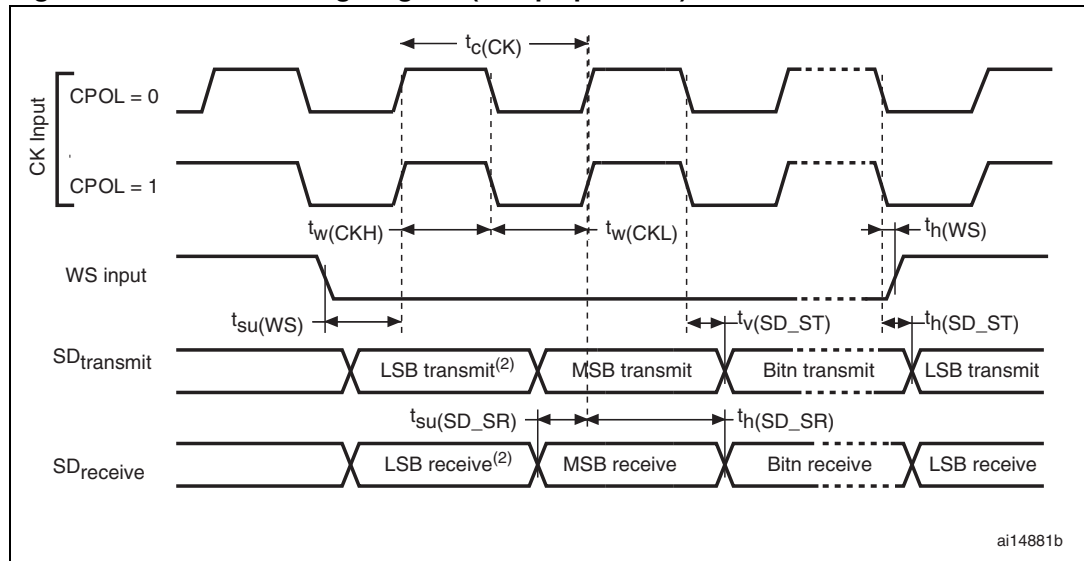
1. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

Table 55. I²S characteristics⁽¹⁾

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--|---|---|------------|-----|------|
| f _{CK} 1/t _{c(CK)} | I ² S clock frequency | Master | TBD | TBD | MHz |
| | | Slave | 0 | TBD | |
| t _{r(CK)} t _{f(CK)} | I ² S clock rise and fall time | capacitive load C _L = 50 pF | - | TBD | ns |
| t _{v(WS)} ⁽²⁾ | WS valid time | Master | TBD | - | |
| t _{h(WS)} ⁽²⁾ | WS hold time | Master | TBD | - | |
| t _{su(WS)} ⁽²⁾ | WS setup time | Slave | TBD | - | |
| t _{h(WS)} ⁽²⁾ | WS hold time | Slave | TBD | - | |
| t _{w(CKH)} ⁽²⁾ t _{w(CKL)} ⁽²⁾ | CK high and low time | Master f _{PCLK} = TBD, presc = TBD | TBD | - | |
| t _{su(SD_MR)} ⁽²⁾ t _{su(SD_SR)} ⁽²⁾ | Data input setup time | Master receiver Slave receiver | TBD TBD | - | |
| t _{h(SD_MR)} ⁽²⁾⁽³⁾ t _{h(SD_SR)} ⁽²⁾⁽³⁾ | Data input hold time | Master receiver Slave receiver | TBD TBD | - | |
| t _{h(SD_MR)} ⁽²⁾ t _{h(SD_SR)} ⁽²⁾ | Data input hold time | Master f _{PCLK} = TBD Slave f _{PCLK} = TBD | TBD TBD | - | |
| t _{v(SD_ST)} ⁽²⁾⁽³⁾ | Data output valid time | Slave transmitter (after enable edge) | - | TBD | |
| | | f _{PCLK} = TBD | - | TBD | |
| t _{h(SD_ST)} ⁽²⁾ | Data output hold time | Slave transmitter (after enable edge) | TBD | - | |
| t _{v(SD_MT)} ⁽²⁾⁽³⁾ | Data output valid time | Master transmitter (after enable edge) | - | TBD | |
| | | f _{PCLK} = TBD | TBD | TBD | |
| t _{h(SD_MT)} ⁽²⁾ | Data output hold time | Master transmitter (after enable edge) | TBD | - | |

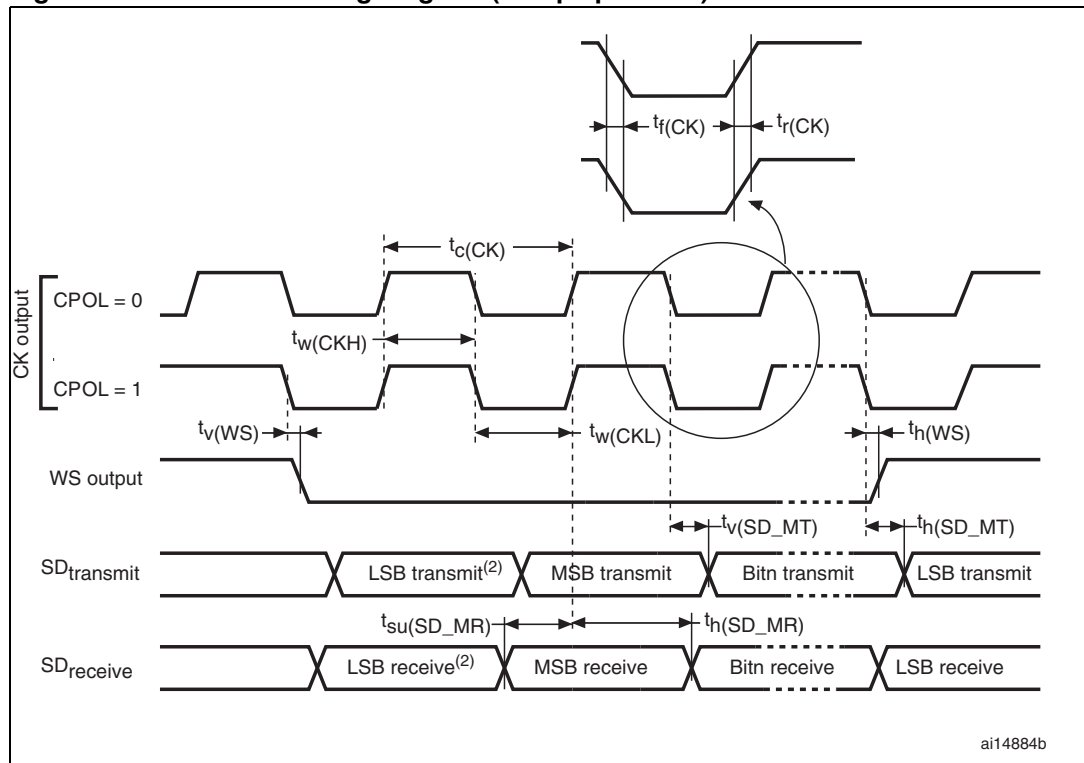
1. TBD stands for “to be defined”.
2. Based on design simulation and/or characterization results, not tested in production.
3. Depends on f_{PCLK}. For example, if f_{PCLK}=8 MHz, then T_{PCLK} = 1/f_{PCLK} =125 ns.

Figure 41. I²S slave timing diagram (Philips protocol)⁽¹⁾



1. Measurement points are done at CMOS levels: $0.3 \times V_{DD}$ and $0.7 \times V_{DD}$.
2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

Figure 42. I²S master timing diagram (Philips protocol)⁽¹⁾



1. Based on characterization, not tested in production.
2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

USB OTG FS characteristics

This interface is present in both the USB OTG HS and USB OTG FS controllers.

Table 56. USB OTG FS startup time

| Symbol | Parameter | Max | Unit |
|---------------------|-------------------------------------|-----|---------|
| $t_{STARTUP}^{(1)}$ | USB OTG FS transceiver startup time | 1 | μs |

1. Guaranteed by design, not tested in production.

Table 57. USB OTG FS DC electrical characteristics

| Symbol | Parameter | Conditions | Min. ⁽¹⁾ | Typ. | Max. ⁽¹⁾ | Unit | |
|---------------|---|---------------------------------|---|------|---------------------|------------|---|
| Input levels | V_{DD} | USB OTG FS operating voltage | 3.0 ⁽²⁾ | - | 3.6 | V | |
| | $V_{DI}^{(3)}$ | Differential input sensitivity | I(USB_FS_DP/DM, USB_HS_DP/DM) | 0.2 | - | - | V |
| | $V_{CM}^{(3)}$ | Differential common mode range | Includes V_{DI} range | 0.8 | - | 2.5 | |
| | $V_{SE}^{(3)}$ | Single ended receiver threshold | | 1.3 | - | 2.0 | |
| Output levels | V_{OL} | Static output level low | R_L of 1.5 k Ω to 3.6 V ⁽⁴⁾ | - | - | 0.3 | V |
| | V_{OH} | Static output level high | R_L of 15 k Ω to $V_{SS}^{(4)}$ | 2.8 | - | 3.6 | |
| R_{PD} | PA11, PA12, PB14, PB15 (USB_FS_DP/DM, USB_HS_DP/DM) | $V_{IN} = V_{DD}$ | 17 | 21 | 24 | k Ω | |
| | PA9, PB13 (OTG_FS_VBUS, OTG_HS_VBUS) | | 0.65 | 1.1 | 2.0 | | |
| R_{PU} | PA12, PB15 (USB_FS_DP, USB_HS_DP) | $V_{IN} = V_{SS}$ | 1.5 | 1.8 | 2.1 | | |
| | PA9, PB13 (OTG_FS_VBUS, OTG_HS_VBUS) | $V_{IN} = V_{SS}$ | 0.25 | 0.37 | 0.55 | | |

1. All the voltages are measured from the local ground potential.
2. The STM32F405xx and STM32F407xx USB OTG FS functionality is ensured down to 2.7 V but not the full USB OTG FS electrical characteristics which are degraded in the 2.7-to-3.0 V V_{DD} voltage range.
3. Guaranteed by design, not tested in production.
4. R_L is the load connected on the USB OTG FS drivers

Figure 43. USB OTG FS timings: definition of data signal rise and fall time

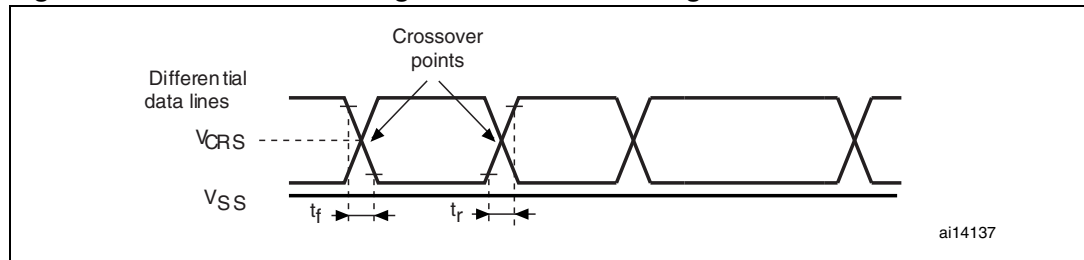


Table 58. USB OTG FS electrical characteristics⁽¹⁾

| Driver characteristics | | | | | |
|------------------------|---------------------------------|-----------------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| t_r | Rise time ⁽²⁾ | $C_L = 50 \text{ pF}$ | 4 | 20 | ns |
| t_f | Fall time ⁽²⁾ | $C_L = 50 \text{ pF}$ | 4 | 20 | ns |
| t_{rfm} | Rise/ fall time matching | t_r/t_f | 90 | 110 | % |
| V_{CRS} | Output signal crossover voltage | | 1.3 | 2.0 | V |

1. Guaranteed by design, not tested in production.
2. Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).

Table 59. USB FS clock timing parameters⁽¹⁾⁽²⁾

| Parameter | | Symbol | Min | Nominal | Max | Unit |
|--|------------|-------------------------|------|---------|-----|------|
| f _{HCLK} value to guarantee proper operation of USB FS interface | | - | 14.2 | | | MHz |
| Frequency (first transition) | 8-bit ±10% | F _{START_8BIT} | TBD | TBD | TBD | MHz |
| Frequency (steady state) ±500 ppm | | F _{STEADY} | TBD | TBD | TBD | MHz |
| Duty cycle (first transition) | 8-bit ±10% | D _{START_8BIT} | TBD | TBD | TBD | % |
| Duty cycle (steady state) ±500 ppm | | D _{STEADY} | TBD | TBD | TBD | % |
| Time to reach the steady state frequency and duty cycle after the first transition | | T _{STEADY} | - | - | TBD | ms |
| Clock startup time after the de-assertion of SuspendM | Peripheral | T _{START_DEV} | - | - | TBD | ms |
| | Host | T _{START_HOST} | - | - | - | |
| PHY preparation time after the first transition of the input clock | | T _{PREP} | - | - | - | µs |

1. Guaranteed by design, not tested in production.
2. TBD stands for “to be defined”.

USB HS characteristics

Table 60 shows the USB HS operating voltage.

Table 60. USB HS DC electrical characteristics

| Symbol | | Parameter | Min. ⁽¹⁾ | Max. ⁽¹⁾ | Unit |
|-------------|-----------------|------------------------------|---------------------|---------------------|------|
| Input level | V _{DD} | USB OTG HS operating voltage | 2.7 | 3.6 | V |

1. All the voltages are measured from the local ground potential.

Table 61. USB HS clock timing parameters⁽¹⁾

| Parameter | | Symbol | Min | Nominal | Max | Unit |
|--|------------|-------------------------|--------|---------|--------|------|
| f _{HCLK} value to guarantee proper operation of USB HS interface | | | 30 | | | MHz |
| Frequency (first transition) | 8-bit ±10% | F _{START_8BIT} | 54 | 60 | 66 | MHz |
| Frequency (steady state) ±500 ppm | | F _{STEADY} | 59.97 | 60 | 60.03 | MHz |
| Duty cycle (first transition) | 8-bit ±10% | D _{START_8BIT} | 40 | 50 | 60 | % |
| Duty cycle (steady state) ±500 ppm | | D _{STEADY} | 49.975 | 50 | 50.025 | % |
| Time to reach the steady state frequency and duty cycle after the first transition | | T _{STEADY} | - | - | 1.4 | ms |
| Clock startup time after the de-assertion of SuspendM | Peripheral | T _{START_DEV} | - | - | 5.6 | ms |
| | Host | T _{START_HOST} | - | - | - | |
| PHY preparation time after the first transition of the input clock | | T _{PREP} | - | - | - | µs |

1. Guaranteed by design, not tested in production.

Figure 44. ULPI timing diagram

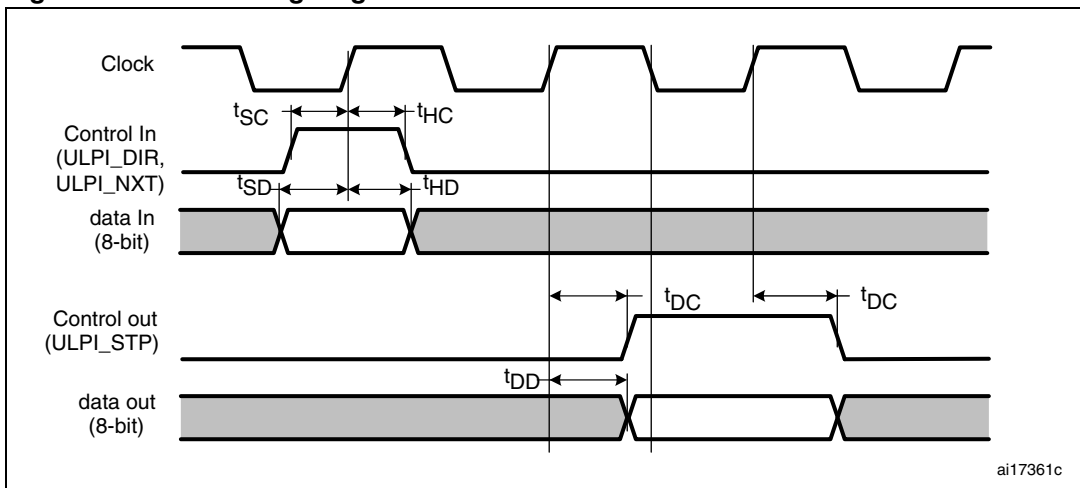


Table 62. ULPI timing

| Parameter | Symbol | Value ⁽¹⁾ | | Unit |
|---|-----------------|----------------------|------|------|
| | | Min. | Max. | |
| Control in (ULPI_DIR) setup time | t _{SC} | - | 2.0 | ns |
| Control in (ULPI_NXT) setup time | | - | 1.5 | |
| Control in (ULPI_DIR, ULPI_NXT) hold time | t _{HC} | | - | |
| Data in setup time | t _{SD} | - | 2.0 | |
| Data in hold time | t _{HD} | 0 | - | |
| Control out (ULPI_STP) setup time and hold time | t _{DC} | - | 9.2 | |
| Data out available from clock rising edge | t _{DD} | - | 10.7 | |

1. V_{DD} = 2.7 V to 3.6 V and T_A = -40 to 85 °C.

Ethernet characteristics

Table 63 shows the Ethernet operating voltage.

Table 63. Ethernet DC electrical characteristics

| Symbol | Parameter | Min. ⁽¹⁾ | Max. ⁽¹⁾ | Unit | |
|-------------|-----------------|----------------------------|---------------------|------|---|
| Input level | V _{DD} | Ethernet operating voltage | 2.7 | 3.6 | V |

1. All the voltages are measured from the local ground potential.

Table 64 gives the list of Ethernet MAC signals for the SMI (station management interface) and Figure 45 shows the corresponding timing diagram.

Figure 45. Ethernet SMI timing diagram

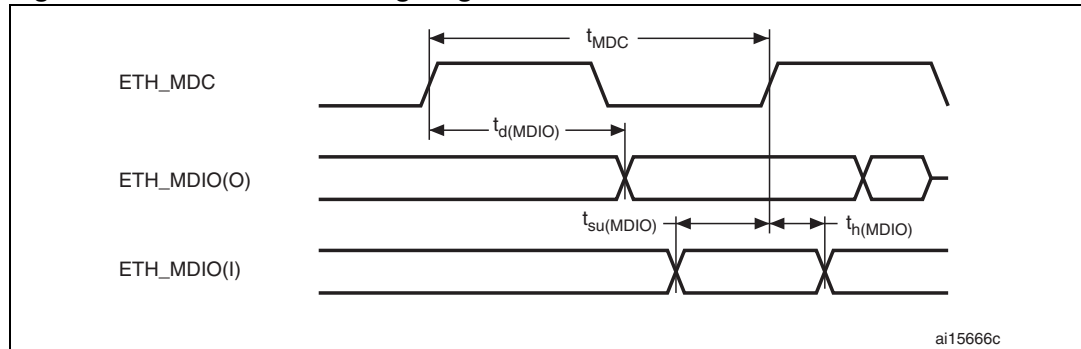


Table 64. Dynamics characteristics: Ethernet MAC signals for SMI⁽¹⁾

| Symbol | Rating | Min | Typ | Max | Unit |
|-----------------------|---|-----|-----|-----|------|
| t _{MDC} | MDC cycle time (1.71 MHz, AHB = 72 MHz) | TBD | TBD | TBD | ns |
| t _{d(MDIO)} | MDIO write data valid time | TBD | TBD | TBD | ns |
| t _{su(MDIO)} | Read data setup time | TBD | TBD | TBD | ns |
| t _{h(MDIO)} | Read data hold time | TBD | TBD | TBD | ns |

1. TBD stands for “to be defined”.

Table 65 gives the list of Ethernet MAC signals for the RMIi and Figure 46 shows the corresponding timing diagram.

Figure 46. Ethernet RMIi timing diagram

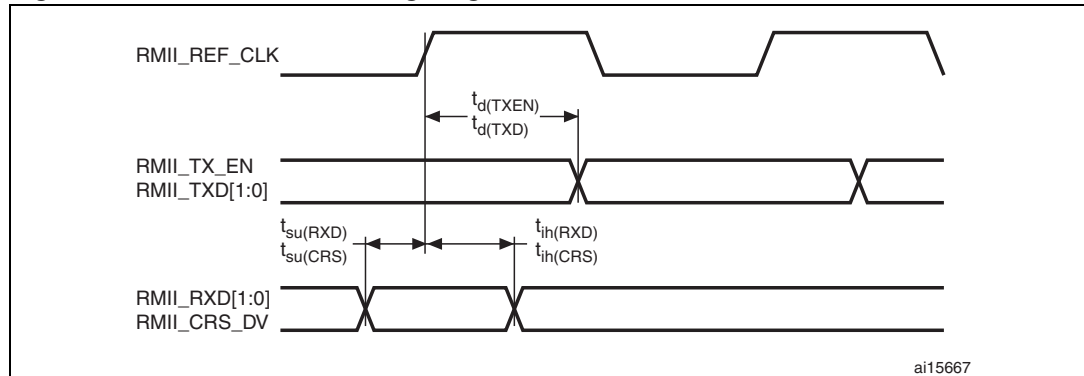


Table 65. Dynamics characteristics: Ethernet MAC signals for RMIi

| Symbol | Rating | Min | Typ | Max | Unit |
|---------------|----------------------------------|-----|-----|------|------|
| $t_{su}(RXD)$ | Receive data setup time | 2 | - | - | ns |
| $t_{ih}(RXD)$ | Receive data hold time | 1 | - | - | ns |
| $t_{su}(CRS)$ | Carrier sense set-up time | 0.5 | - | - | ns |
| $t_{ih}(CRS)$ | Carrier sense hold time | 2 | - | - | ns |
| $t_d(TXEN)$ | Transmit enable valid delay time | 8 | 9.5 | 11 | ns |
| $t_d(TXD)$ | Transmit data valid delay time | 8.5 | 10 | 11.5 | ns |

Table 66 gives the list of Ethernet MAC signals for MII and Figure 47 shows the corresponding timing diagram.

Figure 47. Ethernet MII timing diagram

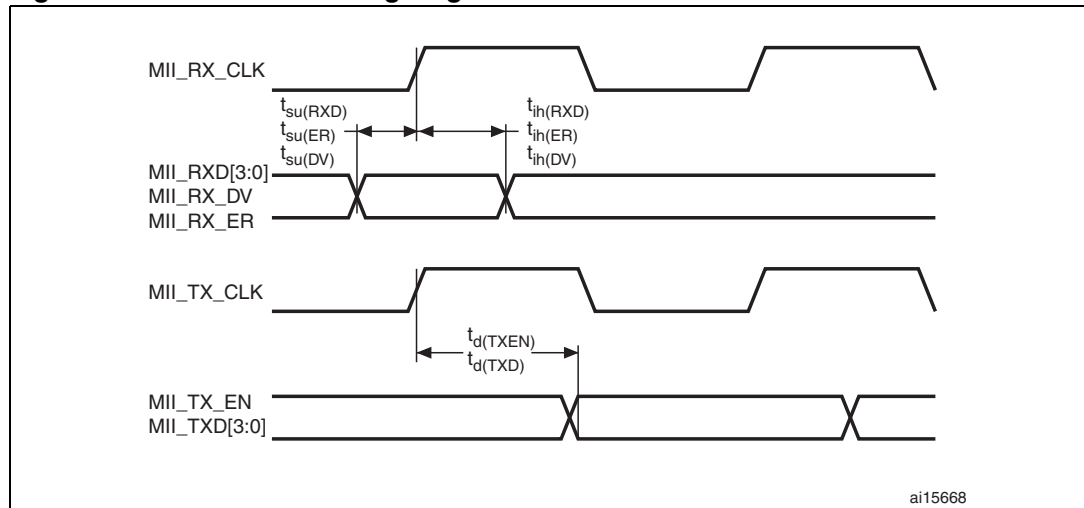


Table 66. Dynamics characteristics: Ethernet MAC signals for MII⁽¹⁾

| Symbol | Rating | Min | Typ | Max | Unit |
|---------------|----------------------------------|------|------|------|------|
| $t_{su}(RXD)$ | Receive data setup time | TBD | TBD | TBD | ns |
| $t_{ih}(RXD)$ | Receive data hold time | TBD | TBD | TBD | ns |
| $t_{su}(DV)$ | Data valid setup time | TBD | TBD | TBD | ns |
| $t_{ih}(DV)$ | Data valid hold time | TBD | TBD | TBD | ns |
| $t_{su}(ER)$ | Error setup time | TBD | TBD | TBD | ns |
| $t_{ih}(ER)$ | Error hold time | TBD | TBD | TBD | ns |
| $t_d(TXEN)$ | Transmit enable valid delay time | 13.4 | 15.5 | 17.7 | ns |
| $t_d(TXD)$ | Transmit data valid delay time | 12.9 | 16.1 | 19.4 | ns |

1. TBD stands for “to be defined”.

CAN (controller area network) interface

Refer to [Section 5.3.16: I/O port characteristics](#) for more details on the input/output alternate function characteristics (CANTX and CANRX).

5.3.20 12-bit ADC characteristics

Unless otherwise specified, the parameters given in [Table 67](#) are derived from tests performed under the ambient temperature, f_{PCLK2} frequency and V_{DDA} supply voltage conditions summarized in [Table 13](#).

Table 67. ADC characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------|---|--|---|-----|------------------|-------------|
| V_{DDA} | Power supply | | 1.8 ⁽¹⁾ | - | 3.6 | V |
| V_{REF+} | Positive reference voltage | | 1.8 ⁽¹⁾⁽²⁾⁽³⁾ | - | V_{DDA} | V |
| f_{ADC} | ADC clock frequency | $V_{DDA} = 1.8^{(1)(3)}$ to 2.4 V | 0.6 | 15 | 18 | MHz |
| | | $V_{DDA} = 2.4$ to 3.6 V ⁽³⁾ | 0.6 | 30 | 36 | MHz |
| $f_{TRIG}^{(4)}$ | External trigger frequency | $f_{ADC} = 30$ MHz, 12-bit resolution | - | - | 1764 | kHz |
| | | | - | - | 17 | $1/f_{ADC}$ |
| V_{AIN} | Conversion voltage range ⁽⁵⁾ | | 0 (V_{SSA} or V_{REF-} tied to ground) | - | V_{REF+} | V |
| $R_{AIN}^{(4)}$ | External input impedance | See Equation 1 for details | - | - | 50 | k Ω |
| $R_{ADC}^{(4)(6)}$ | Sampling switch resistance | | - | - | 6 | k Ω |
| $C_{ADC}^{(4)}$ | Internal sample and hold capacitor | | - | 4 | - | pF |
| $t_{lat}^{(4)}$ | Injection trigger conversion latency | $f_{ADC} = 30$ MHz | - | - | 0.100 | μ s |
| | | | - | - | 3 ⁽⁷⁾ | $1/f_{ADC}$ |

Table 67. ADC characteristics (continued)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------|---|---|-------|-----|-----------|---------------|
| $t_{latr}^{(4)}$ | Regular trigger conversion latency | $f_{ADC} = 30\text{ MHz}$ | - | - | 0.067 | μs |
| | | | - | - | $2^{(7)}$ | $1/f_{ADC}$ |
| $t_S^{(4)}$ | Sampling time | $f_{ADC} = 30\text{ MHz}$ | 0.100 | - | 16 | μs |
| | | | 3 | - | 480 | $1/f_{ADC}$ |
| $t_{STAB}^{(4)}$ | Power-up time | | - | 2 | 3 | μs |
| $t_{CONV}^{(4)}$ | Total conversion time (including sampling time) | $f_{ADC} = 30\text{ MHz}$ 12-bit resolution | 0.50 | - | 16.40 | μs |
| | | $f_{ADC} = 30\text{ MHz}$ 10-bit resolution | 0.43 | - | 16.34 | μs |
| | | $f_{ADC} = 30\text{ MHz}$ 8-bit resolution | 0.37 | - | 16.27 | μs |
| | | $f_{ADC} = 30\text{ MHz}$ 6-bit resolution | 0.30 | - | 16.20 | μs |
| | | 9 to 492 (t_S for sampling +n-bit resolution for successive approximation) | | | | |
| $f_S^{(4)}$ | Sampling rate ($f_{ADC} = 30\text{ MHz}$, and $t_S = 3\text{ ADC cycles}$) | 12-bit resolution Single ADC | - | - | 2 | Msp/s |
| | | 12-bit resolution Interleave Dual ADC mode | - | - | 3.75 | Msp/s |
| | | 12-bit resolution Interleave Triple ADC mode | - | - | 6 | Msp/s |
| $I_{VREF+}^{(4)}$ | ADC V_{REF+} DC current consumption in conversion mode | $f_{ADC} = 30\text{ MHz}$ 3 sampling time 12-bit resolution | - | 300 | 500 | μA |
| | | $f_{ADC} = 30\text{ MHz}$ 480 sampling time 12-bit resolution | - | - | 16 | μA |
| $I_{VDDA}^{(4)}$ | ADC V_{DDA} DC current consumption in conversion mode | $f_{ADC} = 30\text{ MHz}$ 3 sampling time 12-bit resolution | - | 1.6 | 1.8 | mA |
| | | $f_{ADC} = 30\text{ MHz}$ 480 sampling time 12-bit resolution | - | - | 60 | μA |

1. If an inverted reset signal is applied to PDR_ON, this value can be lowered to 1.7 V when the device operates in a reduced temperature range (0 to 70 °C).
2. It is recommended to maintain the voltage difference between V_{REF+} and V_{DDA} below 1.8 V.
3. $V_{DDA} - V_{REF+} < 1.2\text{ V}$.
4. Based on characterization, not tested in production.
5. V_{REF+} is internally connected to V_{DDA} and V_{REF-} is internally connected to V_{SSA} .
6. R_{ADC} maximum value is given for $V_{DD}=1.8\text{ V}$, and minimum value for $V_{DD}=3.3\text{ V}$.

7. For external triggers, a delay of $1/f_{PCLK2}$ must be added to the latency specified in [Table 67](#).

Equation 1: R_{AIN} max formula

$$R_{AIN} = \frac{(k - 0.5)}{f_{ADC} \times C_{ADC} \times \ln(2^{N+2})} - R_{ADC}$$

The formula above ([Equation 1](#)) is used to determine the maximum external impedance allowed for an error below 1/4 of LSB. $N = 12$ (from 12-bit resolution) and k is the number of sampling periods defined in the ADC_SMPR1 register.

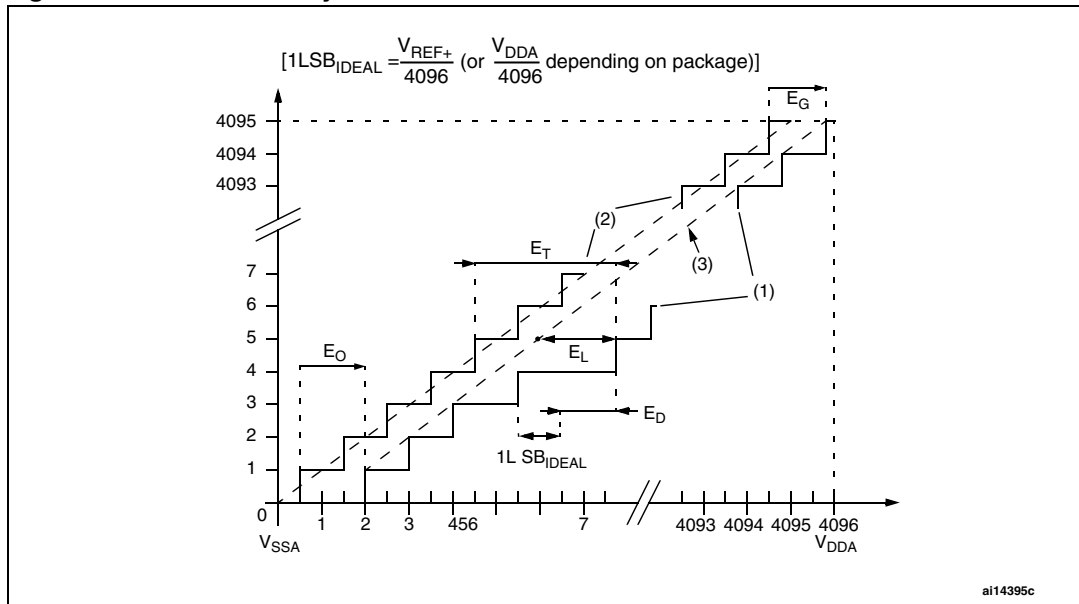
Table 68. ADC accuracy at $f_{ADC} = 30$ MHz⁽¹⁾

| Symbol | Parameter | Test conditions | Typ | Max ⁽²⁾ | Unit |
|--------|------------------------------|--|-----------|--------------------|------|
| ET | Total unadjusted error | $f_{PCLK2} = 60$ MHz, $f_{ADC} = 30$ MHz, $R_{AIN} < 10$ k Ω , $V_{DDA} = 1.8^{(3)}$ to 3.6 V | ± 2 | ± 5 | LSB |
| EO | Offset error | | ± 1.5 | ± 2.5 | |
| EG | Gain error | | ± 1.5 | ± 3 | |
| ED | Differential linearity error | | ± 1 | ± 2 | |
| EL | Integral linearity error | | ± 1.5 | ± 3 | |

- Better performance could be achieved in restricted V_{DD} , frequency and temperature ranges.
- Based on characterization, not tested in production.
- If an inverted reset signal is applied to PDR_ON, this value can be lowered to 1.7 V when the device operates in a reduced temperature range (0 to 70 °C).

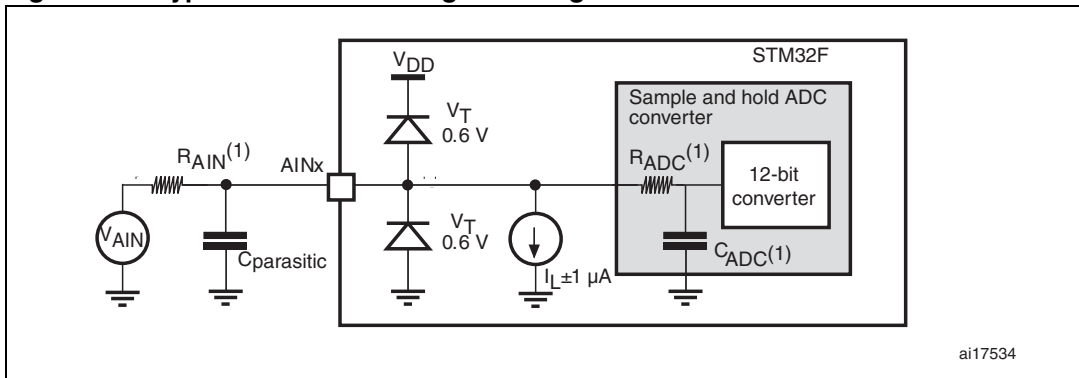
Note: ADC accuracy vs. negative injection current: injecting a negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents. Any positive injection current within the limits specified for $I_{INJ(PIN)}$ and $\Sigma I_{INJ(PIN)}$ in [Section 5.3.16](#) does not affect the ADC accuracy.

Figure 48. ADC accuracy characteristics



1. See also [Table 68](#).
2. Example of an actual transfer curve.
3. Ideal transfer curve.
4. End point correlation line.
5. E_T = Total Unadjusted Error: maximum deviation between the actual and the ideal transfer curves.
 E_O = Offset Error: deviation between the first actual transition and the first ideal one.
 E_G = Gain Error: deviation between the last ideal transition and the last actual one.
 E_D = Differential Linearity Error: maximum deviation between actual steps and the ideal one.
 E_L = Integral Linearity Error: maximum deviation between any actual transition and the end point correlation line.

Figure 49. Typical connection diagram using the ADC

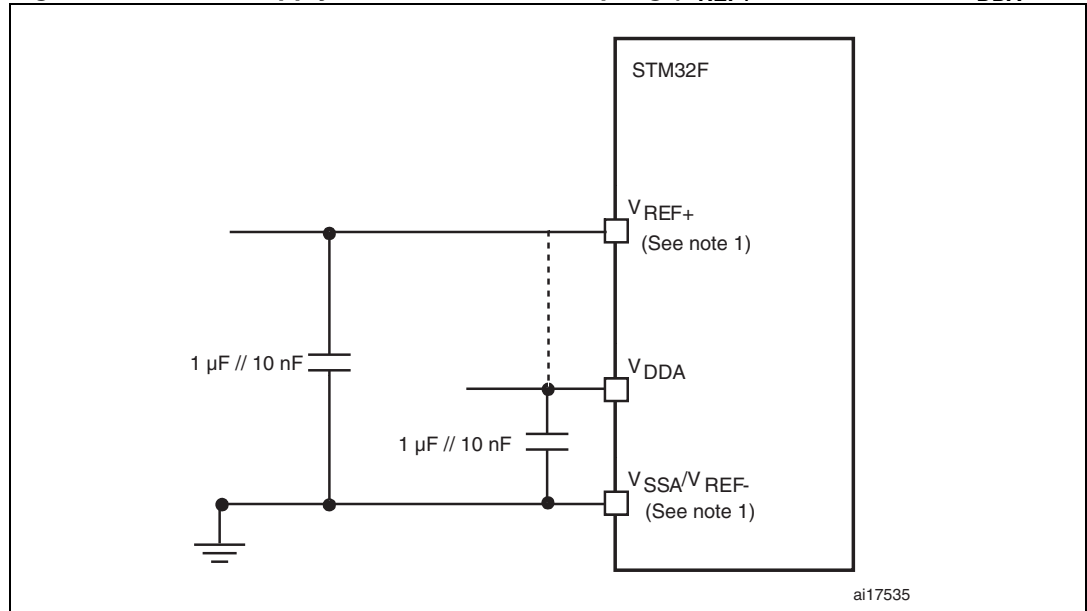


1. Refer to [Table 67](#) for the values of R_{AIN} , R_{ADC} and C_{ADC} .
2. $C_{parasitic}$ represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (roughly 5 pF). A high $C_{parasitic}$ value downgrades conversion accuracy. To remedy this, f_{ADC} should be reduced.

General PCB design guidelines

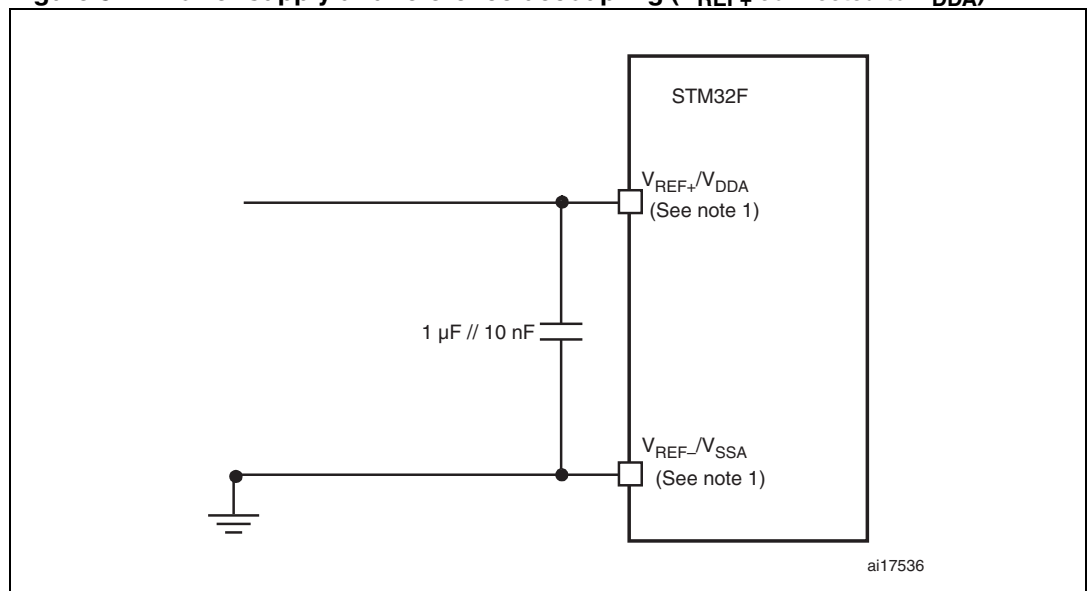
Power supply decoupling should be performed as shown in [Figure 50](#) or [Figure 51](#), depending on whether V_{REF+} is connected to V_{DDA} or not. The 10 nF capacitors should be ceramic (good quality). They should be placed them as close as possible to the chip.

Figure 50. Power supply and reference decoupling (V_{REF+} not connected to V_{DDA})



1. V_{REF+} and V_{REF-} inputs are both available on UFBGA176. V_{REF+} is also available on LQFP100, LQFP144, and LQFP176. When V_{REF+} and V_{REF-} are not available, they are internally connected to V_{DDA} and V_{SSA} .

Figure 51. Power supply and reference decoupling (V_{REF+} connected to V_{DDA})



1. V_{REF+} and V_{REF-} inputs are both available on UFBGA176. V_{REF+} is also available on LQFP100, LQFP144, and LQFP176. When V_{REF+} and V_{REF-} are not available, they are internally connected to V_{DDA} and V_{SSA} .

5.3.21 Temperature sensor characteristics

Table 69. TS characteristics

| Symbol | Parameter | Min | Typ | Max | Unit |
|--------------------------|--|-----|---------|---------|------------------------|
| $T_L^{(1)}$ | V_{SENSE} linearity with temperature | - | ± 1 | ± 2 | $^{\circ}\text{C}$ |
| Avg_Slope ⁽¹⁾ | Average slope | - | 2.5 | | mV/ $^{\circ}\text{C}$ |
| $V_{25}^{(1)}$ | Voltage at 25 $^{\circ}\text{C}$ | - | 0.76 | | V |
| $t_{START}^{(2)}$ | Startup time | - | 6 | 10 | μs |
| $T_{S_temp}^{(3)(2)}$ | ADC sampling time when reading the temperature (1 $^{\circ}\text{C}$ accuracy) | 10 | - | - | μs |

1. Based on characterization, not tested in production.
2. Guaranteed by design, not tested in production.
3. Shortest sampling time can be determined in the application by multiple iterations.

5.3.22 V_{BAT} monitoring characteristics

Table 70. V_{BAT} monitoring characteristics

| Symbol | Parameter | Min | Typ | Max | Unit |
|------------------------|---|-----|-----|-----|---------------|
| R | Resistor bridge for V_{BAT} | - | 50 | - | K Ω |
| Q | Ratio on V_{BAT} measurement | - | 2 | - | |
| $E_r^{(1)}$ | Error on Q | -1 | - | +1 | % |
| $T_{S_vbat}^{(2)(2)}$ | ADC sampling time when reading the V_{BAT} 1 mV accuracy | 5 | - | - | μs |

1. Guaranteed by design, not tested in production.
2. Shortest sampling time can be determined in the application by multiple iterations.

5.3.23 Embedded reference voltage

The parameters given in [Table 71](#) are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 13](#).

Table 71. Embedded internal reference voltage

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------------|---|--|------|------|------|-------------------------|
| V_{REFINT} | Internal reference voltage | $-40\text{ }^{\circ}\text{C} < T_A < +105\text{ }^{\circ}\text{C}$ | 1.18 | 1.21 | 1.24 | V |
| $T_{S_vrefint}^{(1)}$ | ADC sampling time when reading the internal reference voltage | | 10 | - | - | μs |
| $V_{RERINT_s}^{(2)}$ | Internal reference voltage spread over the temperature range | $V_{DD} = 3\text{ V}$ | - | 3 | 5 | mV |
| $T_{Ccoeff}^{(2)}$ | Temperature coefficient | | - | 30 | 50 | ppm/ $^{\circ}\text{C}$ |
| $t_{START}^{(2)}$ | Startup time | | - | 6 | 10 | μs |

1. Shortest sampling time can be determined in the application by multiple iterations.
2. Guaranteed by design, not tested in production.

5.3.24 DAC electrical characteristics

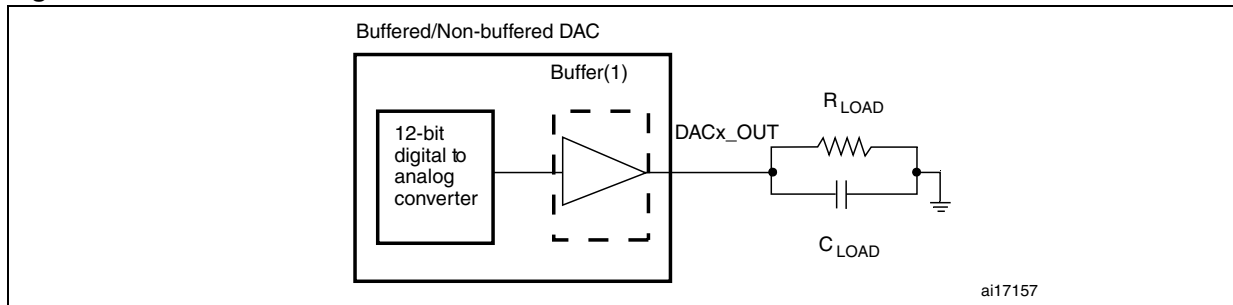
Table 72. DAC characteristics

| Symbol | Parameter | Min | Typ | Max | Unit | Comments |
|------------------------|---|--------------------|-----|-------------------|------------|--|
| V_{DDA} | Analog supply voltage | 1.8 ⁽¹⁾ | - | 3.6 | V | |
| V_{REF+} | Reference supply voltage | 1.8 ⁽¹⁾ | - | 3.6 | V | $V_{REF+} \leq V_{DDA}$ |
| V_{SSA} | Ground | 0 | - | 0 | V | |
| $R_{LOAD}^{(2)}$ | Resistive load with buffer ON | 5 | - | - | k Ω | |
| $R_O^{(2)}$ | Impedance output with buffer OFF | - | - | 15 | k Ω | When the buffer is OFF, the Minimum resistive load between DAC_OUT and V_{SS} to have a 1% accuracy is 1.5 M Ω |
| $C_{LOAD}^{(2)}$ | Capacitive load | - | - | 50 | pF | Maximum capacitive load at DAC_OUT pin (when the buffer is ON). |
| $DAC_OUT_{min}^{(2)}$ | Lower DAC_OUT voltage with buffer ON | 0.2 | - | - | V | It gives the maximum output excursion of the DAC. It corresponds to 12-bit input code (0x0E0) to (0xF1C) at $V_{REF+} = 3.6$ V and (0x1C7) to (0xE38) at $V_{REF+} = 1.8$ V |
| $DAC_OUT_{max}^{(2)}$ | Higher DAC_OUT voltage with buffer ON | - | - | $V_{DDA} - 0.2$ | V | |
| $DAC_OUT_{min}^{(2)}$ | Lower DAC_OUT voltage with buffer OFF | - | 0.5 | - | mV | It gives the maximum output excursion of the DAC. |
| $DAC_OUT_{max}^{(2)}$ | Higher DAC_OUT voltage with buffer OFF | - | - | $V_{REF+} - 1LSB$ | V | |
| $I_{VREF+}^{(3)}$ | DAC DC V_{REF} current consumption in quiescent mode (Standby mode) | - | 170 | 240 | μ A | With no load, worst code (0x800) at $V_{REF+} = 3.6$ V in terms of DC consumption on the inputs |
| | | - | 50 | 75 | | With no load, worst code (0xF1C) at $V_{REF+} = 3.6$ V in terms of DC consumption on the inputs |
| $I_{DDA}^{(3)}$ | DAC DC V_{DDA} current consumption in quiescent mode (Standby mode) | - | 280 | 380 | μ A | With no load, middle code (0x800) on the inputs |
| | | - | 475 | 625 | μ A | With no load, worst code (0xF1C) at $V_{REF+} = 3.6$ V in terms of DC consumption on the inputs |
| $DNL^{(3)}$ | Differential non linearity Difference between two consecutive code-1LSB) | - | - | ± 0.5 | LSB | Given for the DAC in 10-bit configuration. |
| | | - | - | ± 2 | LSB | Given for the DAC in 12-bit configuration. |

Table 72. DAC characteristics (continued)

| Symbol | Parameter | Min | Typ | Max | Unit | Comments |
|--------------------------------------|--|-----|-----|------|------|---|
| INL ⁽³⁾ | Integral non linearity (difference between measured value at Code i and the value at Code i on a line drawn between Code 0 and last Code 1023) | - | - | ±1 | LSB | Given for the DAC in 10-bit configuration. |
| | | - | - | ±4 | LSB | Given for the DAC in 12-bit configuration. |
| Offset ⁽³⁾ | Offset error (difference between measured value at Code (0x800) and the ideal value = $V_{REF+}/2$) | - | - | ±10 | mV | Given for the DAC in 12-bit configuration |
| | | - | - | ±3 | LSB | Given for the DAC in 10-bit at $V_{REF+} = 3.6\text{ V}$ |
| | | - | - | ±12 | LSB | Given for the DAC in 12-bit at $V_{REF+} = 3.6\text{ V}$ |
| Gain error ⁽³⁾ | Gain error | - | - | ±0.5 | % | Given for the DAC in 12-bit configuration |
| t _{SETTLING} ⁽³⁾ | Settling time (full scale: for a 10-bit input code transition between the lowest and the highest input codes when DAC_OUT reaches final value ±4LSB) | - | 3 | 6 | µs | $C_{LOAD} \leq 50\text{ pF}$, $R_{LOAD} \geq 5\text{ k}\Omega$ |
| THD ⁽³⁾ | Total Harmonic Distortion Buffer ON | - | - | - | dB | $C_{LOAD} \leq 50\text{ pF}$, $R_{LOAD} \geq 5\text{ k}\Omega$ |
| Update rate ⁽²⁾ | Max frequency for a correct DAC_OUT change when small variation in the input code (from code i to i+1LSB) | - | - | 1 | MS/s | $C_{LOAD} \leq 50\text{ pF}$, $R_{LOAD} \geq 5\text{ k}\Omega$ |
| t _{WAKEUP} ⁽³⁾ | Wakeup time from off state (Setting the ENx bit in the DAC Control register) | - | 6.5 | 10 | µs | $C_{LOAD} \leq 50\text{ pF}$, $R_{LOAD} \geq 5\text{ k}\Omega$ input code between lowest and highest possible ones. |
| PSRR ⁺ ⁽²⁾ | Power supply rejection ratio (to V _{DDA}) (static DC measurement) | - | -67 | -40 | dB | No R _{LOAD} , C _{LOAD} = 50 pF |

1. If an inverted reset signal is applied to PDR_ON, this value can be lowered to 1.7 V when the device operates in a reduced temperature range (0 to 70 °C).
2. Guaranteed by design, not tested in production.
3. Guaranteed by characterization, not tested in production.

Figure 52. 12-bit buffered /non-buffered DAC

1. The DAC integrates an output buffer that can be used to reduce the output impedance and to drive external loads directly without the use of an external operational amplifier. The buffer can be bypassed by configuring the BOFFx bit in the DAC_CR register.

5.3.25 FSMC characteristics

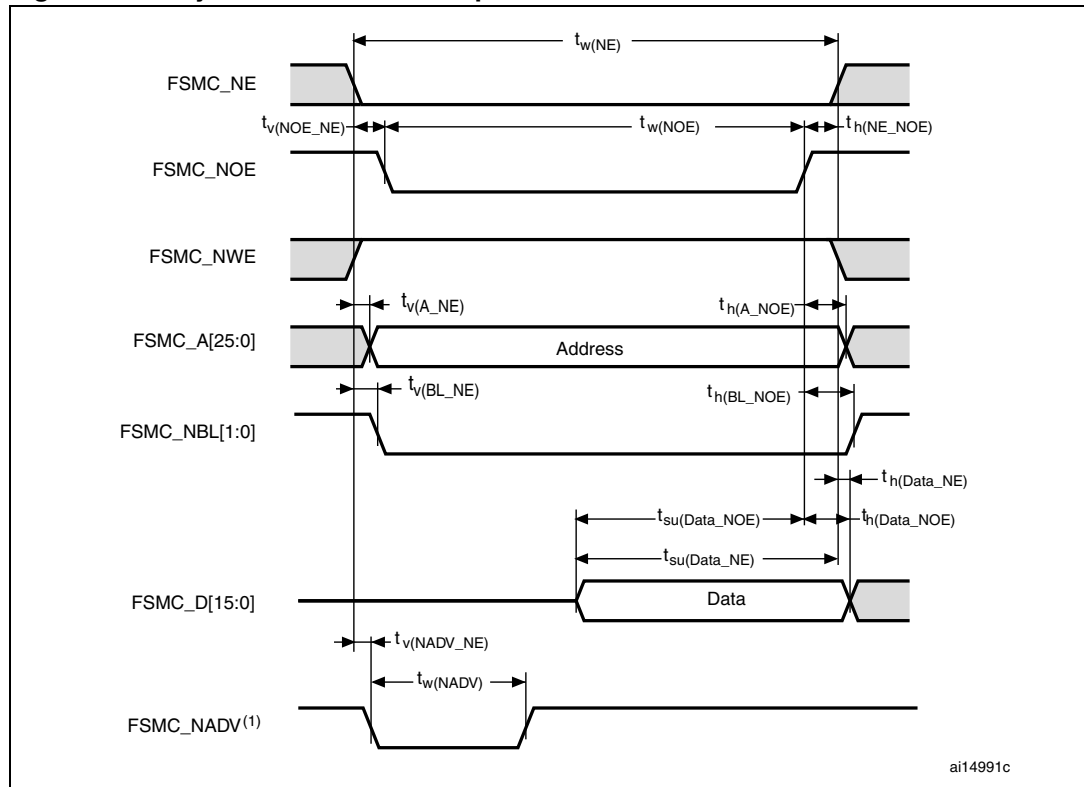
Asynchronous waveforms and timings

[Figure 53](#) through [Figure 56](#) represent asynchronous waveforms and [Table 73](#) through [Table 76](#) provide the corresponding timings. The results shown in these tables are obtained with the following FSMC configuration:

- AddressSetupTime = 1
- AddressHoldTime = 0x1
- DataSetupTime = 0x1
- BusTurnAroundDuration = 0x0

In all timing tables, the T_{HCLK} is the HCLK clock period.

Figure 53. Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms



1. Mode 2/B, C and D only. In Mode 1, FSMC_NADV is not used.

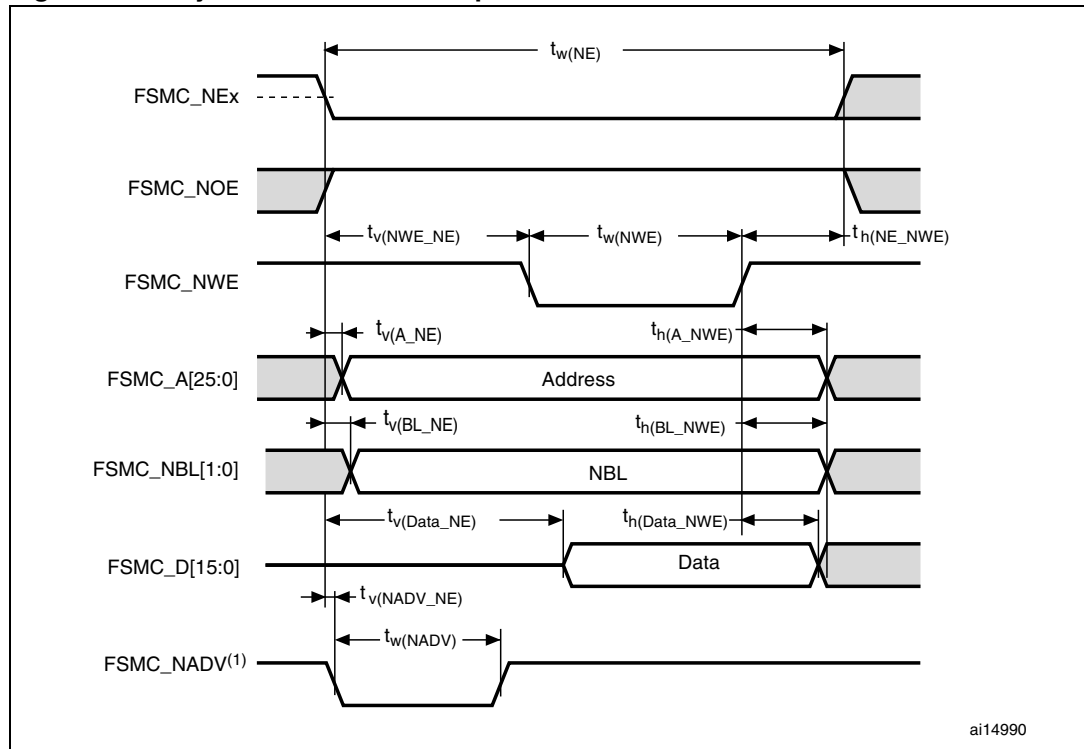
Table 73. Asynchronous non-multiplexed SRAM/PSRAM/NOR read timings⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|---------------------|---|-----------------|---------------|------|
| $t_w(NE)$ | FSMC_NE low time | $2T_{HCLK}-0.5$ | $2T_{HCLK}+1$ | ns |
| $t_{v(NOE_NE)}$ | FSMC_NEx low to FSMC_NOE low | 0.5 | 3 | ns |
| $t_w(NOE)$ | FSMC_NOE low time | $2T_{HCLK}-2$ | $2T_{HCLK}+2$ | ns |
| $t_h(NE_NOE)$ | FSMC_NOE high to FSMC_NE high hold time | 0 | - | ns |
| $t_{v(A_NE)}$ | FSMC_NEx low to FSMC_A valid | - | 4.5 | ns |
| $t_h(A_NOE)$ | Address hold time after FSMC_NOE high | 4 | - | ns |
| $t_{v(BL_NE)}$ | FSMC_NEx low to FSMC_BL valid | - | 1.5 | ns |
| $t_h(BL_NOE)$ | FSMC_BL hold time after FSMC_NOE high | 0 | - | ns |
| $t_{su(Data_NE)}$ | Data to FSMC_NEx high setup time | $T_{HCLK}+4$ | - | ns |
| $t_{su(Data_NOE)}$ | Data to FSMC_NOEx high setup time | $T_{HCLK}+4$ | - | ns |
| $t_h(Data_NOE)$ | Data hold time after FSMC_NOE high | 0 | - | ns |
| $t_h(Data_NE)$ | Data hold time after FSMC_NEx high | 0 | - | ns |
| $t_{v(NADV_NE)}$ | FSMC_NEx low to FSMC_NADV low | - | 2 | ns |
| $t_w(NADV)$ | FSMC_NADV low time | - | T_{HCLK} | ns |

1. $C_L = 30$ pF.

2. Based on characterization, not tested in production.

Figure 54. Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms



1. Mode 2/B, C and D only. In Mode 1, FSMC_NADV is not used.

Table 74. Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|--------------------|---|------------------|------------------|------|
| $t_{w(NE)}$ | FSMC_NE low time | $3T_{HCLK}$ | $3T_{HCLK} + 4$ | ns |
| $t_{v(NWE_NE)}$ | FSMC_NEx low to FSMC_NWE low | $T_{HCLK} - 0.5$ | $T_{HCLK} + 0.5$ | ns |
| $t_{w(NWE)}$ | FSMC_NWE low time | $T_{HCLK} - 1$ | $T_{HCLK} + 2$ | ns |
| $t_{h(NE_NWE)}$ | FSMC_NWE high to FSMC_NE high hold time | $T_{HCLK} - 1$ | - | ns |
| $t_{v(A_NE)}$ | FSMC_NEx low to FSMC_A valid | - | 0 | ns |
| $t_{h(A_NWE)}$ | Address hold time after FSMC_NWE high | $T_{HCLK} - 2$ | - | ns |
| $t_{v(BL_NE)}$ | FSMC_NEx low to FSMC_BL valid | - | 1.5 | ns |
| $t_{h(BL_NWE)}$ | FSMC_BL hold time after FSMC_NWE high | $T_{HCLK} - 1$ | - | ns |
| $t_{v(Data_NE)}$ | Data to FSMC_NEx low to Data valid | - | $T_{HCLK} + 3$ | ns |
| $t_{h(Data_NWE)}$ | Data hold time after FSMC_NWE high | $T_{HCLK} - 1$ | - | ns |
| $t_{v(NADV_NE)}$ | FSMC_NEx low to FSMC_NADV low | - | 2 | ns |
| $t_{w(NADV)}$ | FSMC_NADV low time | - | $T_{HCLK} + 0.5$ | ns |

1. $C_L = 30$ pF.

2. Based on characterization, not tested in production.

Figure 55. Asynchronous multiplexed PSRAM/NOR read waveforms

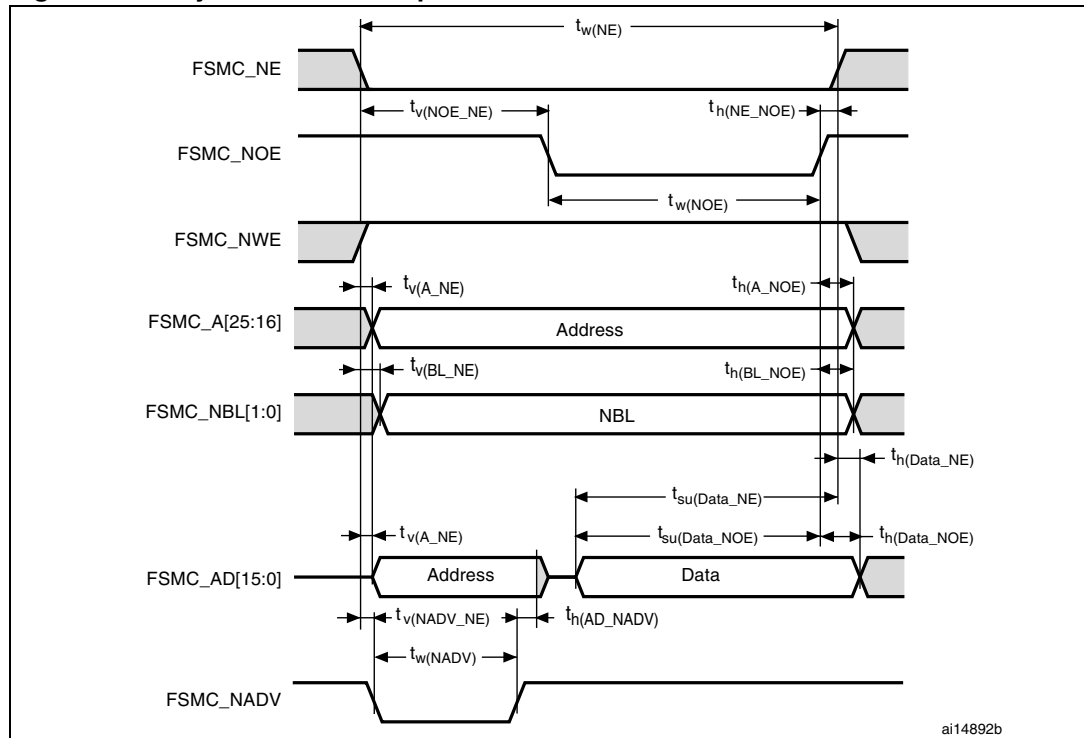


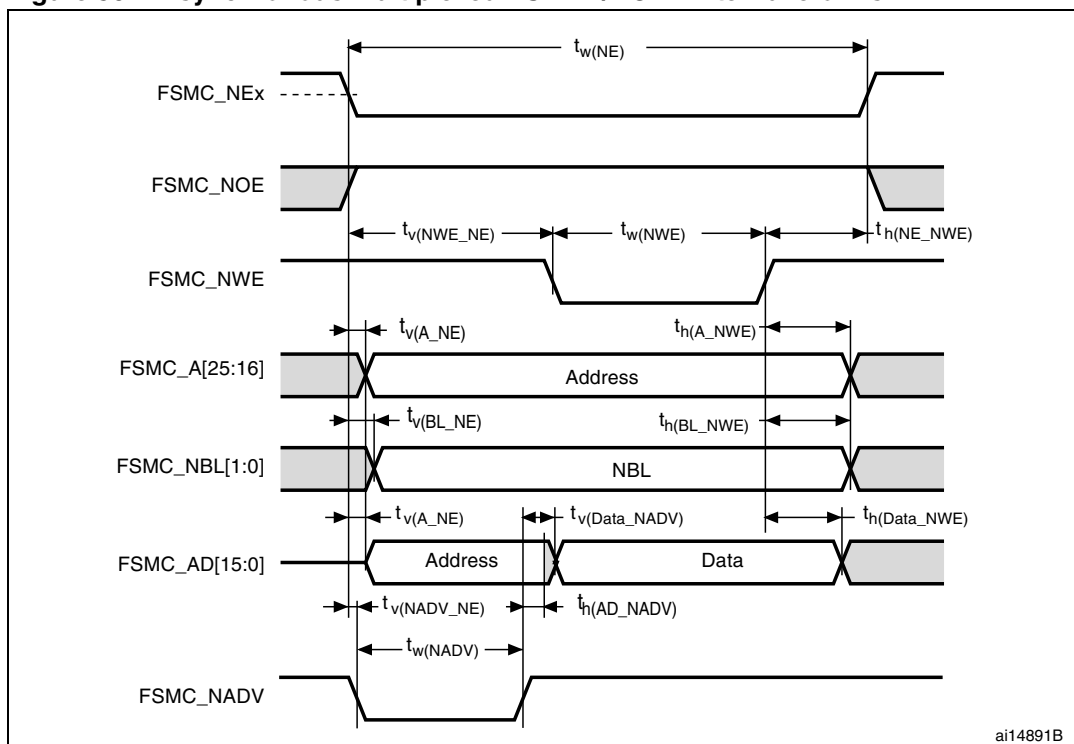
Table 75. Asynchronous multiplexed PSRAM/NOR read timings⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|---------------------|---|-----------------|-----------------|------|
| $t_{w(NE)}$ | FSMC_NE low time | $3T_{HCLK}-1$ | $3T_{HCLK}+1$ | ns |
| $t_{v(NOE_NE)}$ | FSMC_NEx low to FSMC_NOE low | $2T_{HCLK}-0.5$ | $2T_{HCLK}+0.5$ | ns |
| $t_{w(NOE)}$ | FSMC_NOE low time | $T_{HCLK}-1$ | $T_{HCLK}+1$ | ns |
| $t_{h(NE_NOE)}$ | FSMC_NOE high to FSMC_NE high hold time | 0 | - | ns |
| $t_{v(A_NE)}$ | FSMC_NEx low to FSMC_A valid | - | 3 | ns |
| $t_{v(NADV_NE)}$ | FSMC_NEx low to FSMC_NADV low | 1 | 2 | ns |
| $t_{w(NADV)}$ | FSMC_NADV low time | $T_{HCLK}-2$ | $T_{HCLK}+1$ | ns |
| $t_{h(AD_NADV)}$ | FSMC_AD(adress) valid hold time after FSMC_NADV high) | T_{HCLK} | - | ns |
| $t_{h(A_NOE)}$ | Address hold time after FSMC_NOE high | $T_{HCLK}-1$ | - | ns |
| $t_{h(BL_NOE)}$ | FSMC_BL time after FSMC_NOE high | 0 | - | ns |
| $t_{v(BL_NE)}$ | FSMC_NEx low to FSMC_BL valid | - | 2 | ns |
| $t_{su(Data_NE)}$ | Data to FSMC_NEx high setup time | $T_{HCLK}+4$ | - | ns |
| $t_{su(Data_NOE)}$ | Data to FSMC_NOE high setup time | $T_{HCLK}+4$ | - | ns |
| $t_{h(Data_NE)}$ | Data hold time after FSMC_NEx high | 0 | - | ns |
| $t_{h(Data_NOE)}$ | Data hold time after FSMC_NOE high | 0 | - | ns |

1. $C_L = 30$ pF.

2. Based on characterization, not tested in production.

Figure 56. Asynchronous multiplexed PSRAM/NOR write waveforms



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Table 76. Asynchronous multiplexed PSRAM/NOR write timings⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|---------------------|---|-----------------|----------------|------|
| $t_{w(NE)}$ | FSMC_NE low time | $4T_{HCLK}-0.5$ | $4T_{HCLK}+3$ | ns |
| $t_{v(NWE_NE)}$ | FSMC_NEx low to FSMC_NWE low | $T_{HCLK}-0.5$ | $T_{HCLK}-0.5$ | ns |
| $t_{w(NWE)}$ | FSMC_NWE low time | $2T_{HCLK}-0.5$ | $2T_{HCLK}+3$ | ns |
| $t_{h(NE_NWE)}$ | FSMC_NWE high to FSMC_NE high hold time | T_{HCLK} | - | ns |
| $t_{v(A_NE)}$ | FSMC_NEx low to FSMC_A valid | - | 0 | ns |
| $t_{v(NADV_NE)}$ | FSMC_NEx low to FSMC_NADV low | 1 | 2 | ns |
| $t_{w(NADV)}$ | FSMC_NADV low time | $T_{HCLK}-2$ | $T_{HCLK}+1$ | ns |
| $t_{h(AD_NADV)}$ | FSMC_AD(address) valid hold time after FSMC_NADV high | $T_{HCLK}-2$ | - | ns |
| $t_{h(A_NWE)}$ | Address hold time after FSMC_NWE high | T_{HCLK} | - | ns |
| $t_{h(BL_NWE)}$ | FSMC_BL hold time after FSMC_NWE high | $T_{HCLK}-2$ | - | ns |
| $t_{v(BL_NE)}$ | FSMC_NEx low to FSMC_BL valid | - | 1.5 | ns |
| $t_{v(Data_NADV)}$ | FSMC_NADV high to Data valid | - | $T_{HCLK}-0.5$ | ns |
| $t_{h(Data_NWE)}$ | Data hold time after FSMC_NWE high | T_{HCLK} | - | ns |

1. $C_L = 30$ pF.
2. Based on characterization, not tested in production.

Synchronous waveforms and timings

Figure 57 through Figure 60 represent synchronous waveforms and Table 78 through Table 80 provide the corresponding timings. The results shown in these tables are obtained with the following FSMC configuration:

- BurstAccessMode = FSMC_BurstAccessMode_Enable;
- MemoryType = FSMC_MemoryType_CRAM;
- WriteBurst = FSMC_WriteBurst_Enable;
- CLKDivision = 1; (0 is not supported, see the STM32F40xxx/41xxx reference manual)
- DataLatency = 1 for NOR Flash; DataLatency = 0 for PSRAM

In all timing tables, the T_{HCLK} is the HCLK clock period (with maximum FSMC_CLK = 60 MHz).

Figure 57. Synchronous multiplexed NOR/PSRAM read timings

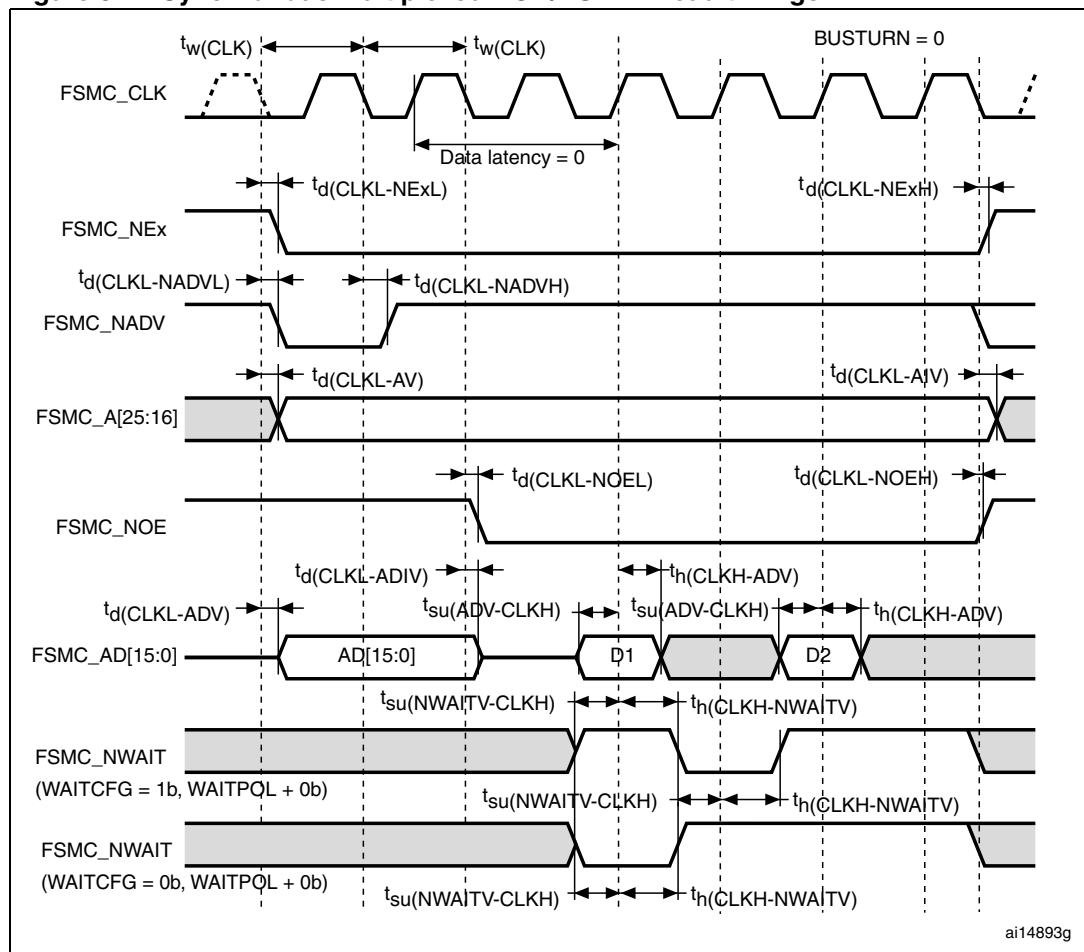


Table 77. Synchronous multiplexed NOR/PSRAM read timings⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|----------------------------|--|--------------------|-----|------|
| $t_{w(\text{CLK})}$ | FSMC_CLK period | $2T_{\text{HCLK}}$ | - | ns |
| $t_{d(\text{CLKL-NExL})}$ | FSMC_CLK low to FSMC_NEx low (x=0..2) | - | 0 | ns |
| $t_{d(\text{CLKL-NExH})}$ | FSMC_CLK low to FSMC_NEx high (x= 0..2) | 2 | - | ns |
| $t_{d(\text{CLKL-NADV})}$ | FSMC_CLK low to FSMC_NADV low | - | 2 | ns |
| $t_{d(\text{CLKL-NADVH})}$ | FSMC_CLK low to FSMC_NADV high | 2 | - | ns |
| $t_{d(\text{CLKL-AV})}$ | FSMC_CLK low to FSMC_Ax valid (x=16...25) | - | 0 | ns |
| $t_{d(\text{CLKL-AIV})}$ | FSMC_CLK low to FSMC_Ax invalid (x=16...25) | 0 | - | ns |
| $t_{d(\text{CLKL-NOEL})}$ | FSMC_CLK low to FSMC_NOE low | - | 0 | ns |
| $t_{d(\text{CLKL-NOEH})}$ | FSMC_CLK low to FSMC_NOE high | 2 | - | ns |
| $t_{d(\text{CLKL-ADV})}$ | FSMC_CLK low to FSMC_AD[15:0] valid | - | 4.5 | ns |
| $t_{d(\text{CLKL-ADIV})}$ | FSMC_CLK low to FSMC_AD[15:0] invalid | 0 | - | ns |
| $t_{su(\text{ADV-CLKH})}$ | FSMC_A/D[15:0] valid data before FSMC_CLK high | 6 | - | ns |
| $t_h(\text{CLKH-ADV})$ | FSMC_A/D[15:0] valid data after FSMC_CLK high | 0 | - | ns |

1. $C_L = 30$ pF.

2. Based on characterization, not tested in production.

Figure 58. Synchronous multiplexed PSRAM write timings

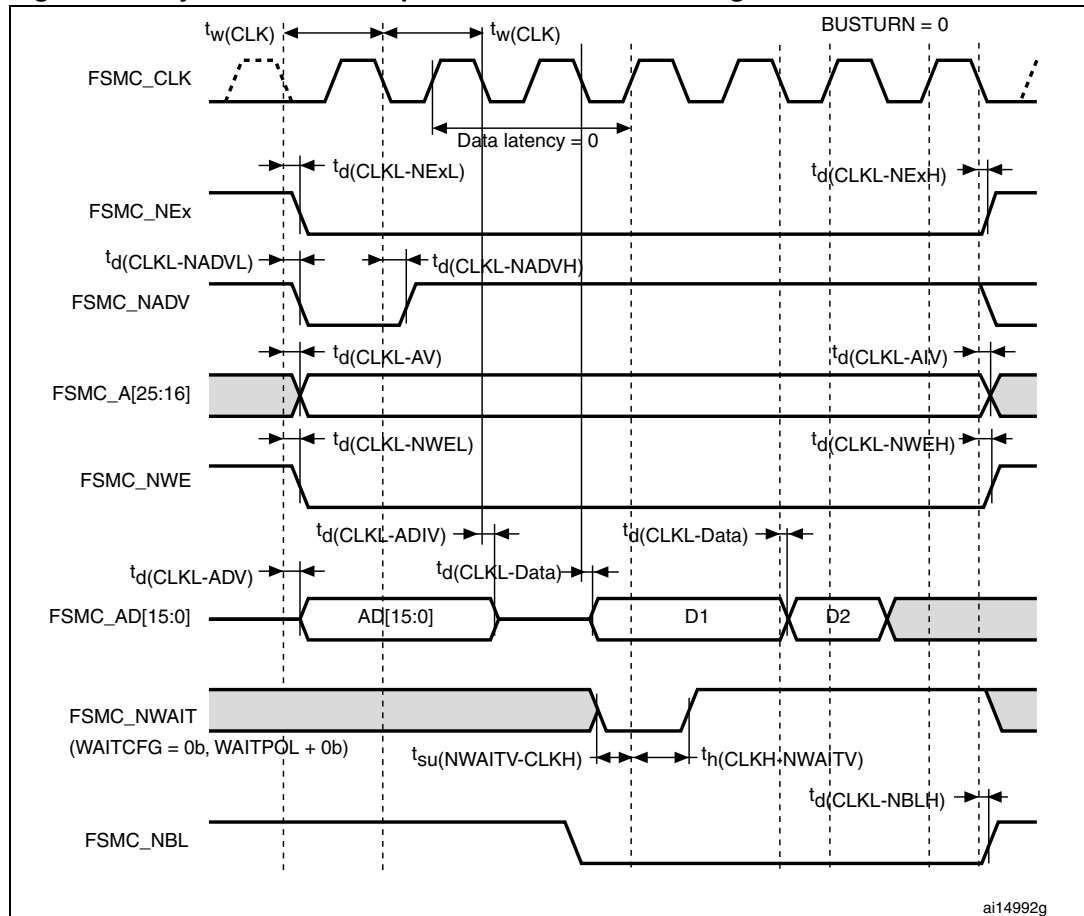


Table 78. Synchronous multiplexed PSRAM write timings⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|--------------------------|--|--------------------|-----|------|
| $t_w(\text{CLK})$ | FSMC_CLK period | $2T_{\text{HCLK}}$ | - | ns |
| $t_d(\text{CLKL-NExL})$ | FSMC_CLK low to FSMC_NEx low (x=0..2) | - | 1 | ns |
| $t_d(\text{CLKL-NExH})$ | FSMC_CLK low to FSMC_NEx high (x= 0...2) | 1 | - | ns |
| $t_d(\text{CLKL-NADV})$ | FSMC_CLK low to FSMC_NADV low | - | 0 | ns |
| $t_d(\text{CLKL-NADVH})$ | FSMC_CLK low to FSMC_NADV high | 0 | - | ns |
| $t_d(\text{CLKL-AV})$ | FSMC_CLK low to FSMC_Ax valid (x=16...25) | - | 0 | ns |
| $t_d(\text{CLKL-AIV})$ | FSMC_CLK low to FSMC_Ax invalid (x=16...25) | 8 | - | ns |
| $t_d(\text{CLKL-NWEL})$ | FSMC_CLK low to FSMC_NWE low | - | 0.5 | ns |
| $t_d(\text{CLKL-NWEH})$ | FSMC_CLK low to FSMC_NWE high | 0 | - | ns |
| $t_d(\text{CLKL-ADIV})$ | FSMC_CLK low to FSMC_AD[15:0] invalid | 0 | - | ns |
| $t_d(\text{CLKL-DATA})$ | FSMC_A/D[15:0] valid data after FSMC_CLK low | - | 3 | ns |
| $t_d(\text{CLKL-NBLH})$ | FSMC_CLK low to FSMC_NBL high | 0 | - | ns |

1. $C_L = 30 \text{ pF}$.
2. Based on characterization, not tested in production.

Figure 59. Synchronous non-multiplexed NOR/PSRAM read timings

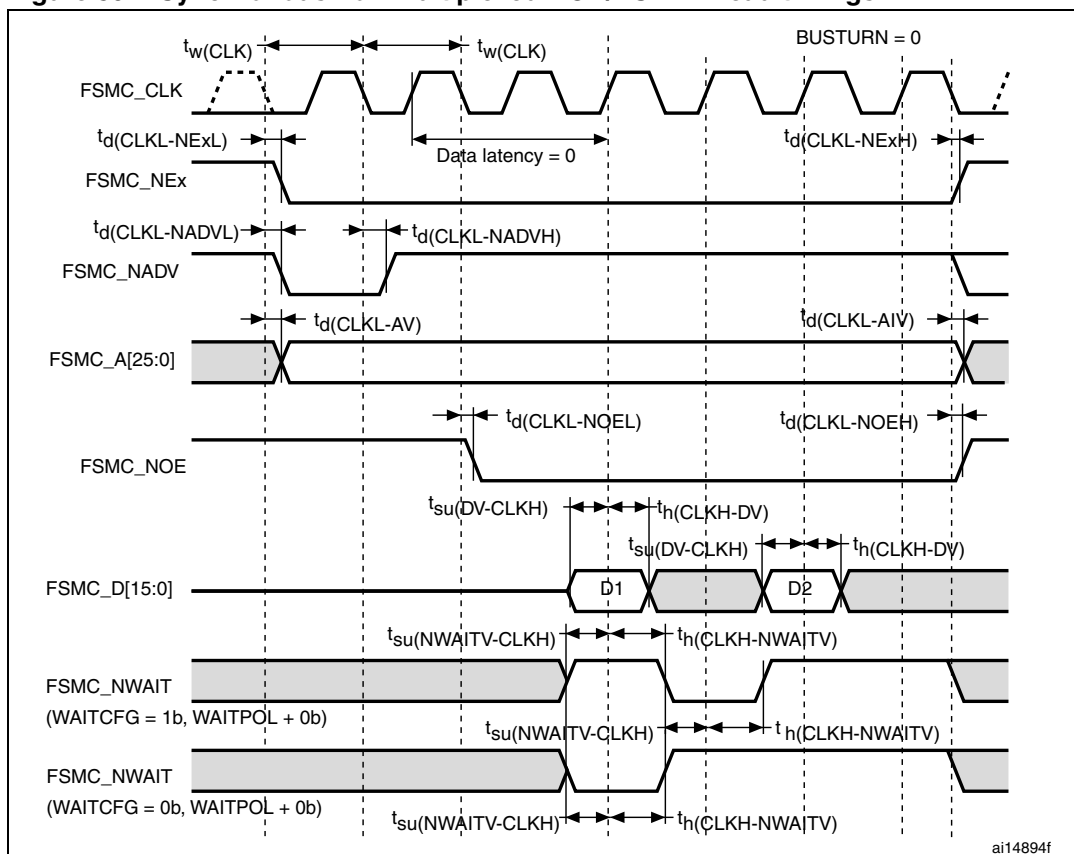


Table 79. Synchronous non-multiplexed NOR/PSRAM read timings⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|--------------------------|--|--------------------------|-----|------|
| $t_w(\text{CLK})$ | FSMC_CLK period | $2T_{\text{HCLK}} - 0.5$ | - | ns |
| $t_d(\text{CLKL-NExL})$ | FSMC_CLK low to FSMC_NEx low (x=0..2) | - | 0.5 | ns |
| $t_d(\text{CLKL-NExH})$ | FSMC_CLK low to FSMC_NEx high (x= 0...2) | 0 | - | ns |
| $t_d(\text{CLKL-NADVl})$ | FSMC_CLK low to FSMC_NADV low | - | 2 | ns |
| $t_d(\text{CLKL-NADVh})$ | FSMC_CLK low to FSMC_NADV high | 3 | - | ns |
| $t_d(\text{CLKL-AV})$ | FSMC_CLK low to FSMC_Ax valid (x=16...25) | - | 0 | ns |
| $t_d(\text{CLKL-AIV})$ | FSMC_CLK low to FSMC_Ax invalid (x=16...25) | 2 | - | ns |
| $t_d(\text{CLKL-NOEL})$ | FSMC_CLK low to FSMC_NOE low | - | 0.5 | ns |
| $t_d(\text{CLKL-NOEH})$ | FSMC_CLK low to FSMC_NOE high | 1.5 | - | ns |
| $t_{su}(\text{DV-CLKH})$ | FSMC_D[15:0] valid data before FSMC_CLK high | 6 | - | ns |
| $t_h(\text{CLKH-DV})$ | FSMC_D[15:0] valid data after FSMC_CLK high | 3 | - | ns |

1. $C_L = 30 \text{ pF}$.

2. Based on characterization, not tested in production.

Figure 60. Synchronous non-multiplexed PSRAM write timings

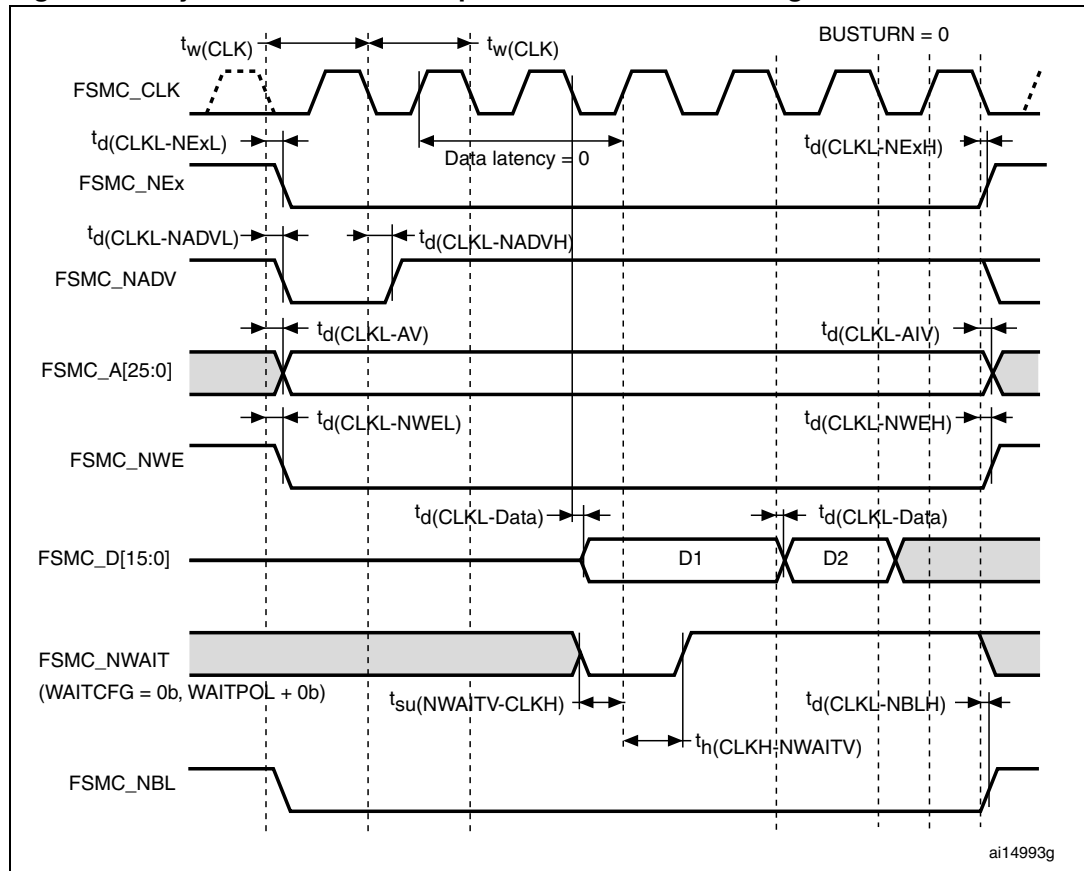


Table 80. Synchronous non-multiplexed PSRAM write timings⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|---------------------|---|-------------|-----|------|
| $t_{w(CLK)}$ | FSMC_CLK period | $2T_{HCLK}$ | - | ns |
| $t_{d(CLKL-NExL)}$ | FSMC_CLK low to FSMC_NEx low (x=0..2) | - | 1 | ns |
| $t_{d(CLKL-NExH)}$ | FSMC_CLK low to FSMC_NEx high (x= 0..2) | 1 | - | ns |
| $t_{d(CLKL-NADVL)}$ | FSMC_CLK low to FSMC_NADV low | - | 7 | ns |
| $t_{d(CLKL-NADVH)}$ | FSMC_CLK low to FSMC_NADV high | 6 | - | ns |
| $t_{d(CLKL-AV)}$ | FSMC_CLK low to FSMC_Ax valid (x=16...25) | - | 0 | ns |
| $t_{d(CLKL-AIV)}$ | FSMC_CLK low to FSMC_Ax invalid (x=16...25) | 6 | - | ns |
| $t_{d(CLKL-NWEL)}$ | FSMC_CLK low to FSMC_NWE low | - | 1 | ns |
| $t_{d(CLKL-NWEH)}$ | FSMC_CLK low to FSMC_NWE high | 2 | - | ns |
| $t_{d(CLKL-Data)}$ | FSMC_D[15:0] valid data after FSMC_CLK low | - | 3 | ns |
| $t_{d(CLKL-NBLH)}$ | FSMC_CLK low to FSMC_NBL high | 3 | - | ns |

1. $C_L = 30$ pF.
2. Based on characterization, not tested in production.

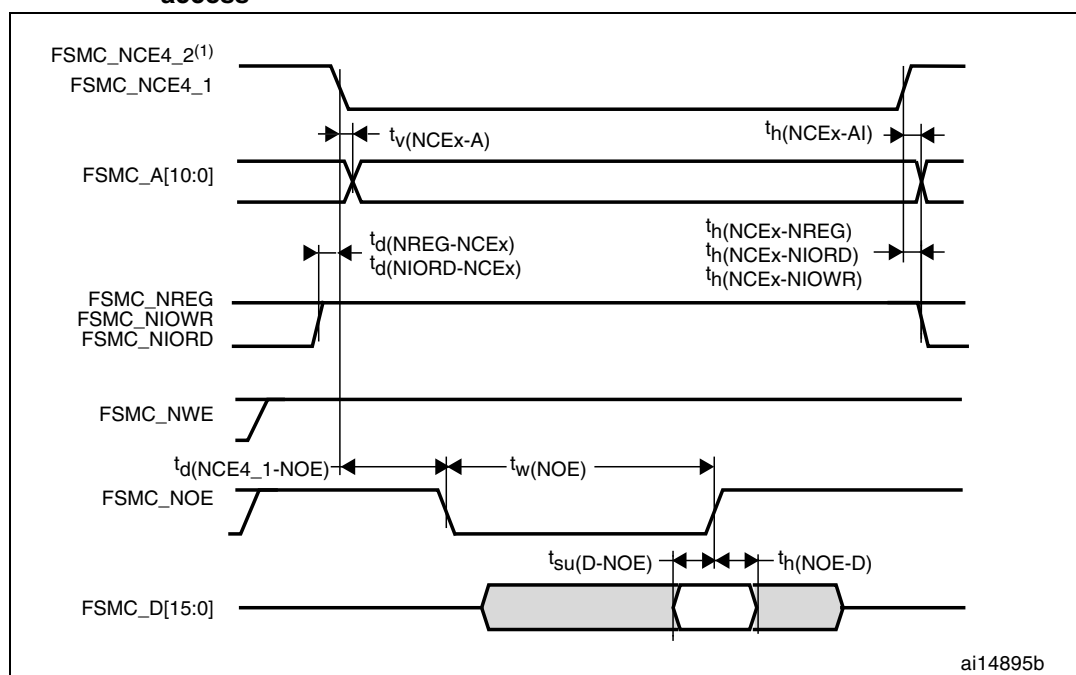
PC Card/CompactFlash controller waveforms and timings

Figure 61 through Figure 66 represent synchronous waveforms, and Table 81 and Table 82 provide the corresponding timings. The results shown in this table are obtained with the following FSMC configuration:

- COM.FSMC_SetupTime = 0x04;
- COM.FSMC_WaitSetupTime = 0x07;
- COM.FSMC_HoldSetupTime = 0x04;
- COM.FSMC_HiZSetupTime = 0x00;
- ATT.FSMC_SetupTime = 0x04;
- ATT.FSMC_WaitSetupTime = 0x07;
- ATT.FSMC_HoldSetupTime = 0x04;
- ATT.FSMC_HiZSetupTime = 0x00;
- IO.FSMC_SetupTime = 0x04;
- IO.FSMC_WaitSetupTime = 0x07;
- IO.FSMC_HoldSetupTime = 0x04;
- IO.FSMC_HiZSetupTime = 0x00;
- TCLRSetupTime = 0;
- TARSetupTime = 0.

In all timing tables, the T_{HCLK} is the HCLK clock period.

Figure 61. PC Card/CompactFlash controller waveforms for common memory read access



1. FSMC_NCE4_2 remains high (inactive during 8-bit access).

Figure 62. PC Card/CompactFlash controller waveforms for common memory write access

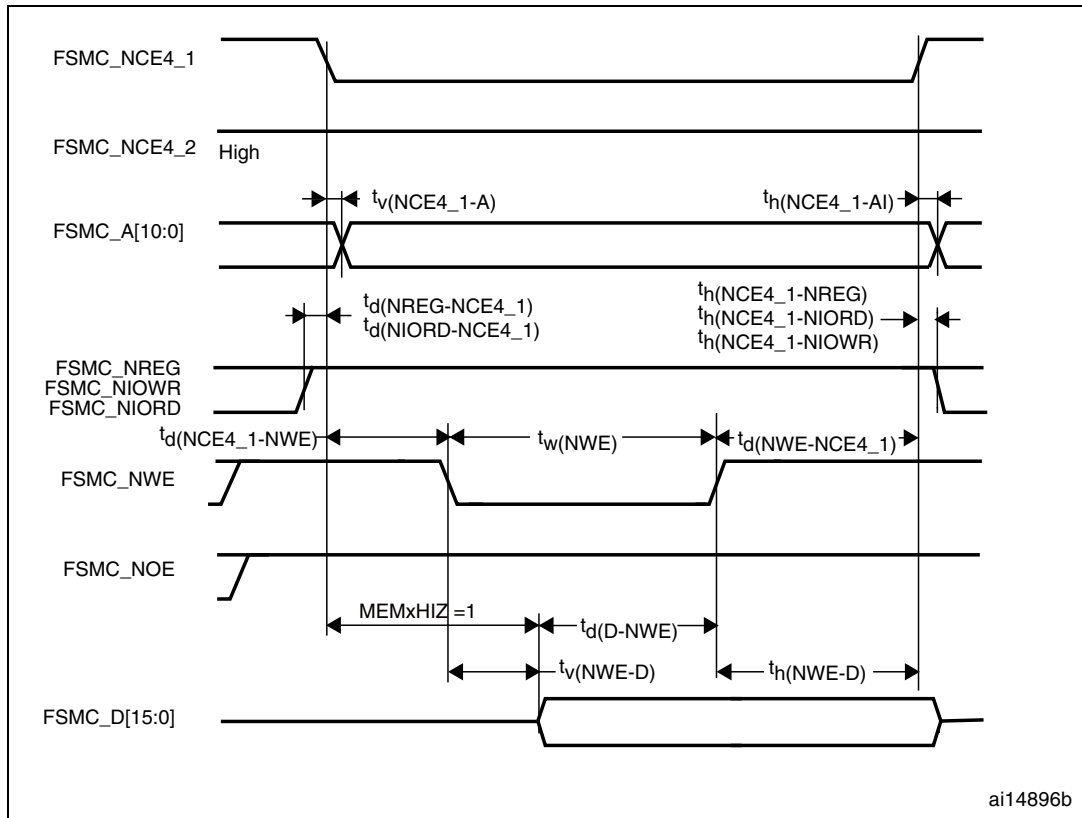
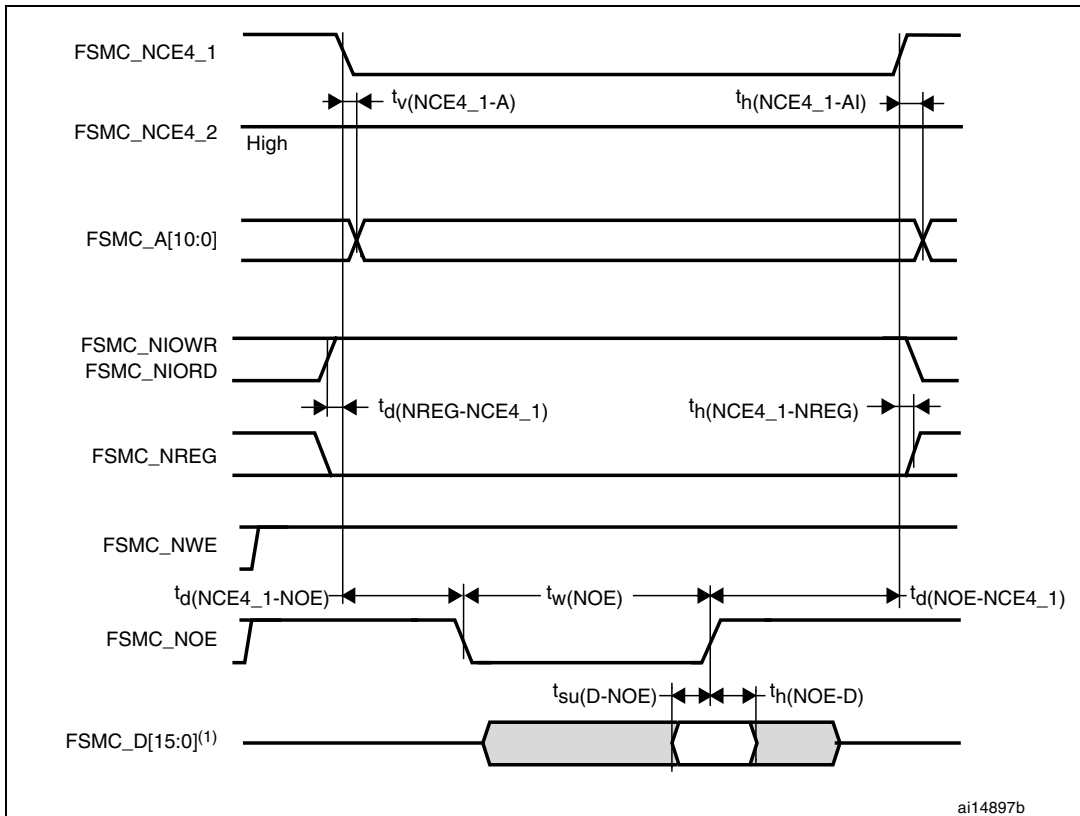
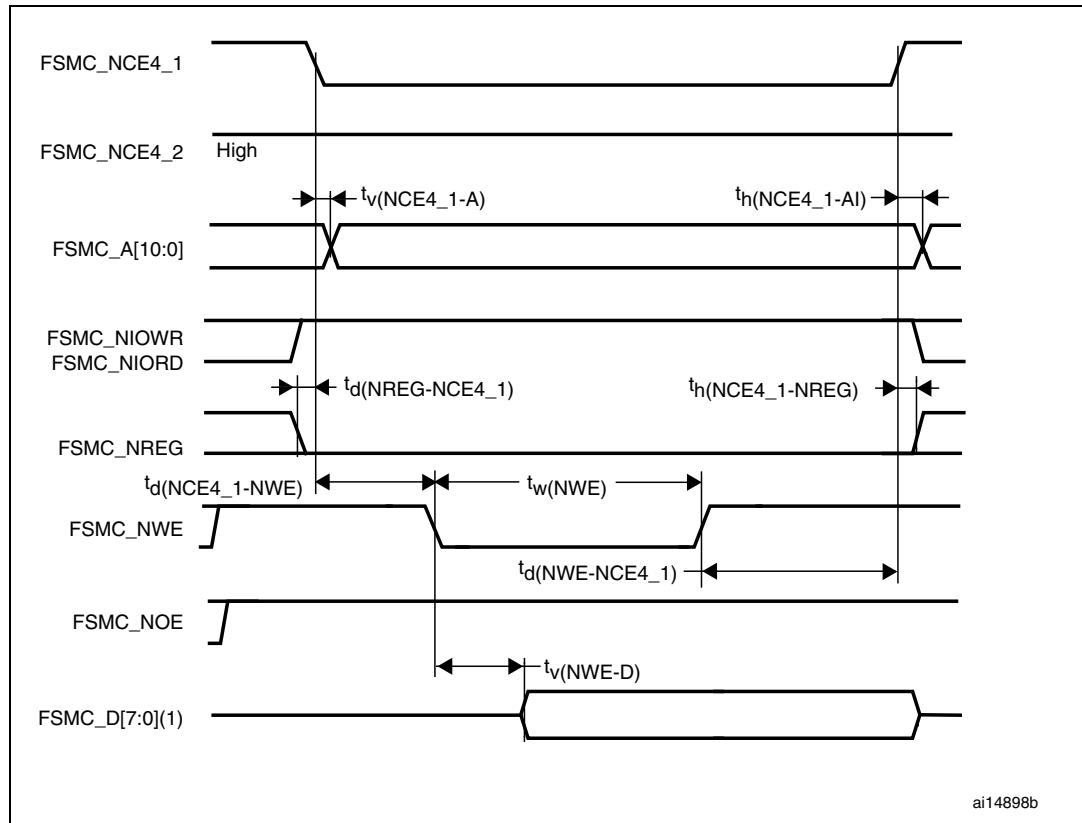


Figure 63. PC Card/CompactFlash controller waveforms for attribute memory read access



1. Only data bits 0...7 are read (bits 8...15 are disregarded).

Figure 64. PC Card/CompactFlash controller waveforms for attribute memory write access



1. Only data bits 0...7 are driven (bits 8...15 remains Hi-Z).

Figure 65. PC Card/CompactFlash controller waveforms for I/O space read access

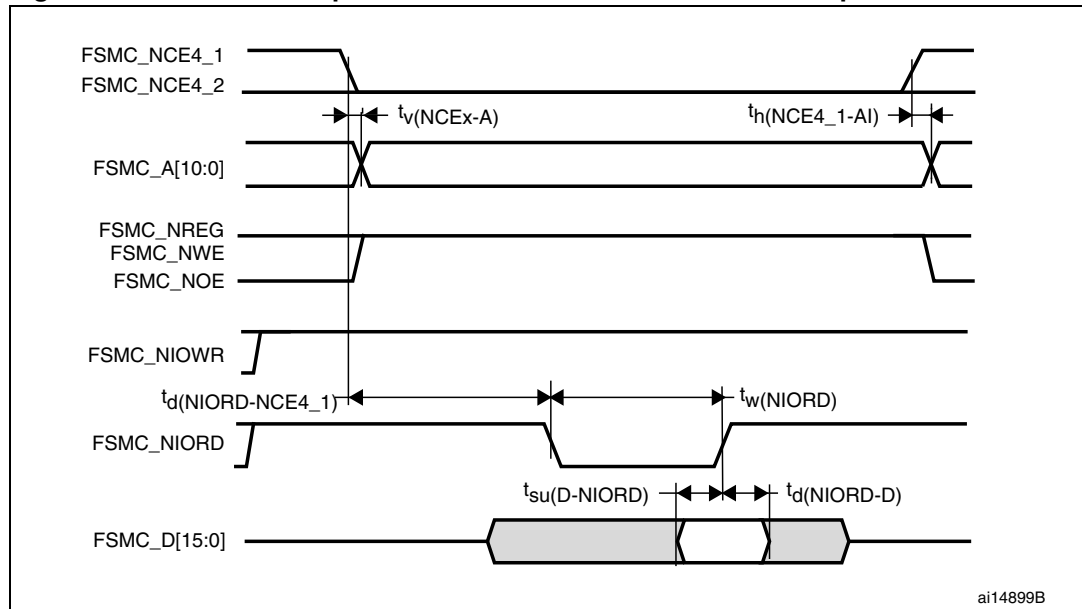
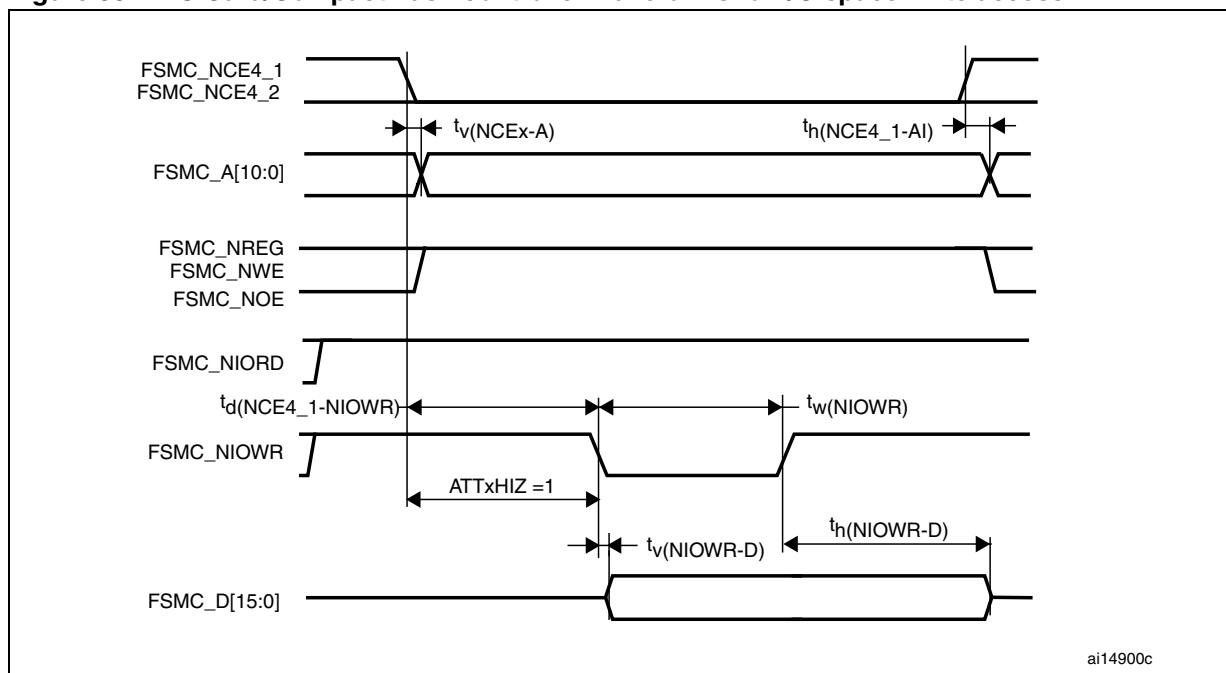


Figure 66. PC Card/CompactFlash controller waveforms for I/O space write access



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Table 81. Switching characteristics for PC Card/CF read and write cycles in attribute/common space⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|--------------------|--|-----------------|-----------------|------|
| $t_{v(NCEx-A)}$ | FSMC_Ncex low to FSMC_Ay valid | - | 0 | ns |
| $t_{h(NCEx-AI)}$ | FSMC_NCEx high to FSMC_Ax invalid | 4 | - | ns |
| $t_{d(NREG-NCEx)}$ | FSMC_NCEx low to FSMC_NREG valid | - | 3.5 | ns |
| $t_{h(NCEx-NREG)}$ | FSMC_NCEx high to FSMC_NREG invalid | $T_{HCLK}+4$ | - | ns |
| $t_{d(NCEx-NWE)}$ | FSMC_NCEx low to FSMC_NWE low | - | $5T_{HCLK}+0.5$ | ns |
| $t_{d(NCEx-NOE)}$ | FSMC_NCEx low to FSMC_NOE low | - | $5T_{HCLK}+0.5$ | ns |
| $t_{w(NOE)}$ | FSMC_NOE low width | $8T_{HCLK}-1$ | $8T_{HCLK}+1$ | ns |
| $t_{d(NOE-NCEx)}$ | FSMC_NOE high to FSMC_NCEx high | $5T_{HCLK}+2.5$ | - | ns |
| $t_{su}(D-NOE)$ | FSMC_D[15:0] valid data before FSMC_NOE high | 4.5 | - | ns |
| $t_{h(NOE-D)}$ | FSMC_NOE high to FSMC_D[15:0] invalid | 3 | - | ns |
| $t_{w(NWE)}$ | FSMC_NWE low width | $8T_{HCLK}-0.5$ | $8T_{HCLK}+3$ | ns |
| $t_{d(NWE-NCEx)}$ | FSMC_NWE high to FSMC_NCEx high | $5T_{HCLK}-1$ | - | ns |
| $t_{d(NCEx-NWE)}$ | FSMC_NCEx low to FSMC_NWE low | - | $5T_{HCLK}+1$ | ns |
| $t_{v(NWE-D)}$ | FSMC_NWE low to FSMC_D[15:0] valid | - | 0 | ns |
| $t_{h}(NWE-D)$ | FSMC_NWE high to FSMC_D[15:0] invalid | $8T_{HCLK}-1$ | - | ns |
| $t_{d}(D-NWE)$ | FSMC_D[15:0] valid before FSMC_NWE high | $13T_{HCLK}-1$ | - | ns |

1. $C_L = 30$ pF.

2. Based on characterization, not tested in production.

Table 82. Switching characteristics for PC Card/CF read and write cycles in I/O space⁽¹⁾⁽²⁾

| Symbol | Parameter | Min | Max | Unit |
|------------------------|---|-------------------|-------------------|------|
| $t_{w(NIOWR)}$ | FSMC_NIOWR low width | $8T_{HCLK} - 1$ | - | ns |
| $t_{v(NIOWR-D)}$ | FSMC_NIOWR low to FSMC_D[15:0] valid | - | $5T_{HCLK} - 1$ | ns |
| $t_{h(NIOWR-D)}$ | FSMC_NIOWR high to FSMC_D[15:0] invalid | $8T_{HCLK} - 2$ | - | ns |
| $t_{d(NCE4_1-NIOWR)}$ | FSMC_NCE4_1 low to FSMC_NIOWR valid | - | $5T_{HCLK} + 2.5$ | ns |
| $t_{h(NCEX-NIOWR)}$ | FSMC_NCEX high to FSMC_NIOWR invalid | $5T_{HCLK} - 1.5$ | - | ns |
| $t_{d(NIORD-NCEX)}$ | FSMC_NCEX low to FSMC_NIORD valid | - | $5T_{HCLK} + 2$ | ns |
| $t_{h(NCEX-NIORD)}$ | FSMC_NCEX high to FSMC_NIORD) valid | $5T_{HCLK} - 1.5$ | - | ns |
| $t_{w(NIORD)}$ | FSMC_NIORD low width | $8T_{HCLK} - 0.5$ | - | ns |
| $t_{su(D-NIORD)}$ | FSMC_D[15:0] valid before FSMC_NIORD high | 9 | - | ns |
| $t_{d(NIORD-D)}$ | FSMC_D[15:0] valid after FSMC_NIORD high | 0 | - | ns |

1. $C_L = 30$ pF.
2. Based on characterization, not tested in production.

NAND controller waveforms and timings

Figure 67 through Figure 70 represent synchronous waveforms, and Table 83 and Table 84 provide the corresponding timings. The results shown in this table are obtained with the following FSMC configuration:

- COM.FSMC_SetupTime = 0x01;
- COM.FSMC_WaitSetupTime = 0x03;
- COM.FSMC_HoldSetupTime = 0x02;
- COM.FSMC_HiZSetupTime = 0x01;
- ATT.FSMC_SetupTime = 0x01;
- ATT.FSMC_WaitSetupTime = 0x03;
- ATT.FSMC_HoldSetupTime = 0x02;
- ATT.FSMC_HiZSetupTime = 0x01;
- Bank = FSMC_Bank_NAND;
- MemoryDataWidth = FSMC_MemoryDataWidth_16b;
- ECC = FSMC_ECC_Enable;
- ECCPageSize = FSMC_ECCPageSize_512Bytes;
- TCLRSetupTime = 0;
- TARSetupTime = 0.

In all timing tables, the T_{HCLK} is the HCLK clock period.

Figure 67. NAND controller waveforms for read access

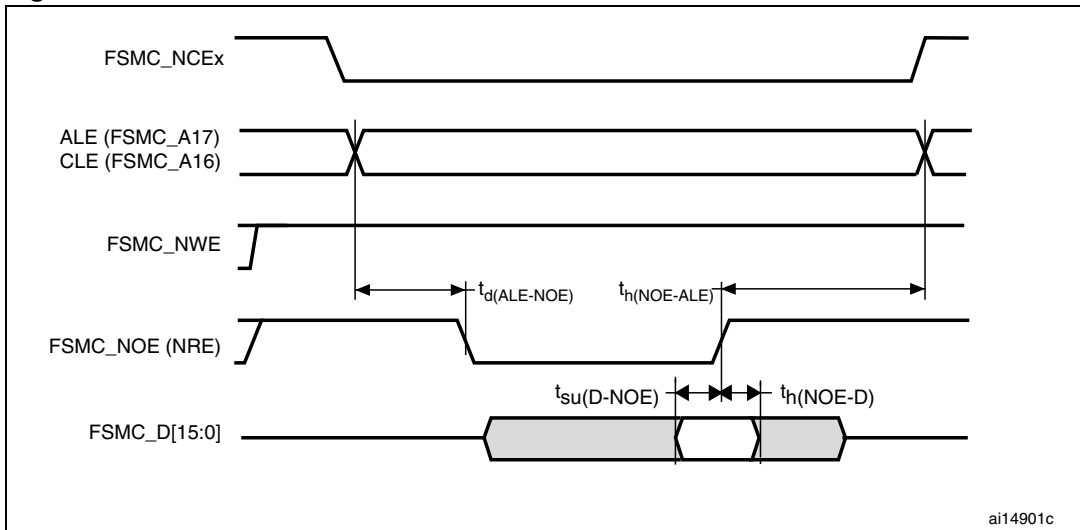


Figure 68. NAND controller waveforms for write access

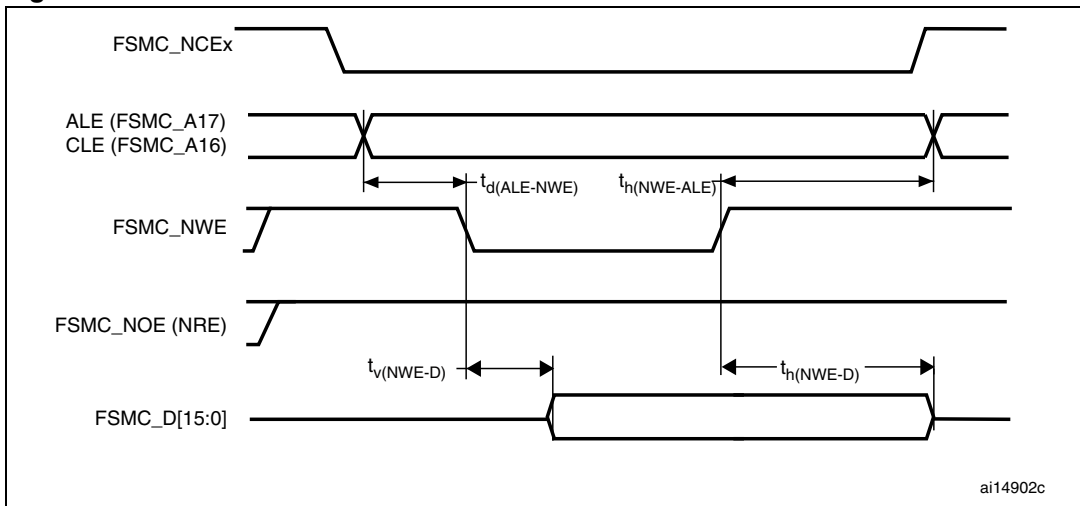


Figure 69. NAND controller waveforms for common memory read access

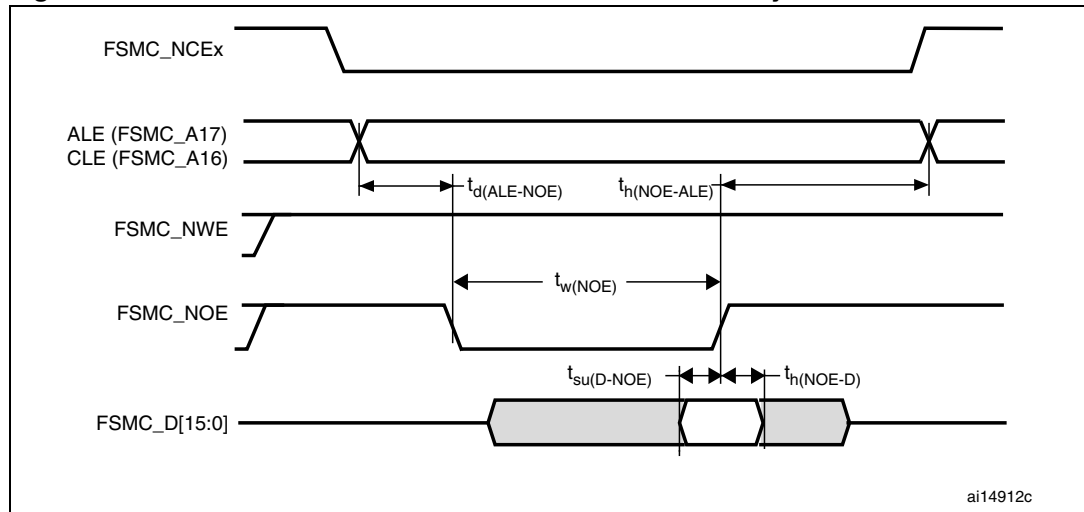


Figure 70. NAND controller waveforms for common memory write access

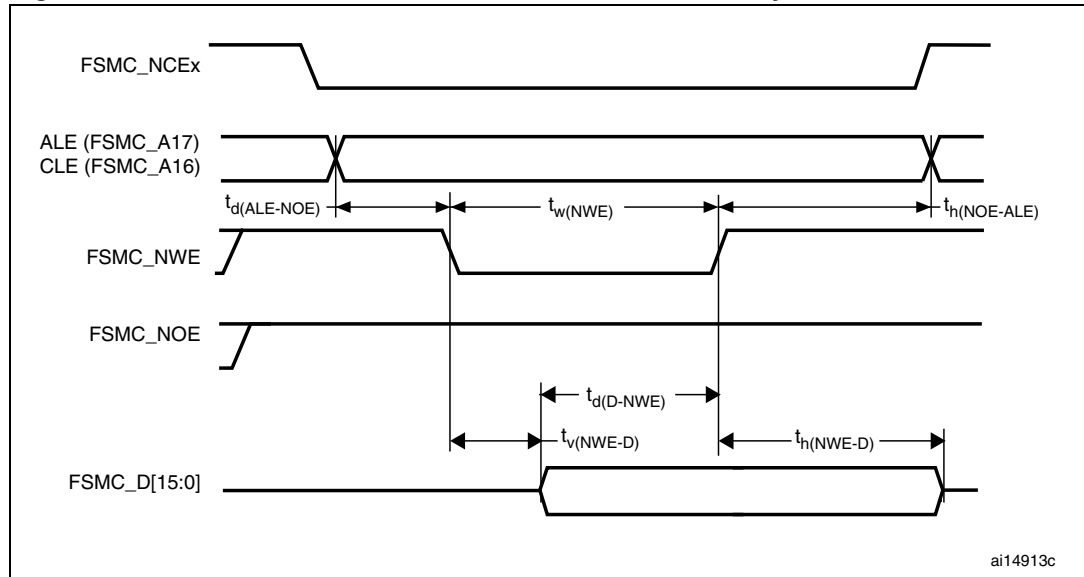


Table 83. Switching characteristics for NAND Flash read cycles⁽¹⁾

| Symbol | Parameter | Min | Max | Unit |
|------------------|--|-------------------|-----------------|------|
| $t_{w(NOE)}$ | FSMC_NOE low width | $4T_{HCLK} - 0.5$ | $4T_{HCLK} + 3$ | ns |
| $t_{su(D-NOE)}$ | FSMC_D[15-0] valid data before FSMC_NOE high | 10 | - | ns |
| $t_{h(NOE-D)}$ | FSMC_D[15-0] valid data after FSMC_NOE high | 0 | - | ns |
| $t_{d(ALE-NOE)}$ | FSMC_ALE valid before FSMC_NOE low | - | $3T_{HCLK}$ | ns |
| $t_{h(NOE-ALE)}$ | FSMC_NWE high to FSMC_ALE invalid | $3T_{HCLK} - 2$ | - | ns |

1. $C_L = 30$ pF.

Table 84. Switching characteristics for NAND Flash write cycles⁽¹⁾

| Symbol | Parameter | Min | Max | Unit |
|------------------|---|---------------|---------------|------|
| $t_{w(NWE)}$ | FSMC_NWE low width | $4T_{HCLK}-1$ | $4T_{HCLK}+3$ | ns |
| $t_{v(NWE-D)}$ | FSMC_NWE low to FSMC_D[15-0] valid | - | 0 | ns |
| $t_{h(NWE-D)}$ | FSMC_NWE high to FSMC_D[15-0] invalid | $3T_{HCLK}-2$ | - | ns |
| $t_{d(D-NWE)}$ | FSMC_D[15-0] valid before FSMC_NWE high | $5T_{HCLK}-3$ | - | ns |
| $t_{d(ALE-NWE)}$ | FSMC_ALE valid before FSMC_NWE low | - | $3T_{HCLK}$ | ns |
| $t_{h(NWE-ALE)}$ | FSMC_NWE high to FSMC_ALE invalid | $3T_{HCLK}-2$ | - | ns |

1. $C_L = 30$ pF.

5.3.26 Camera interface (DCMI) timing specifications

Table 85. DCMI characteristics

| Symbol | Parameter | Conditions | Min | Max |
|--------|---|------------|-----|-----|
| | Frequency ratio $DCMI_PIXCLK/f_{HCLK}^{(1)}$ | | | 0.4 |

1. Maximum value of DCMI_PIXCLK = 54 MHz.

5.3.27 SD/SDIO MMC card host interface (SDIO) characteristics

Unless otherwise specified, the parameters given in [Table 86](#) are derived from tests performed under ambient temperature, f_{PCLKx} frequency and V_{DD} supply voltage conditions summarized in [Table 13](#).

Refer to [Section 5.3.16: I/O port characteristics](#) for more details on the input/output alternate function characteristics (D[7:0], CMD, CK).

Figure 71. SDIO high-speed mode

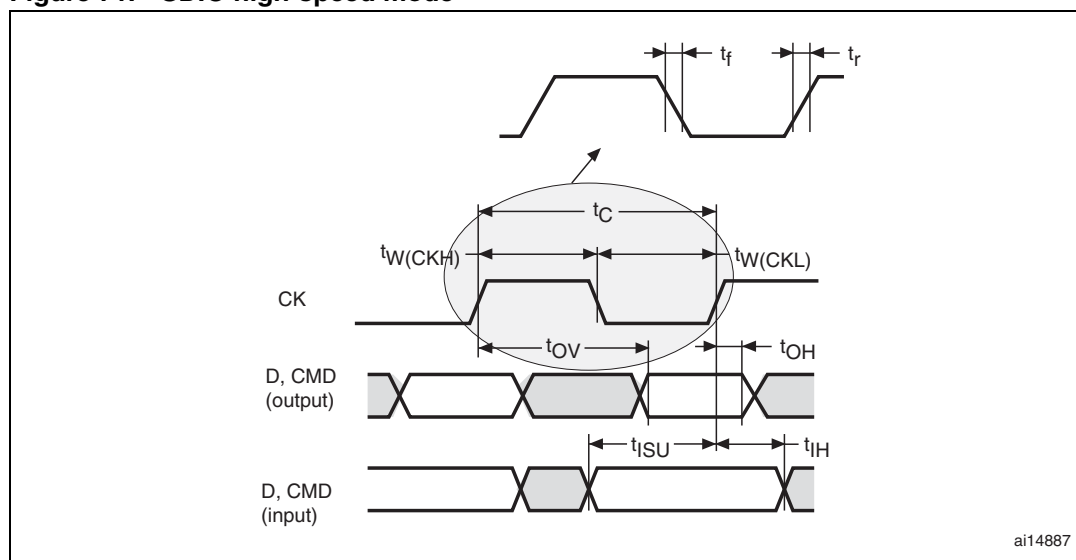


Figure 72. SD default mode

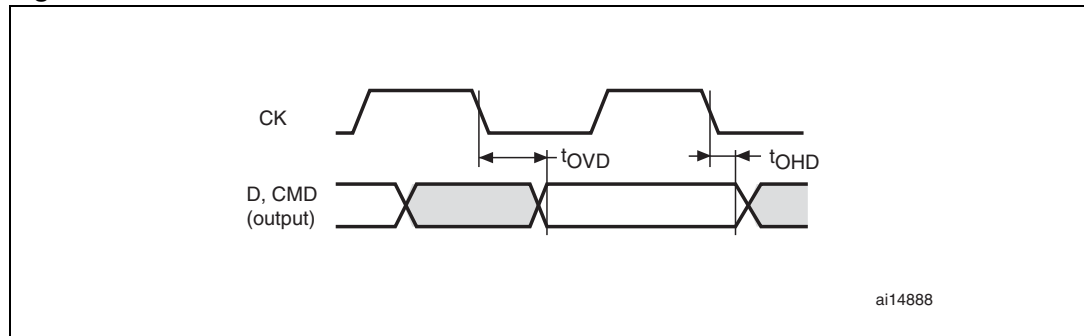


Table 86. SD / MMC characteristics⁽¹⁾

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---|--|------------------------|-----|-----|------|
| f _{PP} | Clock frequency in data transfer mode | C _L ≤ 30 pF | TBD | TBD | MHz |
| - | SDIO_CK/f _{PCLK2} frequency ratio | - | - | TBD | - |
| t _{W(CKL)} | Clock low time, f _{PP} = 16 MHz | C _L ≤ 30 pF | TBD | - | ns |
| t _{W(CKH)} | Clock high time, f _{PP} = 16 MHz | C _L ≤ 30 pF | TBD | - | |
| t _r | Clock rise time | C _L ≤ 30 pF | - | TBD | |
| t _f | Clock fall time | C _L ≤ 30 pF | - | TBD | |
| CMD, D inputs (referenced to CK) | | | | | |
| t _{SU} | Input setup time | C _L ≤ 30 pF | TBD | - | ns |
| t _{IH} | Input hold time | C _L ≤ 30 pF | TBD | - | |
| CMD, D outputs (referenced to CK) in MMC and SD HS mode | | | | | |
| t _{OV} | Output valid time | C _L ≤ 30 pF | - | TBD | ns |
| t _{OH} | Output hold time | C _L ≤ 30 pF | TBD | - | |
| CMD, D outputs (referenced to CK) in SD default mode⁽²⁾ | | | | | |
| t _{OVD} | Output valid default time | C _L ≤ 30 pF | - | TBD | ns |
| t _{OHD} | Output hold default time | C _L ≤ 30 pF | TBD | - | |

1. TBD stands for “to be defined”.

2. Refer to SDIO_CLKCR, the SDI clock control register to control the CK output.

5.3.28 RTC characteristics

Table 87. RTC characteristics

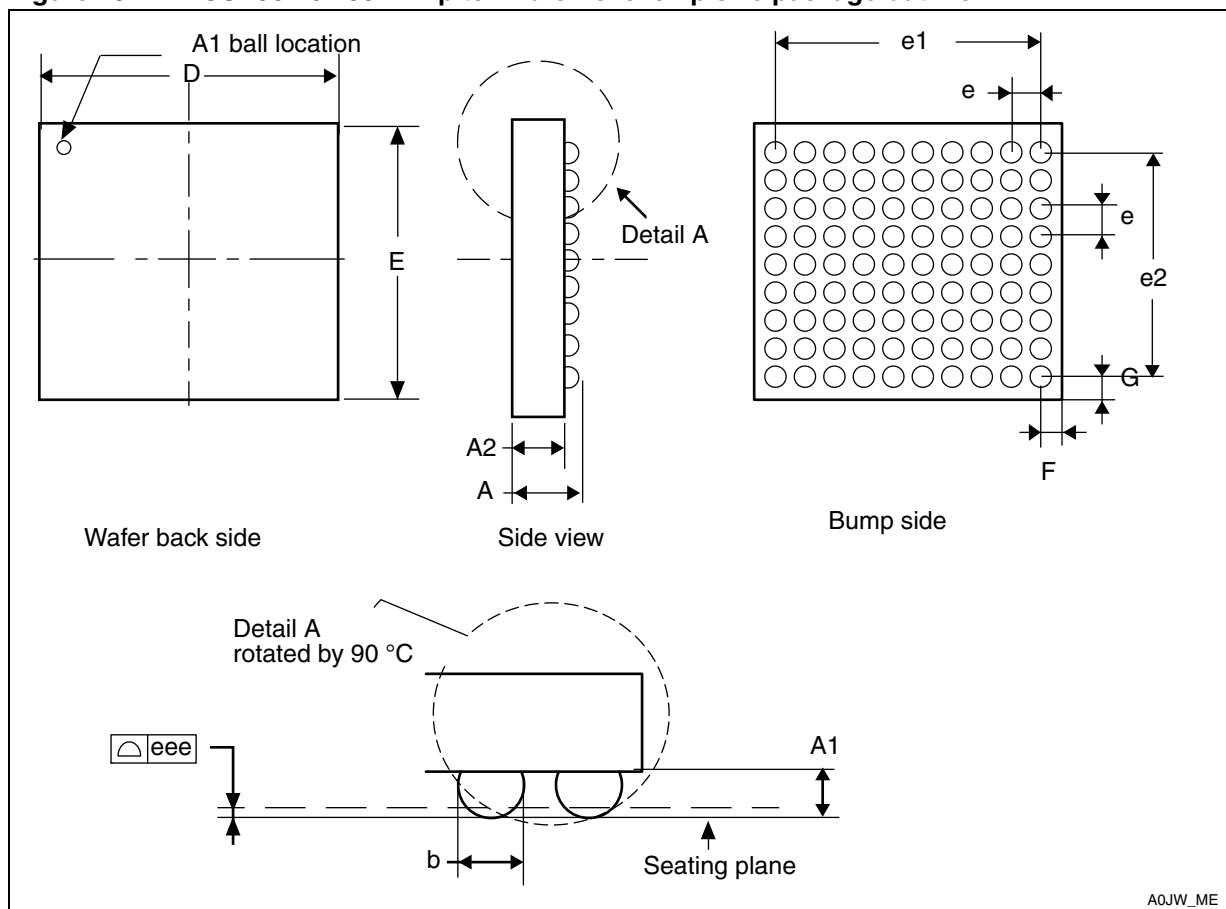
| Symbol | Parameter | Conditions | Min | Max |
|--------|--|--|-----|-----|
| - | f _{PCLK1} /RTCCLK frequency ratio | Any read/write operation from/to an RTC register | 4 | - |

6 Package characteristics

6.1 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 73. WLCSP90 - 0.400 mm pitch wafer level chip size package outline



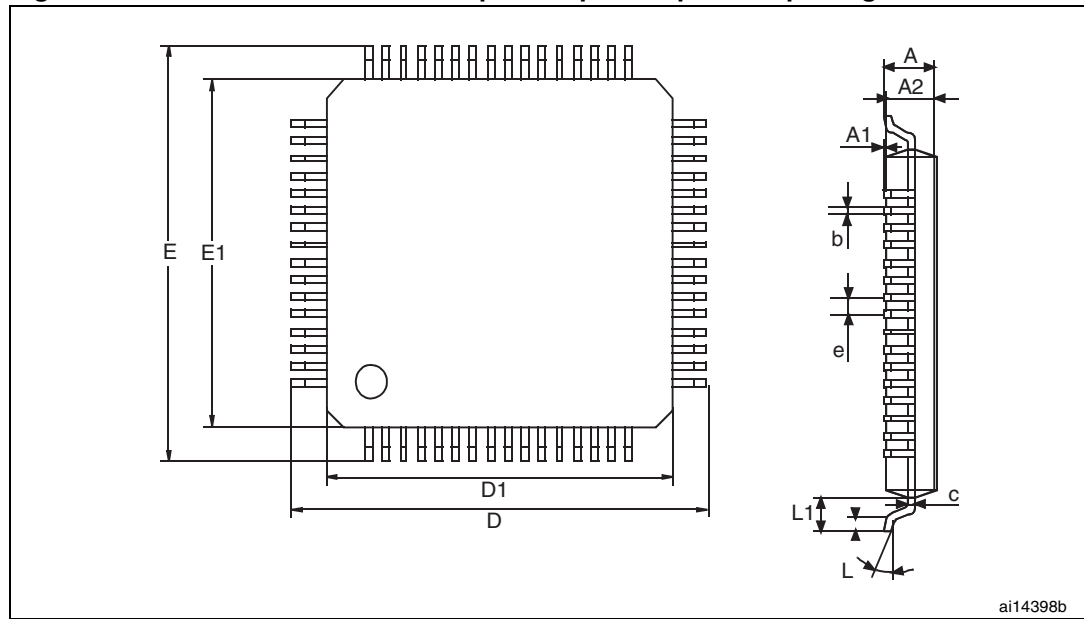
AOJW_ME

Table 88. WLCSP90 - 0.400 mm pitch wafer level chip size package mechanical data

| Symbol | millimeters | | | inches ⁽¹⁾ | | |
|--------|-------------|-------|-------|-----------------------|--------|--------|
| | Min | Typ | Max | Min | Typ | Max |
| A | 0.520 | 0.570 | 0.620 | 0.0205 | 0.0224 | 0.0244 |
| A1 | 0.165 | 0.190 | 0.215 | 0.0065 | 0.0075 | 0.0085 |
| A2 | 0.350 | 0.380 | 0.410 | 0.0138 | 0.015 | 0.0161 |
| b | 0.240 | 0.270 | 0.300 | 0.0094 | 0.0106 | 0.0118 |
| D | 4.178 | 4.218 | 4.258 | 0.1645 | 0.1661 | 0.1676 |
| E | 3.964 | 3.969 | 4.004 | 0.1561 | 0.1563 | 0.1576 |
| e | | 0.400 | | | 0.0157 | |
| e1 | | 3.600 | | | 0.1417 | |
| e2 | | 3.200 | | | 0.126 | |
| F | | 0.312 | | | 0.0123 | |
| G | | 0.385 | | | 0.0152 | |
| eee | | | 0.050 | | | 0.0020 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 74. LQFP64 – 10 x 10 mm 64 pin low-profile quad flat package outline



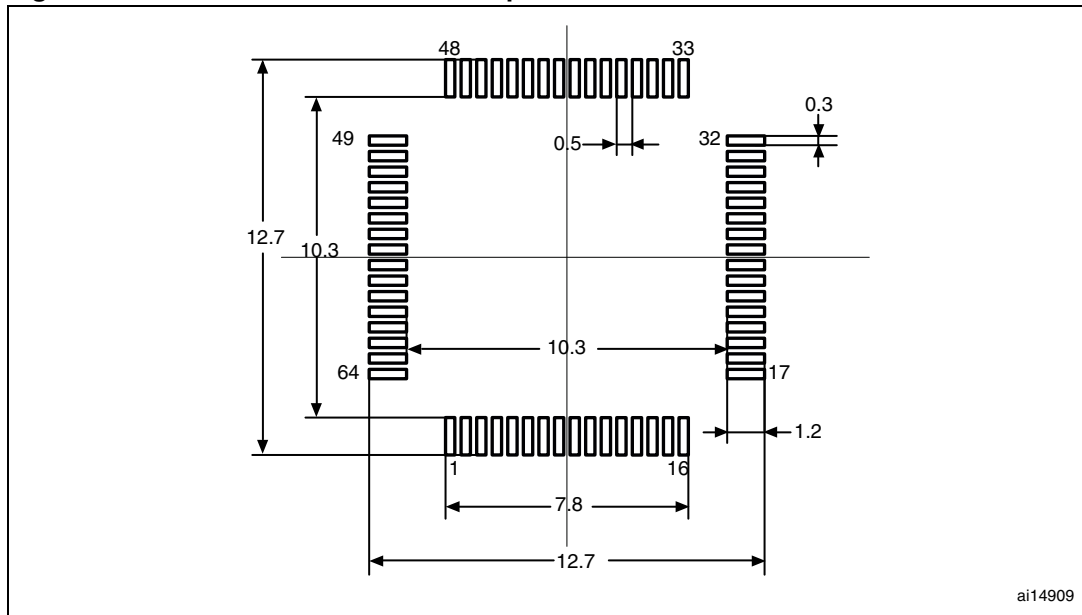
1. Drawing is not to scale.

Table 89. LQFP64 – 10 x 10 mm 64 pin low-profile quad flat package mechanical data

| Symbol | millimeters | | | inches ⁽¹⁾ | | |
|--------|-----------------------|--------|-------|-----------------------|--------|--------|
| | Min | Typ | Max | Min | Typ | Max |
| A | | | 1.600 | | | 0.0630 |
| A1 | 0.050 | | 0.150 | 0.0020 | | 0.0059 |
| A2 | 1.350 | 1.400 | 1.450 | 0.0531 | 0.0551 | 0.0571 |
| b | 0.170 | 0.220 | 0.270 | 0.0067 | 0.0087 | 0.0106 |
| c | 0.090 | | 0.200 | 0.0035 | | 0.0079 |
| D | | 12.000 | | | 0.4724 | |
| D1 | | 10.000 | | | 0.3937 | |
| E | | 12.000 | | | 0.4724 | |
| E1 | | 10.000 | | | 0.3937 | |
| e | | 0.500 | | | 0.0197 | |
| θ | 0° | 3.5° | 7° | 0° | 3.5° | 7° |
| L | 0.450 | 0.600 | 0.750 | 0.0177 | 0.0236 | 0.0295 |
| L1 | | 1.000 | | | 0.0394 | |
| N | Number of pins | | | | | |
| | 64 | | | | | |

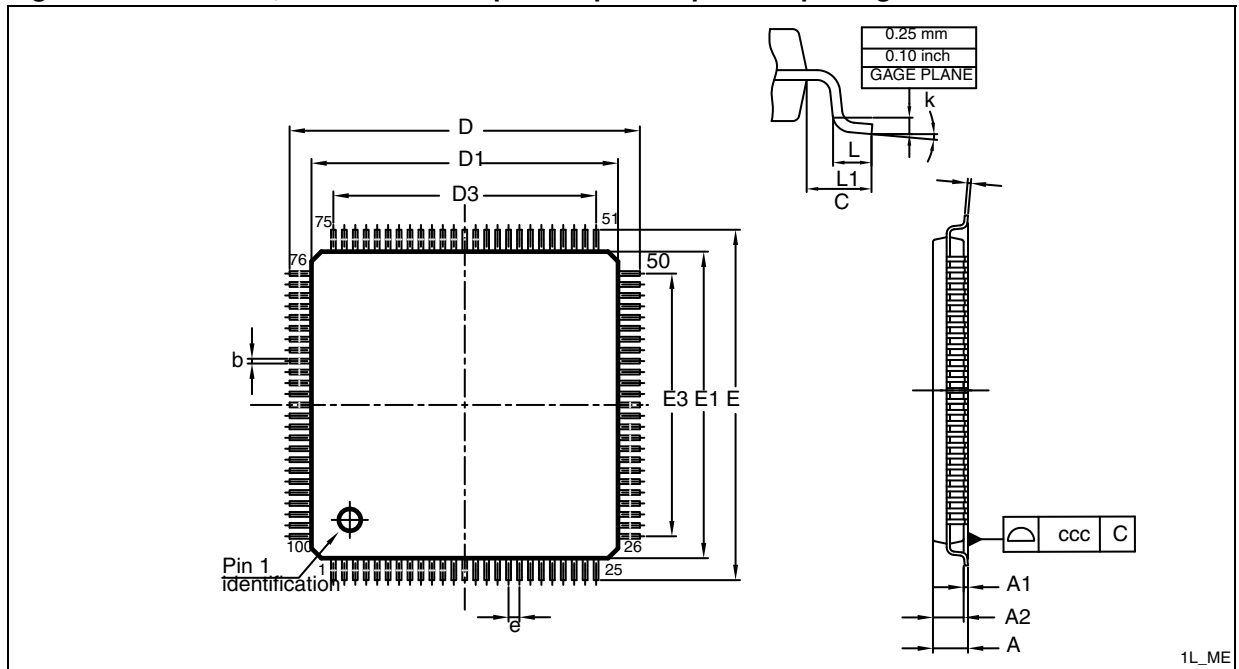
1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 75. LQFP64 recommended footprint



1. Drawing is not to scale.
2. Dimensions are in millimeters.

Figure 76. LQFP100, 14 x 14 mm 100-pin low-profile quad flat package outline



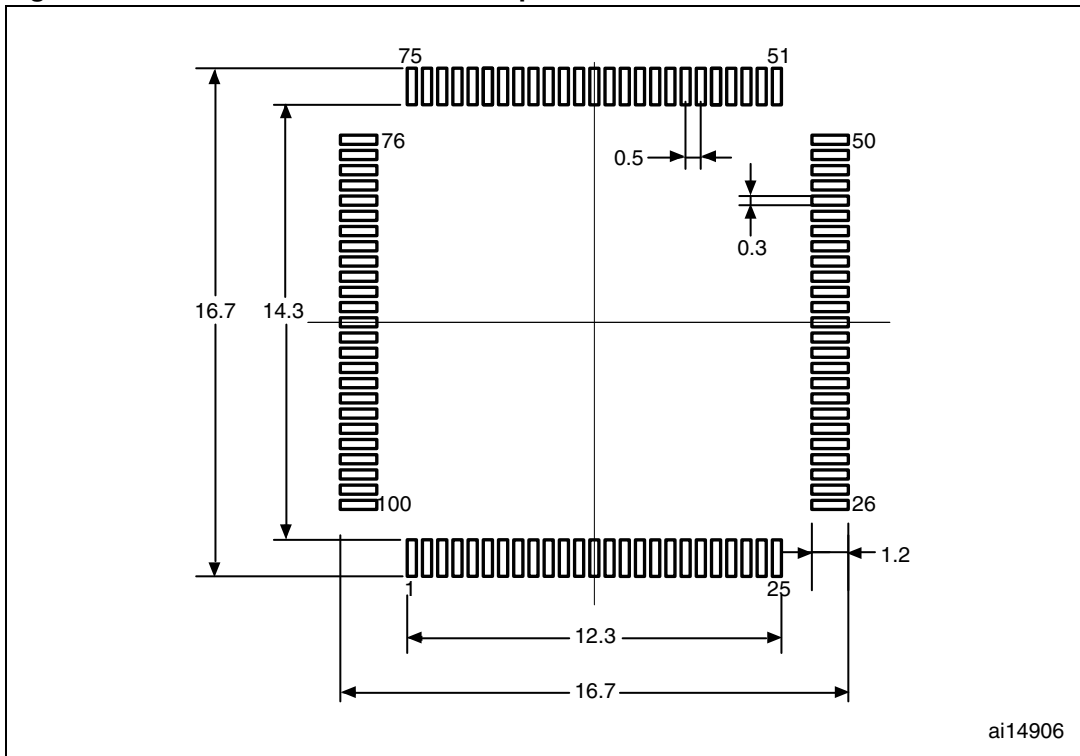
1. Drawing is not to scale.

Table 90. LQFP100 – 14 x 14 mm 100-pin low-profile quad flat package mechanical data⁽¹⁾

| Symbol | millimeters | | | inches | | |
|--------|-------------|--------|--------|--------|--------|--------|
| | Min | Typ | Max | Min | Typ | Max |
| A | | | 1.600 | | | 0.0630 |
| A1 | 0.050 | | 0.150 | 0.0020 | | 0.0059 |
| A2 | 1.350 | 1.400 | 1.450 | 0.0531 | 0.0551 | 0.0571 |
| b | 0.170 | 0.220 | 0.270 | 0.0067 | 0.0087 | 0.0106 |
| c | 0.090 | | 0.200 | 0.0035 | | 0.0079 |
| D | 15.800 | 16.000 | 16.200 | 0.6220 | 0.6299 | 0.6378 |
| D1 | 13.800 | 14.000 | 14.200 | 0.5433 | 0.5512 | 0.5591 |
| D3 | | 12.000 | | | 0.4724 | |
| E | 15.80v | 16.000 | 16.200 | 0.6220 | 0.6299 | 0.6378 |
| E1 | 13.800 | 14.000 | 14.200 | 0.5433 | 0.5512 | 0.5591 |
| E3 | | 12.000 | | | 0.4724 | |
| e | | 0.500 | | | 0.0197 | |
| L | 0.450 | 0.600 | 0.750 | 0.0177 | 0.0236 | 0.0295 |
| L1 | | 1.000 | | | 0.0394 | |
| k | 0° | 3.5° | 7° | 0° | 3.5° | 7° |
| ccc | | | 0.080 | | | 0.0031 |

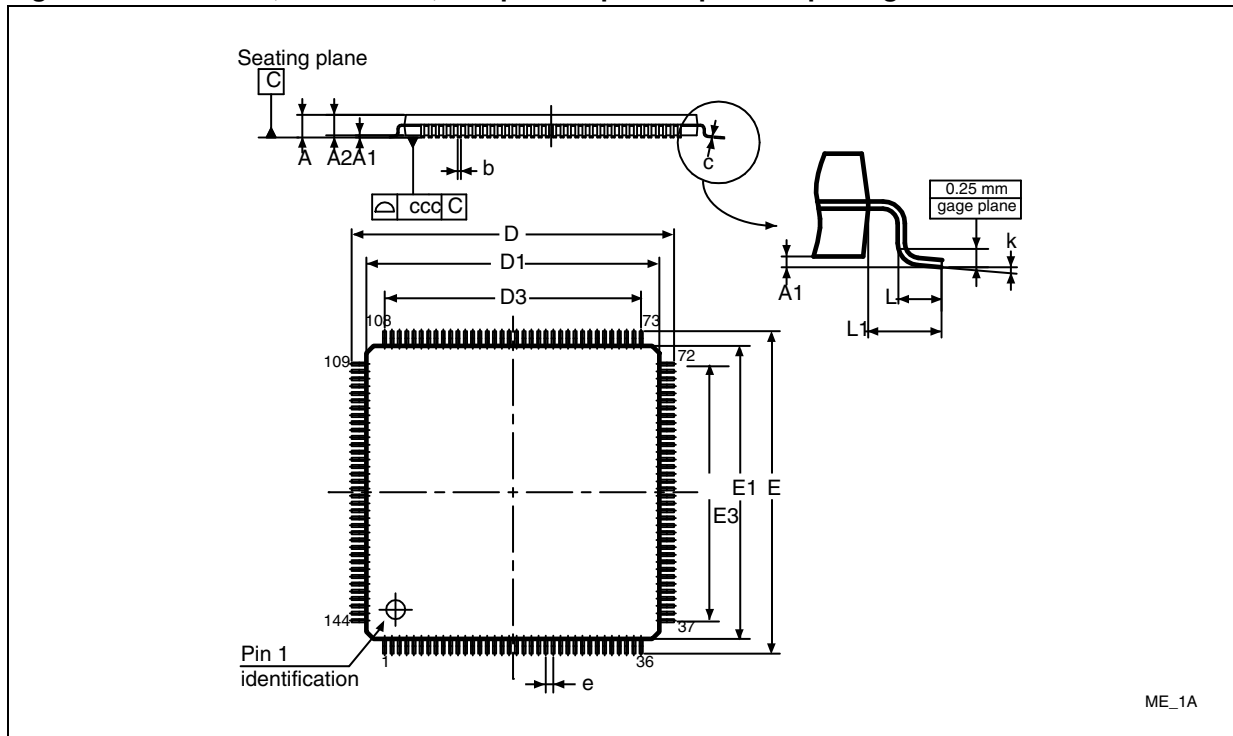
1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 77. LQFP100 recommended footprint



- 1. Drawing is not to scale.
- 2. Dimensions are in millimeters.

Figure 78. LQFP144, 20 x 20 mm, 144-pin low-profile quad flat package outline



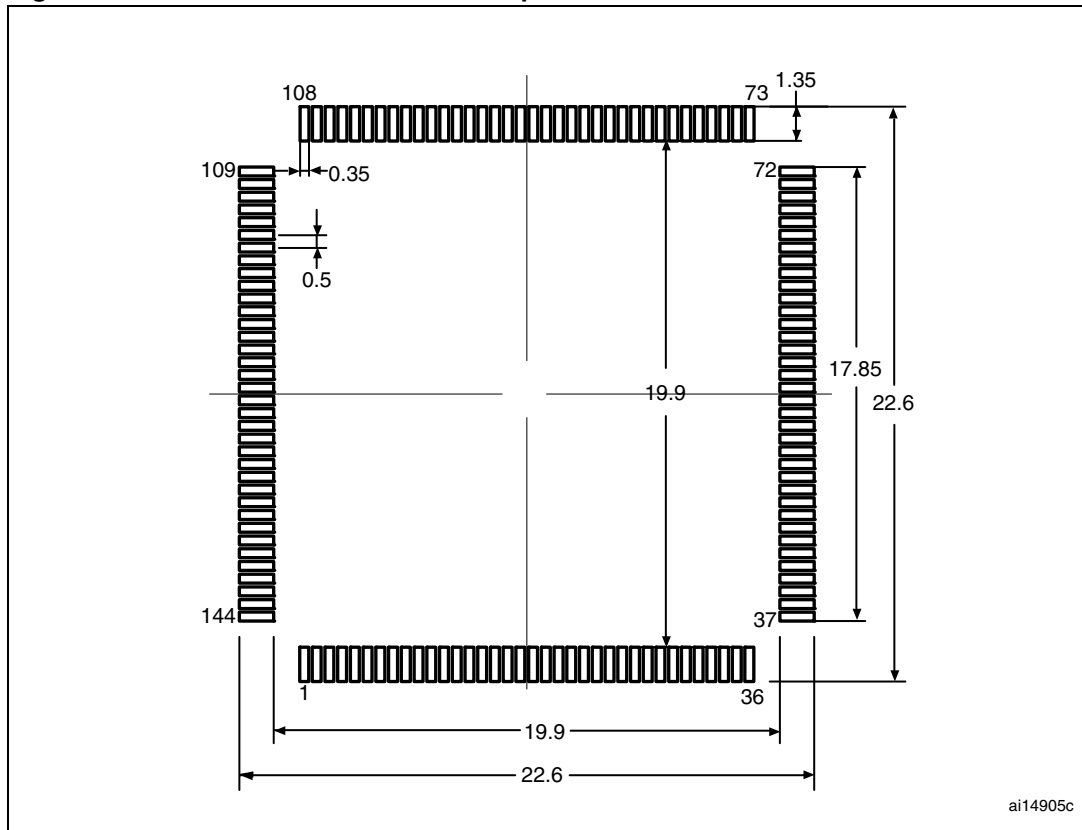
1. Drawing is not to scale.

Table 91. LQFP144, 20 x 20 mm, 144-pin low-profile quad flat package mechanical data

| Symbol | millimeters | | | inches ⁽¹⁾ | | |
|--------|-------------|--------|--------|-----------------------|--------|--------|
| | Min | Typ | Max | Min | Typ | Max |
| A | | | 1.600 | | | 0.0630 |
| A1 | 0.050 | | 0.150 | 0.0020 | | 0.0059 |
| A2 | 1.350 | 1.400 | 1.450 | 0.0531 | 0.0551 | 0.0571 |
| b | 0.170 | 0.220 | 0.270 | 0.0067 | 0.0087 | 0.0106 |
| c | 0.090 | | 0.200 | 0.0035 | | 0.0079 |
| D | 21.800 | 22.000 | 22.200 | 0.8583 | 0.8661 | 0.874 |
| D1 | 19.800 | 20.000 | 20.200 | 0.7795 | 0.7874 | 0.7953 |
| D3 | | 17.500 | | | 0.689 | |
| E | 21.800 | 22.000 | 22.200 | 0.8583 | 0.8661 | 0.8740 |
| E1 | 19.800 | 20.000 | 20.200 | 0.7795 | 0.7874 | 0.7953 |
| E3 | | 17.500 | | | 0.6890 | |
| e | | 0.500 | | | 0.0197 | |
| L | 0.450 | 0.600 | 0.750 | 0.0177 | 0.0236 | 0.0295 |
| L1 | | 1.000 | | | 0.0394 | |
| k | 0° | 3.5° | 7° | 0° | 3.5° | 7° |
| ccc | | | 0.080 | | | 0.0031 |

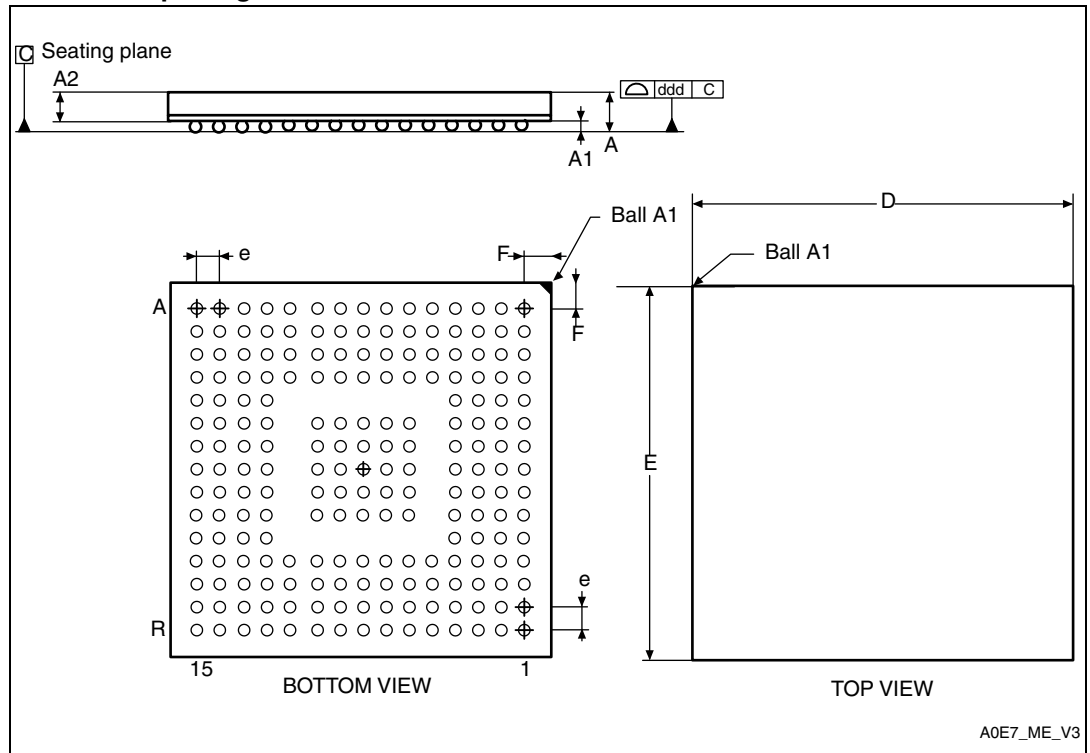
1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 79. LQFP144 recommended footprint



1. Drawing is not to scale.
2. Dimensions are in millimeters.

Figure 80. UFBGA176+25 - ultra thin fine pitch ball grid array 10 × 10 × 0.6 mm, package outline



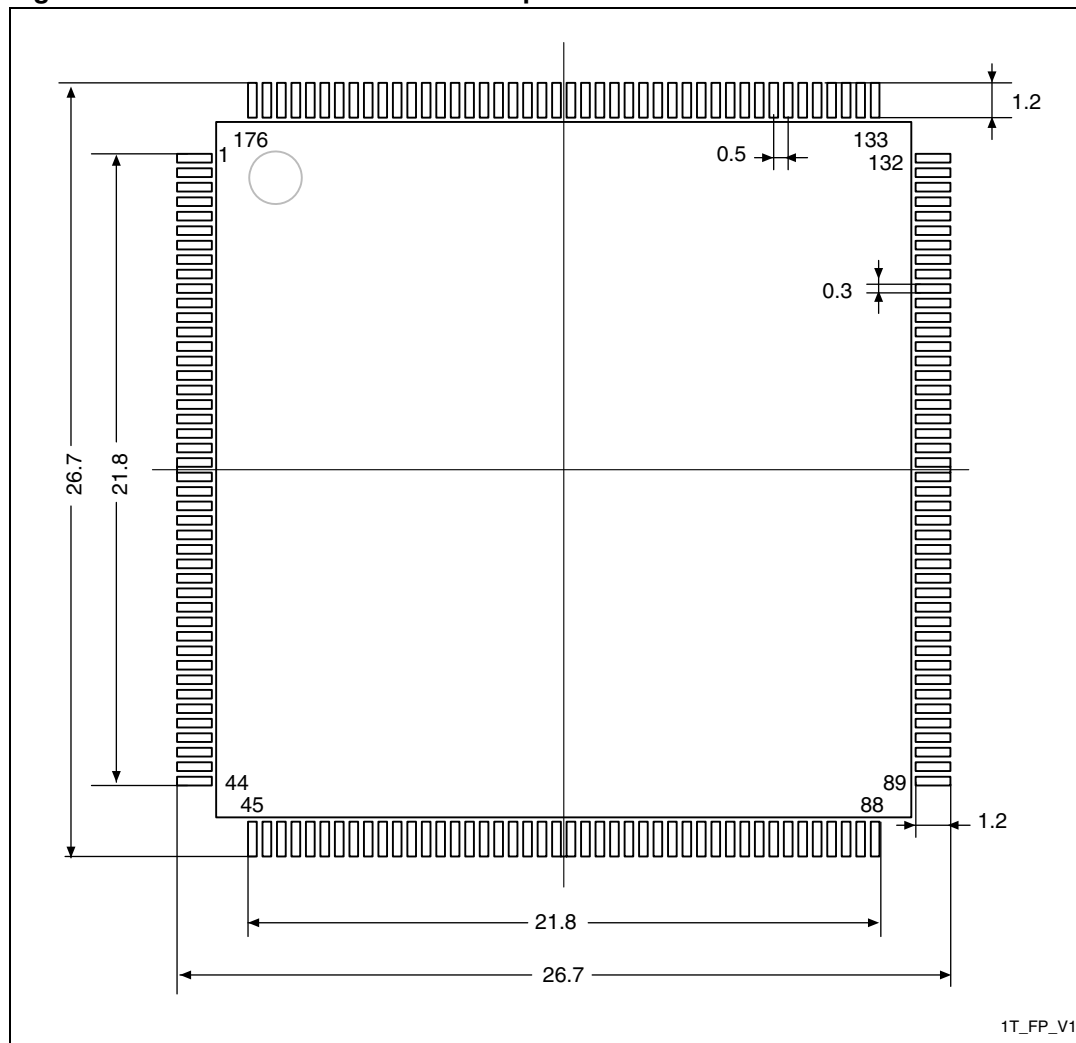
1. Drawing is not to scale.

Table 92. UFBGA176+25 - ultra thin fine pitch ball grid array 10 × 10 × 0.6 mm mechanical data

| Symbol | millimeters | | | inches ⁽¹⁾ | | |
|--------|-------------|--------|--------|-----------------------|--------|--------|
| | Min | Typ | Max | Min | Typ | Max |
| A | 0.460 | 0.530 | 0.600 | 0.0181 | 0.0209 | 0.0236 |
| A1 | 0.050 | 0.080 | 0.110 | 0.002 | 0.0031 | 0.0043 |
| A4 | 0.400 | 0.450 | 0.500 | 0.0157 | 0.0177 | 0.0197 |
| b | 0.230 | 0.280 | 0.330 | 0.0091 | 0.0110 | 0.0130 |
| D | 9.900 | 10.000 | 10.100 | 0.3898 | 0.3937 | 0.3976 |
| E | 9.900 | 10.000 | 10.100 | 0.3898 | 0.3937 | 0.3976 |
| e | | 0.650 | | | 0.0256 | |
| F | 0.425 | 0.450 | 0.475 | 0.0167 | 0.0177 | 0.0187 |
| ddd | | | 0.080 | | | 0.0031 |
| eee | | | 0.150 | | | 0.0059 |
| fff | | | 0.080 | | | 0.0031 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 82. LQFP176 recommended footprint



1. Dimensions are expressed in millimeters.

6.2 Thermal characteristics

The maximum chip-junction temperature, $T_J \text{ max}$, in degrees Celsius, may be calculated using the following equation:

$$T_J \text{ max} = T_A \text{ max} + (P_D \text{ max} \times \Theta_{JA})$$

Where:

- $T_A \text{ max}$ is the maximum ambient temperature in °C,
- Θ_{JA} is the package junction-to-ambient thermal resistance, in °C/W,
- $P_D \text{ max}$ is the sum of $P_{INT \text{ max}}$ and $P_{I/O \text{ max}}$ ($P_D \text{ max} = P_{INT \text{ max}} + P_{I/O \text{ max}}$),
- $P_{INT \text{ max}}$ is the product of I_{DD} and V_{DD} , expressed in Watts. This is the maximum chip internal power.

$P_{I/O \text{ max}}$ represents the maximum power dissipation on output pins where:

$$P_{I/O \text{ max}} = \Sigma (V_{OL} \times I_{OL}) + \Sigma ((V_{DD} - V_{OH}) \times I_{OH}),$$

taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Table 94. Package thermal characteristics

| Symbol | Parameter | Value | Unit |
|---------------|---|-------|------|
| Θ_{JA} | Thermal resistance junction-ambient LQFP64 - 10 × 10 mm / 0.5 mm pitch | 46 | °C/W |
| | Thermal resistance junction-ambient LQFP100 - 14 × 14 mm / 0.5 mm pitch | 43 | |
| | Thermal resistance junction-ambient LQFP144 - 20 × 20 mm / 0.5 mm pitch | 40 | |
| | Thermal resistance junction-ambient LQFP176 - 24 × 24 mm / 0.5 mm pitch | 38 | |
| | Thermal resistance junction-ambient UFBGA176 - 10× 10 mm / 0.65 mm pitch | 39 | |
| | Thermal resistance junction-ambient WLCSP90 - 0.400 mm pitch | 38.1 | |

Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org.

7 Part numbering

Table 95. Ordering information scheme

| | | | | | | | | |
|--------------------------|---|---|-----|---|---|---|---|-----|
| Example: | STM32 | F | 405 | R | E | T | 6 | xxx |
| Device family | STM32 = ARM-based 32-bit microcontroller | | | | | | | |
| Product type | F = general-purpose | | | | | | | |
| Device subfamily | 405 = STM32F40x, connectivity 407 = STM32F40x, connectivity, camera interface, Ethernet | | | | | | | |
| Pin count | R = 64 pins O = 90 pins V = 100 pins Z = 144 pins I = 176 pins | | | | | | | |
| Flash memory size | E = 512 Kbytes of Flash memory G = 1024 Kbytes of Flash memory | | | | | | | |
| Package | T = LQFP H = UFBGA Y = WLCSP | | | | | | | |
| Temperature range | 6 = Industrial temperature range, -40 to 85 °C. 7 = Industrial temperature range, -40 to 105 °C. | | | | | | | |
| Options | xxx = programmed parts TR = tape and reel | | | | | | | |

For a list of available options (speed, package, etc.) or for further information on any aspect of this device, please contact your nearest ST sales office.

Appendix A Application block diagrams

A.1 Main applications versus package

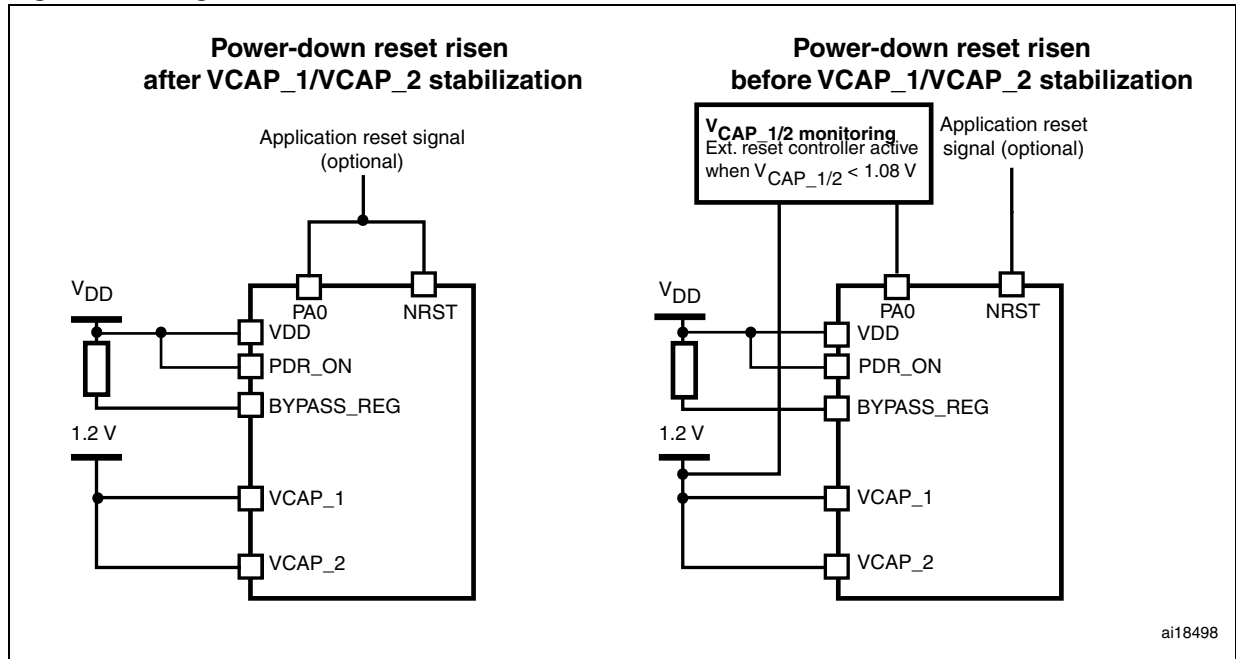
Table 96 gives examples of configurations for each package.

Table 96. Main applications versus package for STM32F407xx microcontrollers

| | | 64 pins | | | 100 pins | | | | 144 pins | | | | 176 pins | | |
|----------------------|---------------|--------------|--------------|----------|--------------|--------------|--------------|----------|--------------|--------------|----------|--------------|----------|----------|---|
| | | Config 1 | Config 2 | Config 3 | Config 1 | Config 2 | Config 3 | Config 4 | Config 1 | Config 2 | Config 3 | Config 4 | Config 1 | Config 2 | |
| USB 1 | OTG FS | X | X | X | X | X | X | - | X | | X | | X | | |
| | FS | X | X | X | X | X | X | X | X | X | X | X | X | | |
| USB 2 | HS ULPI | - | - | - | X | - | - | - | X | X | | | X | X | |
| | OTGFS | - | - | - | X | | | | X | X | | | X | X | |
| | FS | - | - | - | X | X | X | X | X | X | X | X | X | X | |
| Ethernet | MII | - | - | - | - | - | X | X | | | X | X | X | X | |
| | RMII | - | - | - | - | X | X | X | X | X | X | X | X | X | |
| SPI/I2S2 SPI/I2S3 | | - | X | - | - | X | X | X | X | X | X | X | X | X | |
| SDIO | SDIO | | | - | | | | X | | X | | X | X | X | |
| DCMI | 8bits Data | SDIO or DCMI | SDIO or DCMI | - | SDIO or DCMI | SDIO or DCMI | SDIO or DCMI | X | SDIO or DCMI | SDIO or DCMI | X | SDIO or DCMI | X | X | X |
| | 10bits Data | | | - | | | | X | | | X | | | | |
| | 12bits Data | | | - | | | | X | | | X | | | | |
| | 14bits Data | - | - | - | - | - | - | - | X | | X | X | X | | |
| FSMC | NOR/RAM Muxed | - | - | - | X | X | X | X | X | X | X | X | X | X | |
| | NOR/RAM | - | - | - | | | | | X | X | X | X | X | X | |
| | NAND | - | - | - | X | X | X | X | X | X | X | X | X | X | |
| | CF | - | - | - | - | - | - | - | X | X | X | X | X | X | |
| CAN | | - | X | X | - | X | X | X | - | - | X | X | - | X | |

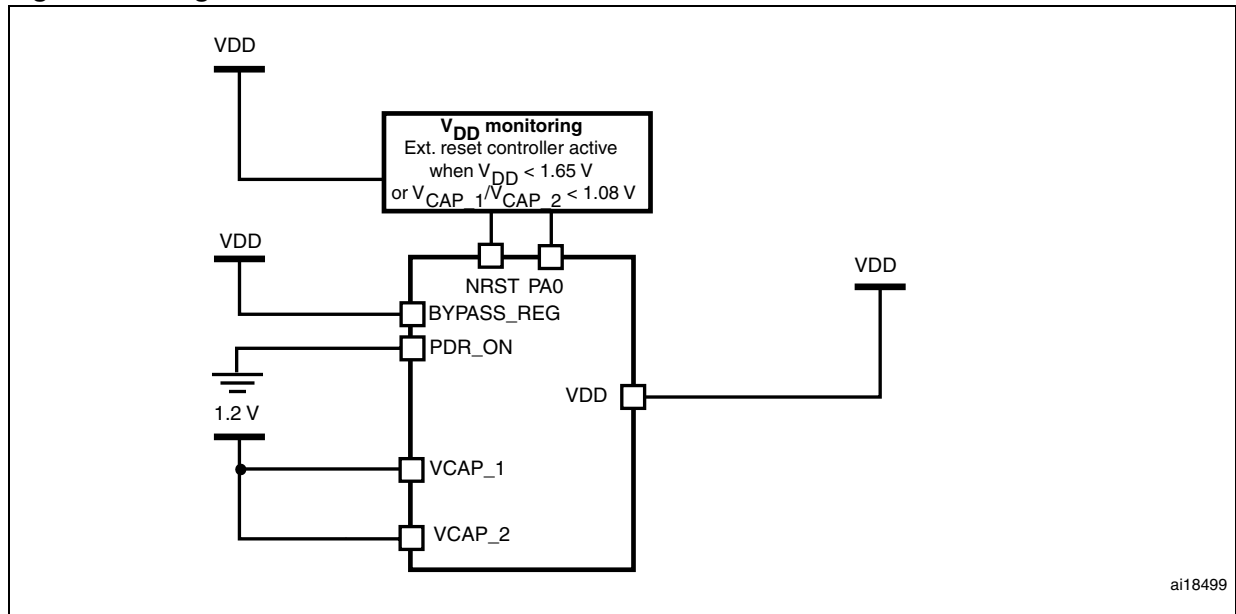
A.2 Application example with regulator OFF

Figure 83. Regulator OFF/internal reset ON



1. This mode is available only on UFBGA176 and WLCSP90 packages.

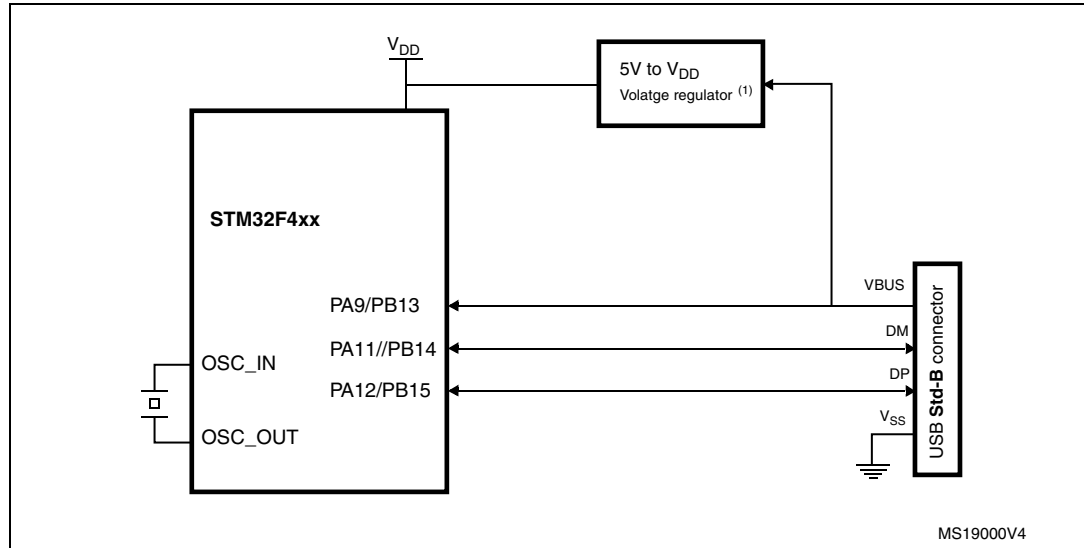
Figure 84. Regulator OFF/internal reset OFF



1. This mode is available only on UFBGA176 and WLCSP90 packages.

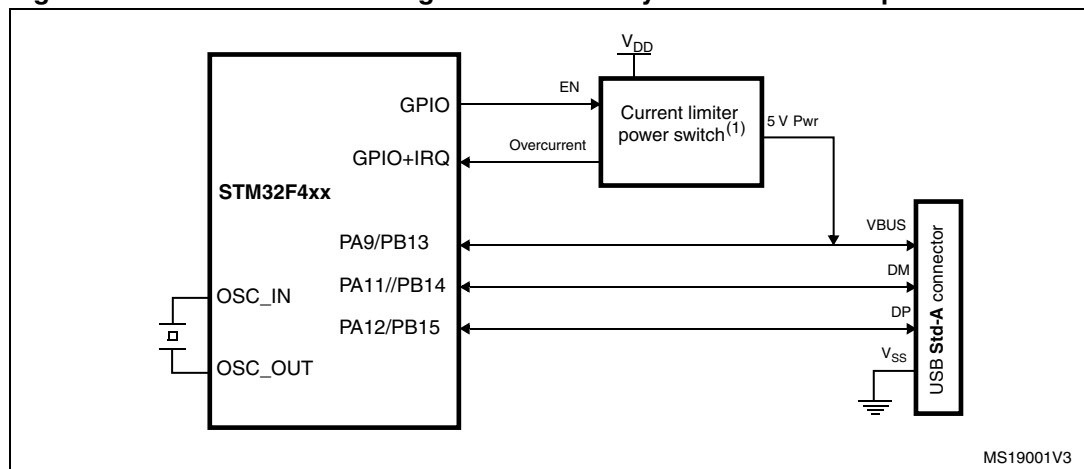
A.3 USB OTG full speed (FS) interface solutions

Figure 85. USB controller configured as peripheral-only and used in Full speed mode



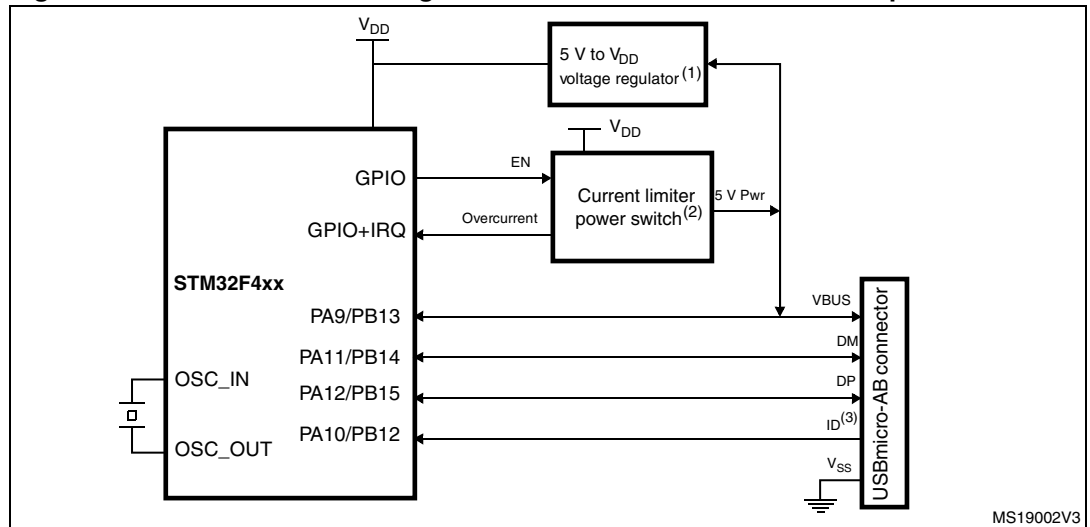
1. External voltage regulator only needed when building a V_{BUS} powered device.
2. The same application can be developed using the OTG HS in FS mode to achieve enhanced performance thanks to the large Rx/Tx FIFO and to a dedicated DMA controller.

Figure 86. USB controller configured as host-only and used in full speed mode



1. The current limiter is required only if the application has to support a V_{BUS} powered device. A basic power switch can be used if 5 V are available on the application board.
2. The same application can be developed using the OTG HS in FS mode to achieve enhanced performance thanks to the large Rx/Tx FIFO and to a dedicated DMA controller.

Figure 87. USB controller configured in dual mode and used in full speed mode

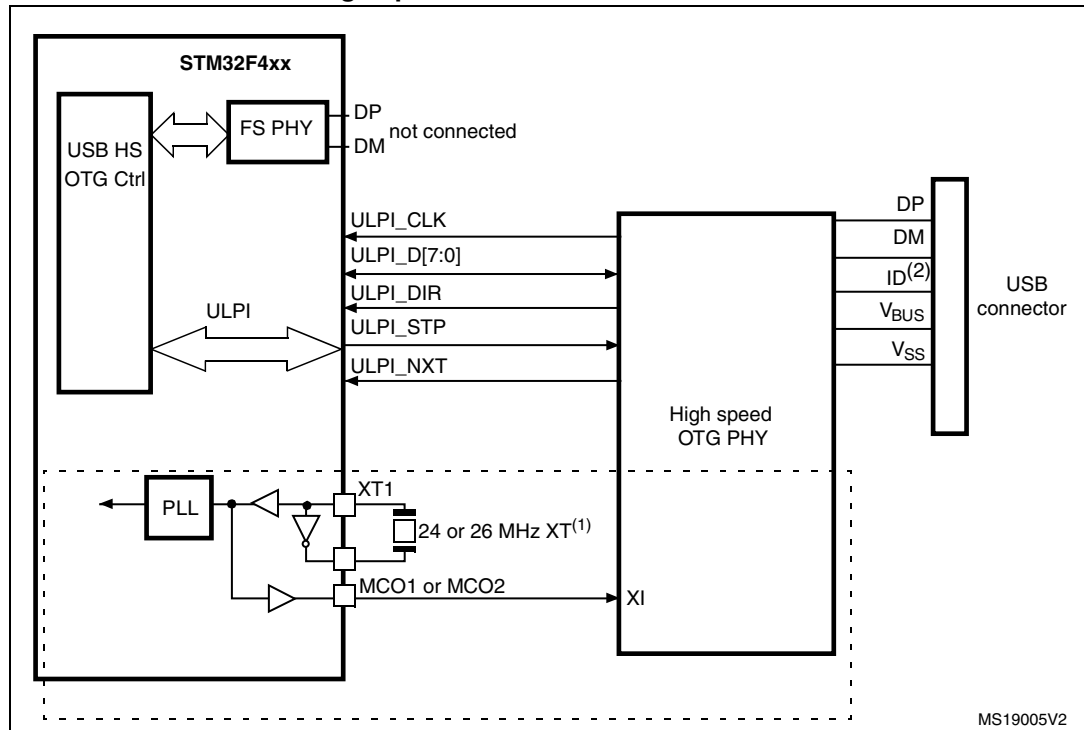


MS19002V3

1. External voltage regulator only needed when building a V_{BUS} powered device.
2. The current limiter is required only if the application has to support a V_{BUS} powered device. A basic power switch can be used if 5 V are available on the application board.
3. The ID pin is required in dual role only.
4. The same application can be developed using the OTG HS in FS mode to achieve enhanced performance thanks to the large Rx/Tx FIFO and to a dedicated DMA controller.

A.4 USB OTG high speed (HS) interface solutions

Figure 88. USB controller configured as peripheral, host, or dual-mode and used in high speed mode



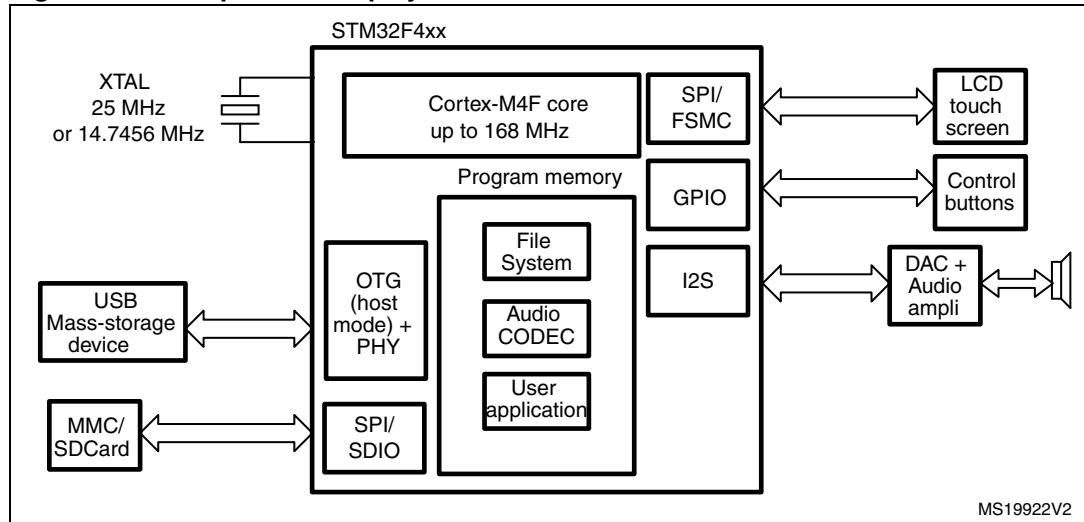
1. It is possible to use MCO1 or MCO2 to save a crystal. It is however not mandatory to clock the STM32F40x with a 24 or 26 MHz crystal when using USB HS. The above figure only shows an example of a possible connection.
2. The ID pin is required in dual role only.

A.5 Complete audio player solutions

Two solutions are offered, illustrated in [Figure 89](#) and [Figure 90](#).

[Figure 89](#) shows storage media to audio DAC/amplifier streaming using a software Codec. This solution implements an audio crystal to provide audio class I²S accuracy on the master clock (0.5% error maximum, see the Serial peripheral interface section in the reference manual for details).

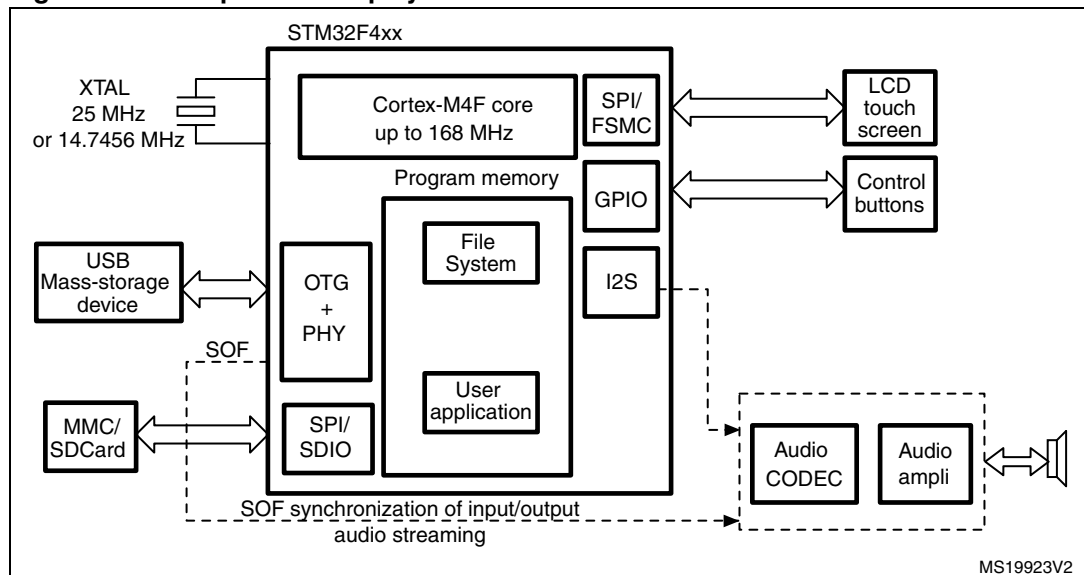
Figure 89. Complete audio player solution 1



MS19922V2

[Figure 90](#) shows storage media to audio Codec/amplifier streaming with SOF synchronization of input/output audio streaming using a hardware Codec.

Figure 90. Complete audio player solution 2



MS19923V2

Figure 91. Audio player solution using PLL, PLLI2S, USB and 1 crystal

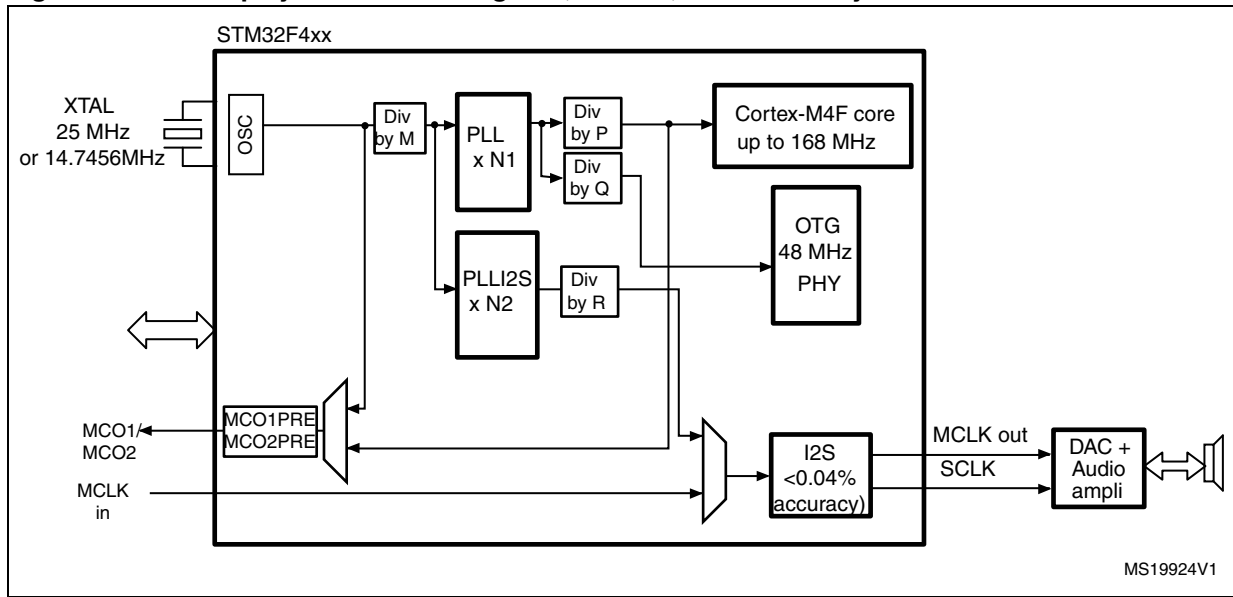


Figure 92. Audio PLL (PLLI2S) providing accurate I2S clock

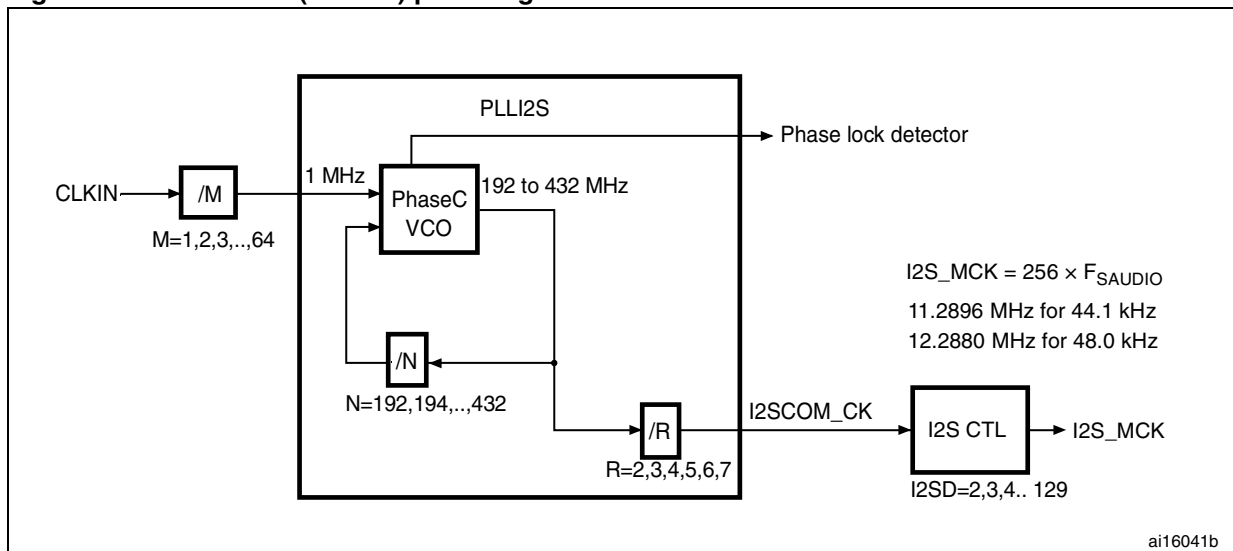
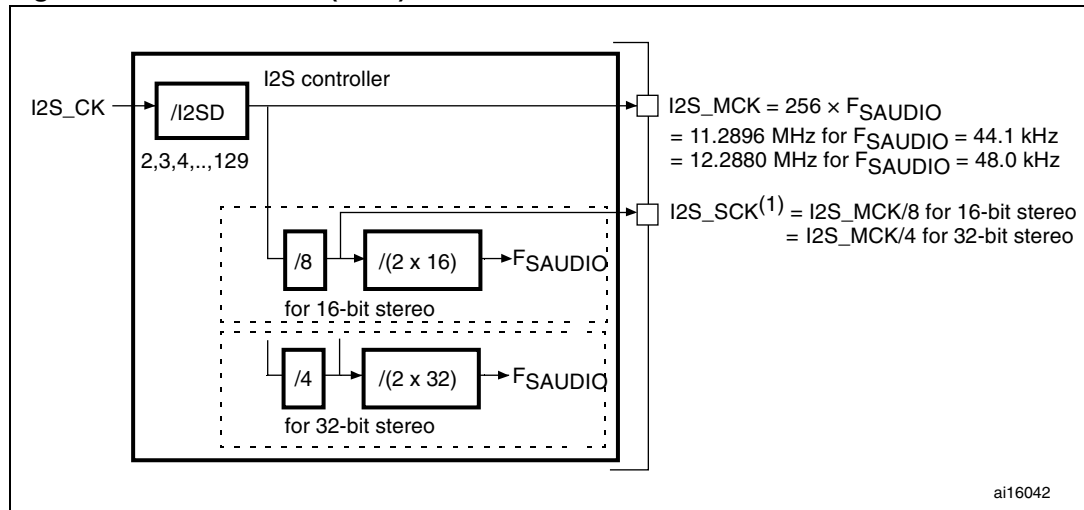
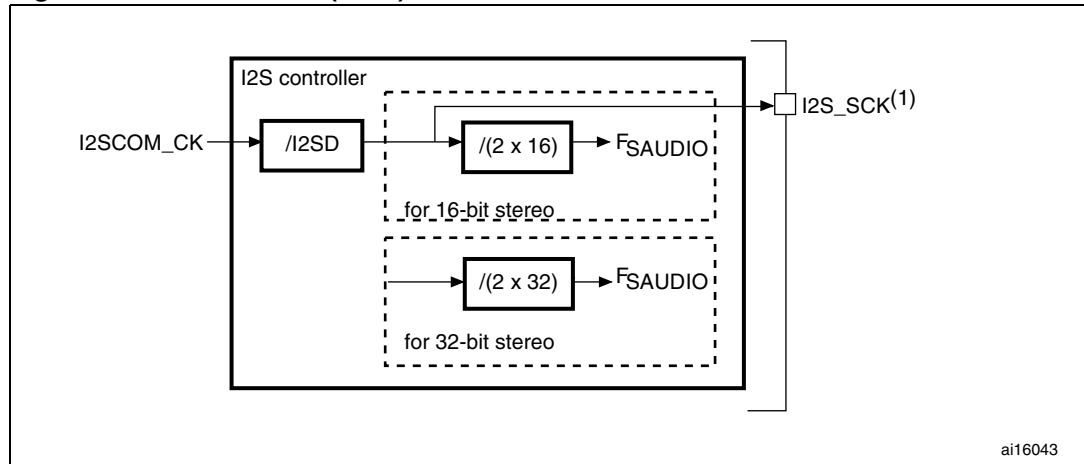


Figure 93. Master clock (MCK) used to drive the external audio DAC



1. I2S_SCK is the I2S serial clock to the external audio DAC (not to be confused with I2S_CK).

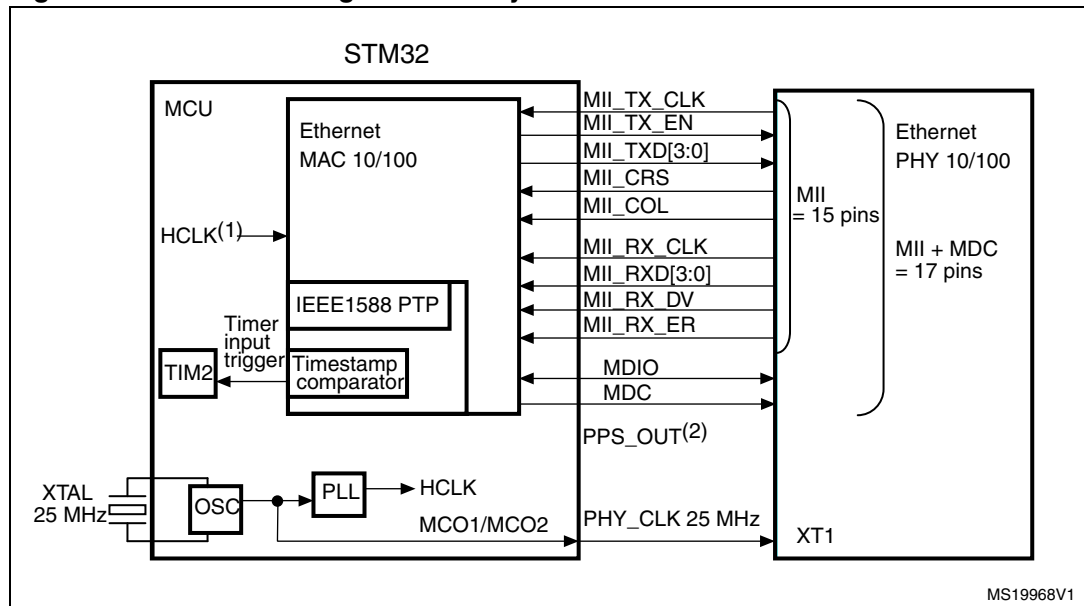
Figure 94. Master clock (MCK) not used to drive the external audio DAC



1. I2S_SCK is the I2S serial clock to the external audio DAC (not to be confused with I2S_CK).

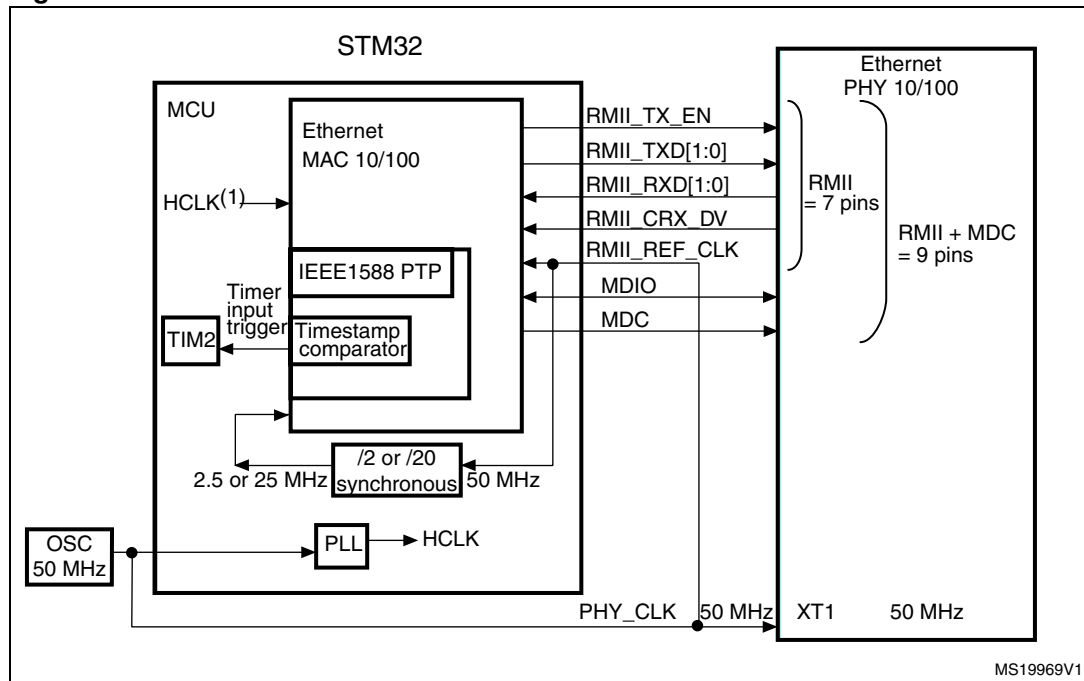
A.6 Ethernet interface solutions

Figure 95. MII mode using a 25 MHz crystal



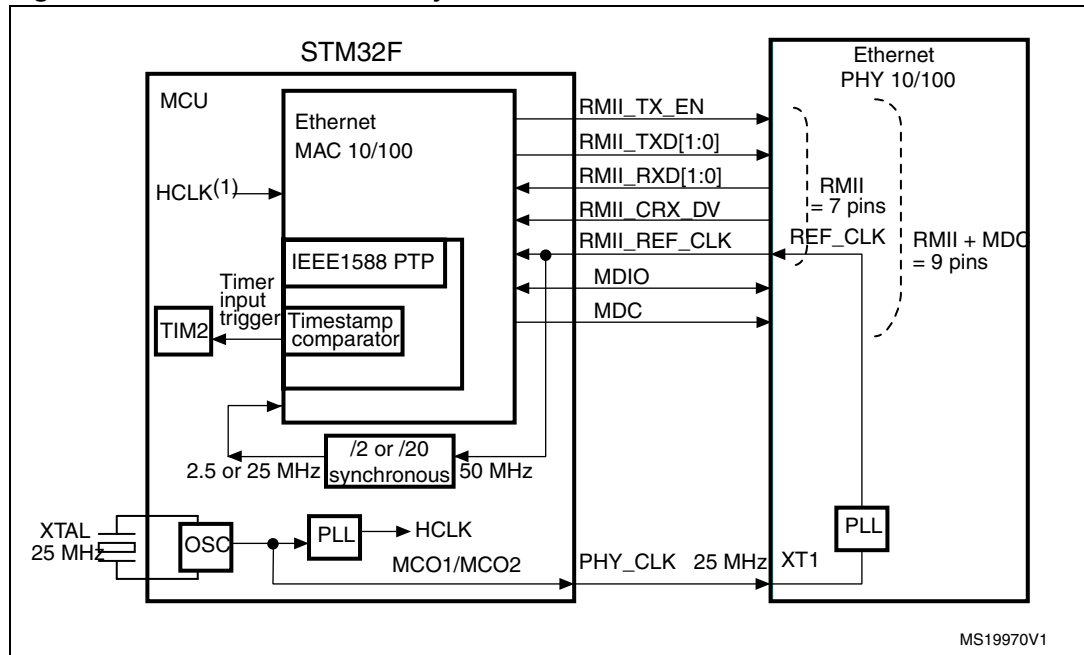
1. f_{HCLK} must be greater than 25 MHz.
2. Pulse per second when using IEEE1588 PTP optional signal.

Figure 96. RMII with a 50 MHz oscillator



1. f_{HCLK} must be greater than 25 MHz.

Figure 97. RMIi with a 25 MHz crystal and PHY with PLL



1. f_{HCLK} must be greater than 25 MHz.
2. The 25 MHz (PHY_CLK) must be derived directly from the HSE oscillator, before the PLL block.

8 Revision history

Table 97. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 15-Sep-2011 | 1 | Initial release. |
| 24-Jan-2012 | 2 | <p>Added WLCSP90 package on cover page.</p> <p>Renamed USART4 and USART5 into UART4 and UART5, respectively.</p> <p>Updated number of USB OTG HS and FS in Table 2: STM32F405xx and STM32F407xx: features and peripheral counts.</p> <p>Updated Figure 3: Compatible board design between STM32F10xx/STM32F2xx/STM32F4xx for LQFP144 package and Figure 4: Compatible board design between STM32F2xx and STM32F4xx for LQFP176 package, and removed note 1 and 2.</p> <p>Updated Section 2.2.9: Flexible static memory controller (FSMC).</p> <p>Modified I/Os used to reprogram the Flash memory for CAN2 and USB OTG FS in Section 2.2.13: Boot modes.</p> <p>Updated note in Section 2.2.14: Power supply schemes.</p> <p>PDR_ON no more available on LQFP100 package. Updated Section 2.2.16: Voltage regulator. Updated condition to obtain a minimum supply voltage of 1.7 V in the whole document.</p> <p>Renamed USART4/5 to UART4/5 and added LIN and IrDA feature for UART4 and UART5 in Table 4: USART feature comparison.</p> <p>Removed support of I2C for OTG PHY in Section 2.2.29: Universal serial bus on-the-go full-speed (OTG_FS).</p> <p>Added Table 5: Legend/abbreviations used in the pinout table.</p> <p>Table 6: STM32F40x pin and ball definitions: replaced V_{SS_3}, V_{SS_4}, and V_{SS_8} by V_{SS}; reformatted Table 6: STM32F40x pin and ball definitions to better highlight I/O structure, and alternate functions versus additional functions; signal corresponding to LQFP100 pin 99 changed from PDR_ON to V_{SS}; EVENTOUT added in the list of alternate functions for all I/Os; ADC3_IN8 added as alternate function for PF10; FSMC_CLE and FSMC_ALE added as alternate functions for PD11 and PD12, respectively; PH10 alternate function</p> <p>TIM15_CH1_ETR renamed TIM5_CH1; updated PA4 and PA5 I/O structure to TTA.</p> <p>Removed OTG_HS_SCL, OTG_HS_SDA, OTG_FS_INTN in Table 6: STM32F40x pin and ball definitions and Table 8: Alternate function mapping.</p> <p>Changed TCM data RAM to CCM data RAM in Figure 16: STM32F40x memory map.</p> <p>Added I_{VDD} and I_{VSS} maximum values in Table 11: Current characteristics.</p> <p>Added Note 1 related to f_{HCLK}, updated Note 2 in Table 13: General operating conditions, and added maximum power dissipation values.</p> <p>Updated Table 14: Limitations depending on the operating power supply range.</p> |

Table 97. Document revision history (continued)

| Date | Revision | Changes |
|-------------|------------------|--|
| 24-Jan-2012 | 2 (continued) | <p>Added V12 in Table 18: Embedded reset and power control block characteristics.</p> <p>Updated Table 19: Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator disabled) and Table 20: Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator enabled) or RAM. Added Figure 23, Figure 24, and Figure 25.</p> <p>Updated Table 21: Typical and maximum current consumption in Sleep mode and removed Note 1.</p> <p>Updated Table 22: Typical and maximum current consumptions in Stop mode and Table 23: Typical and maximum current consumptions in Standby mode, Table 24: Typical and maximum current consumptions in V_{BAT} mode, and Table 25: Switching output I/O current consumption. Section : On-chip peripheral current consumption: modified conditions, and updated Table 26: Peripheral current consumption and Note 2.</p> <p>Changed f_{HSE_ext} to 50 MHz and $t_{r(HSE)}/t_{f(HSE)}$ maximum value in Table 28: High-speed external user clock characteristics.</p> <p>Added $C_{in(LSE)}$ in Table 29: Low-speed external user clock characteristics.</p> <p>Updated maximum PLL input clock frequency, removed related note, and deleted jitter for MCO for RMII Ethernet typical value in Table 34: Main PLL characteristics. Updated maximum PLLI2S input clock frequency and removed related note in Table 35: PLLI2S (audio PLL) characteristics.</p> <p>Updated Section : Flash memory to specify that the devices are shipped to customers with the Flash memory erased. Updated Table 37: Flash memory characteristics, and added t_{ME} in Table 38: Flash memory programming.</p> <p>Updated Table 41: EMS characteristics, and Table 42: EMI characteristics.</p> <p>Updated Table 55: I²S characteristics</p> <p>Updated Figure 44: ULPI timing diagram and Table 62: ULPI timing.</p> <p>Added $t_{COUNTER}$ and t_{MAX_COUNT} in Table 50: Characteristics of TIMx connected to the APB1 domain and Table 51: Characteristics of TIMx connected to the APB2 domain. Updated Table 65: Dynamics characteristics: Ethernet MAC signals for RMII.</p> <p>Removed USB-IF certification in Section : USB OTG FS characteristics.</p> |

Table 97. Document revision history (continued)

| Date | Revision | Changes |
|-------------|------------------|--|
| 24-Jan-2012 | 2 (continued) | <p>Updated Table 59: USB FS clock timing parameters and Table 61: USB HS clock timing parameters</p> <p>Updated Table 67: ADC characteristics.</p> <p>Updated Table 68: ADC accuracy at $f_{ADC} = 30$ MHz.</p> <p>Updated Note 1 in Table 72: DAC characteristics.</p> <p>Section 5.3.25: FSMC characteristics: updated Table 73 to Table 84, changed C_L value to 30 pF, and modified FSMC configuration for asynchronous timings and waveforms. Updated Figure 58: Synchronous multiplexed PSRAM write timings.</p> <p>Updated Table 94: Package thermal characteristics.</p> <p>Appendix A.3: USB OTG full speed (FS) interface solutions: modified Figure 85: USB controller configured as peripheral-only and used in Full speed mode added Note 2, updated Figure 86: USB controller configured as host-only and used in full speed mode and added Note 2, changed Figure 87: USB controller configured in dual mode and used in full speed mode and added Note 3.</p> <p>Appendix A.4: USB OTG high speed (HS) interface solutions: removed figures USB OTG HS device-only connection in FS mode and USB OTG HS host-only connection in FS mode, and updated Figure 88: USB controller configured as peripheral, host, or dual-mode and used in high speed mode and added Note 2.</p> <p>Added Appendix A.6: Ethernet interface solutions.</p> |

Table 97. Document revision history (continued)

| Date | Revision | Changes |
|-------------|----------|---|
| 31-May-2012 | 3 | <p>Updated Figure 5: STM32F40x block diagram and Figure 7: Regulator ON/internal reset OFF</p> <p>Added SDIO, added notes related to FSMC and SPI/I2S in Table 2: STM32F405xx and STM32F407xx: features and peripheral counts.</p> <p>Starting from Silicon revision Z, USB OTG full-speed interface is now available for all STM32F405xx devices.</p> <p>Added full information on WLCSP90 package together with corresponding part numbers.</p> <p>Changed number of AHB buses to 3.</p> <p>Modified available Flash memory sizes in Section 2.2.4: Embedded Flash memory.</p> <p>Modified number of maskable interrupt channels in Section 2.2.10: Nested vectored interrupt controller (NVIC).</p> <p>Updated case of Regulator ON/internal reset ON, Regulator ON/internal reset OFF, and Regulator OFF/internal reset ON in Section 2.2.16: Voltage regulator.</p> <p>Updated standby mode description in Section 2.2.18: Low-power modes.</p> <p>Added Note 1 below Figure 14: STM32F40x UFBGA176 ballout.</p> <p>Added Note 1 below Figure 15: STM32F40x WLCSP90 ballout.</p> <p>Updated Table 6: STM32F40x pin and ball definitions.</p> <p>Added Table 7: FSMC pin definition.</p> <p>Removed OTG_HS_INTN alternate function in Table 6: STM32F40x pin and ball definitions and Table 8: Alternate function mapping.</p> <p>Removed I2S2_WS on PB6/AF5 in Table 8: Alternate function mapping.</p> <p>Replaced JTRST by NJTRST, removed ETH_RMII_TX_CLK, and modified I2S3ext_SD on PC11 in Table 8: Alternate function mapping.</p> <p>Added Table 9: STM32F40x register boundary addresses.</p> <p>Updated Figure 16: STM32F40x memory map.</p> <p>Updated V_{DDA} and V_{REF+} decoupling capacitor in Figure 19: Power supply scheme.</p> <p>Added power dissipation maximum value for WLCSP90 in Table 13: General operating conditions.</p> <p>Updated V_{POR/PDR} in Table 18: Embedded reset and power control block characteristics.</p> <p>Updated notes in Table 19: Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator disabled), Table 20: Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator enabled) or RAM, and Table 21: Typical and maximum current consumption in Sleep mode.</p> <p>Updated maximum current consumption at T_A = 25 °n Table 22: Typical and maximum current consumptions in Stop mode.</p> |

Table 97. Document revision history (continued)

| Date | Revision | Changes |
|-------------|------------------|---|
| 31-May-2012 | 3 (continued) | <p>Removed f_{HSE_ext} typical value in Table 28: High-speed external user clock characteristics. Updated Table 30: HSE 4-26 MHz oscillator characteristics and Table 31: LSE oscillator characteristics ($f_{LSE} = 32.768$ kHz).</p> <p>Added f_{PLL48_OUT} maximum value in Table 34: Main PLL characteristics.</p> <p>Modified equation 1 and 2 in Section 5.3.11: PLL spread spectrum clock generation (SSCG) characteristics.</p> <p>Updated Table 37: Flash memory characteristics, Table 38: Flash memory programming, and Table 39: Flash memory programming with V_{PP}.</p> <p>Updated Section : Output driving current.</p> <p>Table 52: t^2C characteristics: Note 3 updated and applied to $t_{h(SDA)}$ in Fast mode, and removed note 4 related to $t_{h(SDA)}$ minimum value.</p> <p>Updated Table 67: ADC characteristics. Updated note concerning ADC accuracy vs. negative injection current below Table 68: ADC accuracy at $f_{ADC} = 30$ MHz.</p> <p>Added WLCSP90 thermal resistance in Table 94: Package thermal characteristics.</p> <p>Updated Table 88: WLCSP90 - 0.400 mm pitch wafer level chip size package mechanical data.</p> <p>Updated Figure 80: UFBGA176+25 - ultra thin fine pitch ball grid array $10 \times 10 \times 0.6$ mm, package outline and Table 92: UFBGA176+25 - ultra thin fine pitch ball grid array $10 \times 10 \times 0.6$ mm mechanical data.</p> <p>Added Figure 82: LQFP176 recommended footprint.</p> <p>Removed 256 and 768 Kbyte Flash memory density from Table 95: Ordering information scheme.</p> <p>Appendix A.1: Main applications versus package: Removed number of address lines for FSMC/NAND in Table 96: Main applications versus package for STM32F407xx microcontrollers.</p> <p>Appendix A.5: Complete audio player solutions: updated Figure 89: Complete audio player solution 1 and Figure 90: Complete audio player solution 2.</p> |

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